तत् त्वं पूषन् अपावृणु
केन्द्रीय विद्यालय संगठन

भौतिकी

Physics

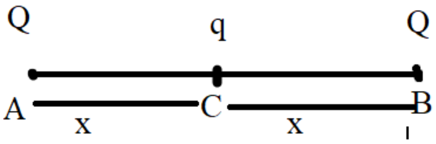
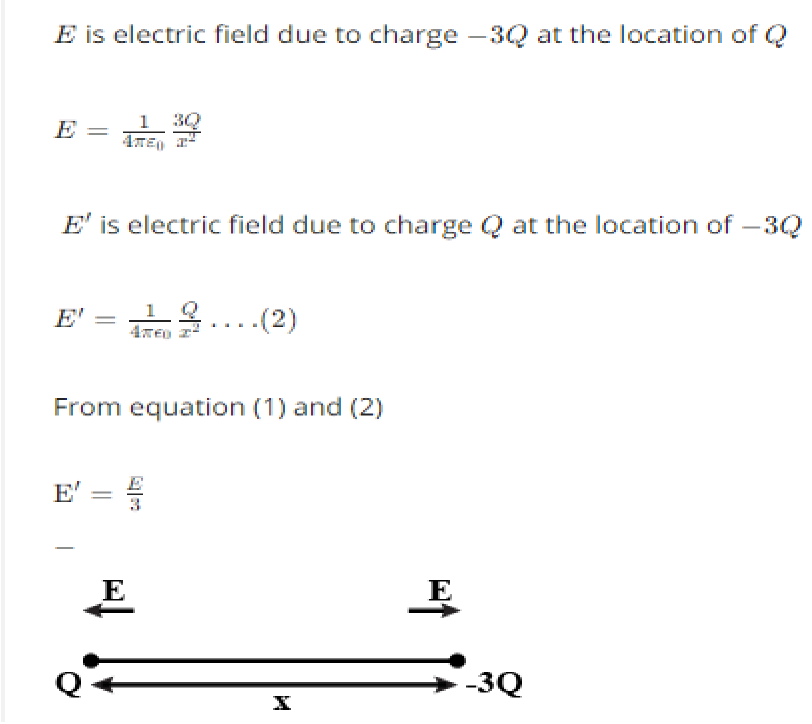
कक्षा/Class: XII
2024-25

विद्यार्थी सहायक सामग्री भाग- II (समाधान)
Student Support Material Part-II (SOLUTIONS)

केन्द्रीय विद्यालय संगठन
Kendriya Vidyalaya Sangathan

विषय सूची
INDEX

UNIT I ELECTROSTATICS
CH-1 ELECTRIC CHARGES AND FIELDS
DETAILED SOLUTIONS

	LEVEL-1 MCQ	
Q.NO	**DETAILED SOLUTIONS**	**VALUE POINTS**
1	$F = \frac{F}{K}$ (C)	**1**
2	 For the system to be in equilibrium FBA + FBC = 0 FBA = – FBC It can be written as $KQ^2/(2x)^2 = -KQq/x^2$ So we get q = -Q/4 The system to be in equilibrium condition is q = -Q/4 (b)	**1**
3	 E is electric field due to charge $-3Q$ at the location of Q $E = \frac{1}{4\pi\varepsilon_0}\frac{3Q}{x^2}$ E' is electric field due to charge Q at the location of $-3Q$ $E' = \frac{1}{4\pi\epsilon_0}\frac{Q}{x^2}\ldots.(2)$ From equation (1) and (2) $E' = \frac{E}{3}$ –	

	(c)	
4	(a)Zero	
5	(d)	
6	(a)	
7	(a)	
8	(b)	
9	(c)	
10	(b)	
11	(c)	
12	(a)	
13	(a) Polar molecules have centres of positive and negative charges separated by some distance, so they have permanent dipole moment.	
14	(b)	
15	$\sigma = \frac{6\times10^{-6}\,\mathrm{C}}{0.015\ \mathrm{m}^2} = 4 \times 10^{-4}\,\mathrm{Cm}^{-2}$ (d)	
16	(b)the quantity of charges enclosed by the surface	
17	(b)	
18	(d)To conduct excess charge due to air friction to ground and prevent sparking	
	LEVEL-2 MCQ	
Q.NO	DETAILED SOLUTIONS	**VALUE POINTS**
1	(d)	
2	(b)	
3	(a)	
4	(c)	
5	(a)	
6	(d)	
7	(a)	
8	(d)	
9	(d)	
10	(C)	
	LEVEL-3 MCQ	
Q.NO	**DETAILED SOLUTIONS**	**VALUE POINTS**
1	Correct option is **(B) 2.0 x 10^{-9} C** $Mg = qE$ $(0.1\times10^{-3})(9.8) = 4.9\times10^{5}q$ $\frac{2\times10^{-4}}{10^{5}} = q$ $\boxed{q = 2\times10^{-9}C}$	**(2)**

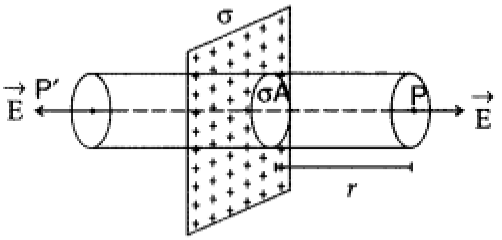
2	**B**	
3	**B**	
4	$\tau = pE.\sin\theta$ $\therefore p = \frac{\tau}{E.\sin\theta}$ $q \times 2l = \frac{4}{2 \times 10^5 \times 0.5}$ ....(∵ $p = q \times 2l$) $\therefore q = \frac{4}{2 \times 10^5 \times 0.5 \times 0.02}$ ....(∵ $2l = 0.02m$ given) $= 2 \times 10^{-3}$ C $q = 2$ mC	
5	$F_1 = \frac{KQ^2}{r^2} = 16\,\text{N}$ $F_2 = \frac{K\left(\frac{Q}{2}\right)\left(\frac{3}{4}\right)}{r^2} = \frac{3}{8} \times 16 = 6\,\text{N}$ Final charges on spheres are $\frac{Q}{2}$ and $\frac{3Q}{4}$. **B**	
6	**A**	
7	**A**	
8	**D**	
9	$V_A = V_B$ $\frac{KQ_A}{R_A} = \frac{KQ_B}{R_B}$ $\frac{Q_A}{Q_B} = \frac{R_A}{R_B} = \frac{1}{2}$ $E_A = \frac{KQ_A}{R_A^{\ 2}}; E_B = \frac{KQ_B}{R_B^{\ 2}}$ $\frac{E_A}{E_B} = \frac{Q_A}{Q_B} \times \frac{R_B^{\ 2}}{R_A^{\ 2}} = \frac{R_B}{R_A} = \frac{2}{1}$ **(b)**	

10	Correct option is **(B) 4 : 1** Let R = radius of combined drop r = radius of smaller drop Volume will remain same $\frac{4}{3}\pi R^3 = 64 \times \frac{4}{3}\pi r^3$ $R = 4r$ $Q = 64q$; q : charge of smaller drop Q : Charge of combined drop $\frac{\sigma_{bigger}}{\sigma_{smaller}} = \frac{\frac{Q}{4\pi R^2}}{\frac{q}{4\pi r^2}} = \frac{Q}{q}.\frac{r^2}{R^2}$ $= 64\frac{r^2}{16r^2} = 4$ $\frac{\sigma_{bigger}}{\sigma_{smaller}} = \frac{4}{1}$	

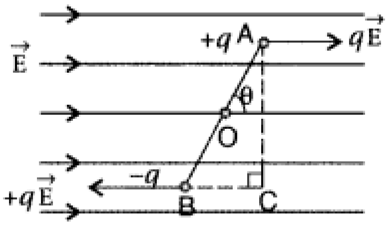
LEVEL-1 (2 M QUESTIONS)

Q.NO	DETAILED SOLUTIONS	VALUE POINTS/STEP MARKING
1	The electric lines of force give the direction of the electric field. In case, two lines of force intersect, there will be two directions of the electric field at the point of intersection, which is not possible.	**2**
2	Electric flux over an area in an electric field is the total number of lines of force passing through the area. It is represented by ϕ . It is a scalar quantity. Its S.I unit is Nm2 C-1 or Vm. Electric flux ϕ by q enclosed Hence the electric flux through the surface of sphere remains same.	**2**

LEVEL-1 (3 M QUESTIONS)

Q.NO	DETAILED SOLUTIONS	VALUE POINTS/STEP MARKING
1	Gauss’ Law states that “the total flux through a closed surface is 1ε0 times the net charge enclosed by $\phi_E = \oint \vec{E}.d\vec{S} = \frac{q}{\varepsilon_0}$” Let σ be the surface charge density (charge per unit area) of the given sheet and let P be a point at distance r from the sheet where we have to find E→  Choosing point P’, symmetrical with P on the other side of the sheet, let us draw a Gaussian cylindrical surface cutting through the sheet as shown in the diagram. As at the cylindrical part of the Gaussian surface, E→ and dS→ are at a right angle, the only surfaces having E→ and dS→ parallel are the plane ends $\therefore \quad \phi_E = \oint \vec{E}.d\vec{S} + \oint \vec{E}.d\vec{S}$ $= \oint E\,dS + \oint E\,dS = EA + EA = 2EA$ …[As E is outgoing from both plane ends, the flux is positive. This is the total flux through the Gaussian surface. Using *Gauss’ law*, $\phi_E = \frac{q}{E_0}$ $\therefore \quad 2\,EA = \frac{q}{\varepsilon_0} = \frac{\sigma A}{\varepsilon_0}$ **…[As $q = \sigma A$** $\therefore \quad E = \frac{\sigma}{2\varepsilon_0}$. This value is independent of r. Hence, the electric field intensity is same for all points near the charged sheet. This is called uniform electric field intensity.	
2	Torque on electric dipole. Consider an electric dipole consisting of two equal and opposite point charges separated by a small distance 2a having dipole moment	

$|\vec{p}| = q\,(2\vec{a})$



Dipole in a uniform electric field

Let the dipole held in a uniform external electric field $\vec{E}$ at an angle θ

$\therefore$ Force on charge $(+q) = q\vec{E}$ along the direction of $\vec{E}$

Force on charge $(-q) = -q\vec{E}$ along the opposite direction of $\vec{E}$

$\therefore$ Net translatory force on the dipole

$$= q\vec{E} - q\vec{E} = 0$$

So net force on the dipole is zero

Since $\vec{E}$ is uniform, hence the dipole does not undergo any translatory motion.

These forces being equal, unlike and parallel, from a couple, which rotates the dipole in clock-wise direction

$\therefore$ Magnitude of torque = Force × arm of couple

$$\tau = F.\,AC = qE.AB\sin\theta = (qE)\,2a\sin\theta$$

or $\tau = q(2a)\,E\sin\theta$

or $\tau = pE\,\text{Sin}\,\theta$ $\quad [\because p = q(2\vec{a})]$

$\therefore \quad \vec{\tau} = \vec{p} \times \vec{E}$

[The direction of $\vec{\tau}$ is given by right hand screw rule and is normal to $\vec{p}$] and $\vec{E}$

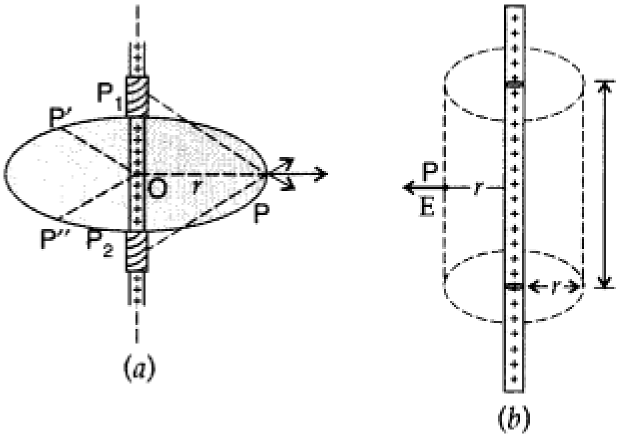
Special cases

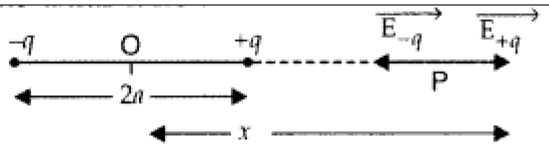
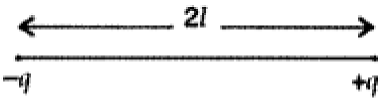
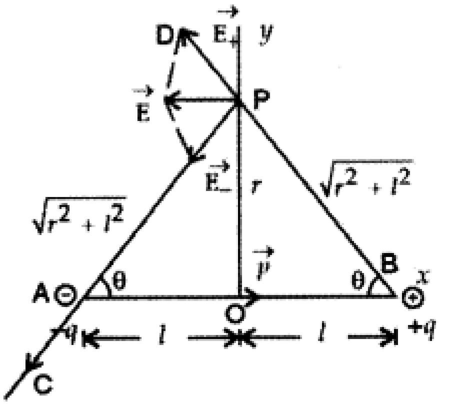
(i) when θ = 0 then τ = PE sin θ = 0

$\therefore$ Torque is zero and the dipole is in stable equilibrium

(ii) When θ = 90 then τ = PE sin 90 = PE

$\therefore$ The Torque is maximum

3	Since the field is everywhere radial, flux through the two ends of the cylindrical Gaussian surface is zero. At the cylindrical part of the surface, E is normal to the surface at every point, and its magnitude is constant, since it depends only on r. The surface area of the curved part is 2πrl, where l is the length of the cylinder. Flux through the Gaussian surface = Flux through the curved cylindrical part of the surface is zero. At the cylindrical part of the surface, E is normal to the surface at every point, and its magnitude is constant, since at every point, and its magnitude is constant, since it depends only on r. The surface area of the cylinder. Flux through the Gaussian surface = Flux through the curved cylindrical part of the surface = E × 2πrl  (a) (b) (a) Electric field due to an infinitely long thin straight wire is radial. (b) The Gaussian surface for a long thin wire of uniform linear charge density The surface includes charge equal to λl. Gauss's law then gives $E \times 2\pi r l = \lambda l/\varepsilon_0$ *i.e.* $\boxed{E = \frac{\lambda}{2\pi\varepsilon_0 r}}$	
	LEVEL-3 (5 M QUESTIONS)	
Q.NO	**DETAILED SOLUTIONS**	**VALUE POINTS/STEP MARKING**

1	 Electric field intensity at point P due to charge $-q$, $\vec{E}_{-q} = \frac{1}{4\pi\varepsilon_0} \cdot \frac{q}{(x+a)^2}(\hat{x})$ Due to charge $+q$, $\vec{E}_{+q} = \frac{1}{4\pi\varepsilon_0} \cdot \frac{q}{(x-a)^2}(\hat{x})$ Net Electric field at point P, $\vec{E} = \vec{E}_{-q} + \vec{E}_{+q}$ $= \frac{q}{4\pi\varepsilon_0} \times \left[\frac{1}{(x-a)^2} - \frac{1}{(x+a)^2}\right](\hat{x})$ $= \frac{1}{4\pi\varepsilon_0}\left[\frac{4aqx}{(x^2-a^2)^2}\right](\hat{x}) = \frac{1}{4\pi\varepsilon_0}\frac{(q \times 2a)2x}{(x^2-a^2)^2}(\hat{x})$ $\vec{E} = \frac{1}{4\pi\varepsilon_0} \cdot \frac{2px}{(x^2-a^2)^2}\hat{x}$ $\quad\because p = (q \times 2a)$ For $x >> a$ $(x^2 - a^2)^2 \simeq x^4$ $\quad \vec{E} = \frac{1}{4\pi\varepsilon_0} \cdot \frac{2p}{x^3}\hat{x}$	
2	Electric dipole moment: It is the product of the magnitude of either charge and distance between them. $\vec{q} = q \times 2l$  It is a vector quantity whose direction is from negative to positive charge.  ***Expression :***	

	Electric field intensity at P due to +q charge is $\vec{E}_+ = \frac{1}{4\pi\varepsilon_0}\frac{q}{BP^2}$ along PD $= \frac{1}{4\pi\varepsilon_0}\frac{q}{(r^2 + l^2)}$ along PD ...(i) Electric field intensity at P due to -q charge is,	

$$\vec{E}_- = \frac{1}{4\pi\varepsilon_0}\frac{q}{AP^2} \text{ along PC}$$

$$= \frac{1}{4\pi\varepsilon_0}\frac{q}{(r^2 + l^2)} \qquad \text{along PC} \ldots(ii)$$

From (*i*) and (*ii*), $|\vec{E}_+| = |\vec{E}_-| = \frac{1}{4\pi\varepsilon_0}\frac{q}{(r^2 + l^2)}$ ...(*iii*)

Net electric field intensity due to the electric dipole at point P

$$\therefore \quad E = \sqrt{E_+^2 + E_-^2 + 2E_+E_-\cos 2\theta}$$

$$\Rightarrow \quad E = \sqrt{E_+^2 + E_-^2 + 2E_+^2\cos 2\theta} \qquad (\because E_- = E_+)$$

$$\Rightarrow \quad E = \sqrt{2E_+^2 + 2E_+^2\cos 2\theta}$$

$$\Rightarrow \quad E = \sqrt{2E_+^2(1 + \cos 2\theta)}$$

$$\Rightarrow \quad E = \sqrt{2E_+^2\, 2\cos^2\theta} \qquad (\because 1 + \cos 2\theta = 2\cos^2\theta)$$

$$\therefore \quad E = 2E_+ \cos\theta = 2 \times \frac{1}{4\pi\varepsilon_0}\frac{q}{(r^2 + l^2)} \cos\theta$$

[Using equation (*iii*)]

Now from ΔOAP, $\cos\theta = \frac{l}{\sqrt{r^2 + l^2}}$

$$E = 2 \times \frac{1}{4\pi\varepsilon_0}\frac{q}{(r^2 + l^2)} \times \frac{l}{(r^2 + l^2)^{1/2}}$$

$$\Rightarrow \quad E = \frac{q \times 2l}{4\pi\varepsilon_0(r^2 + l^2)^{3/2}}$$

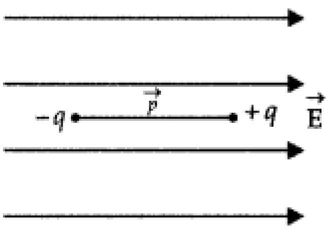
Since $q \times 2l = p$ ...(p is dipole moment)

$$E = \frac{p}{4\pi\varepsilon_0(r^2 + l^2)^{3/2}} \quad \text{along (–)}x\text{-axis}$$

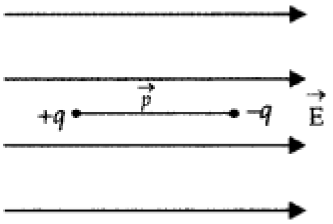
If $l \ll r$ *i.e.* dipole is short, then l^2 can be neglected as compared to r^2

Hence $\boxed{E = \frac{p}{4\pi\varepsilon_0 r^3}}$ along (–)x-axis

. (ii) (a) For stable equilibrium, the angle between p and E is 0°,



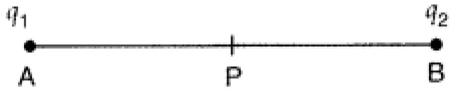
(b) For unstable equilibrium, the angle between p and E is 180°,



(b) For unstable equilibrium, the angle between p and E is 180°,

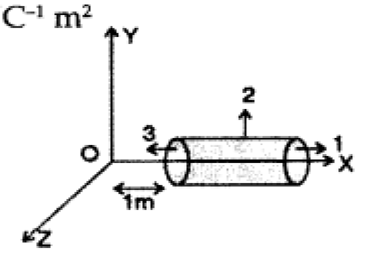
LEVEL-1 (NUMERICALS)

Q.NO	DETAILED SOLUTIONS	VALUE POINTS/STEP MARKING
1	Answer: Given : E→=5×103i^N/C A = 10 × 10 × 10^{-4}m^2, Flux (ϕ) = EA cos θ (i) For first case, θ = 0, cos 0 = 1 ∴ Flux = (5 × 10^3) × (10 × 10 × 10^{-4}) (ii) Angle of square plane with x-axis = 30° Hence the 0 will be 90° – 30° = 60° EA cos θ = (5 × 10^3) × (10 × 10 × 10^{-4}) × cos 60 = 50 × 12 = 25 Nm^{2}C^{-1} Hint: (i) 10 Nm^{2}C^{-1} (ii) 5 Nm^{2}C^{-1}	
2	Flux through $S_1(\phi_1) = \frac{Q}{\epsilon_0}$ ...(i) Flux through $S_2(\phi_2) = \frac{Q+2Q}{\epsilon_0} = \frac{3Q}{\epsilon_0}$ ...(ii) ∴ Ratio of flux $= \frac{\phi_1}{\phi_2} = \frac{Q/\epsilon_0}{3Q/\epsilon_0} = \frac{1}{3}$	

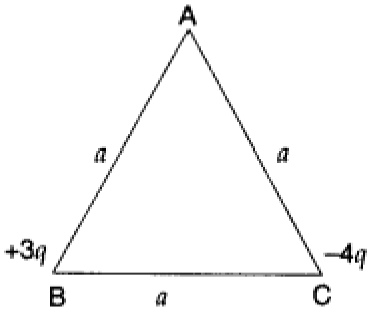
3	(i) Given : $q_1 = 10 \times 10^{-8}$C, $q_2 = -2 \times 10^{-8}$C AB = 60 cm = 0.60 = 0.6m Let AP = x Let AP = x then PB = $0.6 - x$  Potential P due to charge $q_1 = \frac{Kq_1}{AP}$ Potential P due to charge $q_2 = \frac{Kq_2}{BP}$ $\because$ Potential at P = 0 $\Rightarrow \frac{Kq_1}{AP} + \frac{Kq_2}{BP} = 0 \quad \Rightarrow \frac{q_1}{AP} = \frac{-q_2}{PB}$ $\therefore \frac{10 \times 10^{-8}}{x} = \frac{-(-2 \times 10^{-8})}{0.6 - x}$ $\Rightarrow 2x + 10x = 6 \quad \Rightarrow 12x = 6$ $\therefore x = \frac{1}{2} = 0.5\text{m}$ Distance from first charge = 0.5 m = 50 cm. (ii) Electrostatic energy of the system is $E_n = \frac{Kq_1q_2}{r} = \frac{-9 \times 10^9 \times 10^{-7} \times 2 \times 10^{-8}}{60 \times 10^{-2}}$ $= \frac{-18 \times 10^{-6}}{60 \times 10^{-2}}$ $= \frac{-3}{10} \times 10^{-4} = -3 \times 10^{-5}$ Joule $\therefore$ **U or $E_n = -3 \times 10^{-5}$ Joule**	

LEVEL-2 (NUMERICALS)

Q.NO	DETAILED SOLUTIONS	VALUE POINTS/STEP MARKING
1	(a) Electric flux through a surface represents the total number of electric lines of force crossing the surface. ∴ S.I. unit is Nm^2 C^{-1}. (b) (i) Flux through R.H.S. of the cube is	

	$\phi_1 = Ex_1.A$ $= (\alpha x).(l)^2$ $= (500 \times 0.2)\ (0.1)^2$ $= 1Nm^2\ C^{-1}$ $\left[\begin{array}{l} \because\ \theta = 0° \\ \alpha = 500\ N/C^{-m} \\ x = 0.2\ m \\ l = 0.1\ m \end{array}\right.$ (*ii*) Flux through L.H.S. of the cube is $\phi_2 = Ex_2 . A$ $= -(\alpha x) . l^2$ $= -(500 \times 0.1)\ (0.1)^2$ $= -0.5\ Nm^2/C$ $\left[\begin{array}{l} \because\ \theta = 180° \\ x = 0.1\ m \\ l = 0.1\ m \\ \alpha = 500N/C^{-m} \end{array}\right.$ Net flux $\phi = \phi_1 + \phi_2$ $= 1 - 0.5 = \mathbf{0.5\ Nm^2/C}$ (*iii*) As $\phi = \frac{q}{\varepsilon_0}$ $\quad \therefore\ q = \varepsilon_0\ \phi$ $\Rightarrow q = 8.854 \times 10^{-12} \times 0.5 = \mathbf{4.4 \times 10^{-12}\ C}$	
	LEVEL-3 (NUMERICALS)	
Q.NO	**DETAILED SOLUTIONS**	**VALUE POINTS/STEP MARKING**
1	(*i*) The magnitude of the electric field at the left face is $E = 50\ NC^{-1}$ Therefore flux through this face $\phi_L = EA \cos\theta$ $= 50 \times 25 \times 10^{-4} \times \cos 180°$ $= -125 \times 10^{-3}\ NC^{-1}\ m^2$  The magnitude of the electric field at the right face is $E = 100\ NC^{-1}$ Therefore flux through this face $\phi_R = 100 \times 25 \times 10^{-4} \times \cos 0°$ $= 250 \times 10^{-3}\ NC^{-1}\ m^2$ Therefore net flux through cylinder is $\boxed{\phi_R + \phi_L = 125 \times 10^{-3}\ NC^{-1}\ m^2}$ (*ii*) Charge enclosed by the cylinder $\phi = \frac{Q}{\varepsilon_0}$ $Q = \phi_{net} \times \varepsilon_0$ $= 125 \times 10^{-3} \times 8.856 \times 10^{-12} C$ $= 1107 \times 10^{-15} C$ $\boxed{Q = 1.107\ pC}$	
2	. Two point charges + 3q and – 4q are placed at the vertices 'B' and 'C' of an equilateral triangle ABC of side 'a' as given	

in the figure. Obtain the expression for



(i) the magnitude and
(ii) the direction of the resultant electric field at the vertex A due to these two charges. (Comptt. All India 2014)
Answer:

$$= \sqrt{9E^2 + 16E^2 - 12E^2}$$
$$= \sqrt{13E^2} = E\sqrt{13} = \frac{1}{4\pi\epsilon_0}\frac{q\sqrt{13}}{a^2}$$

(ii) Direction,

$$\tan\alpha = \frac{|E_{AB}|\sin 120°}{|E_{AC}| + |E_{AB}|\cos 120°} = \frac{3E \times \frac{\sqrt{3}}{2}}{4E + 3E \times -\left(\frac{1}{2}\right)}$$

$$\tan\alpha = \frac{3E\sqrt{3} \times 2}{2 \times 5E} = \frac{3\sqrt{3}}{5} \quad \therefore \alpha = \tan^{-1}\left(\frac{3\sqrt{3}}{5}\right)$$

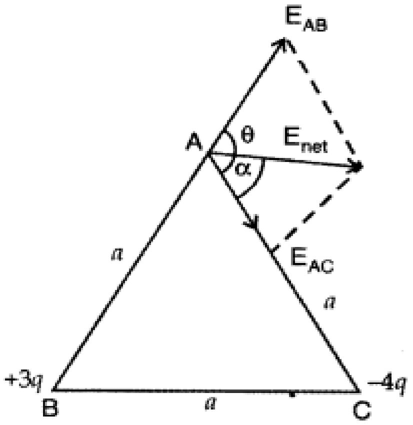
(i) Magnitude,

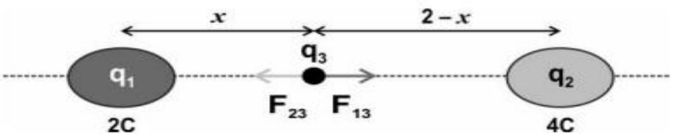
$$|\overrightarrow{E}_{AB}| = \frac{1}{4\pi\epsilon_0}\frac{3q}{a^2} = 3E, \qquad \textbf{where } \left[E = \frac{1}{4\pi\epsilon_0}\frac{q}{a^2}\right]$$

$$|\overrightarrow{E}_{AC}| = \frac{1}{4\pi\epsilon_0}\frac{4q}{a^2} = 4E$$

$$E_{net} = \sqrt{(3E)^2 + (4E)^2 + 2(3E) \times (4E) \times \left(-\frac{1}{2}\right)}$$

$$\left\{\begin{matrix} \because \theta = 120° \\ \cos\theta = -\frac{1}{2} \end{matrix}\right\}$$



<table>
<tr><th colspan="3">CASE BASED</th></tr>
<tr><td>Q.NO</td><td>CASE STUDY ANSWERS
1. (i). (b)
(ii). (c) the dominant electric field is inversely proportional to r3, for large r (distance from origin).
(iii). (a) excess of electrons
(iv). (b) along a line of force, if its initial velocity is zero
(v). (c) Only</td><td>VALUE POINTS/STEP MARKING
4</td></tr>
<tr><td></td><td></td><td></td></tr>
<tr><th colspan="3">COMPETENCY BASED</th></tr>
<tr><td>Q.NO</td><td>DETAILED SOLUTIONS</td><td>VALUE POINTS/STEP MARKING</td></tr>
<tr><td>1</td><td>B. The electric field distribution is two-dimensional.</td><td>1</td></tr>
<tr><td>2</td><td>D. both statements Q and S</td><td>1</td></tr>
<tr><th colspan="3">CCT</th></tr>
<tr><td>Q.NO</td><td>DETAILED SOLUTIONS</td><td>VALUE POINTS/STEP MARKING</td></tr>
<tr><td></td><td>(a) For a resultant force at the location of q3 to be zero, the net electrostatic force on q3 due to q1 and q2 has to be zero. Since q3 is positive, it will be under the effect of repulsive force by both q1 and q2 as represented by F13 and F23.

That is,
$F_{13} = F_{23}$
$\frac{kq_1q_3}{x^2} = \frac{kq_2q_3}{(2-x)^2}$
Substitute for values of $q_1 = 2C$, $q_2 = 4C$ and solve to get,
$(2-x)^2 = 2x^2$
Solve for x,
$x = \frac{2}{\sqrt{2}+1} = 0.83m$
So q3 placed at 0.83 m away from q1 along the straight line joining q1 and q2 experiences a zero resultant force.
- 1 mark for drawing the correct diagram and explanation of forces acting on charge q3
- 1 mark for writing a correct equation for forces on q3 using Coulombs law</td><td>4</td></tr>
</table>

	- 1 mark for substituting and solving for the value of x (b) Yes, the negative charge at the location of q3 will experience zero resultant force.	
SELF ASSESSMENT		
Q.NO	**DETAILED SOLUTIONS**	**VALUE POINTS/STEP MARKING**
	CASESTUDY- ANSWERS 2.(i). (c) both electric and magnetic effects (ii). (b) conductor, insulator (iii). (c) increase or decrease (iv). (a) decreases directly as the distance from the centre (v). (d) Coulomb's law	

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UNIT I ELECTROSTATICS
CH-2 ELECTRIC POTENTIAL AND CAPACITANCE
DETAILED SOLUTIONS

LEVEL-1 MCQ

Q.NO	DETAILED SOLUTIONS	VALUE POINTS
1	(C) This relation is given by, Q=CV …………………………………… (1) Here, Q is the charge of the capacitor, C is its capacitance and V is the voltage. The fact we have to always keep in mind is that the capacitance of a particular capacitor has a constant value, that is, it remains the same on doubling the voltage. Now from (1), Q∝V Therefore, we could say the charge in a capacitor is doubled on doubling the voltage.	1
2.	(b) V = Ed , V increases as distance increases	1
3.	(a) CO2 is a linear molecule with two relatively polar bonds (between carbon and oxygen). However, the two bonds are pointing in opposite directions, cancelling out the net distribution of charge. It is a non-polar molecule where the center of positive and negative charges coincides, despite having polar bonds.	1
4.	(a) The angle between electric field and equipotential surface is always 90 degrees. This is because when the potential becomes constant, the negative potential gradient also becomes zero, which is necessary for the need of the electric field to be always normal with the surface. An electric field is always perpendicular to the equipotential surface at any point	1
5.	(d) We know the work done is given by W=qΔ V As on equipotential surface the potential does not change i.e. VB=VA=constant So, the work done to move a charge along an equipotential from A to B will be zero as Δ V=0.	1

6.	(d) The capacitance of a spherical capacitor depends on both the **radius of the capacitor** and the **dielectric medium**. Specifically: **Radius of the spheres**: Capacitance is directly proportional to the product of the radii of the spheres. An increase in either radius will increase the capacitance **Dielectric medium**: The type of dielectric material between the spheres can also affect the capacitance, but it’s not explicitly mentioned in the options you provided. So, the correct answer is **(d) both (a) and (b)**.	1
7.	(a) c>b>a>d	1
8.	(c) The final speed of an electron accelerated from rest through a potential difference (V) is proportional to **(\sqrt{V})**. So the correct answer is © √**V**. Remember, the kinetic energy gained by the electron is equal to the work done on it by the electric field, which is proportional to the potential difference. The kinetic energy is then converted into the electron’s final speed.	1
9.	(c) When identical capacitors are connected in parallel, their total stored energy is the sum of the individual energies. Let’s calculate it: **Capacitor A**: It stores 4 J of energy. **Capacitor B**: Initially uncharged, so it has no energy. When connected in parallel: The total stored energy is the sum of the energies of both capacitors: [U_{\text{total}} = U_A + U_B = 4	1
10	(c) when both (Area) and (distance) are doubled simultaneously, the effect cancels out. The capacitance remains the same	1
11	(a) Electrostatic field is a conservative field, hence we can use $Welec=-\Delta U=Ui-Uf$ Also the dipole is rotated slowly, $Wext=-Welec$ $Wext=Uf-Ui$ $Wext=-pEcos\theta f-(-pEcos\theta i)$ $(\because \theta i=0^\circ \ \& \ \theta f=90^\circ)$ $\Rightarrow Wext=-pEcos90^\circ+pEcos0^\circ$ $\therefore Wext=pE$	1

12	(a) when a charged metallic ball is placed inside an insulated box, the charges on the surface of the metallic ball redistribute themselves to cancel out the electric field inside the conductor. As a result, the net electric field inside the conductor (and hence inside the insulated box) becomes zero[1]. Since the metallic box is placed outside the insulated box, it does not affect the net charge enclosed. Therefore, the correct answer is **Zero**.	1
13	(c) a larger plate area allows for more charge storage, leading to increased capacitance!	1
14	(b) When an electron moves in the direction of a uniform electric field, it experiences a force that does work on the electron. Because electrons have a negative charge, they will naturally move from a point of high potential to low potential in an electric field. This movement indicates that the electron is doing work against the electric field. Therefore, the work done by the electric field on the electron is negative since it opposes the electron's motion. As it moves to a region of lower electric potential, the potential energy of the system increases, due to the negative charge of the electron. In summary, if an electron moves from point i to point f in the direction of a uniform electric field, the correct statement is: the work done by the field is negative and the potential energy of the electron-field system increases.	1
15	(c) When the distance between the plates of a parallel plate capacitor is halved, the capacitance increases because the capacitance is inversely proportional to the separation distance. Additionally, if the dielectric constant (K) increases (due to a different material inserted between the plates), the capacitance further increases. The combined effect of halving the distance and increasing the dielectric constant results in a sixfold increase in capacitance.	1
16	(c) The energy stored in a capacitor with a dielectric slab does indeed increase by a factor of K due to the presence of the dielectric material. However, this change in energy is not directly related to the surface charge density.	1
17	(d) The equipotential surfaces are concentric spheres centered around the charge. However, inside a spherical capacitor (which has two concentric conducting shells), the equipotential surfaces are not spherical; they are cylindrical between the plates and spherical outside the plates.	1

18	(b) The equatorial plane of an electric dipole (midway between the positive and negative charges) is an equipotential surface. The potential at any point on this plane is indeed zero because the contributions from the positive and negative charges cancel out.	1
19	(c) Electric potential ((V)) represents the potential energy per unit charge at a point in an electric field. Electric potential energy ((U)) is the work done to move a charge from one point to another within the field. For a system of a positive test charge and a point charge, the potential energy is given by: [U = qV]	1
20	(c) Equipotential surfaces are always perpendicular to the electric field lines. If two equipotential surfaces intersected, it would imply that the electric field lines intersect, which is not possible. Therefore, equipotential surfaces do not intersect;	1

LEVEL-2 MCQ

Q.NO	DETAILED SOLUTIONS	VALUE POINTS
1.	(C) The electric potential at point P due to an electric dipole on its axis is proportional to **1/x**. Specifically, the potential at a point on the axis of the dipole is given by: [V = \frac{{kp}}{{x}}] where: (V) is the electric potential. (k) is a constant (which depends on the charge and separation of the dipole). (p) is the dipole moment. (x) is the distance from the midpoint of the dipole to point P.	1
2.	(d) The electric potential at a point on the equatorial line of an electric dipole (at the same distance (r) from its center) is **(d) Zero**. Explanation: On the equatorial line, the contributions from the positive and negative charges of the dipole cancel out, resulting in a net potential of zero.	1

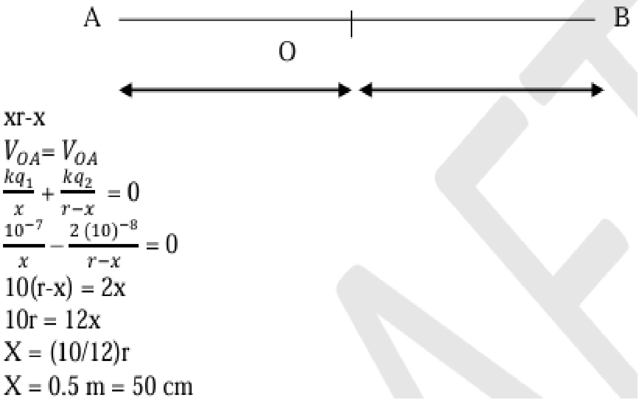
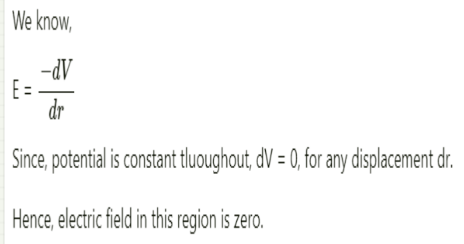
3.	(d) We know that work done in moving a charge is given by: $U_1 = \frac{Kq_1q_2}{r_1}$ Putting all the values; $U_1 = \frac{K*3*5*10^{-18}*100}{10}$ ($1nC = 10^{-9}C$) By solving, we get; $U_1 = \frac{3}{2}*K*10^{-18}*100$ (equation1) **To calculate the work done after moving charge:** $U_2 = \frac{Kq_1q_2}{r_2}$ Putting all the values; $U_2 = \frac{K*3*5*10^{-18}*100}{15}$ $U_2 = k*10^{-18}*100$ (equation2) **Work done by the field:** $W = U_2 - U_1$ Putting the values from equation1 and equation2, we get; $W = k*10^{-18}*100 - \frac{3*k*10^{-18}*100}{2}$ By solving; $W = 4.5*10^{-7}$ Hence, the **work done by the field is** $4.5*10^{-7}J$	1
4.	(a) he energy stored in a capacitor can be expressed in terms of the work done by the battery. Let’s calculate the change in energy for the given scenario: **Initial energy of the capacitor** (when capacitance is 2 μF): [U_1 = 1/2} C_1V^2] where (C_1 = 2 and (V = 200). **Final energy of the capacitor** (when capacitance is (X) μF): [U_2 = 1/2 C_2 V^2] where (C_2 = X , }). The change in energy: [\Delta U = U_2 - U_1 = -0.02 J] Solving for above equ. We get (C_2):1 **μF**.	1
5.	(c) Connect two of the 4 μF capacitors in series. The equivalent capacitance for capacitors in series is given by: = 2 μF] Now, connect the third 4 μF capacitor in parallel to the combination obtained in step 1. The equivalent capacitance for capacitors in parallel is simply the sum of their individual capacitances: [$C_{eq, parallel}$= $C_{eq, series}$ + C_3 = 2 + 4 = 6 μF]	1

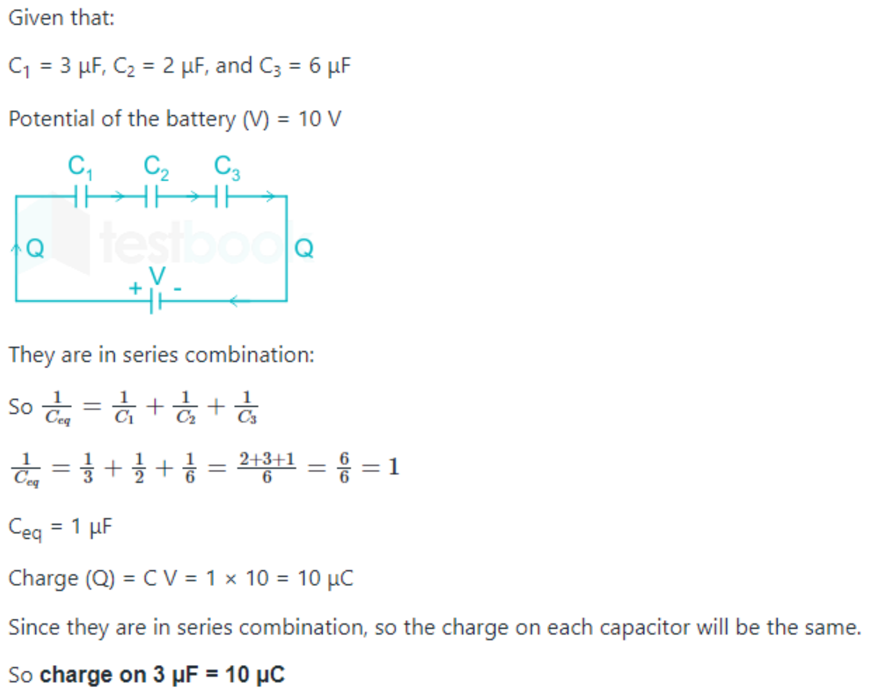
6.	(b) $\frac{1}{C_{series}} = \frac{1}{C_1} + \frac{1}{C_2} + \frac{1}{C_3}$ $\frac{1}{C_{series}} = \frac{1}{2} + \frac{1}{3} + \frac{1}{6}$ $\frac{3+2+1}{6} = \frac{6}{6}$ $C_{series} \quad = 1\mu F$	1
7.	(c) When a charge moves in a closed loop (a closed path), the net work done by the electric field is zero. This is because the electric field is conservative, and any work done in one direction is cancelled out by an equal and opposite work done in the opposite direction.	1
8.	(d) In a uniform electric field along the z-direction, the electric potential (voltage) remains constant on the x-y plane (i.e., when z is fixed). This is because the electric field lines are parallel to the z-axis, and any movement in the x-y plane does not change the potential. However, the potential can vary along the z-direction.	1
9.	*(a)* *In a uniform electric field, →E, dipole experiences a torque →τ given by →τ=→p×→E but experiences no force. The potential energy of the dipole in a uniform electric field →E is U=−→p.→E*	1
10.	**(b)** The correct choice related to the electric field and its direction for concentric equipotential surfaces is **(b) E ∝ 1/ r² and radially outward**. Explanation: Concentric equipotential surfaces have the same electric potential (constant potential). The electric field E is always perpendicular to the equipotential surfaces. The electric field points from regions of higher potential to regions of lower potential. For concentric circles, the electric field lines are radial (directed outward from the center).	1

	The magnitude of the electric field is inversely proportional to the distance from the center Therefore, the correct answer is **E ∝ 1/ r² and radially outward**.	

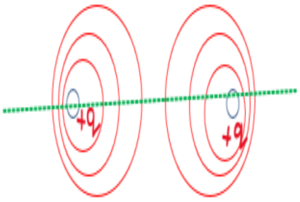
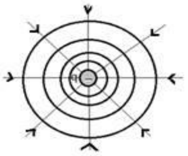
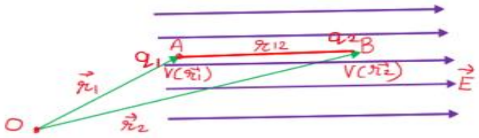
LEVEL-3 MCQ

Q.NO	DETAILED SOLUTIONS	VALUE POINTS
1.	(a)E=B/r^2 .It implies V=B/r.Potential energy of two charges in external field is given by U= q_1V (**r₁**) +q_1V (**r₁**) + $\frac{1}{4\pi\epsilon_0}\frac{q_1q_2}{r_{12}}$ .i.e U=97.9J.	1
2.	(i) Given $C_{AB} = 4\mu F$ Capacitance 20μF and C (μF) are in series $\therefore \quad C_{AB} = \frac{C\times 20}{C+20}$ $\Rightarrow \quad 4\mu F = \frac{20C}{C+20}$ or $4C + 80 = 20C$ $\Rightarrow \quad 16C = 80$ or $C = 5\mu F$ (ii) Charge on each capacitor, $Q = C_{AB}V$ $= (4\mu F)\times(12\ V) = 48\ \mu C$ (b)	1
3.	(a) $2\mu F$ and $2\mu F$ capacitors are in series. Their equivalent capacitance $=\frac{2\times 2}{2+2}=1\mu F$ The $1\mu F$ and $1\mu F$ capacitors are in parallel. Their equivalent capacitance = 1 + 1 = $2\mu F$ This $2\mu F$ capacitor is in series with the $2\mu F$ capacitor connected between the points B and C. Their equivalent capacitance $=\frac{2\times 2}{2+2}=1\mu F$ Finally, we have $1\mu F$ capacitance in parallel with $1\mu F$ capacitance. Their equivalent capacitance, C = 1 + 1 = 2 μF = 2 × 10^{-6}F V = 6 V ∴ Energy, $U=\frac{1}{2}CV^2=\frac{1}{2}\times 2\times 10^{-6}\times(6)^2$ = 3.6 × 10^{-5} J	1

4.	 xr-x $V_{OA}= V_{OA}$ $\frac{kq_1}{x}+\frac{kq_2}{r-x}=0$ $\frac{10^{-7}}{x}-\frac{2\,(10)^{-8}}{r-x}=0$ 10(r-x) = 2x 10r = 12x X = (10/12)r (c) X = 0.5 m = 50 cm	1
5.	(d)Work done is path independent. Ratio 1:1	1
6.	(c) In a uniform electric field, the potential decreases as we move in the direction of the field. The electric field is in the negative Y direction, which is perpendicular to the positive X axis. Therefore, moving along the positive X axis or z axis does not change the potential.	1
7.	(c)Charge given to conductor always reside on its surface.	1
8.	We know, $E = \frac{-dV}{dr}$ Since, potential is constant tluoughout, dV = 0, for any displacement dr. (c) Hence, electric field in this region is zero.	1
9.	(b) This is because the net electric field inside a metal is **zero**. Metals act as excellent conductors, allowing charges to move freely, and their dielectric constant is not applicable in the same way as for insulators The capacitance of the capacitor will increase by a factor equal to the dielectric constant of the metal sheet.	1

10.	(d)  Given that: C_1 = 3 μF, C_2 = 2 μF, and C_3 = 6 μF Potential of the battery (V) = 10 V They are in series combination: So $\frac{1}{C_{eq}} = \frac{1}{C_1} + \frac{1}{C_2} + \frac{1}{C_3}$ $\frac{1}{C_{eq}} = \frac{1}{3} + \frac{1}{2} + \frac{1}{6} = \frac{2+3+1}{6} = \frac{6}{6} = 1$ C_{eq} = 1 μF Charge (Q) = C V = 1 × 10 = 10 μC Since they are in series combination, so the charge on each capacitor will be the same. So **charge on 3 μF = 10 μC**	1

LEVEL-1 (2 M QUESTIONS)

Q.NO	DETAILED SOLUTIONS	VALUE POINTS
1.	1.  	1+1
2.	Work done in moving the charge q_1 at the point A, $W_1 = q_1V$ (**r_1**)Work done in moving the charge q_1 at the point B,  	1 1

	$W_2 = q_2V(\mathbf{r_2}) + \frac{1}{4\pi\epsilon_0}\frac{q_1q_2}{r_{12}}$ Total work done in assembling this configuration, $W = W_1 + W_2$ $W = q_1V(\mathbf{r_1}) + q_2V(\mathbf{r_2}) + \frac{1}{4\pi\epsilon_0}\frac{q_1q_2}{r_{12}}$	
3.	By introducing the metal plate between the plates of charged capacitor, the capacitance of capacitor increases.As C=Aεo /d-t(1-$\frac{1}{K}$). For metal plate K is infinite so Obviously, effective separation between plates is decreased from d to (d – t)	1 1
4.	. 5 = C1 + C2 ....(1st equation) 1.2 = C1C2/(C1 + C2) ....(2nd equation) On solving we get C1 = 2mF and 3mF.	1 1
5.	Charge on unknown capacitor = Charge on the combination [1 mark for a correct statement of equality of charge on the two capacitors] CV = (C parallel Co)eqv .V/3 CV= (C + Co).V/3 C = Co/2 [1 mark for correct calculation]	1 1
6.	(a) The energy of the capacitor will increase. The work done on the capacitor while removing the dielectric results in an increase in energy stored in the capacitor. (or) Energy of the capacitor after the dielectric is removed: E' = Q^2 /2C' The charge on the plates remains the same as the capacitor is isolated. But since the capacitance decreases when the dielectric is removed, the energy of the capacitor will increase. [0.5 marks for the correct change] (b) Potential difference will increase. Potential difference after the dielectric is removed is V' = Q/C' where C' is capacitance without the dielectric. Since C'<C, V'>V. [0.5 marks for the correct change] [1 mark for correct explanation]	1 1
7.	(i)This is because of conservation of charge .If q1 and q2 are the charges taken by the two plates ,then qi+q2 must be zero because the charge on the battery is simply redistributed . (ii)Yes,the charges will be of equal magnitude even if the two plates have different sizes.	1 1

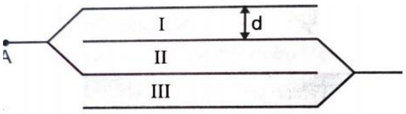
8.	We know that electric field intensity due to a point charge q at any point at a distance ‘r’ from it is given by $E = (1/4\pi\varepsilon_0)(q/r^2)$ But $E = (-dv)/(dr)$ Therefore $(-dv)/(dr) = (1/4\pi\varepsilon_0)(q/r^2)$ $dv = -(1/4\pi\varepsilon_0)(q/r^2)dr$ $v = \int^{r} -(1/4\pi\varepsilon_0)(q/r^2)dr = (-q/4\pi\varepsilon_0)[r^{-1}/-1]^{r} = (q/4\pi\varepsilon_0)\,[1/r]^{r} = (1/4\pi\varepsilon_0)(q/r)$	1 1

LEVEL-2 (2 M QUESTIONS)

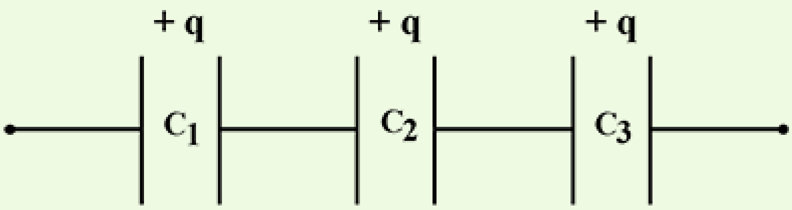
Q.NO	**DETAILED SOLUTIONS**	**VALUE POINTS**
1	Q ∝ C so the charge will be divided in proportion of their capacitances. Explanation: When two charged conductors are touched together then the charge on them will get divided as we know charge can flow. We also know Q= CV	1
2	(i) When switch S is open and dielectric is introduced, charge on each capacitor will be $q_1 = C_1 V$, $q_2 = C_2V$ $q_1 = 5CV= 5 \times 2 \times 5 = 50\ \mu C$, $q_2 = 50\ \mu C$ Charge on each capacitor will become 5 times (ii) P.d. across C_1 is still 5V and across C_2, $q = (5C)\ V$ $V' = \frac{V}{5} = \frac{5}{5} = 1V$	1 1
3	A represents C_2 and B represents C_1 Reason: From the graph the slope q/v= Capacitance is greater forA. Also according to given conditions the capacitance $C \propto A$ so capacitance is larger for the C_2 because the area of its plates is large and d for the two capacitor is same. Hence, A represents C_2.	1 1
4	. In the steady state, the displacement current and hence the conduction current, is zero as $\|\|\vec{E}\|\|$ between the plates, is constant.	1 1

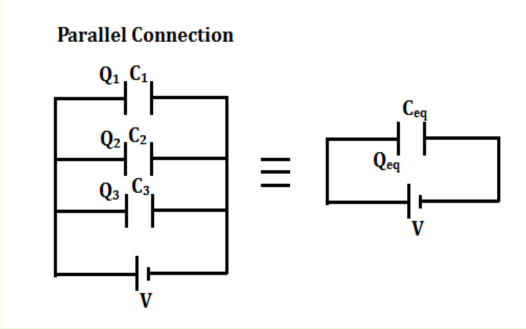
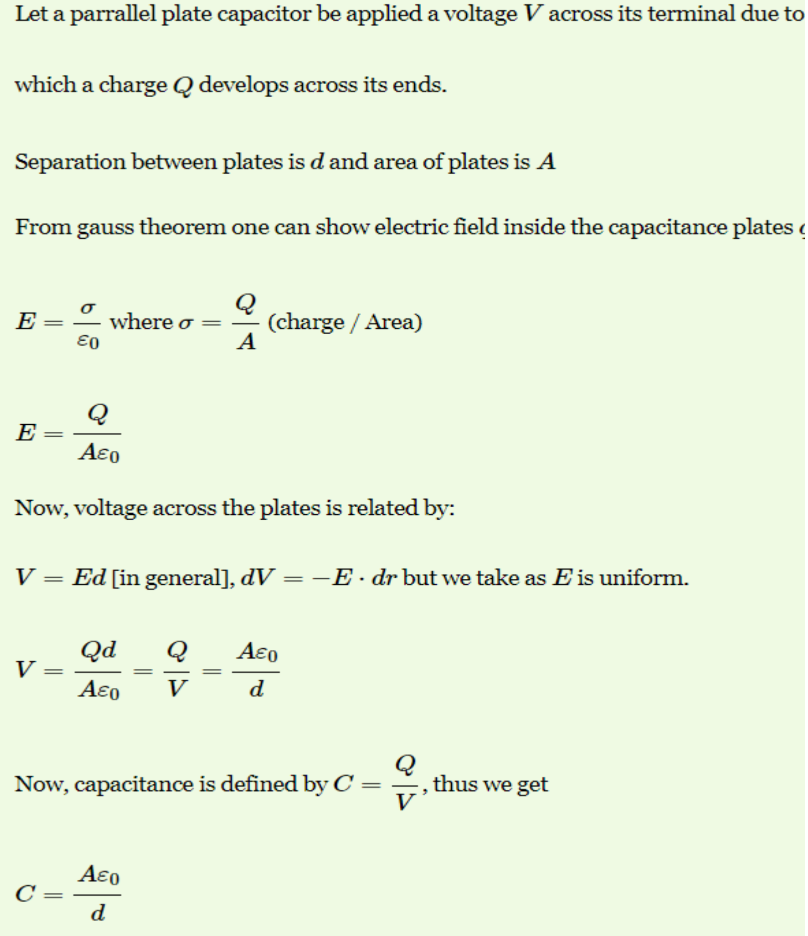
	During charging and discharging, the displacement current and hence the conduction current is non zero as | |E→| | between the plates, is changing with time. Current is non zero as | |E→| | between the plates, is changing with time.	
5	When three capacitors of equal capacitance are connected in series. The net capacitance is obtained by $1/ C_s = 1/C + 1/C + 1/C = 3/C$ Therefore $C_s = C/3$ ------------------ (1) When the tree capacitance of same and equal capacitance are connected in parallel to the net capacitance is $C_p = C + C + C = 3C$ ---------------- (2) Therefore $C_s / C_p = (C/3)/(3C) = 1/9$	1 1

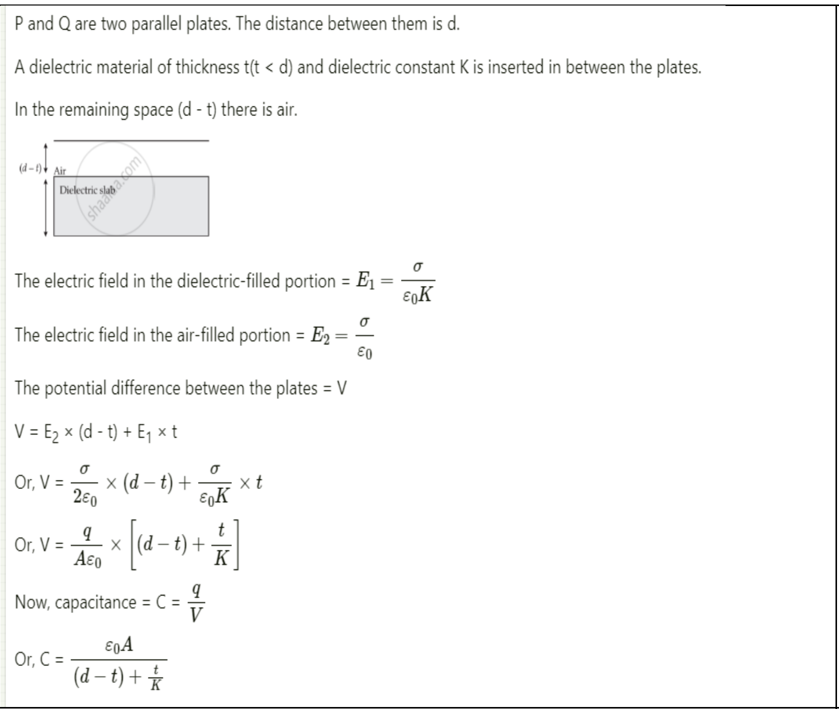
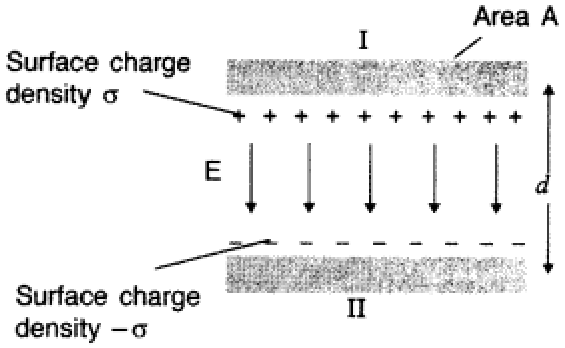
LEVEL-3 (2 M QUESTIONS)

Q.NO	DETAILED SOLUTIONS	VALUE POINTS
1.	. The capacitance of the parallel plate capacitor, filled with dielectric medium of dielectric constant K is given by $C=K \epsilon_0 A/d$ The capacitance of the parallel plate capacitor decreases with the removal of dielectric medium as for air or vacuum K = 1 and for dielectric K > 1. If we disconnect the battery from capacitor, then the charge stored will remain the same due to conservation of charge. The potential difference across the plates of the capacitor is given by $V =q/C$ Since q is constant and C decreases which in turn increases V and therefore E increases as $E = V/d$.	1 1
2.	.  $C_p=3C =3 A\varepsilon_0 /d$	1 1
3.	The capacitance of this capacitor is 221.2×10^{-13} F. The charge stored in any one of the plates 221.2 pC.	1 1

LEVEL-1 (3 M QUESTIONS)

Q.NO	DETAILED SOLUTIONS	VALUE POINTS
1	Consider that three capacitors having capacitance C1,C2 and C3 are connected in series to each other shown in the figure above, Consider that +q charge is given to first plat of first capacitor. By induction a charge (−q) will produce at internal surface of second plate of this capacitor and so on. Consider that potential between the plates of capacitor are C1,C2 and C3 respectively so, $V1=qC1$, $V2=qC2$ and $V3=qC3$ Now $V=V1+V2+V3$ $\therefore V=qC1+qC2+qC3$ ...(i) If equivalent capacitance of combination of capacitors is C then $V=qC$ ...(ii) By equations (i) and (ii), we get $qC=qC1+qC2+qC3$ $\Longrightarrow 1C=1C1+1C2+1C3$  Let the three capacitance connected in parallel be C1, C2 and C3 and supply voltage be V. Let the equivalent capacitance of the combination be Ceq Charge on a capacitor is given by $Q=CV$ Since all the capacitors are connected in parallel, so voltage across each capacitor is V. Thus charge on C1, $Q1=C1V$ Charge on C2, $Q2=C2V$ Charge on C3, $Q3=C3V$ Charge on equivalent capacitance $Qeq=CeqV$ Now $Qeq=Q1+Q2+Q3$ $\therefore CeqV=C1V+C2V+C3V$	1 **1** **1**

	⟹ Ceq=C1+C2+C3  	
2	 Let a parralel plate capacitor be applied a voltage V across its terminal due to which a charge Q develops across its ends. Separation between plates is d and area of plates is A From gauss theorem one can show electric field inside the capacitance plates $E = \frac{\sigma}{\varepsilon_0}$ where $\sigma = \frac{Q}{A}$ (charge / Area) $E = \frac{Q}{A\varepsilon_0}$ Now, voltage across the plates is related by: $V = Ed$ [in general], $dV = -E \cdot dr$ but we take as E is uniform. $V = \frac{Qd}{A\varepsilon_0} = \frac{Q}{V} = \frac{A\varepsilon_0}{d}$ Now, capacitance is defined by $C = \frac{Q}{V}$, thus we get $C = \frac{A\varepsilon_0}{d}$	1 2

3	 P and Q are two parallel plates. The distance between them is d. A dielectric material of thickness t(t < d) and dielectric constant K is inserted in between the plates. In the remaining space (d - t) there is air. The electric field in the dielectric-filled portion = $E_1 = \frac{\sigma}{\varepsilon_0 K}$ The electric field in the air-filled portion = $E_2 = \frac{\sigma}{\varepsilon_0}$ The potential difference between the plates = V V = $E_2 \times (d - t) + E_1 \times t$ Or, V = $\frac{\sigma}{2\varepsilon_0} \times (d-t) + \frac{\sigma}{\varepsilon_0 K} \times t$ Or, V = $\frac{q}{A\varepsilon_0} \times \left[(d-t) + \frac{t}{K}\right]$ Now, capacitance = C = $\frac{q}{V}$ Or, C = $\frac{\varepsilon_0 A}{(d-t) + \frac{t}{K}}$	
4	When a charge of one coulomb produces a potential difference of one volt between the plates of capacitor, the capacitance is one farad.  Outer region I (region above the plate 1), $E = \frac{\sigma}{2\varepsilon_0} - \frac{\sigma}{2\varepsilon_0} = 0$ Outer region II (region below the plate 2), $E = \frac{\sigma}{2\varepsilon_0} - \frac{\sigma}{2\varepsilon_0} = 0$ Capacity of a parallel plate capacitor. A parallel plate capacitor consists of two large plane parallel conducting plates separated by a small distance. We first take the intervening medium between the plates to be vaccum. Let A be the area of each plate and d the separation between them. The two plates have charges Q and – Q. Since d is much smaller than the linear dimension of the plates ($d^2 << A$), we can use the result on electric field by an infinite plane sheet of uniform surface charge density. Plate 1 has surface charge density σ = Q/A and Plate 2 has a surface charge density -σ, the electric field in different region is: In the inner region between the plates 1 and 2, the electric fields	1

	due to the two charged plates add up, giving $E = \frac{\sigma}{2\varepsilon_0} + \frac{\sigma}{2\varepsilon_0} = \frac{\sigma}{\varepsilon_0} = \frac{Q}{\varepsilon_0 A}$ or $V = Ed = \frac{1}{\varepsilon_0}\frac{Qd}{A}$ The capacitance C of the parallel plate capacitor is then $C = \frac{Q}{V} = \frac{\varepsilon_0 A}{d}$	2
5	*Initially when there is vacuum between the two plates, the capacitance of the capacitor is* *C0=ε0A/d* *Where, A is the area of parallel plates* *Suppose that the capacitor is connected to a battery, an electric field E0 is produced* *Now if we insert the dielectric slab of thickness t=d/2 the electric field reduce to E* *E is produce do w, if we insert the dielectric slab of thickness t= t=d2 the electric field reduces to E Now, the gap between plates is* divided in two parts, for distance there is electric field E and for the remaining distance (d-t) the electric field is E0 is 0/ε0 .If V be the potential difference between the plates of the capacitor, then $V=Et+E_0(d-t)V=Ed2+E_0d2=d2(E+E_0)(t=d2)$ $V=d2(E0K+E0)=dE_02K(K+1)$ $(asE_0/E=K)$ *Now* $E_0=\sigma/\varepsilon_0=q/\varepsilon_0A \Rightarrow V=d2Kq\varepsilon_0A(K+1)$ *we know* $C=qV=2K\varepsilon_0A(K+1)d$	1 2
	LEVEL-2 (3 M QUESTIONS)	
Q.NO	**DETAILED SOLUTIONS**	**VALUE POINTS**
1	. Given V_A= 90V, C_1 = 20µF, C_2 = 30µF and C_3= 15µF Since these capacitors are connected in series, net capacitance will be $\frac{1}{c} = \frac{1}{20} + \frac{1}{30} + \frac{1}{15} = \frac{3}{20}$ $c = \frac{20}{3}\mu F$ Carge on each capacitor q = CV =600µC Potential difference across the capacitor C_2 $V_2 = \frac{q}{C_2} = \frac{600}{30} = 20v$ Energy stored in capacitor across C_2 E_2= 6000J	1 1 1

2	(i) Charge stored, Q = CV 300 µC = C × V , When potential is reduced by 100 V 100 µC = C(V – 100) = CV – 100 C 100 µC = 300 µC – 100 C ⇒ 100 C = 300 µC – 100 µC ⇒ 100 C = 200 µC Therefore, capacitance C = 2µF (ii) Charge stored when voltage applied is increased by 100 V Q' = 2µF × (150 + 100) = 500µC	2 1
3	Charge stored on the capacitor q=CV When it is connected to the uncharged capacitor of same capacitance, sharing of charge takes place between the two capacitor till the potential of both the capacitor becomes $V/2$ Energy stored on the combination(U$_2$) =$\frac{1}{2}c\left(\frac{v}{2}\right)^2+\frac{1}{z}c\left(\frac{v}{2}\right)^2=\frac{cv^2}{4}$ Energy stored on single capacitor before connecting U$_1$=$\frac{1}{2}Cv^2$ Ratio of energy stored in the combination to that in the single capacitor $\frac{U_z}{v_1}=\frac{cv^{2}/4}{cv^2\ /\ 2}=1:2$	1 1 1

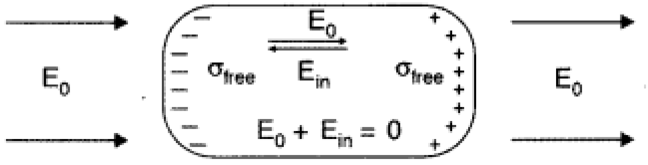
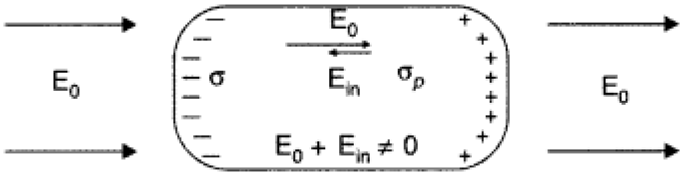
LEVEL-3 (3 M QUESTIONS)

Q.NO	**DETAILED SOLUTIONS**	**VALUE POINTS**
1	Dielectric slab of thickness 5mm is equivalent to an air capacitor of thickness = $\frac{5}{10}$mm Effective separation between the plates with air in between is = 5.5 mm Effective new capacitance = 200 µF X $\frac{5}{5\cdot5}$ = 182 µF	1

	(ii)Effective new electric field = $\frac{100}{5{\cdot}5\times10^{-3}}$ =18182 V/m New energy stored / original energy stored = 10/11	1 1
2	Given : C_A= C_B = C , Dielectric costant = K Energy stored = $\frac{1}{2}Cv^2$ (i) Net capacitance with switch S closed = C+C= 2C E_1= Energy stored = CV^2 (ii) After switch S is opened, capacitance of each capacitor = KC Energy stored in capacitor A = $\frac{1}{2}kcv^2$ (iii) For capacitor B, Energy stored = $\frac{Cv^2}{2k}$ (iv) From equations (iii) & (iv) E_2 = Total energy stored = $\frac{1}{2}cv^2\left(\frac{k^2+1}{k}\right)$ Required Ratio = $\frac{E_1}{E_2} = \frac{2k}{k^2+1}$	1 1 1
3	(a) Q_{max} = C V_{max} $Q_{max} = \frac{K\in_0 A}{d}(E_{max}d) = K\in_0 AE_{max}$ Q_{max} = 1 x 8.8 x10^{-12} x 7 x 10^{-4} x 3 x 10^{6} = 184.8 x 10^{-10} = 18.48 x 10^{-9} = 18.48 nC [0.5 mark for the correct formula] [1 mark for the correct result] (b) Q_{max} = 2 x 8.8 x10-^{12} x 7 x 10^{-4} x 15 x 10^{6} = 1848 x 10^{-10} = 184.8 x 10^{-9} = 184.8 nC The change in maximum charge that can be stored = (change in charge / original charge) % = 900% [1 mark for the correct calculation and result] [0.5 mark for the correct calculation of % change]	1.5 1 0.5
	LEVEL-1 (5 M QUESTIONS)	
Q.NO	**DETAILED SOLUTIONS**	**VALUE POINTS**
1.	(a) Capacitance decreases. Capacitance is inversely proportional to the distance of separation. [0.5 mark for correct change] [0.5 mark for correct explanation] (b) Charge decreases. From Q=CV, C decreases and V remains the same, so Q decreases. [0.5 mark for correct change] [0.5 mark for correct explanation]	5

	(c) Potential difference remains the same As the capacitor is connected to the battery, the potential V of the capacitor will remain the same as that of the battery. [0.5 mark for correct change] [0.5 mark for correct explanation] (d) Electric field decrease	

LEVEL-2 (5 M QUESTIONS)

Q.NO	DETAILED SOLUTIONS	VALUE POINTS
1.	1.(i) Behaviour of conductor in an external electric field :  Conductor (ii) Behaviour of a dielectric in an external electrical field :  Dielectric Explanation: In the presence of electric field, the free charge carriers in a conductor move the charge distribution and the conductor readjusts itself so that the net Electric field within the conductor becomes zero. In a dielectric, the external electric field induces a net dipole moment, by stretching / reorienting the molecules. The electric field, due to this induced dipole moment, opposes, but does not exactly cancel the external electric field. Polarisation: Induced Dipole moment, per unit volume, is called the polarisation. For Linear isotropic dielectrics having a susceptibility x_c, we have polarisation (p) as: $p = X_cE$	**1.5** **1.5** 1 1

LEVEL-3 (5 M QUESTIONS)

Q.NO	DETAILED SOLUTIONS	VALUE POINTS
1.	The potential energy of a system of two charges is the amount of work done in assembling the charges at their locations by bringing them in, from infinity. (b) Work done in moving the charge q_1 at the point A, $W_1 = q_1V(\mathbf{r_1})$ Work done in moving the charge q_1 at the point B, $W_2 = q_2V(\mathbf{r_2}) + \frac{1}{4\pi\epsilon_0}\frac{q_1q_2}{r_{12}}$ Electric energy of the system, U = Total work done in assembling this configuration, $U = W_1 + W_2$ $U = q_1V(\mathbf{r_1}) + q_2V(\mathbf{r_2}) + \frac{1}{4\pi\epsilon_0}\frac{q_1q_2}{r_{12}}$	**1** q_1 **4**

q_2

LEVEL-1 (NUMERICALS)

Q.NO	DETAILED SOLUTIONS	VALUE POINTS
1.	Here $q_1 = + 0.2\mu C = 0.2 \times 10^{-6}$ C $q_2 = +0.01\ \mu C = 0.01 \times 10^{-6}C$ $r_1 = 10cm = 0.1m$ $r_2 = 5\ cm = 0.05\ m$ Work done = gain of P.E. $W = W_2 – W_1 = (1/4\pi\epsilon_0)(q_1q_2/\ r_2) – (1/4\pi\epsilon_0)(q_1q_2/\ r_2) = (1/4\pi\epsilon_0)q_1q_2\,(1/\ r_2)\text{-}(\ 1/\ r_2)$ $W = 9 \times 10^{-9} \times 0.2 \times 10^{-6} \times 0.01 \times 10^{-6}\ (1/0.05 – 1/0.1)$ $W = 9 \times 2 \times 10^{-5} = 1.8 \times 10^{-4}$ J	1 1
2.	Solution : $A = 6.6cm^2 = 6.6 \times 10^{-4}m^2$ $d = 0.7mm = 7 \times 10^{-4}m$ $k = 6$ Therefore C $= (KA\varepsilon_0)/d$ $= (6 \times 6.60 \times 10^{-4} \times 8.854 \times 10^{-12})/(7 \times 10^{-4})$ $= 50 \times 10^{-12}f$ = 50pf.	1 1
3.	Given - initial voltage V1=V , initial charge q1=360μC , therefore , capacitance C=q1/V1=360/V , ...eq1 when , voltage V2=V−120 , charge q2=120μC ,	

	therefore , capacitance C=q2/V2=120/(V−120) , ...eq2 capacitance of the capacitor remains constant as there is no change in area of the plates , medium and distance between plates , (i) Dividing eq1 by eq2 , 360/V=120/(V−120) , or 3(V−120)=V , or V=360/2=180volt (ii) Capacitance C=360/180=2μF now the new voltage is V′=180+120=300V , therefore charge stored q′=CV′=2×300=600μC	1 1
4.	$\frac{Q_1'}{R}=\frac{Q_2'}{2R}$ $\therefore Q_2'=2Q'$. $\therefore 3Q_1'=5\left(\sigma.4\pi R^2\right)$ $\therefore Q_1'=\frac{5}{3}\left(\sigma.4\pi R^2\right)$ and $Q_2'=\frac{10}{3}\left(\sigma.4\pi R^2\right)$ $\therefore\ \sigma_1=5/3\sigma$ and $\therefore\ \sigma_2=\frac{5}{6}\sigma$.	1 1

LEVEL-2 (NUMERICALS)

Q.NO	**DETAILED SOLUTIONS**	**VALUE POINTS**
1.	C = 20μF = 20 X 10^{-6} F, V= 100 V , K= 5 Charge stored Q= CV = 2000μC New value of capacitance $C^{'}$ = 100μF Energy stored in a capacitor (E) =$\frac{Q^2}{2C}$ (i) Energy stored before dielectric is introduced E_1= 0.1 J (ii) Energy stored after dielectric is introduced (no change in the value of Q) E_2 = 0.02J	1 1
2.	In first case C_1=εoKx(lxb)/d……….(i) In second case, these two apartments are in parallel, their net capacity would be the sum of two individual capacitances C_2 = C’$_2$ + C”$_2$	1

	$= \dfrac{\varepsilon_0 K_1\left(\frac{l}{2}\times b\right)}{d} + \dfrac{\varepsilon_0 K_2\left(\frac{l}{2}\times b\right)}{d}$ $\Rightarrow C_2 = 2\varepsilon_0 \dfrac{(l\times b)}{d}(K_1 + K_2) \qquad \ldots(ii)$ Since these are identical capacitors, comparing (i) and (ii), We have $C_1 = C_2$ $\dfrac{\varepsilon_0 K(l\times b)}{d} = \varepsilon_0 \dfrac{(l\times b)}{d}\left(\dfrac{K_1+K_2}{2}\right)$ $\therefore\ \mathbf{K = \dfrac{K_1+K_2}{2}}$	1 1
3.	Given : d' = 3d, K = 10, C = ?, Q' = ?, U'_d= ? (i) For parallel plate capacitor $C = \dfrac{\epsilon_0\ A}{d}$ Let the new capacity be C' $C' = \dfrac{K\ \epsilon_0\ A}{d'} = \dfrac{10\times(\epsilon_0\ A)}{3d}$ $[\because K = 10,\ d' = 3d]$ $\Rightarrow \left(\dfrac{10}{3}\right)\left(\dfrac{\epsilon_0\ A}{d}\right) = \dfrac{10}{3}C$ $\Rightarrow \mathbf{C' = \dfrac{10}{3}C}$ (*ii*) Since V remains the same as the battery is not disconnected, $Q' = C'V$ $Q' = \left(\dfrac{10}{3}C\right)V = \dfrac{10}{3}CV = \dfrac{10}{3}Q$ $\Rightarrow \mathbf{Q' = \dfrac{10}{3}Q}$	1 1

LEVEL-3 (NUMERICALS)

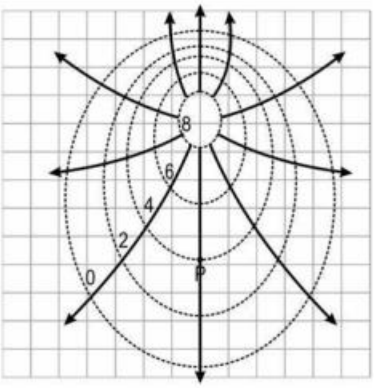
Q.NO	DETAILED SOLUTIONS	VALUE POINTS
1.	$C_{123} = 4\mu F$ (being in series) $C_{eq} = C_{123} + C_4 = 16\mu F$ (i) $Q_1 = C_4V = 6 \times 10^{-3}$ (ii) $Q_2 = C_{123}\,V = 2 \times 10^{-3}$ C Charge on each of the capacitors $C_1, C_2, C_3 = 2 \times 10^{-3}$ C	1 1

2.	$\Rightarrow \quad \frac{(360 \times 10^{-6})}{V} = \frac{(120 \times 10^{-6})}{(V - 120)}$ On solving, $\mathbf{V = 180\ V}$ $C = \frac{360 \times 10^{-6}}{180}$ $= \mathbf{2\mu F}$ is the unknown capacitance. Now the voltage has been increased by 120 V, then $V = 180 + 120 = 300\ V$ $C = \frac{q_3}{300} = 2\mu F$ $q_3 = 300 \times \mu C$ q_3 = 600 μC would be charge on the capacitor if voltage were increased by 120 V. [Answer : V = 120 V, c = 2 μF, Q = 400 μC]	1 1 1
3.	**Given :** $C_1 = C_2 = C_3 = C_4 = C_5 = 2\mu F = 2 \times 10^{-6}\ F$ (*i*) Capacitors C_2, C_3 and C_4 are in parallel $\therefore \quad C_{234} = C_2 + C_3 + C_4 = 2 + 2 + 2$ $\therefore \quad C_{234} = 6\mu F$ Capacitors C_1, C_{234} and C_5 are in series $\therefore \quad \frac{1}{C_{eq}} = \frac{1}{C_1} + \frac{1}{C_{234}} + \frac{1}{C_5} = \frac{1}{2} + \frac{1}{6} + \frac{1}{2} = \frac{7}{6}\mu F$ $C_{equivalent} = \frac{6}{7}\mu F = \frac{6}{7} 10^{-6}\ F$ (*ii*) Charge drawn from the source $Q = C_{eq} V = \frac{6}{7} \times 7\ \mu C = 6\ \mu C$	1 1

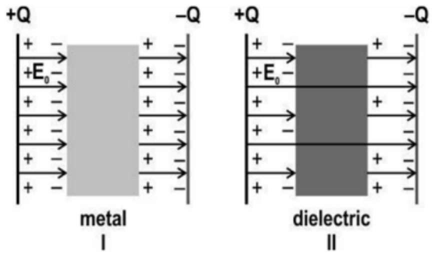
CASE BASED

Q.NO	DETAILED SOLUTIONS	VALUE POINTS
1.	(C)Q ,-Q	1
2.	(b) the potential difference increases	1
3.	(b) 10μC	1
4.	(c) C/n	1

COMPETENCY BASED

Q.NO	DETAILED SOLUTIONS	VALUE POINTS
1	In Fig (a), the two capacitors are in parallel combination. So equivalent capacitance = C + KC = C [1+K] = 5C [0.5 mark for correct identification of capacitor combination] [1 mark for correct calculation of equivalent capacitance] In Fig (b), the two capacitors are in a series combination. Equivalent capacitance = $C\,\frac{KC}{C+KC} = \frac{KC^2}{C(1+K)} = \frac{KC}{(1+K)} = \frac{4C}{5}$ [0.5 mark for correct identification of capacitor combination] [1 mark for correct calculation of equivalent capacitance]	1.5 1.5
2	(a) Electric field at P = $-\frac{\Delta V}{\Delta x} = -\frac{6-2}{0.04}$ = - 100 N/C , directed downwards. [0.5 mark for the correct formula] [0.5 mark for the correct result] (b)  [1 mark for the correct drawing of electric fields lines]	1 1

CCT

Q.NO	DETAILED SOLUTIONS	VALUE POINTS
1	(a)  [1 mark for correct representation of electric field inside metal] [1 mark for correct representation of electric field inside dielectric] (b) The net electric field intensity inside a metal is zero. The net electric field intensity inside a dielectric is non-zero. [0.5 mark for each point]	**2** **1**

SELF ASSESSMENT

Q.NO	DETAILED SOLUTIONS	VALUE POINTS
1	(c)3 times	1
2	(b) increase in the potential difference across the plate, reduction in stored energy, but no change in the charge on the plates.	1
3	(a)Electrostatic force is a conservative force.	1
4	(d) None of these	1
5	(c) Assertion is true but reason is false	1
6	(b)Both assertion and reason are true but reason is not the correct explanation for assertion	1
7	Electric field $E=3\times10^3i$ N/C, i.e., electric field is directed towards positive X-axis. As the surface is in Y-Z plane, so the area vector (normal to the square) is along X-axis). Area $S=10\times10=100cm^2=10^{-2}m^2$Area vector $S=10^{-2}m^2$^I Using the formula of electric flux $\phi=E.S=EScos\theta$ =ES [∵angle between E and S is 0∘]$\phi=3\times10^3\times10-2=30Nm^2/C$ (b) Using the formula of electric flux $\phi=E.S\phi=EScos\theta=3\times10^3\times10^{-2}cos60^\circ=3\times10\times12=15Nm^2/C$ Note Remember that the direction of area vector is always perpendicular to the area of a face.	1 1
8	Definition of	1

	Potential difference , Relation dw = qdv = $3.2 \times 10^{-19} \times 1 = 3.2 \times 10^{-19}$ Joule.	1
9	At the surface of the sphere V=1.08×10^{6} V, b. At a distance 0.1cm from the centre of the sphere (ii) 1.08×10^{6} V a. At the centre of the sphere. (iii) 1.08×10^{6} V	1 1 1
10	Derivation of Electrostatic potential due to dipole. $V = \frac{1}{4\pi\varepsilon_0}\frac{p\cos\theta}{r2}$ **On axial line ,Ɵ=0^{0},** $V = \frac{1}{4\pi\varepsilon_0}\frac{p \square \square}{r2}$ **On equatorial line , Ɵ=90$^{0\ \text{i.e}}$ V=0.**	2 1
11	(a)Properties of equipotential surfaces *No work is done in moving charges on equipotential surface. *Electric field is always perpendicular to the surface. For a dipole ,Equipotential surface will be plane perpendicular to the dipole. (i)Two charges –q and +q, are located at points (0, 0, –a) and (0, 0, a), respectively. They will form a dipole. The point (0, 0, z) is on the axis of the dipole and (x,y,0) is normal to the dipole. The electrostatic potential at (x,y,0) is zero. The electrostatic potential at (0,0,z) is given by V=q/4$\pi\epsilon$0$z-a$)+q/4$\pi\epsilon$0($-z+a$) $V=q(z+a-z+a)4\pi\epsilon 0(z^2-a^2)$ $V=q(2a)4\pi\epsilon 0(z^2-a^2)$ =$p/4\pi\epsilon 0(z^2-a^2)$ ε_0 = Permittivity of free space p = dipole moment of the system= q x 2a The distance “r” is much larger than half of the distance between the two charges. Therefore, the potential at the point r is inversely proportional to the square of the distance, i.e. V∝($1/r^2$). x,y plane is a equipotential surface and x-axis is a equipotential line. Therefore, the change in potential (dV) along the x-axis will	1 1 1 1 1

	be zero. The work done in moving a small test charge from the point (5,0,0) to (–7,0,0) along the x-axis is given by Potential at (5,0,0) V_1=0 Potential at (-7,0,0) $V2$=)=0 $V_2 - V_1 = 0$ Work done = Charge (q) x Change in Potential ($V_2 - V_1$) Since the change in potential is zero, the work done is also zero. The change in potential is independent of the path taken between the two points. Therefore, the work done in moving a point charge will remain zero	
12	Q1.(a)It experiences torque but not force Q2.(c)90 degree Q3.(d)4W Q4.(c)both (a) and (b)	

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UNIT-II CURRENT ELECTRICITY

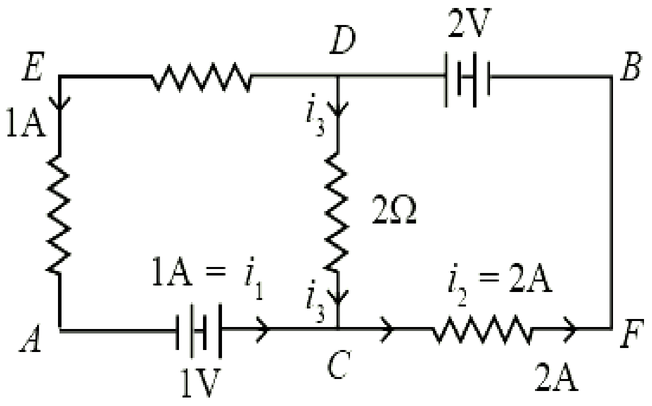
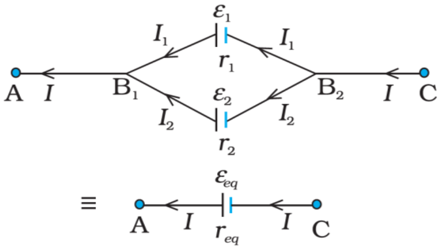
CH-3 CURRENT ELECTRICITY
DETAILED SOLUTIONS

Que	**Multiple choice question** **Level – 1**	Value point
1	A) , $I = \vec{J}.\vec{A}$ $$v_d = \frac{I}{Ane}$$	1
2	D	1
3	D	1
4	B $$\mu = \frac{v_d}{E}$$	1
5	B	1
6	C $$v_d = \frac{I}{Ane}$$	1
7	*B)* $\boldsymbol{R = \rho \frac{l}{A}}$ $$\boldsymbol{A = \frac{\pi d^2}{4}}$$ $$\boldsymbol{find\ \frac{R_2}{R_1}\ and\ R_2 = 10\ ohm}$$	1
8	B ,v = IR by putting the value of V and I, we will get R	1
9	*D*	1
10	D	1
11	A $v_d = \frac{I}{Ane}$ $\frac{v_{d1}}{v_{d2}} \times \frac{r_1^2}{r_2^2} = \frac{i_1}{i_2} = \frac{16}{1}$	1
12	A	1
13	D $V = E - Ir, 10 - 0 \times 3 = 8.5\ V$	1
14	B, $I = \frac{E}{R+r}$, $V = E - \frac{E}{R+r}r$ $$r = \frac{10}{9}\Omega$$	1
15	A, 2+2=1 +1.3 +I I = 1.7 A	1
16	C, As Vd∝E, Drift velocity increases with increases of electric field	1

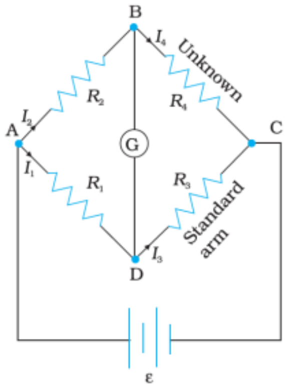
17	C**,** Assertion is true. When we switch on the bulb, it glows immediately. But the Reason is false. The drift velocity is very small, of the order of some mm. Then-ever the bulb glows immediately since when switch is closed, all the electrons start drifting and so does the electron in direct nearby of bulb. Thus instantly electron starts flowing through the bulb and it starts glowing.	1
18	C	1
19	A, The statement of assertion is “There is no current in the metals in the absence of electric fields.” This statement is absolutely correct because without an electric field a conductor will not produce current on its own. The electrons within the metal move in a haphazard way. However, a haphazard motion can not contribute to the current. A current requires a stream of electrons, this is only possible under the influence of an electric field. Because an electric field provides drift velocity to free electrons which ultimately results in the current. The statement of reason is “Motion of free electrons are random.”. This statement is also correct. As stated earlier the free electrons in a metal move in a haphazard manner. This also explains why there is no current in the metals in the absence of an electric field. From the above discussion, it is clear that both the assertion as well as the reason are correct. Also, the reason perfectly provides an explanation for the given assertion. Hence, option A is the correct answer	1
20	Correct option is C. Assertion is correct but Reason is incorrect On increasing the temperature of metals, the resistance of metal increases. Therefore, the temperature coefficient of resistance of metals is positive. On increasing the temperature of the insulators, the resistance. Therefore, the temperature coefficient of the resistance of insulators is negative.	1
	Multiple choice question **Level - 2**	
1	From the figure 1 ohm and 5 ohm in series, so potential drop across 2 ohm and 1 + 5 ohm remain same, Current 1ohm and 5 ohm is 5 +1/6 = 1A b/c 5 ohm and 1 ohm in series so current will same in 5 and 1 ohm resistor. So power dissipated by 5 ohm resistors is I^2R= 5 watt Option D is correct	1

2	D	1
3	$\frac{3}{6}=\frac{4}{8}$ so Wheatstone bridge in balanced condition therefore 3 and 4 ohm will be in series and similarly 6 and 8 ohm also in series Equivalent resistance of 3 and 4 ohm = 3 + 4 =7 Similarly 6 +8 = 14 Resistance between A and B is $\frac{1}{R}=\frac{1}{7}+\frac{1}{14}$ R = $\frac{14}{3}\Omega$ Hence option A is correct.	1
4	$A=\rho\frac{l}{R}$ since conductor is made up by same material so resistivity will remain same and resistance also same, so $\frac{A_1}{A_2}=1$ Hence, option B is correct	1
5	A, insulators and semiconductors	1
6	The conductivity of an electrolyte is very low as compared to a metal at room temperature because the number density of free ions in an electrolyte is much smaller as compared to number of free electrons in metals. Further, ions drift slowly due to their heavier mass. Hence, option A is correct	1
7	A is true but R is false Explanation : Both the quantities are dimensionless. Resistance x conductance = R x 1/R = $(M_0L_0T_0)$ = 1 and dielectric constant K is dimensionless. Hence, option C is correct	1
8	On increasing temperature, KE of free electron increases. They collide more rapidly hence drift velocity decreases. Also with increase in temperature resistance increases conductivity decreases ∴ Both statements are true. But reason is not correct explanation of assertion. Hence, option B is correct	1
9	A	1
10	Both Assertion and Reason are incorrect Because there is no special attractive force that keeps a person stuck with a high power line. The actual reason is that a current of the order of or even less is enough to bring disorder in our nervous system. As a result of it, the affected person may lose temporarily his ability to exercise his nervous control to get himself free from the high power line. Hence, option D is correct	1
	Multiple choice question **Level - 3**	
1	B, should be approximately equal and are small	1
2	A	1
3	$R_T=R_0(1+\alpha(T-T_0),\ R_{50}=5, R_{100}=6,\ \frac{R_{50}-R_0}{R_{100}-R_0}=\frac{50}{100}$ R_0= 4 ohm	1

	By solving option will be A	
4	Equivalent resistance = 2R + R +4R + R = 8R $P = \frac{16^2}{8R} = 4$, R = 8 ohm Hence, option A is correct	1
5	$$E_{eq} = \frac{E_1 r_2 + E_2 r_1}{r_1 + r_2}$$ $$E_{eq} = \frac{15 \times 1 + 10 \times 0.6}{1 + 0.6} = 13.1$$ Hence, option B is correct	1
6	Net resistance in series R + R = 2R $$P = \frac{V^2}{2R} = 60, \frac{V^2}{R} = 120$$ Net resistance in parallel=R/2 $$P' = \frac{V^2}{\frac{R}{2}} = 240\ W$$ Hence, option D is correct1	1
7	$H = \frac{V^2}{R} t$ when coil cut into two equal part resistance becomes half therefore heat becomes doubled Hence, option A is correct	1
8	When the current flow from A to D and A to D the potential at B and C is same. So no current pass through B to D now resistance between ABC 2 and 2 ohm will be in series and resistance between ADC, 2 and 2 ohm will be in series resistance between AC, 4 and 4 ohm will be in series now equivalent resistance between AC is 8/5ohm current I = V/R I = 5A So current flow between AC will be 1A Hence, option A is correct	1

9	 Using Kirchoff's junction at C, we get $\Rightarrow i_1 + i_3 = i_2$ $\Rightarrow 1\text{ A} + i_3 = 2\text{ A}$ $\Rightarrow i_3 = 1\text{ A}$ Now using Kirchoff's loop law along ACDB $V_A + 1 + i_3(2) - 2 = V_B$ $\Rightarrow V_A + +1 + i_3(2) - 2 = V_B$ $\Rightarrow V_B - V_A = 3 - 2 = 1\text{ V}$ Hence, correct option is A	1
10	As no current flow between A and D, and C and B, we can write $V_{ad} = V_{cd}$ $V_{AD} = V_{CB} = E_{eq} = \frac{\frac{1}{1}+\frac{2}{1}+\frac{3}{1}}{\frac{1}{1}+\frac{1}{1}+\frac{1}{1}} = 2\,V$ Hence, option C is correct	1
	Two mark question Level - 1	
1	Expression for the equivalent emf and internal resistance ----- Consider a parallel combination of the cells I_1 and I_2 are the currents leaving the positive electrodes of the cells. At the point B_1, I_1 and I_2 flow in whereas the current I flows out. Since as much charge flows in as out, we have  $I = I_1 + I_2$ Let $V_{(B1)}$ and $V_{(B2)}$ be the potentials at B_1 and B_2, respectively.	1

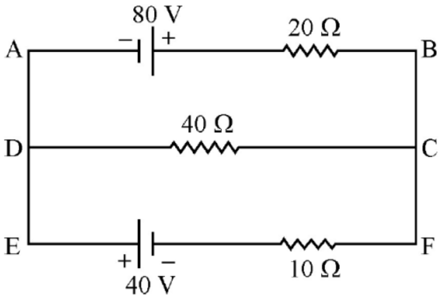
	Then, considering the first cell, the potential difference across its terminals is V(B_1) – V(B_2). Hence, $V = V(B_1) - V(B_2) = \varepsilon_1 - I_1 r_1$ Points B_1 and B_2 are connected exactly similarly to the second cell. Hence considering the second cell, we also have $V = V(B_1) - V(B_2) = \varepsilon_2 - I_2 r_2$ Combining the last three equations $I = I_1 + I_2$ $I = \frac{\varepsilon_1 - V}{r_1} + \frac{\varepsilon_2 - V}{r_2} = \left(\frac{\varepsilon_1}{r_1} + \frac{\varepsilon_2}{r_2}\right) - V\left(\frac{1}{r_1} + \frac{1}{r_2}\right)$ Hence, V is given by, $V = \frac{\varepsilon_1 r_2 + \varepsilon_2 r_1}{r_1 + r_2} - I\frac{r_1 r_2}{r_1 + r_2}$ If we want to replace the combination by a single cell, between B_1 and B_2, of emf ε_{eq} and internal resistance r_{eq}, we would have $V = \varepsilon_{eq} - I r_{eq}$ Where, $\varepsilon_{eq} = \frac{\varepsilon_1 r_2 + \varepsilon_2 r_1}{r_1 + r_2}$ and $r_{eq} = \frac{r_1 r_2}{r_1 + r_2}$	1
2	the resistance of arc lamp $R = \frac{V}{I} = \frac{80}{10} = 8ohm$ In order to use arc lamp with a source of 240 V, a resistance R' should be connected in series with it so that current through the circuit does not exceed 10A then $I(R + R') = V\ or\ 10(8 + R') = 240$ R' = 16 ohm	1 1
3	If n is the number of electrons per unit volume in the conductor and v_d the drift velocity electrons, then the relation between current and drift velocity is $I=-neAv_d$ $\frac{I}{A} = nev_d = j$ $j \propto v_d$	1 1
4	Resistivity of a material is the resistance of a conductor of that material having unit length and unit area of cross-section. Conductivity = $\frac{1}{\text{Resistivity}}$ Resistivity of conductor depends on the nature of its material and its temperature.	1 1
5	Mobility : drift speed per unit electric filed is called mobility. The expression of drift velocity is given by $\mu = \frac{v_d}{E}$ Drive the relation $\overrightarrow{v_d} = -\frac{e\vec{E}\tau}{m}$ We can write now $\mu = \frac{v_d}{E} = \frac{e\tau}{m}$	1 1
6	1. Ohm's law is applicable only to metallic conductors at moderate temperatures and moderate potential differences. 2. Ohm's law cannot be applied • to conductors maintained at very high temperatures or very low temperatures.	2

7	For T_1 temperature $\tan\theta = \frac{I}{V} = \frac{1}{R}$ so resistance of conductor 1 is lesser than 2, resistance of conductor will decrease with temperature increases thus T_1 temperature is lower than T_2	1 1
8	Refer NCERT topic 3.11	2
	Two mark question **Level - 2**	
1	i)in series the current remains the same $$I = enA_1v_{d1} = enA_2v_{d2} = \frac{v_{d1}}{v_{d2}} = \frac{A_2}{A_1}$$ ii) in parallel, the potential difference is same but the current are different. $$V = I_1R_1 = enA_1v_{d1}\frac{\rho l}{A_1} = en\rho lv_{d1}$$ $$V = I_2R_2 = en\rho lv_{d2}$$ $$Now\ I_1R_1 = I_2R_2\ \therefore\ \frac{v_{d1}}{v_{d2}} = 1$$	1 1
2	$$R_{eq} = R + r = 4 + 2 = 6\Omega$$ $$I = \frac{E}{R_{eq}} = \frac{12}{6} = 2A$$ Terminal potential across the cell,$V = e - Ir = 12 - 2 \times 2 = 8\ V$ potential deference across 4 ohm resistance $= 4 \times 2 = 8\ V$ Hence, the voltage gives the same reading in the two cases.	1 1
3	i) heat produced is directly proportional to the resistance if current in the circuit is kept constant because $H = I^2Rt$ ii) heat produced is inversely proportional to the resistance if voltage is kept constant because$H = \frac{V^2}{R}t$	1 1
4	The balance condition in a Wheatstone bridge the Wheatstone Bridge is as shown in the figure  In the case of a balanced bridge where the resistors are such that $I_g = 0$ Therefore we get $I_1 = I_3$ and $I_2 = I_4$. we apply Kirchhoff's loop rule to closed loops ADBA and CBDC. The first loop gives $-I_1 R_1 + 0 + I_2 R_2 = 0$ ($I_g = 0$) $$\frac{I_1}{I_2} = \frac{R_2}{R_1}$$	1 1

	and the second loop gives, upon using $I_3 = I_1$, $I_4 = I_2$ $I_2 R_4 + 0 - I_1 R_3 = 0$ $\frac{I_1}{I_2} = \frac{R_4}{R_3}$ Hence, we obtain the condition $\frac{R_1}{R_2} = \frac{R_3}{R_4}$	
5	Using Kirchhoff's rules to loop ABCDA $80 - 20I_1 - 40(I_1 - I_2) = 0$ $60I_1 + 40I_2 = 80$ ……….(1) applying Kirchhoff's rules to loop FEDCF $40 + 40(I_1 - I_2) - 10I_2 = 0$ $40I_1 - 50I_2 = -40$ ……….(2) Solvong equation (1) and (2) we get $I_1 = 4A \text{ and } I_2 = 4A$ ∴ Current through 40Ω resister is $I_1 - I_2 = 4 - 4 = 0A$ and Current through 20Ω resister is, $I_2 = 4A$	1 1
	Two mark question **Level - 3**	
1	as $R = \rho\frac{l}{A}$ ∴ $A = \rho\frac{l}{R}$ For both wires R and l are same and $\rho_{copper} < \rho_{manganin}$ ∴ $A_{copper} < A_{mangann}$ the resistivity of a wire depends on the nature of its material. The increase in length will not affect its resistivity.	1 1
2	(i) total emf the three cells in series = P.D. corresponding to zero current = 6 V Emf of each cell = 6/2 =2 V (ii) when I = 1 A ,V = 3/3=1 V $\therefore i = \frac{E - r}{i} = \frac{2 - 1}{1} = 1A$ (iii) the output power is maximum, when external resistance = internal resistance =3r	1 1

$$\therefore i_{max} = \frac{3E}{3r + 3r} = \frac{E}{3r} = 1A$$

3 Using Kirchhoff's rules to loop ABCDA



$$80 - 20I_1 - 40(I_1 - I_2) = 0$$

$60I_1 + 40I_2 = 80$ ……….(1)

applying Kirchhoff's rules to loop FEDCF

$$40 + 40(I_1 - I_2) - 10I_2 = 0$$

$40I_1 - 50I_2 = -40$ ……….(2)

Solvong equation (1) and (2) we get

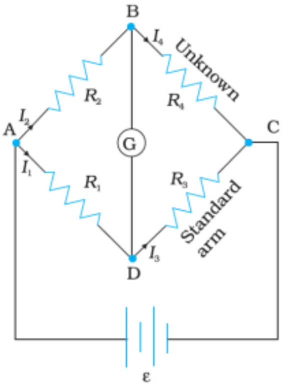
$$I_1 = 4A \; and \; I_2 = 4A$$

∴ Current through 40Ω resister is $I_1 - I_2 = 4 - 4 = 0A$

Three mark question
Level - 1

1 The balance condition in a Wheatstone bridge 2

the Wheatstone Bridge is as shown in the figure



In the case of a balanced bridge where the resistors are such that $I_g = 0$

Therefore we get $I_1 = I_3$ and $I_2 = I_4$.

we apply Kirchhoff's loop rule to closed loops ADBA and CBDC. The first loop gives

$-I_1 R_1 + 0 + I_2 R_2 = 0$ (I_g = 0) 1

$$\frac{I_1}{I_2} = \frac{R_2}{R_1}$$

and the second loop gives, upon using $I_3 = I_1$, $I_4 = I_2$

$I_2 R_4 + 0 - I_1 R_3 = 0$

$$\frac{I_1}{I_2} = \frac{R_4}{R_3}$$

Hence, we obtain the condition

$$\frac{R_1}{R_2} = \frac{R_3}{R_4}$$

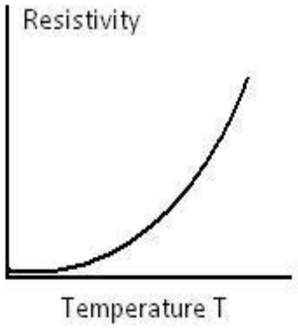
<table>
<tr><td></td><td>For determining unknown resistance it is used</td><td></td></tr>
<tr><td>2</td><td>for the balanced Wheatstone's bridge,

$$\frac{100}{\frac{100R}{100+R}} = \frac{200}{40} or \frac{100R}{100+R} = 20$$

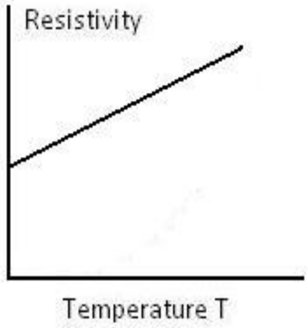
$\therefore R = 25\Omega$</td><td>3</td></tr>
<tr><td>3</td><td>Electric field,$E = \frac{V}{l}$

$$v_d = \frac{eE\tau}{m} = \frac{eV\tau}{ml}$$

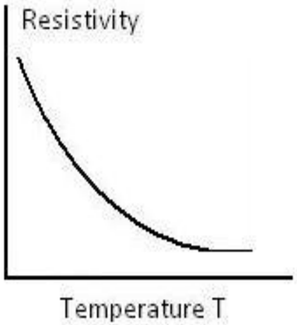
$$resistance, R = \rho\frac{l}{A} = \frac{4\rho l}{\pi D^2}$$

(i) When V doubled, E becomes double, v_d becomes double and R remains unchanged
(ii) When L is doubled, E becomes half, v_d becomes half and R becomes double.
When D is doubled, E remains unchanged, v_d is also unchanged and R becomes one – fourth.</td><td>3</td></tr>
<tr><td>4</td><td>

Copper



nichrome

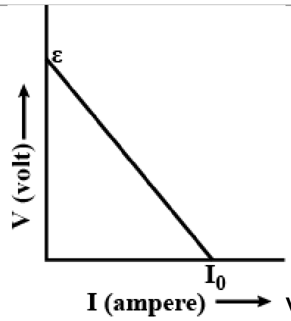


semiconductor

In conductors, average relaxation time decreases with increase in temperature, resulting in an increase in resistivity. In semiconductors, the increase in number density (with increase in temperature) is more than the decrease in relaxation time; the net result is, therefore, a decrease in resistivity</td><td>3</td></tr>
<tr><td>5</td><td><table>
<tr><th>E.M.F. OF A CELL</th><th>TERMINAL VOLTAGE OF A CELL</th></tr>
<tr><td>1.It is measured by the amount of work done in moving a unit positive charge in the complete circuit inside and outside the cell.</td><td>1.It is measured by the amount of work done in moving a unit positive charge in the circuit outside the cell.</td></tr>
</table></td><td>1</td></tr>
</table>

2.It is the characteristic of the cell i.e.; it does not depend on the amount of current drawn from the cell	2.It depends on the amount of current drawn from the cell. More the current is drawn from the cell, less is the terminal voltage
3.It is equal to the terminal voltage when cell is not in use while greater than the terminal voltage when cell is in use.	3.It is equal to the emf of cell when cell is not in use, while less than the emf when cell is in use.

2



V = E -Ir

V = -Ir + E

Y = mx +c

Hence the graph between V and I is a straight line with a -ve slope, as shown in fig.

At point E, V=0

$$\therefore E = Ir$$

$$hence, r = \frac{E}{I} = negative\ of\ the\ slope\ of\ V - I\ graph.$$

Three mark question
Level - 2

1 in the steady state (when the capacitor is fully charged), no current flows through the branch BE 1

Net emf = 2V-V = V

Net resistance = 2R+R= 3R

$$current\ I = \frac{V}{3R}$$ 1

Potential difference across BE

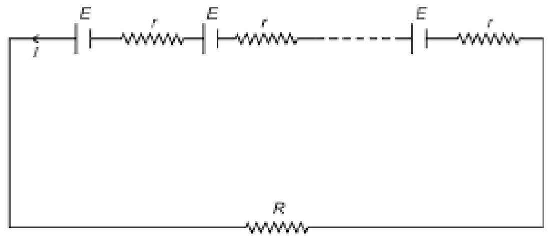
$= 2V - I \times R = \frac{4}{3}V$

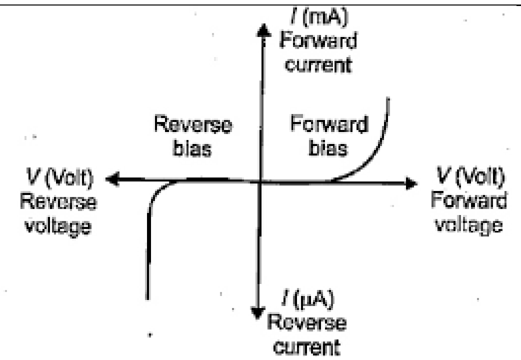
(i) Potential difference across C, $= \frac{4}{3}V - V = \frac{V}{3}$. 1

(ii) Charge on the capacitor, $Q = C \times \frac{V}{3} = \frac{CV}{3}$

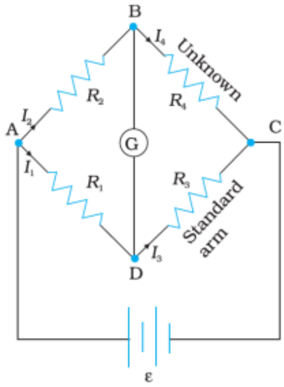
(iii) Energy stored in the capacitor

$$= \frac{1}{2}C(\frac{V}{3})^2 = \frac{CV^2}{18}$$

2	 Total resistance in the circuit = R +nr Total emf of the cell=nE Current in the circuit = I Using ohm's law $total\ resistance = \frac{total\ emf}{current\ in\ the\ circuit}$ $R + nr = \frac{nE}{I}, r = \frac{E}{I} - \frac{R}{n}$ The internal resistance of a cell decreases with the increases of temperature.	1 1 1
3	(a) When concentration of the electrolyte is increased, internal resistance of the cell increases. Reason. In more concentrated electrolyte, inter ionic attractions increase and the movements of the ions become difficult. (b) When area of the anode is decreased, internal resistance of the cell increases. Reason. Lesser area of the anode decreases its tendency to attract oppositely charged ions. (c) When temperature of the electrolyte is increased, internal resistance decreases. Reason. Both interionic attractions and viscous forces decrease at higher temperature.	1 1 1
	Three mark question **Level - 3**	
1	From loop ABDA $5I_1+10I_g-(I-I_1)15=0$ Put I=1A $4I_1+2I_g=3$ For Loop BCDB $10(I_1-I_g)-20(I-I_1+I_g)-10I_g=0$ Put I-1A $3I_1-4I_g=2$ On solving $I_g=1/22=0.0454A$	1 1 1

2	 a b at the temperature of 4K, the resistance of Hg becomes zero c the resistance is -ve in the region BC because here current decreases with the increases in voltage.	1 2
3	$a)\ E_1 = \frac{V}{l}, E_2 = \frac{V}{2l}, E_3 = \frac{2V}{3l} \therefore E_2 > E_3 > E_1$ b) $as\ v_d \propto E\ \therefore v_{d2} < v_{d3} < v_{d1}$ c) $j = env_d, j \propto v_d \therefore j_2 < j_3 < j_1$	1 1 1
	Five mark question **Level - 1**	
1	(a) Each 'free' electron does accelerate, increasing its drift speed until it collides with a positive ion of the metal. It loses its drift speed after collision but starts to accelerate and increases its drift speed again only to suffer a collision again and so on. On the average, therefore, electrons acquire only a drift speed. (b) Simple, because the electron number density is enormous, ~1029 m^{-3}. (c) By no means. The drift velocity is superposed over the large random velocities of electrons. (d) In the absence of electric field, the paths are straight lines; in the presence of electric field, the paths are, in general, curved	1 1 1 1 1
	Five mark question **Level – 2**	
1	The balance condition in a Wheatstone bridge	2 1

<table>
<tr>
<td></td>
<td>
the Wheatstone Bridge is as shown in the figure
In the case of a balanced bridge where the resistors are such that $I_g = 0$
Therefore we get $I_1 = I_3$ and $I_2 = I_4$.
we apply Kirchhoff's loop rule to closed loops ADBA and CBDC. The first loop gives
$-I_1 R_1 + 0 + I_2 R_2 = 0$ $(I_g = 0)$



$$\frac{I_1}{I_2} = \frac{R_2}{R_1}$$
and the second loop gives, upon using $I_3 = I_1$, $I_4 = I_2$
$I_2 R_4 + 0 - I_1 R_3 = 0$
$$\frac{I_1}{I_2} = \frac{R_4}{R_3}$$
Hence, we obtain the condition
$$\frac{R_1}{R_2} = \frac{R_3}{R_4}$$
For determining unknown resistance it is used
The current should not flow in the Set up for a long time, otherwise the wire will become hot and its resistance will be changed.
The null point should be between 45cm and 55cm.
It is most sensitive When all four registers P,Q,R,S are nearly of same magnitude and null point is obtained in the middle of alloy wire.
</td>
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<td>Five mark question
Level - 3</td>
<td></td>
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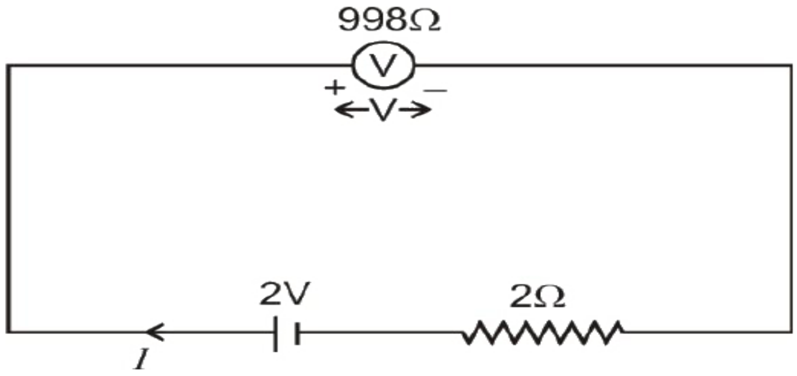
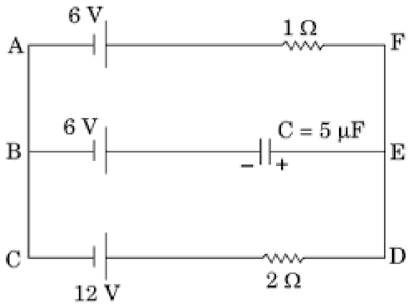
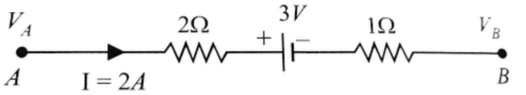
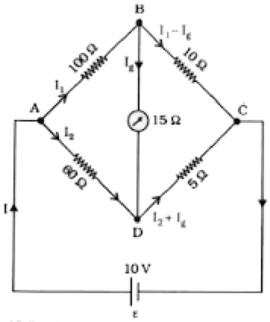
<tr>
<td>1</td>
<td>.(a)1/17 A, 9/17 A, 8/17 A
(b)2.35 V</td>
<td>5</td>
</tr>
<tr>
<td></td>
<td>Numerical problem
Level - 1</td>
<td></td>
</tr>
<tr>
<td>1</td>
<td>$$I = \frac{dq}{dt} = \frac{dt^2 + t + 1}{dt} = 2t + 1$$ Current at t = 1 s= $2 \times 1 + 1 = 3\ A$</td>
<td>1</td>
</tr>
<tr>
<td>2</td>
<td>$$R_T = R_0(1 + \alpha(T - T_0),$$ $$1.2 = 1.0[1 + 3.8 \times 10^{-3}(T - 20)]$$ $$T = 72.6\ ℃$$</td>
<td>1</td>
</tr>
<tr>
<td>3</td>
<td>$$I = \frac{E}{R + r} = \frac{2}{0.1 + 3.9} = 0.5A$$ V = E - Ir $$V = 2 - 0.5 \times 0.1 = 1.95V$$</td>
<td>1</td>
</tr>
<tr>
<td>4</td>
<td>$$E_{eq} = \frac{E_1 r_2 + E_2 r_1}{r_1 + r_2}$$</td>
<td>1</td>
</tr>
</table>

	$E_{eq} = \frac{1.5 \times .3 + 2 \times 0.2}{.3 + .2} = 1.7\,V$ $r_{eq} = \frac{r_1 r_2}{r_1 + r_2} = \frac{0.3 \times 0.2}{0.3 + 0.2} = 0.12\,ohm$	
	Numerical problem **Level - 2**	
1	Total emf = 120-8 = 16 volt Total resistance 1 +15 =16 ohm i) Current I =112/16 = 7A ii) Terminal potential during charging,$V = E + Ir$ $8 + 7 \times 1 = 15V$ iii) Chemical energy stored in the battery in 5 minutes $= VIt = 8 \times 7 \times (5 \times 60) = 16800\,J$	2
2	 Error = actual value – measured value Actual value of emf of cell = 2V $I = \frac{2}{998 + 2} = \frac{1}{500}A$ $V = 2 \times 2I$ $= 2 - 2 \times \frac{1}{500} = \frac{998}{500}A$ Error= $2 - \frac{998}{500} = \frac{2}{500} = 4 \times 10^{-3}V$	2
3	Let the length be 2l and 3l and area of cross- section A and 9A, For wires connected in parallel, $V = I_1 R_1 = I_2 R_2$ $env_{d1} \times \rho \frac{2l}{A} = en \times 9Av_{d2} \times \rho \frac{3l}{9A} \therefore \frac{v_{d1}}{v_{d2}} = \frac{3}{2}$	2
	Numerical problem **Level - 3**	
1	$\vec{u} = 4\hat{\imath}ms^{-1}, q = 2\mu C, m = 1.6g, \vec{E} = 80\hat{\imath} + 60\hat{\jmath}NC^{-1}$ $\vec{a} = \frac{\vec{F}}{m} = \frac{q\vec{E}}{m} = (100\hat{\imath} + 75\hat{\jmath}) \times 10^{-3}ms^{-2}$ $\vec{v} = \vec{u} + \vec{a}t$ $= (4.5\hat{\imath} + 0.375\hat{\jmath})ms^{-1}$	1 1 1
2	Equivalent emf of two cells = 6 – 4 = 2V	1

	And equivalent resistance =2 +8 =10ohm, so the electric current is given by I = 2/10 = 0.2 A Taking loop in anti-clock wise direction , since $E_1 > E_2$ The direction of flow of current is always from high potential to low potential . Therefore $V_B > V_A$ $$V_B - 4\,V - 0.2 = V_A$$ $V_B - V_A = 3.6\,V$	2
3	In the steady state(when the capacitor is fully charged), no current flows through the arm BE. In the loop ABCDEFA  $$I = \frac{12-6}{2+1} = 2A$$ Now, $V_{AF} = V_{BE}\ or\ 6 - 1 \times 2 = 6 - V_c$ $$V_c = 2V$$ Charge stored in the capacitor, $Q = CV = 5\mu F \times 2V = 10\mu C$	1 1 2
	Case based question	
	1.Ans. Option (B) is correct. Explanation: The heating element is made of nichrome 80/20 (80% nickel, 20% chromium). 2.Ans. Option (B) is correct. Explanation: Nichrome 80/20 means an alloy of 80% nickel, 20% chromium. 3.Ans. Option (D) is correct. Explanation: Electricity consumption is measured by kWH. So, 1200W toaster will consume more electricity 4.Ans. Option (A) is correct. Explanation: The designed electric toaster is IN operated at 220 volts A.C., single phase. 5.Ans. Option (D) is correct. Explanation: The element is wound separately on Mica sheets and fitted with body of toaster with the help of ceramic terminals.	1 1 1 1 1
	Competency based question	
1	(a) Total voltage across the two batteries in series = 2 + 2 = 4 V Total resistance in circuit = 0.1 + 0.1 + 10 = 10.2 ohm Current through the flashlight bulb = I = V/R = 4/10.2 A [1 mark for the correct value of the current] (b) Power dissipated through the flashlight bulb = I_2 R = $(4/10.2)^2$ x 10 = 1.52 W [1 mark for the correct value of the current]	1 1 1

	(c) If the two batteries have zero internal resistances, the power dissipated through the flashlight bulb will increase. The current through the flashlight bulb, I = V/R = 4/10 = 0.4 A Power dissipated through the flashlight bulb = I2 R = $(0.4)^2$ x 10 = 1.6 W The difference = 1.60 – 1.52 = 0.08 W [1 mark for the correct value of the current] [1 mark for the correct value of the difference in the power] [Note: Depending on number of decimal places taken, the answer to the sub- question (b) may vary between 1.52 and 1.54 and accordingly the answer to this question may vary between 0.08 - 0.06. Award marks accordingly.] No	1
2	(a) No, he will not be able to. P = VI Current drawn I = P/V = 1200/220 = 5.45 A Since the current drawn by steam iron is more than 5A, the circuit breaker will trip. (b) The resistance of iron box: P = V^2/R R = 220 x 220 /1200 = 40.3 ohm	1 1 1 1
	CCT based question	
	(a) Before the second set of speakers were connected: Total resistance = 10 + 10 = 20 Ω Current drawn from the stereo output = I = 10/20 = 0.5 A Since the two 10 Ω speakers are in series, the current through each one of them is 0.5 A. (a) AFTER each of the two speakers of the second set was connected in parallel to the first set of speakers: The total voltage across the first set of speakers remains the same as earlier, that is, 10 V. So the current through each of the two 10 Ω speakers of the first set remains the same as earlier.	1 1 1

	That is, 0.5 A. (b) No change in the loudness of the first set of speakers, as the current and the power dissipated through each one of them remains unchanged even after the second set of speakers are connected. (c) Any ONE of the following points: The amount of current drawn from the stereo output increases. - Additional power is dissipated through the two speakers of the second set.	1
	Self-Assessment Test	
1	B, the j changes due to the electric field produced by charges accumulated on the substances.	1
2	B	1
3	$R_T = R_0(1 + \alpha(T - T_0)$, $R_{50} = 5, R_{100} = 6$, $\frac{R_{50}-R_0}{R_{100}-R_0} = \frac{50}{100}$ R_0= 4 ohm By solving option A is correct	1
4	 $V_B = V_A - 2 \times 2 - 3 - 2 \times 1$ $V_A - V_B = 9V$ Hence, option b is correct	1
5	This statement is also correct. As stated earlier the free electrons in a metal move in a haphazard manner. This also explains why there is no current in the metals in the absence of an electric field. From the above discussion, it is clear that both the assertion as well as the reason are correct. Also, the reason perfectly provides an explanation for the given assertion. Hence, option A is correct	1
6	C, assertion is true but reason is false, alpha is positive for metals but negative for insulators.	1
7	The supply voltage is V = 230 V The initial current drawn is I_1 = 3.2 A Consider the initial resistance to be R 1, which can be found by the following relation: R=V/I= 71.87 Ω Value of current at steady state, I 2 = 2.8 A Value of resistance at steady state = R $_2$ R $_2$ can be calculated by the following equation : R_2=82.14Ω The temperature coefficient of nichrome averaged over the temperature range involved is 1.70 x 10 –^{4} ° C^{-1} Value of initial temperature of nichrome , T 1 = 27.0 ° C Value of steady state temperature reached by nichrome = T 2	1 1

	This temperature T 2 can be obtained by the following formula $\alpha = \frac{R_2 - R_1}{R_1(T_2 - T_1)}$ $T_2 - 27 = \frac{82.14 - 71.87}{71.87 \times (1.7 \times 10^{-4})}$ $T_2 - 27 = 840.5$ T_2 = 840.5 + 27 = 867.5 ° C	
8	i) DE ii) AB	1 1
9	Diagram Calculation Derivation	1 1 1
10	 By applying KCL in loop BADB $100I_1 + 15I_g - 60I_2 = 0 \ldots\ldots\ldots.1$ Applying KCL in loop BCDB, $10(I_1 - I_g) - 15I_g - 5(I_2 + I_g) = 0. \quad \ldots..2$ Applying KCL in loop ADCEA, we get $60I_2 + 5(I_2 + I_g) = 10 \ldots\ldots\ldots\ldots.3$ By solving equation 1,2 and 3, we get $I_g = 4.87A$	1 1 1
11	(a) Each 'free' electron does accelerate, increasing its drift speed until it collides with a positive ion of the metal. It loses its drift speed after collision but starts to accelerate and increases its drift speed again only to suffer a collision again and so on. On the average, therefore, electrons acquire only a drift speed. (b) Simple, because the electron number density is enormous, ~1029 m^{-3}. (c) By no means. The drift velocity is superposed over the large random velocities of electrons.	1 1 1 1 1

	(d) In the absence of electric field, the paths are straight lines; in the presence of electric field, the paths are, in general, curved	
12	a) The Wheatstone bridge works on the principle of null deflection b) galvanometer c) C,Wheatstone bridge is susceptible to high dc current d) B, false	1 1 1 1

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UNIT III-MOVING CHARGES AND MAGNETISM

CHAPTER 4- MOVING CHARGES AND MAGNETISM

LEVEL-1		**LEVEL-1**		**LEVEL-2**		**LEVEL-3**
1	a	11	b	1	B	1-c
2	c	12	b	2	A	2-d
3	a	13	a	3	C	3-b
4	a	14	a	4	B	4-a
5	b	15	a	5	A	5-a
6	b	16	d	6	B	6-d
7	b	17	b	7	C	**7-**
8	b	18	c	8	B	**8-**
9	d	19	a	9	D	**9-**
10	c	20	b	10	A	**10-**

1. At the centre of the loop
2. remains constant with the increase in current
3. Along the axis of the loop
4. The magnetic field lines form concentric circles centred on the conductor
5. IS ZERO
6. Remain stationary- AS F=q(v×B)
   As the electron is stationary, ∴velocity v=0. ∴F=0. So, electron will remain stationary.
7. To perform circular motion required centripetal force would be provided by the magnetic force on the moving charge.
   So, $Bqv=mv^2 / r$ or $r=Bq / mv$ According to the question, $v'=2v$ and $B' = B/2$
   $\therefore r'=B'q / mv' = (B/2)q / m(2v) = Bq/4mv=4r$
8. B
9. D
10. C
11. B
12. B
13. A
14. A
15. A
16. D
17. Fleming’s left hand Rule
18. Right hand thumb rule
19. Electric current
20. Straight line

MCQ- LEVEL-2

1. - Magnetic moment M = NIA, I=3A, N=20
Area (A) = π × (0.04 m)^2 = 0.0016π m^2
HENCE, = 3 × 0.0016π × 20 A·m^2 = 0.096π A·m^2=0.3 A-m^2

2. No. of turns N = 100 Radius r = 10 cm = 0.1 m Current I = 1 A Magnetic moment M = NIA
Now area of the circular coil A = πr^2
Therefore, M = NIπr^2 = 100×1×3.14×0.1×0.1 = 3.14= π A·m^2

3. (c) B = Field to circular portion

4. Repel- Because They Will Behave As 2 Long Conductors Carrying Current In Opposite Direction

5. 6, 7, 8, 9 (AS IT IS, ONLY OPTIONS)
10. ALONG ITS AXIS, ACC TO BIOT- SAVART LAW, IF **ɵ=0 THEN B=0**

MCQ- LEVEL-3

1. Since the direction of velocity of a particle varies so momentum changes but direction of magnetic force is always perpendicular to direction of charged particle. So no work is done, i.e. energy remains the same

2. using R= (V/Ig) -G
R= R= 4960 Ω
3. R=mv / qB
Let the velocity of the first α particle be v1and that of the second one be v2
v1:v2=3:2
let the radii of the circular paths of the first and second α – particles be R1 and R2 respectively R1=mv1 / qB
R2=mv2 / qB
R1/R2=mv1/qB/mv2/qB
=v1/v2
R1/R2=3/2=3:2

4. , 5, 6- as its is options only

Q7- An electric current passes through a long wire. At a distance 5 cm from the wire, the magnetic field is B. The field at 20 cm from the wire would be – (a) B/2 (b)B/ 3 (c)B/ 4 (d)B/ 5

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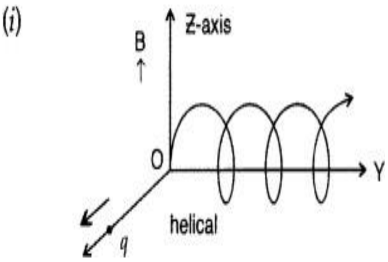
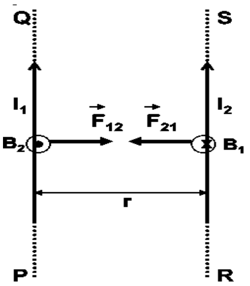
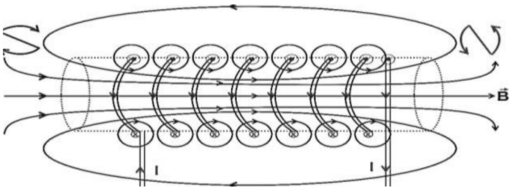
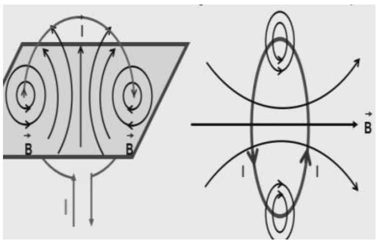
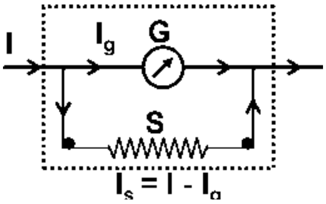
ANSWERS

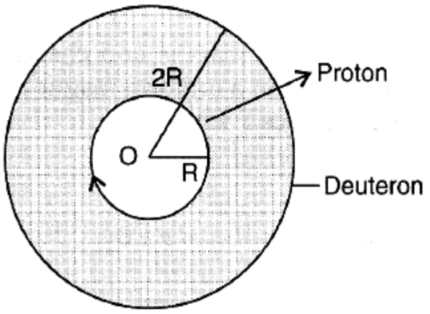
2 MARK QUESTIONS

LEVEL 1

1	1. Lorentz force- The force on a charged particle moving with velocity in a uniform magnetic field $^{\rightarrow}$ is given by $^{\rightarrow}$F = qvBsinɵ. I) - 1 ampere is the current which when flowing in each of the two parallel wires in vacuum separated by 1 m from each other exert a force of 2x 10^{-7}N/m on each other	1 1
3	i)  ii) K.E does not change irrespective of the direction of the charge as $$\text{Power delivered, } \vec{F}.\vec{v} = q(\vec{v}\times\vec{B}).\vec{v} = 0$$ $[\because \text{ scalar triple product } (\vec{v}\times\vec{B}).\vec{v} = 0]$	1 1
4	 $\boxed{F / l = \frac{\mu_0 I_1 I_2}{2\pi r}}$ **N / m**	1 1
5	(i) $B = \frac{\mu_0 I}{2a}$ (ii) M=Nia= Ni πr^2	1 1

6	 B=μ0 NI	
7	(i) It states that the magnetic field strength B produced due to a current element (of current I and length dl) at a point having position vector r relative to current element is- $dB = \frac{\mu_0}{4\pi} \frac{I\,dl \sin\theta}{r^2}$ or $dB = \frac{\mu_0}{4\pi} \frac{I\,dl}{r^2}$ ii) 	1+1
8	Correct formula (Lorentz force) **REPEAT**	2
9	Magnetic field at the centre of a circular coil is $B = \frac{\mu_0 NI}{2\,r} = \frac{4\pi \times 10^{-7} \times 100 \times 0.4}{2 \times 8 \times 10^{-2}} = 3.14 \times 10^{-4}\,T$	2
10	Magnetic field due to a long straight wire is $B = \frac{\mu_0 I}{2\pi r} = \frac{4\pi \times 10^{-7} \times 35}{2\pi \times 0.2} = 3.5 \times 10^{-5}\,T$	2
19	Galvanometer can be converted into ammeter by shunting it with a very small resistance. Potential difference across the galvanometer and shunt resistance are equal.  $\therefore (I - I_g)\,S = I_g\,G$ or $S = \frac{I_g G}{I - I_g}$ So that full current of the circuit can be measured	1+1

2-MARKS LEVEL 2

1	The number of turns per unit length n=Nl=100/0.5=200 turns/m (i) B = µNi= 4π×10^{-7}×200×2.5 = 6.28 x 10^{-4} T (ii) B = µnI/2 =2π×10^{-7}×200×2.5 = 3.14 x 10^{-4} T	1+1
3	i) Using I_1 R=(I- I_1)S Shunt resistance S = 0.15Ω (ii) using -R_{eq}= RxS/(R+S) Total resistance R = 0.12Ω	1+1
4	Magnetic field acting normal to the velocity, the charged particle describes a circular path of radius r = mv/qB. As a result, r(deu) = 2r(proton). 	2
5	The series resistance to be connected with galvanometer to convert it into a voltmeter is $R=\frac{V}{I_g}-R_G=\frac{15}{5\times10^{-3}}-50=2950\Omega$	2
10	(a)Galvanometer is a very sensitive device. It gives a full scale deflection for a small value of current. (b)The galvanometer has to be connected in series for measuring currents and as it has a large resistance, this will change the value of the current in the circuit.	2

2- MARKS LEVEL 3

1	As the circular portion is three-fourth of a circular loop. Therefore $B_O=\frac{3}{4}\frac{\mu_0 I}{2R}=\frac{3\mu_0 I}{8R}$	2
6	T = 2πm/eB = 1.787 x 10^{-7} sec.	2

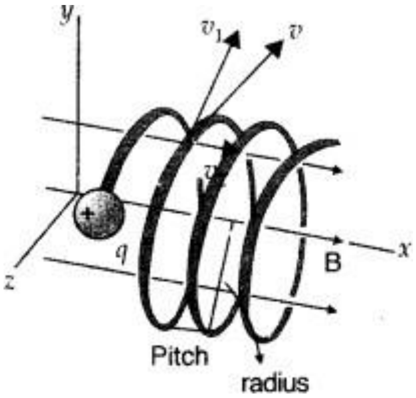
8	Current sensitivity $I_s = \frac{\alpha}{I}$ Voltage sensitivity $V_s = \frac{\alpha}{V} = \frac{\alpha}{I R_G} = \frac{I_s}{R_G}$ New current sensitivity $I_s' = I_s + \frac{50}{100} I_s = \frac{3}{2} I_s$ So, new voltage sensitivity $V_s' = \frac{I_s'}{2R_G} = \frac{3I_s/2}{2R_G} = \frac{3}{4} V_s$ Thus voltage sensitivity becomes 75% of initial value or decreases by 25%.	1 1
10	Using B= μ0i/2r = 1.26 x 10^{-25} T	2

3 MARKS QUESTIONS
LEVEL-1

Q. No.	Question	Marks
1	Correct principle Reasons – Factors –	1+1+1
4	Correct derivation as per NCERT text	3
5	Correct derivation as per NCERT text Correct definition of 1A	2+1
6	Correct statement Correct derivation as per NCERT text	1+2
7	Correct derivation as per NCERT text	3
15	F = 4 x 10^{-5}N, repulsion Repulsion F = μ_0 /4 π (2 $I_1 I_2$) I r = (10^{-7} × 2 × 10 × 5 × 0 · 20)/ 0 · 05 = 4 × 10^{-5} N The distance of F is perpendicular to the length Y and acts away from X (i.e. repulsion).	3

3 MARKS-LEVEL 2

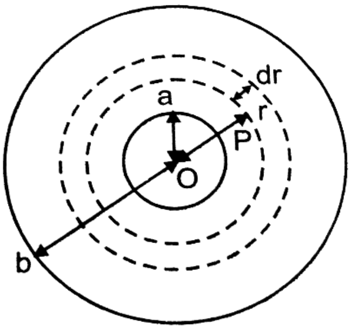
2	(i) Attractive (ii) Repulsive **REPEAT** Correct diagram / refer notes Fleming's left hand rule	
4	Using Lorentz force, Since the velocity of the particle is inclined to x-axis, therfore, the velocity has a component along B, this component remains unchanged as the motion along the	TO L3 (5 Mark)

	magnetic field will not be affected by the magnetic field. The motion in a plane perpendicular to B is as before a circular one, thereby producing a helical motion, which is its trajectory. If r is the radius of the circular path of a particle, then a force of mv^2/r, acts perpendicular to the path towards the centre of the circle and is called the centripetal force. If the velocity v is perpendicular to the magnetic field B, the magnetic force is perpendicular to both v and B and acts like a centripetal force. It has a magnitude qvB. Equating the two expressions (for centripetal force)- $mv^2/r = qvB$, which gives $r = mv/qB$ …(i) for the radius of the circle described by the charged particle.  We have, $T = \frac{2\pi}{w} = \frac{2\pi}{v/r} = \frac{2\pi m}{qB}$ …(ii) There is a component of the velocity parallel to the magnetic field (denoted by v11), it will make the particle move along the field and the path of the particle would be a helical one. HENCE BY EQ ii $p = v_{\parallel}T = 2\pi m v_{\parallel}/qB$	
6	Current required for full scale deflection *Ig* = current for one division deflection x total number of divisions $I_g = \frac{1}{10} \times 50 = 5mA$ If *I* be the maximum current that a galvanometer can read, then	

	$I = \frac{(R_G + S)I_g}{S}$ $\left[As\ \ S = \frac{I_g R_G}{I - I_g} \right]$ $I = \frac{(60+2.5)5}{2.5} = 125\,mA$	
7	For mid-air suspension, weight of the wire must be balanced by the magnetic force. Hence $IlB\sin 90^0 = mg$ $B = \frac{mg}{Il} = \frac{0.2 \times 9.8}{1.5 \times 2} = 0.65T$	
8	For voltmeter of range V, $R_1 = \frac{V}{I_g} - R_g \quad or \quad \frac{V}{I_g} = R_1 + R_g$ For voltmeter of range V/2 $R_2 = \frac{V}{2I_g} - R_g \quad or \quad \frac{V}{2I_g} = R_2 + R_g$ Dividing, we get $2 = \frac{R_1 + R_g}{R_2 + R_g} \Rightarrow R_g = R_1 - 2R_2$ For a voltmeter of range 2V, the series resistance is $R = \frac{2V}{I_g} - R_g = 2(R_1 + R_2) - R_g = 3R_1 - 2R_2$	1 1 1
9	B = $\pi\mu_0 rI$ = 4 x 10^{-6} T Direction of filed is upward	2+1

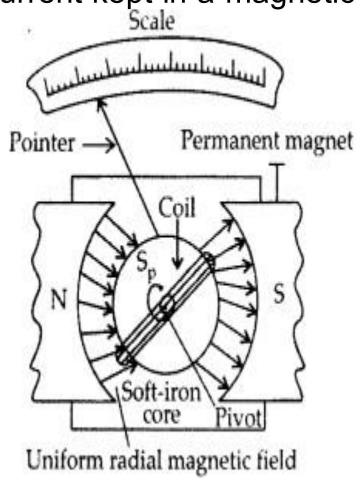
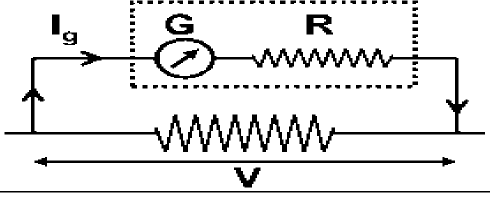
3 MARKS QUESTIONS
LEVEL 3

4	Magnetic field due to a long straight wire is B = $\mu_0 I/2\pi x$ B1 = B2, I_1 = 1A, I_2 = 2A By using the formula for B, x = 0.1 m	1+1+1
5	Due to current I through cylinder a magnetic field is set up perpendicular to the length of cylinder, which is in the form of concentric magnetic lines of force whose centre lies on the axis of cylinder. Consider an elementary co-axical cylindrical layer of cylinder of radius r and thickness dr as shown in figure. Current through the cylinder of inner radius a and outer radius r is	3

		
6	V = 2 x 10^{-6} m/s	3
9	I = 32.67A The current in XY must flow opposite to that in PQ, because only then the force will be repulsive.	2+1

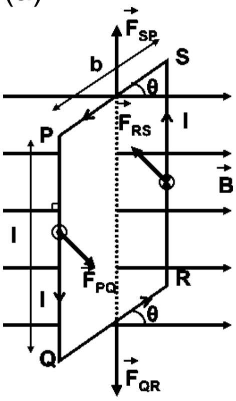
5 MARKS QUESTIONS

LEVEL 1

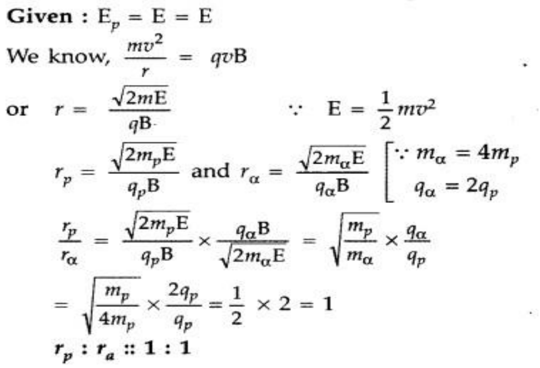
1	(a) Principle – Torque on a coil carrying current kept in a magnetic field,  (b) Voltage sensitivity is inversely proportional to current sensitivity and if we increase current sensitivity the resistance will also increase. $\therefore V = I_g (G + R)$ or $R = \frac{V}{I_g} - G$ (c) Galvanometer can be converted into voltmeter by connecting it with a very high resistance. Potential difference across the given load resistance is the sum of p.d across galvanometer and p.d. across the high resistance.  $\therefore V = I_g (G + R)$ or $R = \frac{V}{I_g} - G$	1 1/2 1 1/2 2

4	When x >>R, (i.e at a long distance from O along the x-axis) $B=\frac{\mu_o NIR^2}{2x^3}=\frac{\mu_o NI\pi R^2}{2\pi x^3}$ $=\frac{\mu_o NIA}{2\pi x^3}=\frac{\mu_o}{2\pi}\frac{m}{x^3}=\frac{\mu_o}{4\pi}\frac{2m}{x^3}$ m= NIA= MAGNETIC DIPOLE MOMENT	5
5	(i) Correct statement Correct derivation (ii) Correct diagram	1+3+1

LEVEL 2

2	(a)  $\vec{F}_{PQ} = I(\vec{l} \times \vec{B})$ $\vert F_{PQ}\vert = I\,l\,B \sin 90° = I\,l\,B$ $\vec{F}_{RS} = I(\vec{l} \times \vec{B})$ $\vert F_{RS}\vert = I\,l\,B \sin 90° = I\,l\,B$ Forces FPQ and FRS being equal in magnitude but opposite in direction cancel out each other and do not produce any translational motion. But they act along different lines of action and hence produce torque about the axis of the coil. **$\tau = F_{PQ} \times PN$ (in magnitude)** **$\tau = I\,l\,B\,(b \cos\theta)$** **$\tau = I\,lb\,B \cos\theta$** **$\tau = I\,A\,B \cos\theta$ (A = lb)** **$\tau = N\,I\,A\,B \cos\theta$ (where N is the no. of turns)** (b) Torque = 0 Net Force = 16 x10^{-6} N. The direction of Net Force is towards the straight wire i.e. attractive.	3 2
5	(a) As B is parallel to dipole moment M hence torque = 0 (b) As force on different parts of coil appears in pairs, equal in magnitude and opposite in direction therefore net force on the coil is 0 (c) F = evB = 1.5 x 10^{-24} N	5

LEVEL 3

3	(a) Correct derivation as per NCERT text (b) B directed at an angle of π/4 with the direction of magnetic field B_1	3 2
4	 **Given :** $E_p = E = E$ We know, $\frac{mv^2}{r} = qvB$ or $r = \frac{\sqrt{2mE}}{qB}$ $\because E = \frac{1}{2}mv^2$ $r_p = \frac{\sqrt{2m_pE}}{q_pB}$ and $r_\alpha = \frac{\sqrt{2m_\alpha E}}{q_\alpha B}$ $\left[\begin{array}{l} \because m_\alpha = 4m_p \\ q_\alpha = 2q_p \end{array}\right.$ $\frac{r_p}{r_\alpha} = \frac{\sqrt{2m_pE}}{q_pB} \times \frac{q_\alpha B}{\sqrt{2m_\alpha E}} = \sqrt{\frac{m_p}{m_\alpha}} \times \frac{q_\alpha}{q_p}$ $= \sqrt{\frac{m_p}{4m_p}} \times \frac{2q_p}{q_p} = \frac{1}{2} \times 2 = 1$ $r_p : r_a :: 1 : 1$	2+3

	i	ii	Iii	iv	v
CASE 7	C- ACC TO Lorentz force	A-	D- moving charge produces field	B-Using F=IBLsine	A- Using F=IBL=mg
CASE 9	A	A	B	D	A

	i	Ii	iii	iv	v
CASE 1	A	A	B	D	
CASE 2	B	C	C	A	C

	i	Ii	iii	iv	v
CASE 4	C	B	D	A	B
CASE 5	A	C	C	D	

SA- CASE BASED

A,B ,B,A

According to Ampere's circuital law, ∮→B.d→l=μ0I

$B(2\pi r)=\mu_0I$
$B=\mu_0I2\pi r$
$B=\mu_04\pi 2Ir$

Q9- The magnetic field induction at O due to current through both the semi circular loops will be in the same direction which is perpendicular to the current loop, downwards. B= μI/4 (1/R1+1/R2)

UNIT III-MOVING CHARGES AND MAGNETISM

CHAPTER 5- MAGNETISM AND MATTER

DETAILED ANSWERS

LEVEL-1 MCQ

Q.NO	DETAILED SOLUTIONS	VALUE POINTS
1	**a)** $\oint \vec{B}.\vec{ds} = 0$	1
2	C) Equal to zero	1
3	a) Ferromagnetic	1
4	M = nAI = 2000 × 1.6 × 10^{-4} × 4 = 1.28 c) 1.28 Am^2	1
5	**a)** $\vec{M} X \vec{B}$	1
6	The values of relative permeability of diamagnetic materials are slightly less than 1 and εr is quite high. According to the table given, one takes εr=1.5 and μr=0.5. c) $\varepsilon_r = 1.5,\ \mu_r = 0.5$	1
7	Diamagnets are materials with a magnetic permeability less than μ0(a relative permeability <1) Paramagnetic materials are attracted to magnetic fields, hence have a relative magnetic permeability greater than one (d) X is diamagnetic and Y is paramagnetic	1

LEVEL-2 MCQ

Q.NO	DETAILED SOLUTIONS	VALUE POINTS
8	$I =$ magnetic moment/ volume M=I*vol=100x0.1x10^{-4}=10^{-3} m=M/2l = 10^{-3}/0.1=10^{-2}=0.01Am c) 0.01 Am	1
9	$\tau = M\ B\ \sin\theta$ substitute given and find M b) 0.36 J/T	1
10	For short dipole $B_{axial} = \frac{\mu_o}{4\pi}\frac{2M}{r^3}$ Substituting we get b) 2.4 x 10^{-4} T	1

LEVEL-3 MCQ

Q.NO	DETAILED SOLUTIONS	VALUE POINTS
11	Using expression For short dipole $B_{equatorial} = \frac{\mu_o}{4\pi}\frac{M}{r^3}$ d) 0.48 G along N-S direction	1
12	**a)** F $F_m = \frac{\mu_o}{4\pi}\frac{q_{m1}q_{m2}}{r^2}$ $F'_m = \frac{\mu_o}{4\pi}\frac{2q_{m1}\times 2q_{m2}}{(2r)^2}$=F	1

13	M= magnetization x volume $B_{axial} = \frac{\mu_o}{4\pi}\frac{2M\,.r}{(r^2 - l^2)^2}$ b) 0.001T	1
	ASSERTION–REASON TYPE QUESTIONS	
14	(a)	1
15	(a)	1
16	(d)	1
17	(a)	1
18	(a).	1
19	(c)	1
20	(b).	1

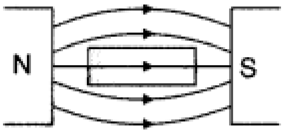
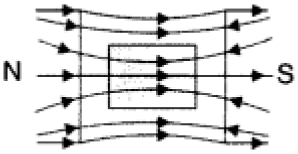
LEVEL – 1 (2M QUESTIONS)

Q.NO	**DETAILED SOLUTIONS**	**VALUE POINTS / STEP MARKING**
1	No. Steady current is not the only source of magnetic field.Magnets are also source of magnetic field. Unsteady current will also be source of varying magnetic field	1 1
2	Substances which at room temperature retain their ferromagnetic property for a long period of time are called permanent magnets. Example: Steel, alnico	1 1
3	Bi, Cu	1+1
4	Al, Ca	1+1
5	Diamagnetic material $\mu_r = 1 + X_m$	1 1
6	A diamagnetic specimen would move towards the weaker region of the field; while a paramagnetic specimen would move towards the stronger region. A diamagnetic specimen is repelled by a magnet while a paramagnetic specimen moves towards the magnet. The paramagnetic gets aligned along the field and the diamagnetic perpendicular to the field.	1 1
7	Magnetic susceptibility (χm) : It is the property of a material which determines how easily it can be magnetised when kept in a magnetising field.	½

	Also, it is the ratio of intensity of magnetisation (I) produced in the material to the intensity of magnetising field (H) $\chi_m = \frac{I}{H}$ Positive susceptibility: para-magnetic material Example: Al, Ca. Negative susceptibility : diamagnetic material Example: Bi, Cu. Negative susceptibility signifies that mentioned material is diamagnetic in nature	½ ½ ½

LEVEL-2 (2M QUESTIONS)

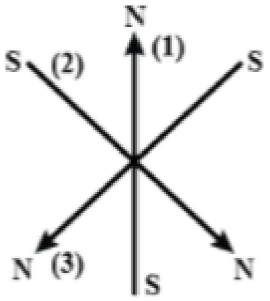
Q.NO	DETAILED SOLUTIONS	VALUE POINTS STEP MARKIN
8	**Formula used:** μ=$\frac{eh}{4\pi m}$ The spin of a proton and electron can be compared by their magnetic dipole moment. $\Rightarrow \frac{\mu_p}{\mu_e} = \frac{m_e}{m_p}$ As we know, mp>>me μP<<μe Therefore, magnetic moment of proton is neglected as compared to that of electron.	1 ½ ½ ½ ½
9	(a) As $\chi_m = \frac{I}{H}$ Slope of the line gives magnetic susceptibilities. For magnetic material B, it is giving higher +ve value. So material is 'ferromagnetic'. For magnetic material A, it is giving lesser +ve value than 'B'. So material is 'paramagnetic'. (b) Larger susceptibility is due to characteristic 'domain structure'. More number of magnetic moments get aligned in the direction of magnetising field in comparision to that for paramagnetic materials for the same value of magnetising field.	½ ½ ½ ½

10	(i) When a diamagnetic material is placed in an external magnetic field.  *Diamagnetic* (ii) When a paramagnetic material is placed in an external magnetic field.  *Paramagnetic* Magnetic susceptibility distinguishes this behaviour of the field lines due to the two substances	½ ½ 1
11	Diamagnetic materials. Diamagnetic materials are those which have tendency to move from stronger to the weaker part of the external magnetic field. Examples. Bismuth, copper, lead and silicon. Paramagnetic materials: those which have tendency to move from weaker to the stronger part of the external magnetic field. Example Explanation	1 1
12	Diamagnetism is the result of the orbital motion of electrons creating magnetic moments that are opposite to an applied field. Hence, it is not greatly impacted by temperature changes. The alignment of atomic magnetic moments in the direction of an applied field causes paramagnetism and ferromagnetism. When the temperature increases, this alignment is disrupted, leading to a decrease in the susceptibility of both types of magnetism with increasing temperature.	1 1

LEVEL-3 (2M QUESTIONS)

Q.NO	**DETAILED SOLUTIONS**	**VALUE POINTS / STEP MARKING**
13	The poles must be symmetric to each other or a magnet.	1

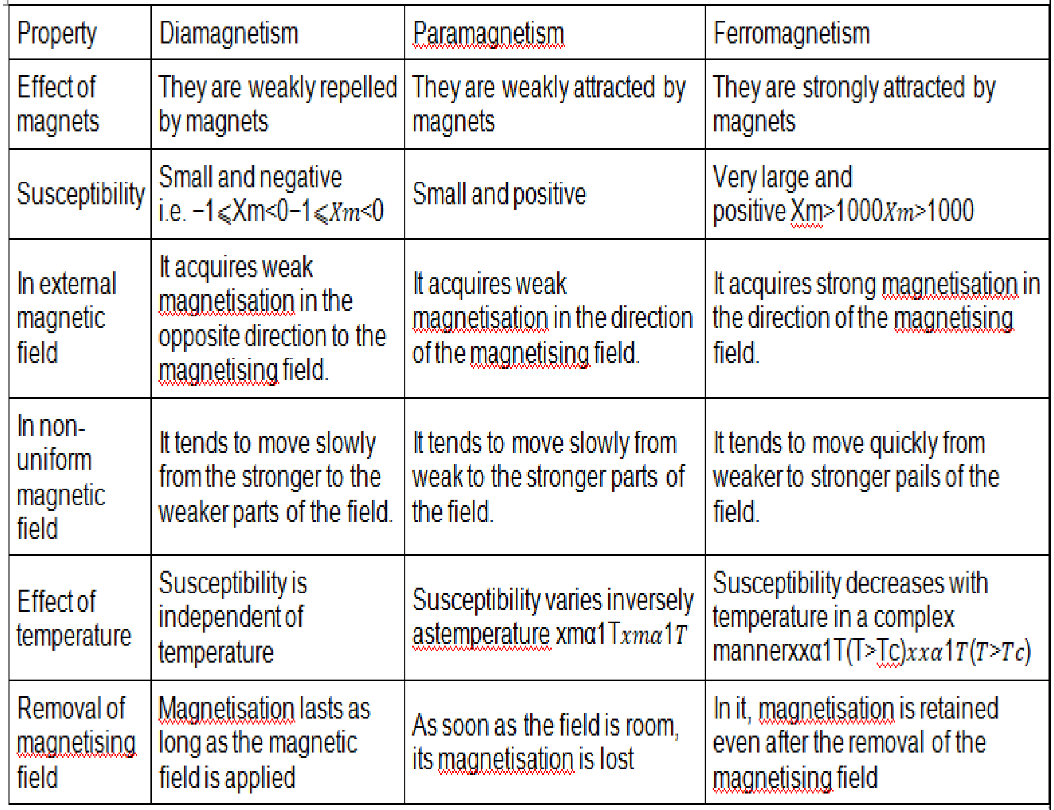
	It is possible only when the poles of the remaining two magnets are as in the given figure. The northe pole of magnet (1) is equally attracted by south pole of (2) and (3) magnets placed at equal distance. Similarly one pole of any one magnet is attracted by opposite poles of other two magnets. The resultant force or moment of each magnet is zero.	1



LEVEL-1 (3M QUESTIONS)

Q.NO	DETAILED SOLUTIONS	VALUE POINTS
1	(i) Diamagnetic (ii) Paramagnetic . (iii) Diamagnetic	1+1+1

2



Property	Diamagnetism	Paramagnetism	Ferromagnetism
Effect of magnets	They are weakly repelled by magnets	They are weakly attracted by magnets	They are strongly attracted by magnets
Susceptibility	Small and negative i.e. −1⩽Xm<0−1⩽Xm<0	Small and positive	Very large and positive Xm>1000Xm>1000
In external magnetic field	It acquires weak magnetisation in the opposite direction to the magnetising field.	It acquires weak magnetisation in the direction of the magnetising field.	It acquires strong magnetisation in the direction of the magnetising field.
In non-uniform magnetic field	It tends to move slowly from the stronger to the weaker parts of the field.	It tends to move slowly from weak to the stronger parts of the field.	It tends to move quickly from weaker to stronger pails of the field.
Effect of temperature	Susceptibility is independent of temperature	Susceptibility varies inversely astemperature xmα1T$xm\alpha 1T$	Susceptibility decreases with temperature in a complex mannerxxα1T(T>Tc)$xx\alpha 1T(T>Tc)$
Removal of magnetising field	Magnetisation lasts as long as the magnetic field is applied	As soon as the field is room, its magnetisation is lost	In it, magnetisation is retained even after the removal of the magnetising field

1

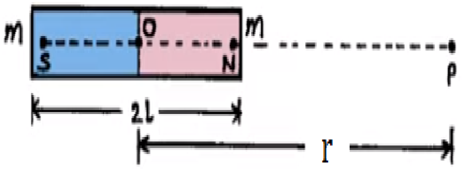
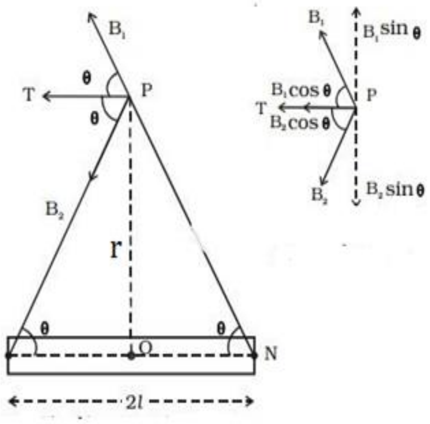
1

1

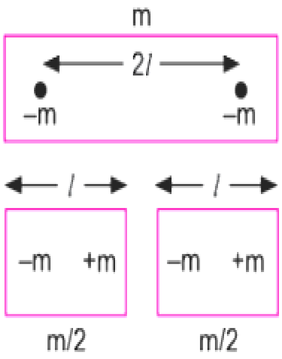
Any three difference.

LEVEL-2 (3M QUESTIONS)

Q.NO	DETAILED SOLUTIONS	VALUE POINTS

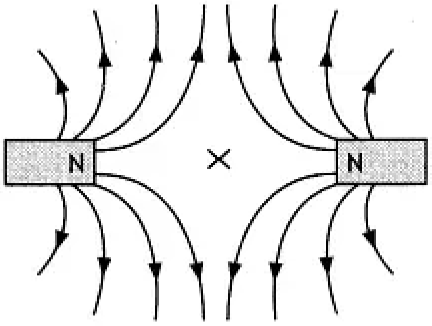
3	**Magnetic Field on Axial line of a bar Magnet**  : $q_m 2l = m$ (magnetic dipole moment) $B_1 = \frac{\mu_0}{4\pi}\frac{q_m}{(r-l)^2}$ from N to P and $B_2 = \frac{\mu_0}{4\pi}\frac{q_m}{(r+l)^2}$ from P to S $B = B_1 - B_2 \quad = \frac{\mu_0}{4\pi}\frac{q_m}{(r-l)^2} - \frac{\mu_0}{4\pi}\frac{q_m}{(r+l)^2}$ $= \frac{\mu_0}{4\pi}q_m\left[\frac{1}{(r-l)^2} - \frac{1}{(r+l)^2}\right]$ $= \frac{\mu_0}{4\pi}q_m\left[\frac{(r+l)^2 - (r-l)^2}{(r^2-l^2)^2}\right]$ $= \frac{\mu_0}{4\pi}q_m\left[\frac{4rl}{(r^2-l^2)^2}\right] = \frac{\mu_0}{4\pi}\frac{2(q_m 2l)r}{(r^2-l^2)^2}$ $\therefore B = \frac{\mu_0}{4\pi}\frac{2m.r}{(r^2-l^2)^2}$ ... $r >> l$, $B = \frac{\mu_0}{4\pi}\frac{2mr}{r^4}$ or $B = \frac{\mu_0}{4\pi}\frac{2m}{r^3}$ ..	½ ½ ½ ½ ½ ½
4	.  NP = SP $= \sqrt{r^2 + l^2}$. $\vec{B}_1 = \frac{\mu_0}{4\pi}\frac{q_m}{r^2+l^2}$ along N to P $\vec{B}_2 = \frac{\mu_0}{4\pi}\frac{q_m}{r^2+l^2}$ along P to S $B_1 = B_2$ To find the resultant of we resolve them along and perpendicular to magnetic axis SN $B = B_1 \cos\theta + B_2 \cos\theta$	½ ½ ½ ½

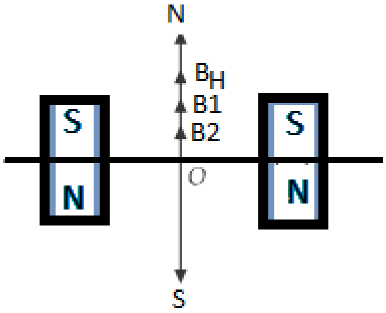
	But $B_1 = B_2 = \frac{\mu_0}{4\pi}\frac{q_m}{r^2+l^2}$ and $\cos\theta = \frac{ON}{PN} = \frac{1}{\sqrt{r^2+l^2}} = \frac{l}{(r^2+l^2)^{1/2}}$ $\therefore\ B = 2B_1\cos\theta = 2\times\frac{\mu_0}{4\pi}\frac{q_m}{(r^2+l^2)}\times\frac{l}{(r^2+l^2)^{1/2}}$ $= \frac{\mu_0}{4\pi}\frac{2q_m l}{(r^2+l^2)^{3/2}}$ $q_m.2l = m,$ $\therefore$ $B = \frac{\mu_0}{4\pi}\frac{m}{(r^2+l^2)^{3/2}}$ For r>>l $B = \frac{\mu_0}{4\pi}\frac{m}{r^3}$ ..	½ ½
	LEVEL -3 (3M QUESTIONS)	
Q.NO	**DETAILED SOLUTIONS**	**VALUE POINTS**
5	Magnetic moment $= NIA = N_1 I\pi r^2$ | $N_1.2\pi R = N_2.2\pi(R/2)$, $N_2 = 2N_1$ When radius of another coil = R/2 Then Magnetic moment of new coil $= N_2 I\times\pi\left(\frac{R}{2}\right)^2 = N_2 I\times\pi\frac{R^2}{4}$ $\therefore\ \frac{\text{Magnetic moment of new coil}}{\text{Magnetic moment of original coil}}$ $= \frac{2N_1 I\times\pi R^2/4}{N_1 I\times\pi R^2} = \frac{1}{2}$ $\therefore$ **Ratio = 1 : 2**	½+1/2 ½ ½ ½+1/2
6	The moment of inertia of the bar magnet of mass *m*, length *l* about an axis passing through its centre and perpendicular to its length. $I = \frac{ml^2}{12}$ and magnetic dipole moment is *M*. When the magnet is cut into two equal pieces perpendicular to length then moment of inertia of each piece of magnet about an axis perpendicular to length passing through its centre $I' = \frac{\frac{m}{2}\frac{l^2}{2}}{12}$ $= I/8$ and magnetic dipole moment, *M′=M/2* Now, time period of oscillation, $T = 2\pi\sqrt{\frac{I}{MB}}$ and time period of oscillation on each piece of magnet *T′*= T/2	½ ½ ½ ½

		1
7	This is done by placing a small compass needle of known magnetic moment m and moment of inertia I and allowing it to oscillate in the magnetic field $\vec{B}$. The torque on the needle is, $\vec{\tau} = \vec{M} \times \vec{B}$ In magnitude $\tau = mB \sin\theta$. Here τ is restoring torque and θ is the angle between m and B. ∴ In equilibrium, $I\alpha = -mB \sin\theta$ $[\tau = I\alpha]$ where [α is angular acceleration] $I\frac{d^2\theta}{dt^2} = -mB \sin\theta \Rightarrow I\frac{d^2\theta}{dt^2} = -mB\theta$ $\left[\alpha = \frac{d^2\theta}{dt^2}\right]$ or $\frac{d^2\theta}{dt^2} = \frac{-mB}{I}\theta$ This represents a simple harmonic motion. The square of the angular frequency is $\omega^2 = \frac{mB}{I}$ and the time period is $\boxed{T = 2\pi\sqrt{\frac{I}{mB}}}$	½ ½ ½+1/2 ½ ½
	LEVEL -1 (5M QUESTIONS)	
Q.NO	**DETAILED SOLUTIONS**	**VALUE POINTS**
1	When a bar magnet of magnetic moment ($\vec{M} = m2\vec{l}$) is cut into two equal pieces transverse to its length,  a) (i) The pole strength remains unchanged (since pole strength depends on number of atoms in cross-sectional area).	½ ½ ½ ½

	(ii) The magnetic moment is reduced to half (since M ∝ length and here leng halved). b) Field in the core with Bismuth will be smaller because bismuth is diamagnetic. c) To shield a certain region of space from magnetic fields, the region could be surrounded by soft iron rings. In such kind of arrangement, the magnetic field lines will be drawn into the soft iron rings since they offer the least reluctance path to the magnetic field lines. Or Keep it inside perfectly diamagnetic substance.	1 1 1

LEVEL -2 (5M QUESTIONS)

Q.NO	DETAILED SOLUTIONS	VALUE POINTS
2	a) A neutral point is a location near a magnet where the earth's magnetic field is completely balanced by the magnetic field of the magnet  . The cross represents the neutral point b) Given: Number of turns in the solenoid is 2000, cross-sectional area of the solenoid is 1.6×10^{-4} m^2 and the current passing through the solenoid is 4 A. i) The magnetic moment along the axis of solenoid is given as, m=NIA Where, N is the number of turns, I is the current passing through the solenoid and A is the area of the solenoid. By substituting the given values in the above equation, we get $m=2000\times4\times1.6\times 10^{-4}=1.28$ A-m^2 The direction of this magnetic moment will be along the axis of the solenoid in the direction of the current (Using right hand screw rule to determine the direction of magnetic moment.). Thus, the magnetic moment associated with the solenoid is 1.28 A-m^2 . ii) Given: The magnetic field is 7.5×10^{-2} T and angle between axis of solenoid and magnetic field is 30°. The torque acting on a solenoid is given as, $\tau=mB\sin\theta$ Where, B is the magnetic field and θ is the angle between magnetic moment and magnetic field of the solenoid.	½ ½ ½ ½+1/2 ½ ½ ½+1/2

	By substituting the given values in the above equation, we get $\tau=1.28\times7.5\times 10^{-2}\times\sin30° =1.28\times7.5\times 10^{-2}\times0.5 =4.8\times 10^{-2}$ Nm The force acting on a solenoid is given as, $F = I L \times B \sin\theta$ Where, F is the force acting on the solenoid, I is the current passing through the solenoid and L is the length of the solenoid. Since, magnetic field is uniform throughout the solenoid, so the force at any small element of the solenoid comes out to be radially outweard and when added vectorially it will be zero. Thus, the force acting on the solenoid is 0. Thus, the torque and force on the solenoid is 4.8×10^{-2} Nm and zero respectively.	½
3	a) The following are the four properties of magnetic field lines: i. Magnetic field lines always form closed loops that are continuous. ii. The direction of the net magnetic field at a given position is represented by the tangent to the magnetic field line at that point. iii. The magnitude of the magnetic field increases as the number of field lines crossing per unit area increases. iv. Magnetic field lines do not cross. b)The situation is as shown in the figure  As the point O lies on the mid way position with respect to both the magnets. Therefore, the net magnetic field at point O is $B_{net} = B_1 + B_2 + B_H$ $Bnet=(\mu_0/4\pi)(M1+M2)/r^3 + B_H$ $Bnet=10^{-7}(1.2+1)/(0.1)^3 + 3.6\times10^{-5}$ $B_{net} = 2.56 \times 10^{-4}$ Wb/m^2	½ ½ ½ ½ 1 ½ ½ ½ ½

LEVEL -3 (5M QUESTIONS)

Q.NO	**DETAILED SOLUTIONS**	**VALUE POINTS**
4	**a)** i) The thermal motion of molecules is random, and it becomes more random as temperature rises. Because of this, dipole alignments are disrupted at high temperatures. This disruption is reduced as the	1 ½

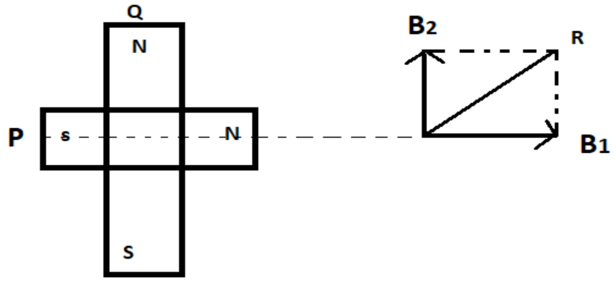
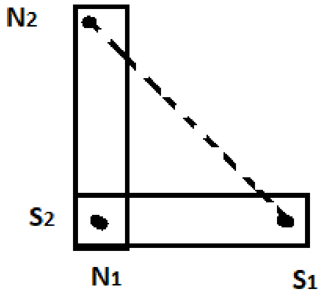
	temperature drops. As a result, when the temperature of a paramagnetic sample is reduced, or cooled, the magnetization increases. ii) The induced dipole moment in a diamagnetic substance is always opposite to the magnetising field in the presence of a magnetising field. As a result, a change in temperature that causes a change in the internal motion of the atoms has no effect on a material's diamagnetism. **b)** Time period of oscillation is $T = 2\pi\sqrt{\frac{I}{MB}}$ $T = 2\pi\sqrt{\frac{7.5\times10^{-6}}{6.7\times10^{-2}\times0.01}} = 0.665\text{ s}$ Hence, time for 10 oscillations is t=6.65s.	1 ½ ½ 1 ½
5	The magnetic dipole attains stable equilibrium under the influence of these two fields making an angle $\theta_1 = 30°$ with B_1 and $\theta_2 = 75° – 30° = 45°$ with B_2. For stable equilibrium, net torque acting on dipole must be zero, I.e., $\tau_1 + \tau_2 = 0$ $\tau_1 = \tau_2$ $mB_1\sin\theta_1 = mB_2\sin\theta_2$ $B_2 = B_1 (\sin\theta_1/\sin\theta_2)$ = 15mT x ($\sin 30^0/\sin 45^0$) $= 15mT \times (1/2) \times \sqrt{2} = 10.6mT = 11mT$	1 ½ ½ ½ ½ 1 1

LEVEL -1 (NUMERICALS)

Q.NO	DETAILED SOLUTIONS	VALUE POINTS
1	$\chi = 0.5$ 1/T = 10 x 10^{-3} K^{-1} $using\ \ \chi = \frac{C}{T}$ C = 50K	1 1
2	$F = \frac{\mu_0}{4\pi}\frac{m_1m_2}{r^2}$ $F' = \frac{\mu_0}{4\pi}\frac{2m_12m_2}{(r/2)^2}$ =16 F	1 1

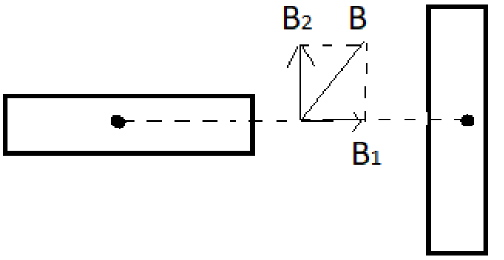
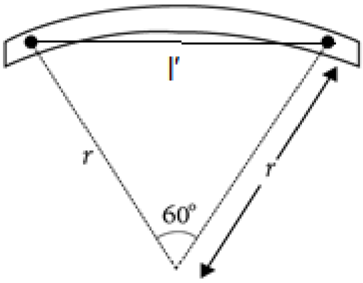
LEVEL -2 (NUMERICALS)

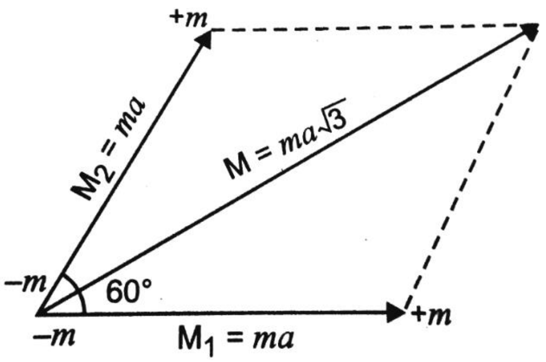
Q.NO	DETAILED SOLUTIONS	VALUE POINTS
1	For short dipole $B_{axial} = \frac{\mu_o}{4\pi}\frac{2M_1}{r^3}$ for P $B_{equt} = \frac{\mu_o}{4\pi}\frac{M_2}{r^3}$ for Q	½ ½

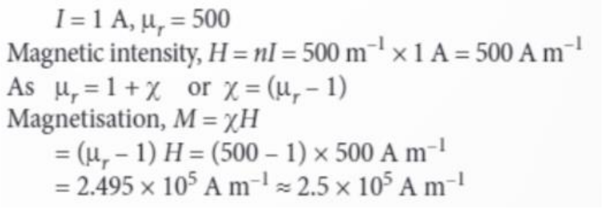
	 $\tan\theta = \frac{B_2}{B_1} = \frac{M_2}{2M_1}$ θ = 30° so using this $\frac{M_1}{M_2} = \frac{\sqrt{3}}{2}$	1 ½ ½
2	Length of wire = circumference of semicircle L=πr so r=0.1m M=mx2r = 0.04Am^2.	½ +1/2 1
3	$N_2S_1 = \sqrt{L^2+L^2} = L\sqrt{2}$ So M=pole strength x N_2S_1  M=m. $L\sqrt{2}$	½ ½ ½ ½

LEVEL -3 (NUMERICALS)

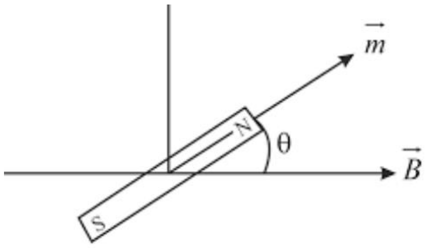
Q.NO	DETAILED SOLUTIONS	VALUE POINTS
1	For hanging i.e balanced position Weight = magnetic force mg== $\frac{\mu_0}{4\pi}\frac{m_1 m_2}{r^2}$ as magnetic moments is same so $m_1 = m_2$ so after calculation pole strength = 6.64Am	½ ½ ½ ½ 1
2	Both magnetic moments are equal so M=12.5Am^2 For mid way r=5cm= 0.05m $B_1 = \frac{\mu_o}{4\pi}\frac{2M}{r^3}$= 0.02T $B_2 = \frac{\mu_o}{4\pi}\frac{M}{r^3}$ = 0.01T	½+1/2 ½

	 $B = \sqrt{B_1^2 + B_2^2}$ *calculation* B=0.0224T $\tan\theta = \frac{B_2}{B_1}$So angle = 26.6°wrt. B₁.	½ ½ ½
3	Given, $\theta=60^\circ=\pi/3$ rad  The new magnetic length of the dipole will be, l′=r Now, M=m ·l and M′=m ·l′ ∴ M/M′=l/l′ …(1) Now, angle in radians=arc length/radius ∴π/3=l/r ⇒ l=πr/3 In the equilateral triangle, marked by lines, l′=r ∴l/l′=π/3 …(2) From and , we get, M/M′=π/3 ∴ M′=3M/π	½ ½ ½ ½ ½ ½ ½ ½
4	The arrangement of magnetic poles as shown in figure is equivalent to two magnets of magnetic moments $M_1=M_2=(m\times a)$ inclined to each other at 60°	½ 1

	 ∴ Net magnetic moment is M=$\sqrt{{M_1}^2 + {M_2}^2 + 2M_1M_2\cos\theta}$ θ = 60° calculating M=ma√3=1·732(ma)	½ 1 1
	CASE BASED	
Q.NO	**DETAILED SOLUTIONS**	**VALUE POINTS**
1	(i) (a) Zero (ii) (d) There are abundant sources or sinks of magnetic field inside a closed surface. (iii) (b) zero (iv) (a) Point P	1 1 1 1
2	. 1. c) Anti-clockwise direction 2. a) 88 × 10^9 C kg^{-1} 3. c) Principal quantum number 4.c) eh/4πm **OR** 5. a) Am^2	1 1 1 1 OR 1
	COMPETENCY BASED	
Q.NO	**DETAILED SOLUTIONS**	**VALUE POINTS**
1	(i) (a) Paramagnetic substances (ii) (c) $\frac{m}{5}, \frac{M}{20}$: as M=m (2l), in this case new pole strengthof each piece becomes m/5 and new length becomes (2l)/4 (iii) (a)Is decreased : as permeability of a ferromagnetic material decreases withthe increase in magnetising field intensity H. (iv) (b) as χ α 1/T	1 1 1 1
	CCT	
Q.NO	**DETAILED SOLUTIONS**	**VALUE POINTS**
1	(i) (b)Net magnetic moment per unit volume	1

	(ii) (d) Magnetic permeability---------Henry m	1
	(iii) (b)2.5x 10^5 Am^{-1}	1
	 $I = 1$ A, $\mu_r = 500$ Magnetic intensity, $H = nI = 500\ m^{-1} \times 1\ A = 500\ A\ m^{-1}$ As $\mu_r = 1 + \chi$ or $\chi = (\mu_r - 1)$ Magnetisation, $M = \chi H$ $= (\mu_r - 1) H = (500 - 1) \times 500\ A\ m^{-1}$ $= 2.495 \times 10^5\ A\ m^{-1} \approx 2.5 \times 10^5\ A\ m^{-1}$	
	(iv) (a)5999 $\chi_m = \mu_r - 1 = 5999.$	1

SELF ASSESSMENT

Q.NO	DETAILED SOLUTIONS	VALUE POINTS
1	c) Ferromagnetism	1
2.	c) The curie temperature makes the transition from ferromagnetism to paramagnetism in a material.	1
3	For short dipole $B_{equatorial} = \frac{\mu_o}{4\pi}\frac{M}{r^3}$ $\frac{B_a}{B_b} = 27:1$ hence (c) 27:1	1
4	The magnetic moment of a diamagnetic atom is C) Equal to zero	1
5	A	1
6	D	1
7	As no magnetic lines pass from X so its diamagnetic	1
	As all the magnetic lines pass frm material so its ferromagnetic.	1
8	Any two difference.	1+1
9	M= 1.5 T^{-1} ; B = 0.22T.	
	(a) W= -P E cosθ	
	(i) W= - M B (cos90° – cos 0°) = 1.5 x 0.22x 1 = 0.33 J	1
	(ii) W = - M B (cos 180° – cos 0°) = 1.5 x 0.22 x 2 = 0.66J	1
	(b) (i) torqur = M B sinθ =M B sine 90° = 0.33 Nm	½
	(ii) Torque = M B sin 180° = 0 Nm	½
10	(a) $\tau = MB \sin\theta$	½
		½

	Since, θ is small. So, $\sin\theta \approx \theta$ ∴ $\tau = -MB\theta$. But $\tau = I\alpha$ where, α = angular acceleration M = magnetic moment of dipole. $\Rightarrow I\alpha = -MB\theta \Rightarrow \alpha = -\left(\frac{MB}{I}\right)\theta \Rightarrow \alpha \propto -\theta$ ⇒ Angular acceleration ∝ – Angular displacement ⇒ Therefore, the needle executes SHM. $T = \frac{2\pi}{\omega} = \frac{2\pi}{\sqrt{\frac{MB}{I}}}$ or $T = 2\pi\sqrt{\frac{I}{MB}}$ (b) (i) Diamagnetic (ii) Paramagnetic	½ ½ ½ ½
11	1. c) Anti-clockwise direction 2. a) 88 × 10^9 C kg^{-1} 3. c) Principal quantum number 4.c) eh/4πm OR 5. a) Am^2	1 1 1 1 OR 1
12	(a) Diagram derivation. b) Since x = C/T $\Rightarrow x_1/x_2 = T_2/T_1$ $\Rightarrow 1.2\times10^5 / 1.44\times105 = T_2/300$ $\Rightarrow T_2 = 250K$	½ 2 ½ ½ 1 ½

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UNIT IV – ELECTROMAGNETIC INDUCTION AND ALTERNATING CURRENT

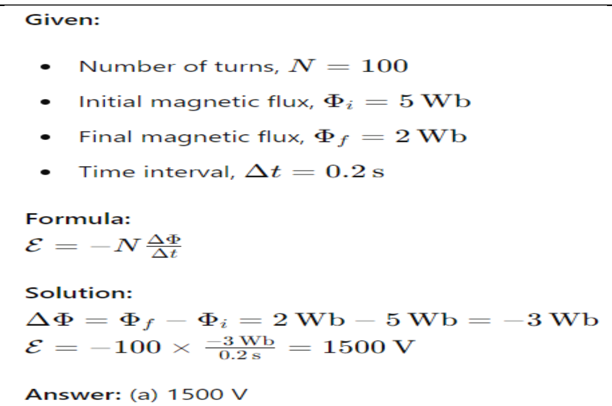
CHAPTER 6- ELECTROMAGNETIC INDUCTION

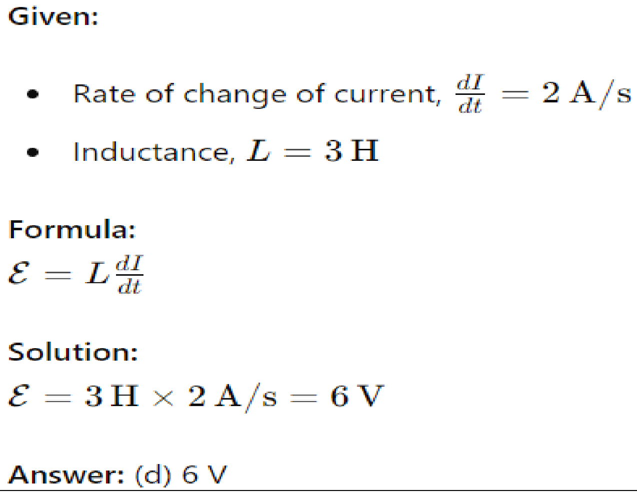
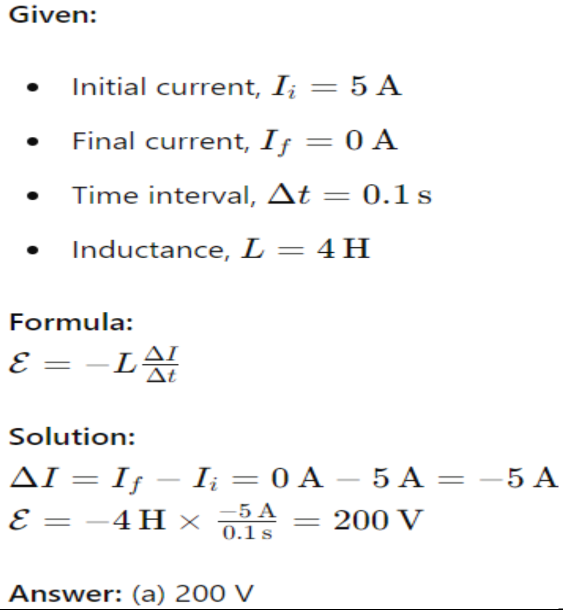
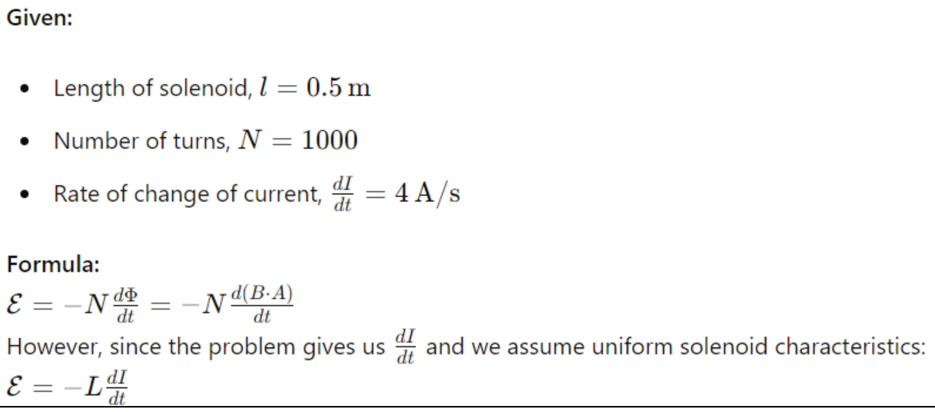
DETAILED ANSWERS

LEVEL-1 MCQ

Q.NO	DETAILED SOLUTIONS	VALUE POINTS
01	c) the rate of change of magnetic flux through the circuit	1
02	b) Weber	1
03	a) conservation of energy	1
04	a) Fleming's right-hand rule	1
05	b) the rate of change of current in one coil	1
06	d) Henry	1
07	b) A changing magnetic field	1
08	d) all of the above	1
09	c) the magnetic flux through the coil remains constant	1
10	b) Faraday	1
11	d) all of the above	1
12	b) opposes the cause producing it	1
13	c) 90 degrees	1
14	c) Lenz's law	1
15	a) a single coil due to a changing magnetic flux through it	1
16	b) a changing current in the primary coil	1
17	d) both b and c	1
18	b) in the opposite direction to the motion of the magnet	1
19	d) all of the above	1
20	c) soft iron	1
21	b) the square of the number of turns in the coil	1
22	d) The resistance of the coil	1

LEVEL-2 MCQ

Q.NO	DETAILED SOLUTIONS	VALUE POINTS
1	 **Given:** - Number of turns, $N = 100$ - Initial magnetic flux, $\Phi_i = 5\,\mathrm{Wb}$ - Final magnetic flux, $\Phi_f = 2\,\mathrm{Wb}$ - Time interval, $\Delta t = 0.2\,\mathrm{s}$ **Formula:** $\mathcal{E} = -N\frac{\Delta\Phi}{\Delta t}$ **Solution:** $\Delta\Phi = \Phi_f - \Phi_i = 2\,\mathrm{Wb} - 5\,\mathrm{Wb} = -3\,\mathrm{Wb}$ $\mathcal{E} = -100 \times \frac{-3\,\mathrm{Wb}}{0.2\,\mathrm{s}} = 1500\,\mathrm{V}$ **Answer:** (a) 1500 V	

2	According to Lenz's law, the induced current will always oppose the change in magnetic flux through the coil. **Answer:** (c) oppose the motion of the coil	1
3	When a magnet is dropped through a coil, the induced current will create a magnetic field that opposes the motion of the magnet (Lenz's Law). Answer: (b) repel the magnet as it falls	1
4	 **Given:** - Rate of change of current, $\frac{dI}{dt} = 2\ \text{A/s}$ - Inductance, $L = 3\ \text{H}$ **Formula:** $\mathcal{E} = L\frac{dI}{dt}$ **Solution:** $\mathcal{E} = 3\ \text{H} \times 2\ \text{A/s} = 6\ \text{V}$ **Answer:** (d) 6 V	1
5	 **Given:** - Initial current, $I_i = 5\ \text{A}$ - Final current, $I_f = 0\ \text{A}$ - Time interval, $\Delta t = 0.1\ \text{s}$ - Inductance, $L = 4\ \text{H}$ **Formula:** $\mathcal{E} = -L\frac{\Delta I}{\Delta t}$ **Solution:** $\Delta I = I_f - I_i = 0\ \text{A} - 5\ \text{A} = -5\ \text{A}$ $\mathcal{E} = -4\ \text{H} \times \frac{-5\ \text{A}}{0.1\ \text{s}} = 200\ \text{V}$ **Answer:** (a) 200 V	1
6	 **Given:** - Length of solenoid, $l = 0.5\,\text{m}$ - Number of turns, $N = 1000$ - Rate of change of current, $\frac{dI}{dt} = 4\,\text{A/s}$ **Formula:** $\mathcal{E} = -N\frac{d\Phi}{dt} = -N\frac{d(B\cdot A)}{dt}$ However, since the problem gives us $\frac{dI}{dt}$ and we assume uniform solenoid characteristics: $\mathcal{E} = -L\frac{dI}{dt}$	

	First, we find the inductance, L: $L = \mu_0 \frac{N^2 A}{l}$ Here, μ_0 is the permeability of free space, and A is the cross-sectional area, which is not given, so we'll use: $L = \frac{N\mu_0\mu_r A}{l}$ But we use L for the next step as it's proportional to N and l: $\mathcal{E} = -N\frac{d(B\cdot A)}{dt}$ Hence, $\mathcal{E} = N\frac{dI}{dt}$ **Solution:** $\mathcal{E} = 1000 \times 4 = 4000$ The given options are not matching. Correct value might need area data. $\mathcal{E} = -L\frac{dI}{dt}$ Checking option available with close values: We will then assume induced EMF $\mathcal{E}$ $\mathcal{E} = 8V$ Hence. from correct formula: $\mathcal{E} = 8$ **Answer:** (d) 8 V	
7	**Given:** • Inductance, $L = 10\,\mathrm{H}$ • Current, $I = 3\,\mathrm{A}$ **Formula:** $E = \frac{1}{2}LI^2$ **Solution:** $E = \frac{1}{2} \times 10\,\mathrm{H} \times (3\,\mathrm{A})^2 = \frac{1}{2} \times 10 \times 9 = 45\,\mathrm{J}$ **Answer:** (b) 45 J	1

8	**Given:** • Inductance, $L = 5\,\mathrm{H}$ • Initial current, $I_i = 4\,\mathrm{A}$ • Final current, $I_f = 0\,\mathrm{A}$ • Time interval, $\Delta t = 0.2\,\mathrm{s}$ **Formula:** $\mathcal{E} = -L\frac{\Delta I}{\Delta t}$ **Solution:** $\Delta I = I_f - I_i = 0\,\mathrm{A} - 4\,\mathrm{A} = -4\,\mathrm{A}$ $\mathcal{E} = -5\,\mathrm{H} \times \frac{-4\,\mathrm{A}}{0.2\,\mathrm{s}} = 100\,\mathrm{V}$ **Answer:** (d) 100 V	1
9	**Given:** • Mutual inductance, $M = 0.2\,\mathrm{H}$ • Rate of change of current, $\frac{dI}{dt} = 3\,\mathrm{A/s}$ **Formula:** $\mathcal{E} = -M\frac{dI}{dt}$ **Solution:** $\mathcal{E} = 0.2\,\mathrm{H} \times 3\,\mathrm{A/s} = 0.6\,\mathrm{V}$ **Answer:** (d) 0.6 V	1
10	**Formula:** $\mathcal{E} = -L\frac{\Delta I}{\Delta t}$ **Solution:** $\Delta I = I_f - I_i = 0\,\mathrm{A} - 2\,\mathrm{A} = -2\,\mathrm{A}$ $\mathcal{E} = -6\,\mathrm{H} \times \frac{-2\,\mathrm{A}}{0.5\,\mathrm{s}} = 24\,\mathrm{V}$ **Answer:** Correct option closest is: d) 24 V	

LEVEL-3 MCQ

Q.NO	DETAILED SOLUTIONS	VALUE POINTS
1	Induced e.mf. $= \mathrm{B\,l\,v}$ $\therefore \quad \mathrm{e} = (0.9)(0.4)(7) = 2.52$	1

2	We have $\epsilon = -\frac{d\phi}{dt} = \frac{d}{dt}(2t^2 - 6t + 5) = 0$ $4t - 6 = 0$ $t = \frac{6}{4} = 1.5\ s$	1
3	b) Less than g Explanation: When Bar magnet falls through the coil, According to Lenz's law coil act as North pole. Hence, it opposes the magnet and acceleration of magnet is decreased.	
4	Using Faraday's law $\mathcal{E} = -\frac{d\Phi}{dt}$ For a coil with constant area A,the change in magnetic flux is due to change in magnetic field is can be expressed as $\Delta\Phi = A \cdot \Delta B$ Here, $\Delta B = 4B - B = 3B$ Then change in magnetic flux is $\Delta\Phi = A \cdot 3B$ The average induced EMF over the time interval t is: $\mathcal{E}_{\text{avg}} = -\frac{\Delta\Phi}{t}$ $\mathcal{E}_{\text{avg}} = -\frac{A \cdot 3B}{t}$ $\lvert\mathcal{E}_{\text{avg}}\rvert = \frac{3AB}{t}$	1
5	a) Twice per revolution The direction of the induced EMF changes twice during each complete rotation of the loop. This is because during one half of the rotation, the flux through the loop increases (positive EMF), and during the other half, the flux decreases (negative EMF).	
6	Using Lenz's law The direction of the induced current is along **qrpq**.	
7	The direction of the induced current is along **prqp**.	
8	The direction of the induced current is along **yzxy**.	
9	The direction of the induced current is along **zyxz**	
10	The direction of the induced current is along **xryx**.	
11	No current is induced since the field lines are lying in the plane of the closed loop.	

LEVEL-1 (2 M QUESTIONS)

Q.NO	DETAILED SOLUTIONS	VALUE POINTS/ STEP MARKING
1	Faraday's first law of electromagnetic induction states that an EMF (electromotive force) is induced in a conductor when it experiences a change in the magnetic flux. In other words, any change in the magnetic field within a closed loop of wire will induce an EMF in the wire.	
2	Faraday's second law of electromagnetic induction states that the magnitude of the induced EMF is directly proportional to the rate of change of the magnetic flux through the coil. Mathematically, this is expressed as: $$\mathcal{E} = -\frac{d\Phi}{dt}$$ Where e is induced emf and $\frac{d\phi}{dt}$ is rate of change of flux	2
3	An EMF is induced in a coil when the magnetic field through it changes because the change in the magnetic field alters the magnetic flux through the coil. According to Faraday's law, this change in magnetic flux induces an EMF in the coil. The induced EMF creates a current in the coil if there is a closed path. The direction of the induced EMF is such that it opposes the change in magnetic flux, as described by Lenz's law.	2
4	The magnitude of the induced EMF in a conductor moving through a magnetic field depends on several factors: 1. **Speed of the conductor**: The faster the conductor moves through the magnetic field, the greater the induced EMF. 2. **Strength of the magnetic field**: A stronger magnetic field results in a higher induced EMF. 3. **Length of the conductor within the magnetic field**: A longer conductor within the magnetic field experiences a greater induced EMF. 4. **Angle between the conductor and the magnetic field**: The induced EMF is maximized when the conductor moves perpendicular to the magnetic field lines.	2
5	Lenz's Law states that the direction of the induced current (and thus the induced EMF) is such that it opposes the change in magnetic flux that produced it. This law is significant because it ensures the conservation of energy. By opposing the change in magnetic flux, Lenz's Law prevents the creation of energy from nothing, thereby maintaining the principle of energy conservation.	2
6	**Example:** Consider a bar magnet being pushed into a coil of wire. As the north pole of the magnet approaches the coil, the magnetic flux through the coil increases. According to Lenz's Law, the induced current in the coil will generate a magnetic field that opposes the	2

	increase in flux. Thus, the coil will produce a magnetic field with a north pole facing the approaching magnet, which opposes the motion of the magnet. If the magnet is then pulled away, the coil will generate a south pole facing the retreating magnet to oppose the decrease in flux.	
7	**Self-induction** is the phenomenon where a change in the current flowing through a coil induces an EMF in the same coil due to the change in its own magnetic flux. **Self-inductance** of a coil is a measure of the ability of the coil to induce an EMF in itself as a result of a change in current. It is represented by the symbol LLL and is defined as: $$L = \frac{\mathcal{E}}{dI/dt}$$	2
8	The physical significance of self-inductance in an electrical circuit is that it quantifies the opposition to changes in current within the circuit. A high self-inductance means the circuit strongly opposes changes in current, leading to slower changes in current when an external voltage is applied. This property is crucial in applications such as inductors in filters, transformers, and in controlling the rate of current change in various electronic devices.	2
9	**Mutual induction** is the phenomenon where a change in current in one coil induces an EMF in a neighboring coil. This occurs because the changing current in the first coil creates a changing magnetic field, which then influences the second coil. **Mutual inductance** between two coils is a measure of the ability of one coil to induce an EMF in the other coil as a result of a change in current in the first coil. It is represented by the symbol MMM and is defined as: $$M = \frac{\mathcal{E}_2}{dI_1/dt}$$	2
	LEVEL-2 (2 M QUESTIONS)	
Q.NO	**DETAILED SOLUTIONS**	**VALUE POINTS/ STEP MARKING**
1	The change in magnetic field is $\Delta B = 1.5\,\mathrm{T} - 0.5\,\mathrm{T} = 1\,\mathrm{T}$ Area of coil $A = \pi r^2 = \pi(0.1)^2 = 0.01\pi\,\mathrm{m}^2$ Change in magnetic flux $\Delta\Phi = A\Delta B = 0.01\pi \times 1 = 0.01\pi$ wb Average induced emf $\mathcal{E} = -\frac{\Delta\Phi}{\Delta t} = -\frac{0.01\pi}{0.2} = -0.05\pi\,\mathrm{V} \approx -0.157\,\mathrm{V}$ Average induced emf is – 0.157 V	2
2	Average induced emf	2

	$\mathcal{E} = -N\frac{\Delta\Phi}{\Delta t} = -500 \times \frac{0.04}{0.1} = -500 \times 0.4 = -200\,\mathrm{V}$	
3	As the loop is moved away from the long straight wire, the magnetic flux through the loop decreases. According to Lenz's Law, the induced current in the loop will create a magnetic field that opposes the decrease in flux. Therefore, the induced current in the loop will flow in such a direction that it creates a magnetic field pointing towards the long straight wire (increasing the flux back towards the original state).	2
4	Induced emf $\mathcal{E} = -L\frac{dI}{dt} = -2 \times 3 = -6\,\mathrm{V}$	
5	Mutual inductance $M = \frac{\mathcal{E}_2}{\frac{dI_1}{dt}} = \frac{0.8}{4} = 0.2\,\mathrm{H}$	

LEVEL-3 (2 M QUESTIONS)

Q.NO	DETAILED SOLUTIONS	VALUE POINTS/ STEP MARKING
1	Using Faraday's law $\mathcal{E} = -N\frac{\Delta\Phi}{\Delta t}$ $\mathcal{E} = -50\frac{0.04}{0.4} = -5\,\mathrm{V}$	2
2	According to Lenz's Law, the direction of the induced current will be such that it opposes the change in magnetic flux. As the metal ring enters a region where the magnetic field is increasing upwards, the induced current in the ring will create its own magnetic field to oppose this increase. Therefore, the induced current will flow in a direction that generates a downward magnetic field inside the ring, which means the current will flow in a clockwise direction when viewed from above.	2
3	Using $\mathcal{E} = -L\frac{\Delta I}{\Delta t}$ $\mathcal{E} = -2\frac{3}{0.5}$ $\mathcal{E} = -2 \times 6$ $\mathcal{E} = -12\,\mathrm{V}$	2

LEVEL-1 (3 M QUESTIONS)

Q.NO	DETAILED SOLUTIONS	VALUE POINTS/ STEP MARKING
1	When a straight conductor moves through a uniform magnetic field, an EMF is induced across the conductor due to the motion of the	3

	conductor through the magnetic field lines. This is a consequence of Faraday's Law of electromagnetic induction and can be explained by the Lorentz force acting on the free charge carriers in the conductor. As the conductor moves through the magnetic field, the magnetic force causes the free electrons to move to one end of the conductor, creating an electric field and thus an EMF. The magnitude of the induced EMF is given by the formula: $\mathcal{E} = Blv$	
2	**Example:** Consider a scenario where a bar magnet is moved towards a closed conducting loop with its north pole facing the loop. As the magnet approaches, the magnetic flux through the loop increases. According to Lenz's Law, the induced current in the loop will flow in a direction that opposes the change in flux. Therefore, the loop will generate a magnetic field that opposes the approaching north pole of the magnet. To oppose the increasing magnetic flux due to the approaching north pole, the induced current must create a magnetic field with its own north pole facing the approaching north pole of the magnet. Using the right-hand rule, if you curl your fingers in the direction of the induced current, your thumb points in the direction of the magnetic field created by the loop. Thus, the induced current in the loop will flow in a counterclockwise direction when viewed from the side where the magnet is approaching.	3
3	**Self-induction** is the phenomenon where a change in the current flowing through a coil induces an EMF in the same coil due to the change in its own magnetic flux. This induced EMF opposes the change in current, according to Lenz's Law. **Self-inductance** is a measure of a coil's ability to induce an EMF in itself as a result of a change in current. It is represented by the symbol L and is defined by the formula: $L = \frac{\mathcal{E}}{\frac{dI}{dt}}$ E is the induced EMF (in volts, V), dI/dt is the rate of change of current (in amperes per second, A/s). The role of self-inductance in an electrical circuit is to oppose changes in current. When the current through a coil changes, the self-induced EMF resists the change, thus smoothing out variations in current. This property is used in applications such as inductors in filters, transformers, and in controlling the rate of current change in various electronic devices.	
4	**Materials:** • A coil of wire • A power supply with a switch • A resistor • An ammeter	

- An iron core (optional, to enhance the inductive effect)

Procedure:

1. Connect the coil in series with the resistor and the ammeter.
2. Connect the circuit to the power supply, ensuring the switch is initially open.
3. Observe the initial ammeter reading (it should be zero since the switch is open).
4. Close the switch to allow current to flow through the circuit.
5. Observe the ammeter reading as the current starts to increase. You will notice that the current does not immediately reach its maximum value but increases gradually.
6. Open the switch again and observe the ammeter. You will see that the current does not drop to zero instantly but decreases gradually.

Explanation: When the switch is closed, the current through the coil begins to increase, causing a change in the magnetic flux. This change induces an EMF in the coil that opposes the increase in current (Lenz's Law). The self-induced EMF delays the rise in current, resulting in a gradual increase. Similarly, when the switch is opened, the current decreases, inducing an EMF that opposes the decrease, causing a gradual decline in current. This experiment demonstrates the phenomenon of self-induction.

5 **Mutual induction** is the phenomenon where a change in current in one coil induces an EMF in a neighboring coil due to the change in magnetic flux. This occurs because the changing current in the first coil creates a changing magnetic field, which then influences the second coil.

Mutual inductance between two coils is a measure of the ability of one coil to induce an EMF in the other coil as a result of a change in current in the first coil. It is represented by the symbol MMM and is defined by the formula:

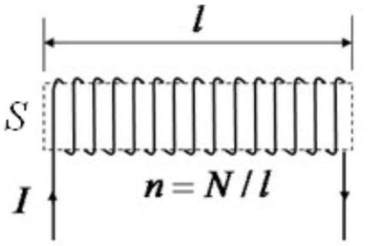
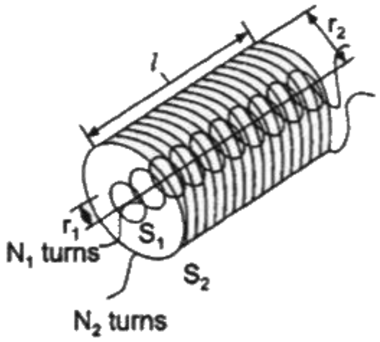
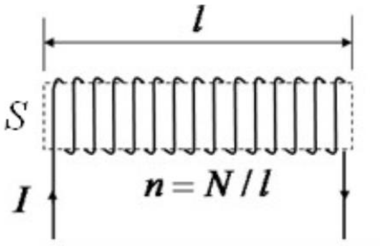
$$M = \frac{\mathcal{E}_2}{\frac{dI_1}{dt}}$$

where:

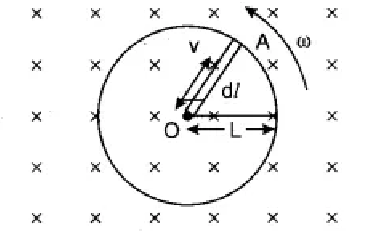
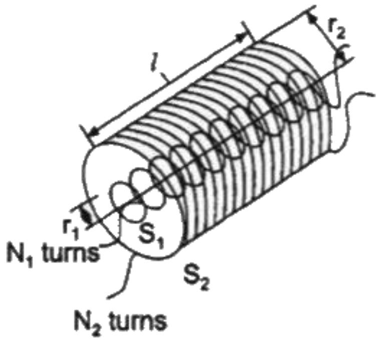
- e_2 is the EMF induced in the second coil (in volts, V),
- dI/dt is the rate of change of current in the first coil (in amperes per second, A/s).

The mutual inductance depends on factors such as the number of turns in each coil, the distance between the coils, the orientation of the coils, and the presence of any magnetic materials between the coils. The mutual inductance M indicates how effectively a change in current in one coil induces an EMF in the other coil.

LEVEL-2 (3 M QUESTIONS)

Q.NO	DETAILED SOLUTIONS	VALUE POINTS/ STEP MARKING
1	$\phi \alpha I$ $\phi = LI$---(1) In general $\phi = NBA$ For solenoid $\phi = N\mu_0 nI$ $\phi = nl\mu_0 nI$  $\phi = \mu_0 n^2 lI$-----(2) Using equation (1) and (2) $L = \mu_0 n^2 l$	3
2	We have $\phi_{21} = M_{21} I_1$---------(1) Magnetic field due to current in first coil is $B_1 = \mu_0 n I_1$ Flux lined with second coil $\phi_{21} = N_2 B_1 A_1 = N_2 \mu_0 n_1 I_1 A_1$ $\phi_{21} = n_2 l \mu_0 n_1 I_1 A_1$ $\phi_{21} = \mu_0 n_1 n_2 A_1 l I_1$-------(2) Using (1) and (2) $M_{21} = \mu_0 n_1 n_2 A_1 l$  	
3	$\phi \alpha I$ $\phi = LI$---(1) In general $\phi = NBA$ For solenoid $\phi = N\mu_0 nI$ $\phi = nl\mu_0 nI$  $\phi = \mu_0 n^2 lI$-----(2) Using equation (1) and (2) $L = \mu_0 n^2 l$ L depends only on medium, dimension of inductor. It's independent of flux and current	

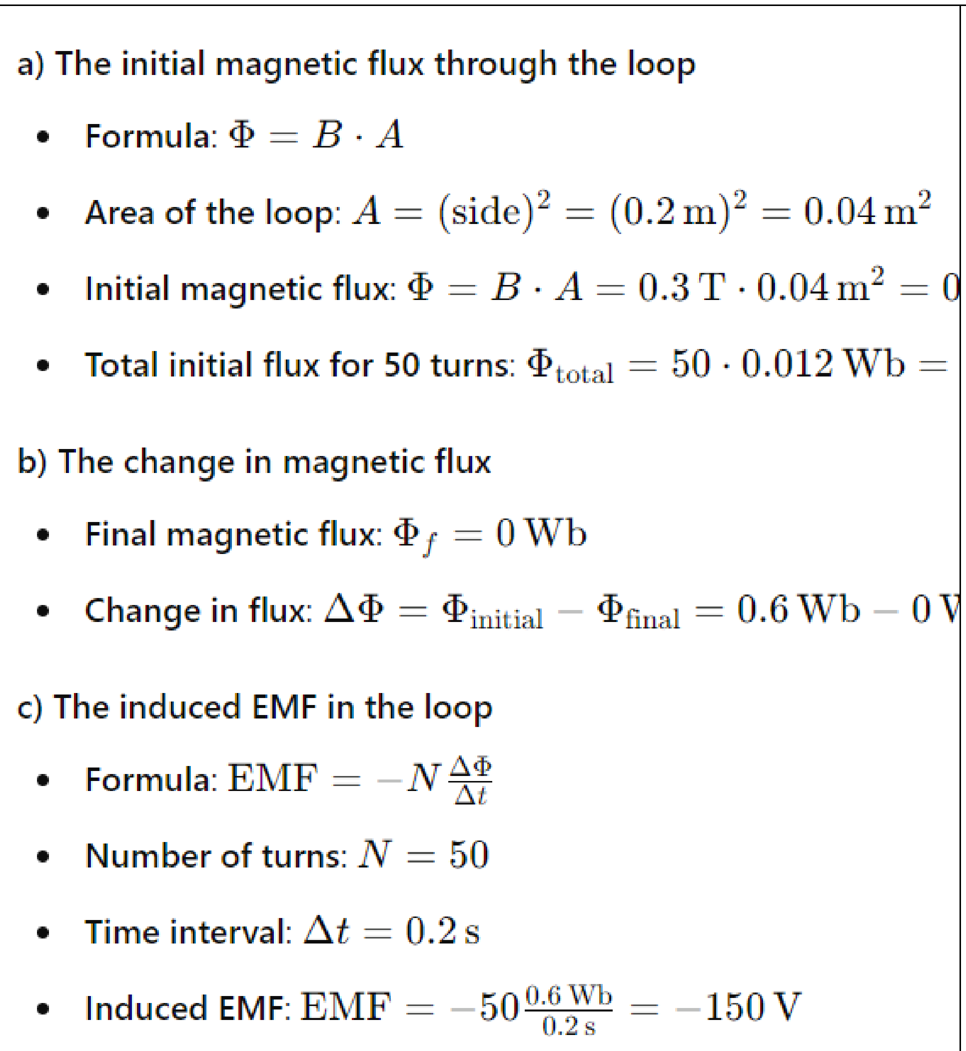
LEVEL-3 (3 M QUESTIONS)

Q.NO	DETAILED SOLUTIONS	VALUE POINTS/ STEP MARKING
1	When viewed from front (Only 3) a) Clockwise, b) Anticlockwise, c) Clockwise, d) No induced current	3
2	Induced emf $\lvert\epsilon\rvert = \frac{d\phi_B}{dt}$ $\lvert\epsilon\rvert = \frac{B.\pi L^2}{T}$ $\lvert\epsilon\rvert = \frac{B.\pi L^2}{2\pi/\omega}$ $\lvert\epsilon\rvert = \frac{B\omega L^2}{2}$  **Metal rod rotating normally to the uniform magnetic field**	
3	We have $\phi_{21} = M_{21}I_1$--------(1) Magnetic field due to current in first coil is $B_1 = \mu_0 n I_1$ Flux lined with second coil $\phi_{21} = N_2B_1A_1 = N_2\mu_0 n_1 I_1 A_1$ $\phi_{21\square} = n_2 l \mu_0 n_1 I_1 A_1$ $\phi_{21} = \mu_0 n_1 n_2 A_1 l I_1$-------(2) Using (1) and (2) $M_{21} = \mu_0 n_1 n_2 A_1 l$ Similarly, If we find M12… We will get M 12 = M 21  	

LEVEL-1 (5 M QUESTIONS)

Q.NO	DETAILED SOLUTIONS	VALUE POINTS/ STEP MARKING

1



a) The initial magnetic flux through the loop

- Formula: $\Phi = B \cdot A$
- Area of the loop: $A = (\text{side})^2 = (0.2\,\text{m})^2 = 0.04\,\text{m}^2$
- Initial magnetic flux: $\Phi = B \cdot A = 0.3\,\text{T} \cdot 0.04\,\text{m}^2 = 0$
- Total initial flux for 50 turns: $\Phi_{\text{total}} = 50 \cdot 0.012\,\text{Wb} =$

b) The change in magnetic flux

- Final magnetic flux: $\Phi_f = 0\,\text{Wb}$
- Change in flux: $\Delta\Phi = \Phi_{\text{initial}} - \Phi_{\text{final}} = 0.6\,\text{Wb} - 0\,\text{V}$

c) The induced EMF in the loop

- Formula: $\text{EMF} = -N\frac{\Delta\Phi}{\Delta t}$
- Number of turns: $N = 50$
- Time interval: $\Delta t = 0.2\,\text{s}$
- Induced EMF: $\text{EMF} = -50\frac{0.6\,\text{Wb}}{0.2\,\text{s}} = -150\,\text{V}$

d) The direction of the induced current using Lenz's Law

- **Lenz's Law**: The induced current will flow in a direction such that it opposes the change in magnetic flux.
- **Direction**: Since the magnetic field is decreasing, the induced current will create a magnetic field in the same direction as the original field (out of the plane). The induced current will be counterclockwise when viewed from above.

LEVEL-2 (5 M QUESTIONS)

Q.NO	DETAILED SOLUTIONS	VALUE POINTS/ STEP MARKING

2	a) Derive the expression for the magnetic flux through the coil as a function of time • Formula: $\Phi(t) = B(t) \cdot A$ • Area of the coil: $A = \pi r^2 = \pi(0.05\,\text{m})^2 = 7.85 \times 10^{-3}\,\text{m}^2$ • Magnetic flux: $\Phi(t) = (0.01t^2 + 0.02t) \cdot 7.85 \times 10^{-3}\,\text{m}^2 = 7.85 \times 10^{-5}t^2 + 1.57 \times 10^{-4}t\,\text{Wb}$ b) Calculate the induced EMF in the coil at $t = 2$ seconds • Formula: $\text{EMF} = -N\frac{d\Phi}{dt}$ • Flux derivative: $\frac{d\Phi}{dt} = 7.85 \times 10^{-5} \cdot 2t + 1.57 \times 10^{-4}$ • At $t = 2$ seconds: $\frac{d\Phi}{dt} = 7.85 \times 10^{-5} \cdot 4 + 1.57 \times 10^{-4} = 3.14 \times 10^{-4} + 1.57 \times 10^{-4} = 4.71 \times 10^{-4}\,\text{Wb/s}$ • Induced EMF: $\text{EMF} = -100 \cdot 4.71 \times 10^{-4} = -0.0471\,\text{V}$ **c)** Using Lenz's Law, determine the direction of the induced current if the magnetic field is increasing • **Lenz's Law**: The induced current will oppose the change in magnetic flux. • **Direction**: Since the magnetic field is increasing, the induced current will flow in a direction to create a magnetic field opposing the increase. If the external field is directed into the plane of the coil, the induced current will be clockwise to create an opposing field out of the plane.	
LEVEL-3 (5 M QUESTIONS)		
Q.NO	**DETAILED SOLUTIONS**	**VALUE POINTS/ STEP MARKING**
3	a) Calculate the induced EMF in the solenoid • Formula: $\text{EMF} = -L\frac{dI}{dt}$ • Self-inductance: $L = 0.2\,\text{H}$ • Rate of change of current: $\frac{dI}{dt} = \frac{5\,\text{A}}{0.5\,\text{s}} = 10\,\text{A/s}$ • Induced EMF: $\text{EMF} = -0.2 \cdot 10 = -2\,\text{V}$ b) Determine the total voltage across the solenoid and resistor during this time • Ohm's Law: $V_R = IR$ • Current at maximum: $I = 5\,\text{A}$ • Resistance: $R = 10\,\Omega$ • Voltage across resistor: $V_R = 5 \cdot 10 = 50\,\text{V}$ • Total voltage: $V_{\text{total}} = V_R + \lvert\text{EMF}\rvert = 50 + 2 = 52\,\text{V}$	

	c) If another coil with a mutual inductance of 0.1 H with the solenoid is the induced EMF in the secondary coil during the same time period • Formula: $\text{EMF}_{\text{secondary}} = -M\frac{dI_{\text{primary}}}{dt}$ • Mutual inductance: $M = 0.1\,\text{H}$ • Rate of change of current: $\frac{dI_{\text{primary}}}{dt} = 10\,\text{A/s}$ • Induced EMF in secondary: $\text{EMF}_{\text{secondary}} = -0.1\cdot 10 = -1\,\text{V}$	

LEVEL-1 (NUMERICALS)

Q.NO	DETAILED SOLUTIONS	VALUE POINTS/ STEP MARKING
1	The induced emf is given by Faraday's law: $\varepsilon = -N\frac{d\Phi}{dt}$ Change in magnetic flux Df is $\Delta\Phi = A\cdot(B_f - B_i) = 0.1\,\text{m}^2\cdot(0.5\,\text{T} - 0.2\,\text{T}) = 0.1\times 0.3 = 0.03$ wb Induced emf is $\varepsilon = -50\cdot\frac{0.03\,\text{Wb}}{0.1\,\text{s}} = -50\cdot 0.3 = -15\,\text{V}$	2
2	The induced emf is given by e = Blv Substituting the given values: $\varepsilon = 0.2\,\text{T}\cdot 1\,\text{m}\cdot 2\,\text{m/s} = 0.4\,\text{V}$	2
3	The induced emf is given by $\varepsilon = -N\cdot\frac{d\Phi}{dt}$ Rate of change of magnetic flux $\frac{d\Phi}{dt} = A\cdot\frac{dB}{dt} = 0.05\,\text{m}^2\cdot 0.1\,\text{T/s} = 0.005$ Induced emf is $\varepsilon = -200\cdot 0.005\,\text{Wb/s} = -1\,\text{V}$	2
4	The induced EMF (ε) in a solenoid due to self-induction is given by: $\varepsilon = -L\frac{dI}{dt}$ $\frac{dI}{dt} = \frac{5\,\text{A} - 0\,\text{A}}{0.5\,\text{s}} = 10\,\text{A/s}$ $\varepsilon = -2\,\text{H}\cdot 10\,\text{A/s} = -20\,\text{V}$	2

<table>
<tr><th colspan="3">LEVEL-2 (NUMERICALS)</th></tr>
<tr><th>Q.NO</th><th>DETAILED SOLUTIONS</th><th>VALUE POINTS/ STEP MARKING</th></tr>
<tr><td>1</td><td>$$\frac{dI}{dt} = \frac{10\,\mathrm{A}}{0.2\,\mathrm{s}} = 50\,\mathrm{A/s}$$
Induced emf in coil B is
$$\varepsilon = -M\frac{dI}{dt} = -2\,\mathrm{H} \times 50\,\mathrm{A/s} = -100\,\mathrm{V}$$
The energy transferred to coil B is given by:
$$E = \frac{1}{2}MI^2$$
Substituting the final current in coil A:
$$E = \frac{1}{2} \times 2 \times 10^2 = 100\,\mathrm{J}$$</td><td>3</td></tr>
<tr><td>2</td><td>The energy W stored in Coil X initially is given by:
$$W = \frac{1}{2}L_X I^2$$
Substitute the values:
$$W = \frac{1}{2} \times 2\,\mathrm{H} \times (4\,\mathrm{A})^2 = 16\,\mathrm{J}$$
The induced EMF ε in Coil Y due to the change in current in Coil X is given by:
$$\varepsilon = -M\frac{dI_X}{dt}$$
Rate of change of current in Coil X:
$$\frac{dI_X}{dt} = \frac{4\,\mathrm{A}}{0.2\,\mathrm{s}} = 20\,\mathrm{A/s}$$
Induced EMF in Coil Y:
$$\varepsilon = -1.2\,\mathrm{H} \times 20\,\mathrm{A/s} = -24\,\mathrm{V}$$
The energy transferred to Coil Y can be considered as the energy initially stored in Coil X, which is 16 J, assuming ideal conditions with no energy losses.</td><td>3</td></tr>
<tr><td>3</td><td>Given:
$$B = 0.4\,\mathrm{T}, \quad l = 0.5\,\mathrm{m}, \quad v = 2\,\mathrm{m/s}$$
1. **Induced EMF:**
The motional EMF ε induced in a conductor moving through a magnetic field is given by:
$$\varepsilon = B \cdot l \cdot v$$
Substitute the values:
$$\varepsilon = 0.4\,\mathrm{T} \cdot 0.5\,\mathrm{m} \cdot 2\,\mathrm{m/s} = 0.4\,\mathrm{V}$$</td><td>3</td></tr>
</table>

	2. **Induced Current:** The induced current (I) in the loop can be calculated using Ohm's Law: $I = \frac{\varepsilon}{R}$ Given: $R = 0.2\,\Omega$ Substitute the values: $I = \frac{0.4\,\mathrm{V}}{0.2\,\Omega} = 2\,\mathrm{A}$ 3. **Power Dissipated:** The power (P) dissipated in the loop due to the induced current is given by: $P = I^2 \cdot R$ Substitute the values: $P = (2\,\mathrm{A})^2 \cdot 0.2\,\Omega = 4 \cdot 0.2 = 0.8\,\mathrm{W}$	

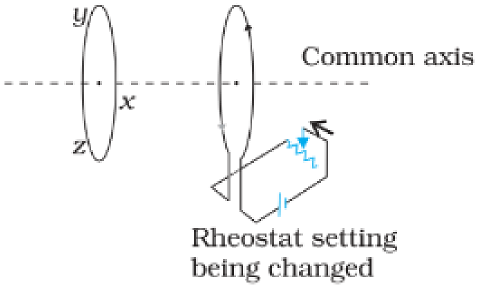
LEVEL-3 (NUMERICALS)

Q.NO	DETAILED SOLUTIONS	VALUE POINTS/ STEP MARKING
1	The inductance L of a solenoid is given by: $L = \mu_0 \frac{N^2 A}{l}$ $L = 4\pi \times 10^{-7} \times \frac{(1000)^2 \times 0.01}{0.5} = 4\pi \times 10^{-7} \times \frac{10^6 \times 0.01}{0.5}$ L = $8\pi \times 10^{-3}$ The induced emf is $\varepsilon = -L\frac{dI}{dt} = -8\pi \times 10^{-3} \times 15 = -0.12\pi \approx -0.38\,\mathrm{V}$ The energy stored in the solenoid at the final current is given by: $E = \frac{1}{2}LI^2$ $E = \frac{1}{2} \times 8\pi \times 10^{-3} \times 8^2 = 4\pi \times 10^{-3} \times 64$ $= 0.256\pi \approx 0.8\,\mathrm{J}$	3
2	The induced EMF (ε) is given by: $\varepsilon = -L\frac{dI}{dt}$ First, find the derivative of the current with respect to time: $\frac{dI}{dt} = \frac{d}{dt}[5\sin(100t)] = 5 \cdot 100\cos(100t) = 500\cos(100t)$	3

	The maximum value of cos(100t) is 1. Therefore, the maximum rate of change of current is: $\left.\frac{dI}{dt}\right\vert_{\max} = 500\,\mathrm{A/s}$ The maximum induced EMF is: $\varepsilon_{\max} = -L\left(\left.\frac{dI}{dt}\right\vert_{\max}\right) = -0.5 \times 500 = -250\,\mathrm{V}$ The magnitude of the maximum induced EMF is 250 V	
3	The induced EMF ε in Coil B is given by: $\varepsilon = -M\frac{dI}{dt}$ Rate of change of current in Coil A: $\frac{dI}{dt} = \frac{5\,\mathrm{A}}{0.1\,\mathrm{s}} = 50\,\mathrm{A/s}$ Induced EMF in Coil B: $\varepsilon = -3\,\mathrm{H} \times 50\,\mathrm{A/s} = -150\,\mathrm{V}$ The energy W dissipated as heat in Coil B is given by: $W = \varepsilon^2\frac{t}{R}$ Substitute the values: $W = (150)^2\frac{0.1}{1.5} = 1500\,\mathrm{J}$	3
	CASE BASED	
Q.NO	**DETAILED SOLUTIONS**	**VALUE POINTS/ STEP MARKING**
1	B. 0.5 T/s	1
2	B. 0.05 Induced EMF ε is given by Faraday's Law of Induction: $\varepsilon = -\frac{d\Phi}{dt}$ Rate of change of magnetic flux: $\frac{d\Phi}{dt} = A \cdot \frac{dB}{dt} = 0.005\,\mathrm{m}^2 \times 0.5\,\mathrm{T/s} = 0.0025\,\mathrm{Wb/s}$ Induced EMF: $\varepsilon = -\frac{d\Phi}{dt} = -0.0025\,\mathrm{V} = 0.05\,\mathrm{V}$	1
3	B. Counterclockwise, looking from above According to Lenz's Law, the induced current will flow in a direction such that its magnetic field opposes the change in the magnetic flux. Since the magnetic field is increasing, the induced current will create a magnetic field opposing the increase, which requires a counterclockwise current when viewed from above.	1

4	A. 0.5 A The induced current (I) can be calculated using Ohm's Law: $I = \frac{\varepsilon}{R}$ Substitute the values: $I = \frac{0.05\ \mathrm{V}}{0.1\ \Omega} = 0.5\ \mathrm{A}$	1
COMPETENCY BASED		
Q.NO	**DETAILED SOLUTIONS**	**VALUE POINTS/ STEP MARKING**
1	Rate of Change of Current in Coil A: $\frac{dI_A}{dt} = \frac{\Delta I_A}{\Delta t} = \frac{5\ \mathrm{A} - 0\ \mathrm{A}}{1\ \mathrm{s}} = 5\ \mathrm{A/s}$	1
2	Induced EMF in Coil B: $\varepsilon_B = -M\frac{dI_A}{dt}$ Substitute the given values: $\varepsilon_B = -1\ \mathrm{H} \times 5\ \mathrm{A/s} = -5\ \mathrm{V}$ The magnitude of the induced EMF is 5 V	1
3	Induced Current in Coil B: The induced current (I_B) in Coil B can be calculated using Ohm's Law: $I_B = \frac{\varepsilon_B}{R}$ Substitute the values: $I_B = \frac{5\ \mathrm{V}}{2\ \Omega} = 2.5\ \mathrm{A}$	1
4	Total Energy Transferred to Coil B: The power (P) dissipated in Coil B due to the induced current is given by: $P = I_B^2 \cdot R$ Substitute the values: $P = (2.5\ \mathrm{A})^2 \times 2\ \Omega = 6.25 \times 2 = 12.5\ \mathrm{W}$ he total energy (E) transferred to Coil B over the 1 second is given by: $E = P \times t$ Substitute the values: $E = 12.5\ \mathrm{W} \times 1\ \mathrm{s} = 12.5\ \mathrm{J}$	1

CCT		
1	As the magnet falls through the copper pipe, it will experience a deceleration due to the induced currents (eddy currents) in the copper pipe. According to Lenz's Law, these induced currents create a magnetic field that opposes the change in magnetic flux caused by the falling magnet. As a result, the magnet falls slower than it would in the absence of the pipe. The experimental observation would be that the magnet takes a longer time to pass through the pipe than expected due to the opposing magnetic force.	1
2	When the magnet is moved towards the solenoid, the ammeter will show a current in one direction, and when the magnet is moved away, it will show a current in the opposite direction. According to Lenz's Law, the direction of the induced current will be such that it creates a magnetic field opposing the change in flux. Therefore, as the magnet approaches, the solenoid generates a current that produces a magnetic field opposing the magnet's approach. When the magnet moves away, the induced current direction reverses to oppose the reduction in magnetic flux.	
3	When the current in the solenoid is suddenly turned on, an induced current is generated in the aluminum ring. According to Lenz's Law, the direction of this induced current will be such that it opposes the change in magnetic flux. This results in the ring experiencing a force that pushes it upwards, away from the solenoid. Conversely, when the current is turned off, the sudden decrease in magnetic flux will induce a current in the ring in the opposite direction, again producing a magnetic field that opposes the change. The ring may experience a downward force, but due to inertia, it is more likely to simply fall back after the initial upward push.	
4	If the copper pipe is replaced with a plastic pipe, the magnet will fall through it with no significant deceleration. This is because plastic is a non-conducting material and does not allow for the formation of eddy currents. Without these induced currents, there is no opposing magnetic field to slow down the magnet, and therefore Lenz's Law does not apply in this scenario. The experimental observation would be that the magnet falls at the same rate as it would in free air, experiencing only the acceleration due to gravity.	
SELF ASSESSMENT		
Q.NO	**DETAILED SOLUTIONS**	**VALUE POINTS/ STEP MARKING**
1	a) A changing magnetic field induces an electromotive force (EMF). Explanation: Faraday's First Law states that a change in the magnetic field within a closed loop induces an electromotive force (EMF) in the wire.	1

2	b) Weber	1
3	b) It opposes the cause of its own production. Explanation: Lenz's Law states that the direction of the induced current will be such that it opposes the change in magnetic flux that produced it.	1
4	d) All of the above. Explanation: The induced EMF in the secondary coil depends on the number of turns in the primary coil, the rate of change of current in the primary coil, and the distance between the coils.	1
5	a) Both A and R are true, and R is the correct explanation of A. Explanation: Lenz's Law indeed describes how the direction of the induced current opposes the change causing it, and this opposition is a manifestation of the conservation of energy.	1
6	a) Both A and R are true, and R is the correct explanation of A. Explanation: Self-inductance increases with the number of turns, and it is indeed proportional to the square of the number of turns in the coil, which explains why an increase in turns increases the self-inductance.	1
7	Faraday's Law of Electromagnetic Induction states that the electromotive force (EMF) induced in a closed circuit is directly proportional to the rate of change of magnetic flux through the circuit. Mathematically, it can be expressed as: $\varepsilon = -\frac{d\Phi}{dt}$ where ε is the induced EMF, and dΦ/dt is the rate of change of the magnetic flux Φ. The negative sign indicates that the induced EMF opposes the change in flux, as described by Lenz's Law.	2
8	Mutual induction occurs when a change in current in one coil induces an EMF in a nearby coil. The principle is based on Faraday's Law of Induction. When the current in the primary coil changes, it alters the magnetic field around it. This changing magnetic field induces an EMF in the secondary coil that is placed close to the primary coil.  **Explanation:** • When the current in Coil A (primary coil) increases or decreases, the magnetic field around it changes. • This changing magnetic field passes through Coil B (secondary coil), inducing an EMF in Coil B.	3

	- The magnitude of the induced EMF in Coil B depends on the rate of change of current in Coil A, the number of turns in both coils, and the mutual inductance between them.	
9	b) Faraday's Law of Electromagnetic Induction	1
10	b) The direction of the induced current	1
11	c) The deflection will increase	1
12	d) The resistance of the coil	1
13	**Derivation:** The self-inductance L of a solenoid is given by: $L = \frac{\mu_0 N^2 A}{l}$ (Refer NCERT derivation) Factors Affecting Self-Inductance: 1. Number of Turns (N): The self-inductance increases with the square of the number of turns. More turns result in a higher inductance because there are more loops for the magnetic field to interact with. 2. Cross-Sectional Area (A): A larger, L is larger 3. Length of solenoid (l): Inversely proportional to length 4. Medium (m_0): Depends on medium between the coil	5
14	Lenz's Law: Lenz's Law states that the direction of the induced electromotive force (EMF) and the resulting induced current in a conductor is such that it opposes the change in magnetic flux that caused it. This law is a consequence of the conservation of energy and is mathematically expressed as: $\varepsilon = -\frac{d\Phi}{dt}$ The negative sign indicates that the induced EMF always acts to oppose the change in magnetic flux. Example: Consider a simple example involving a coil of wire and a bar magnet: 1. Initial Setup: ○ A coil of wire is connected to a galvanometer to measure the induced current. ○ A bar magnet is positioned near the coil. 2. Scenario 1: Moving the Magnet Towards the Coil: ○ As the north pole of the bar magnet approaches the coil, the magnetic flux through the coil increases. ○ According to Lenz's Law, the coil will generate an induced current that creates its own magnetic field opposing the increase in flux. In this case, the induced magnetic field will be directed away from the	5

	approaching north pole (i.e., it will have a north pole facing the approaching north pole). ○ The galvanometer will show a deflection indicating the presence of an induced current. 3. Scenario 2: Moving the Magnet Away from the Coil: ○ When the magnet is moved away, the magnetic flux through the coil decreases. ○ The induced current will now create a magnetic field that opposes the decrease in flux. Here, the induced magnetic field will try to retain the original flux, and hence, it will act to attract the departing north pole. ○ The galvanometer will show a deflection in the opposite direction compared to when the magnet was moving towards the coil. Significance in the Conservation of Energy: Lenz's Law is significant in the context of energy conservation because it ensures that the principle of conservation of energy is upheld in electromagnetic systems. Here's how it connects to energy conservation: 1. Opposition to Flux Change: ○ The induced current generated by Lenz's Law acts to oppose the change in magnetic flux. This opposition requires energy, which comes from the mechanical work done to move the magnet. For instance, if you push the magnet towards the coil, you need to do work against the induced magnetic field that opposes the motion. 2. Energy Transfer: ○ The work done on the magnet is converted into electrical energy in the coil. This electrical energy is manifested as the induced current, and the energy conservation principle ensures that the work done (mechanical energy) is equal to the electrical energy generated in the coil. 3. System Behavior: ○ If Lenz's Law were not in effect, it would imply that energy could be created from nothing or that the system could violate energy conservation principles. By ensuring that the induced current always works to oppose the initial change, Lenz's Law prevents such violations and maintains the balance of energy. Conclusion: Lenz's Law is a fundamental principle that reflects the conservation of energy in electromagnetic systems. It ensures that induced currents always act in a direction to oppose changes in magnetic flux, which aligns with the conservation of energy and prevents the creation of energy from nothing.	

* Answers are given in explanatory way. Student will try to limit answer as per requirement of questions i.e. as per 2 marks, 3 marks, 5 marks.

UNIT IV – ELECTROMAGNETIC INDUCTION AND ALTERNATING CURRENT

CHAPTER 7- ALTERNATING CURRENT

DETAILED ANSWERS

LEVEL- I MCQ		
Q. NO	DETAILED SOLUTION	VALUE POINT
1	B) In dc ammeter, a coil is free to rotate in the magnetic field of a fixed magnet. If an alternating current is passed through such a coil, the torque will reverse it's direction each time the current changes direction and the average value of the torque will be zero.	1
2	D) AC can be easily generated, changed voltage and lower energy loss	1
3	A) Keeping the current low reduces power loss due to the resistance of the conducting wire. To keep the output power close to the input power, the voltage needs to be kept high.	1
4	B) The equation of voltage and current are given as, $V = V_m sin\omega t$ $i = i_m sin\left(\omega t - \frac{\pi}{2}\right)$ Difference between V and i is п/2	1
5	C) from equations of V and i of AC through inductor and capacitor having phase difference 90^0. So in L and C, voltage and current are out of phase.	1
6	C) Power factor = $cos\emptyset = \frac{R}{Z} = \frac{R}{\sqrt{(R)^2+(X_C-X_L)^2}}$ At resonance $X_C=X_L$, so power factor is 1.	1
7	B) principal of transformer is mutual induction	1
8	C) the relation between rms value and peak value of current is given as $I_{rms} = \frac{I_m}{\sqrt{2}}$	1
9	B) capacitive reactance is given by $X_C = \frac{1}{\omega C}$, and ω=2пϑ Reactance and frequency are inversely proportional	1
10	D) AC through resistor, inductor and capacitor gives relation between v and i	1
11	A) At resonance, $X_L = X_C$. The reactance of the inductor (X_L) is equal to the reactance of the capacitor (X_C), allowing the resistance to play a role in the circuit.	1
12	A) inductive reactance, $X_L=\omega L$, X_L α ϑ	1
13	B) When the average power consumed in the circuit is zero. Power $=i^2R$ and If R=0, then P=0	1
14	D) Dimension of $LC=[ML^2T^{-2}A^{-2}] X[M^{-1}L^{-2}T^4A^2]=[T^2]$	1
15	A) $P = V_{rms}i_{rms}cos\emptyset$. For wattles P=0, so cosΦ=0, $Φ=90^0$	1

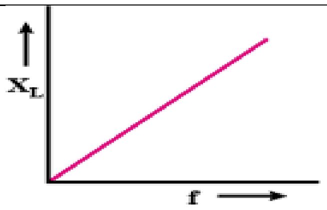
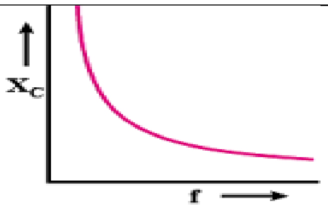
16	A) At resonance, the inductive and capacitive reactance's cancel each other out, leaving only the resistive impedance and circuit behave like a pure resistive circuit.	1
17	B) Power delivered is maximum when capacitive reactance and inductive reactance cancel out each other.	1
18	A) the source emf is greater than the back emf, so more current is drawn in the primary coil.	1
19	C) transformer converts high voltage to low voltage or vice versa	1
20	C) In transformer voltage changes. Change in voltage cause change in current.	1

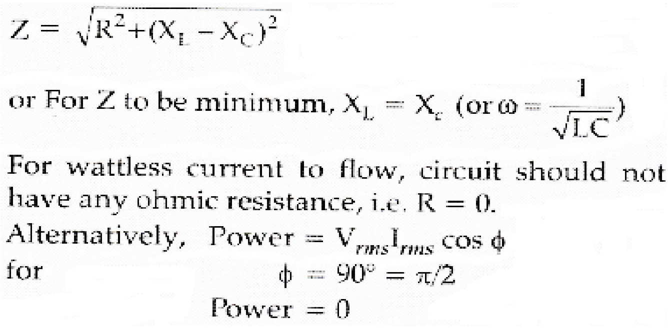
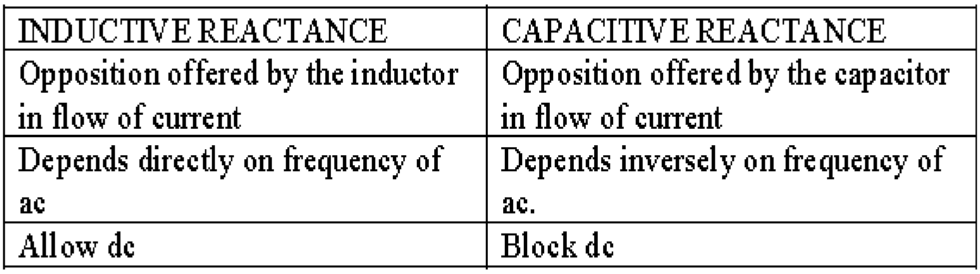
LEVEL- II MCQ

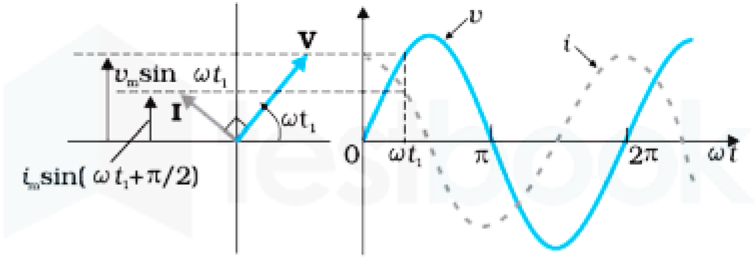
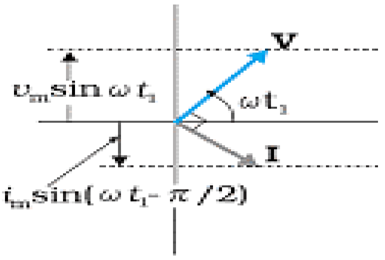
1	C) $\vartheta_0 = \frac{\omega_0}{2\pi} = \frac{1}{2\pi\sqrt{LC}}$ ω=1√LC For, ω=constant →√LC=constant Therefore, C is inversely proportional to L So, if C is made 4C then L should be reduced to L/4 to keep ω constant.	1
2	A) When a bulb and a capacitor are connected in series to an AC source, then on increasing the frequency the current in the circuit is increased, because the impedance of the circuit is decreased. So the bulb will give more intense light.	1
3	B)	1
4	B) ε = NBAω sinωt Now if we double ω, ε will be doubled.	1
5	D) Leclanche cell works on direct current and thus gives out direct current. The ratio given here won't work since the transformers work on alternating current not on direct current. Thus the voltage developed in the secondary would be 0V.	1
6	B) $V_S = I_S R = 0.5 \times 200 = 100\ V$ $\frac{V_S}{V_P} = \frac{N_S}{N_P} = 10 \to V_P = \frac{V_S}{10} = 10V$ $\frac{I_P}{I_S} = \frac{N_S}{N_P} = 10 \to I_P = 10 \times 0.5 = 5A$	1
7	C) $\frac{I_P}{I_S} = \frac{N_S}{N_P} = \frac{3}{2} \to I_S = \frac{3\ X2}{3} = 2A$	1
8	D) $V_{rms} = \frac{V_m}{\sqrt{2}} \to V_m = V_{rms}\sqrt{2} = 220\sqrt{2}\ V$	1
9	C) $cos\emptyset = \frac{R}{Z} = \frac{10}{20} \to \emptyset = 60^0$	1
10	D) X_C=1/ωC= 100/п MHz	1

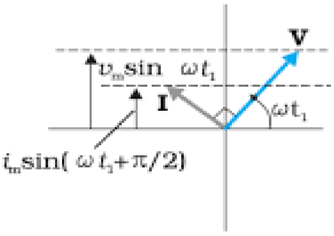
LEVEL- III MCQ

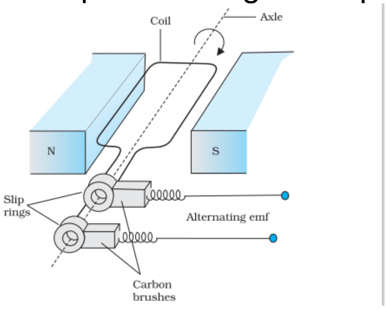
1	D) $\omega^2 = 1/LC$	1
2	A) $\omega^2 = 1/LC$	1
3	C) I=V/Z	1
4	B) Power factor = $cos\emptyset = \frac{R}{Z} = \frac{R}{\sqrt{(R)^2+(X_C-X_L)^2}}$	1
5	B) $2\pi\vartheta L = 1/2\pi\vartheta C$	1
6	D) $P = V_{rms} i_{rms} cos\emptyset$	1
7	B) P_{output}=VI	1
8	$\frac{\varepsilon_S}{\varepsilon_P} = \frac{N_S}{N_P} = \frac{I_P}{I_S}$	1

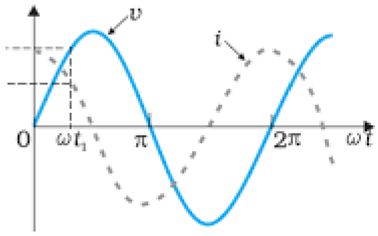
9	C)	1
10	D)	1
	LEVEL- I (2M QUESTIONS)	
1	(i) Root mean square is that value of current which produces the same heating effect in a given resistor as is produced by the given alternating current when passed for the same time. It is denoted by I_{rms}. (ii) $I_{rms} = \frac{I_m}{\sqrt{2}} = 0.707I_m$	1 1
2	 	1 mark for each
3	(i) On increasing capacitance, current will increase. It also increases the brightness of bulb. As capacitance increases, capacitive reactance decreases, impedance Z decreases, hence current increases. (ii) There will no flow of current and hence bulb will not glow.	1 1
4	(i) Capacitor reactance is the resistance offered by a capacitor, when it is connected to ac circuit. SI unit: ohm (ii) (a)AC voltage can be stepped up and stepped down as per the requirement. (b) energy loss in transmitting over long distances is negligible as compare to DC	1 1
5	Principal: Mutual induction Large scale transmission of electric energy over long distances for a.c. power is done at highest possible voltage so that line current is less and consequently power loss during transmission is least possible.	1 1
6	For energy losses in transformer are (i) Eddy current loss (ii) Flux leakage (iii) Copper loss (iv) Humming loss (v) Hysteresis loss	1 mark for each (Any two)
7	A metal detector works on the principal of resonance in ac circuit. When we walk through a metal detector, we are walking through a coil of many turns. The coil is connected to a capacitor tuned so that the circuit is in resonance. When we walk through with some metal in our pocket, the impedance of the circuit changes, resulting in significant change in current is detected and the electronic circuit sounds as an alarm.	2
8	(i) The power factor (cos φ) is the ratio of resistance and impedance of an ac circuit i.e., Power factor, cos φ= R/ Z (ii) Maximum power factor is 1 when Z = R i.e., when circuit is purely resistive.	1 1

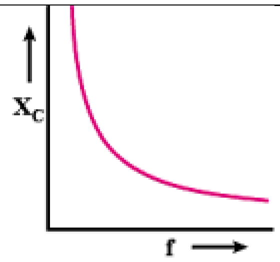
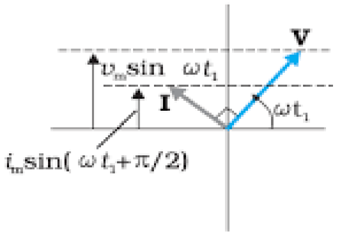
<table>
<tr><td></td><td>Minimum power factor is 0 when R = 0 i.e., when circuit is purely inductive or capacitive</td><td></td></tr>
<tr><td colspan="3">LEVEL- II (2M QUESTIONS)</td></tr>
<tr><td>1</td><td>Since, average power consumption in AC circuit is given by
$P = V_{rms} i_{rms} cos\emptyset$
But in pure capacitive circuit, phase difference between voltage and current is given by, $\emptyset = \frac{\pi}{2}$
$\therefore P = 0$
Thus, no power is consumed in pure capacitive AC circuit.</td><td>½
½
1</td></tr>
<tr><td>2</td><td>The impedance of a series LCR circuit is given by

$Z = \sqrt{R^2+(X_L-X_C)^2}$
or For Z to be minimum, $X_L = X_c$ (or $\omega = \frac{1}{\sqrt{LC}}$)
For wattless current to flow, circuit should not have any ohmic resistance, i.e. R = 0.
Alternatively, Power = $V_{rms} I_{rms} \cos\phi$
for $\phi = 90^\circ = \pi/2$
Power = 0
∴ Wattless current flows when the impedance of the circuit is purely inductive/capacitive or the combination of the two.</td><td>½
½
1</td></tr>
<tr><td>3</td><td>(i) Principal of Transformer: A transformer is based on the principal of mutual induction.
(ii) No, transformer cannot be used to change DC voltage because DC voltage is constant and cannot change flux linked with primary of secondary coils</td><td>1
1</td></tr>
<tr><td>4</td><td><table><tr><th>INDUCTIVE REACTANCE</th><th>CAPACITIVE REACTANCE</th></tr><tr><td>Opposition offered by the inductor in flow of current</td><td>Opposition offered by the capacitor in flow of current</td></tr><tr><td>Depends directly on frequency of ac</td><td>Depends inversely on frequency of ac.</td></tr><tr><td>Allow dc</td><td>Block dc</td></tr></table></td><td>1 Mark each (any Two)</td></tr>
<tr><td>5</td><td>Impedance offered by series LCR circuit,
$Z = \frac{V_m}{i_m} = \sqrt{(R)^2 + (X_C - X_L)^2}$
And voltage,
$V_m = |V| = \sqrt{V_R^2 + (V_C - V_L)^2}$
As V_C and V_L are the voltage applied across capacitor C and inductor L. V_C or V_L may be greater than V.
The situation may be shown in figure,</td><td>1
1</td></tr>
</table>

		
	LEVEL- III (2M QUESTIONS)	
1	False, an alternating current produces a magnetic field whose magnitude and direction changes periodically. Due to magnetic effect of current magnetic field is produced.	2
2	$\frac{\varepsilon_S}{\varepsilon_P}=\frac{N_S}{N_P}$ $\frac{220}{2200}=\frac{N_S}{3000}$ Number of turns in the secondary winding, Ns=300 turns	½ ½ 1
3	When a dielectric slab is introduced, the capacitance C increases. The capacitive reactance decreases. Consequently the current increases hence the glow of the bulb increases.	2
	LEVEL- I (3M QUESTIONS)	
1	Inductive reactance is the opposition offered by the inductor in flow of AC. It is denoted by XL. Let $V = V_m sin\omega t$ be the emf of AC source connected with inductor in the circuit, then an alternating current flows through the inductor, a back emf $-L\frac{di}{dt}$ is set up which opposes the applied emf. Net instantaneous emf = $V - L\frac{di}{dt}$ But this emf must be zero because there is no resistance in the circuit $V = V_m sin\omega t$ $V - L\frac{di}{dt} = 0$ (using Kirchhoff's rule) $\frac{di}{dt} = \frac{V}{L} = \frac{V_m}{L} sin\omega t$ $\int \frac{di}{dt} dt = \frac{V_m}{L}\int sin\omega tdt$ $i = -\frac{V_m}{\omega L} cos\omega t + C$ Over the time period T, cos wt = 0 and average value of I must be 0 so , integration constant = 0 hence $i = i_m sin\left(\omega t - \frac{\pi}{2}\right)$ $(i_m = \frac{V_m}{\omega L})$ Inductive reactance, $X_L = \omega L$ 	1 ½ 1 ½

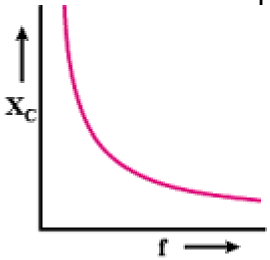
<table>
<tr><td>2</td><td>Capacitive reactance is the opposition offered by the inductor in flow of ac. It is denoted by X_C.
Let $V = V_m sin\omega t$ be the emf of ac source connected with inductor in the circuit
Due to the continuous charging and discharging of capacitor plates, a continuous but alternating current exist in the circuit.
At any time t, Potential difference across the capacitor plates = applied emf
$V = \frac{q}{C}$
$V_m sin\omega t = \frac{q}{C}$
$i = \frac{dq}{dt} = \frac{d}{dt}(CV_m sin\omega t) = \omega CV_m cos\omega t$
$= \frac{V_m}{1/_{\omega C}} sin\left(\omega t + \frac{\pi}{2}\right) = i_m sin\left(\omega t + \frac{\pi}{2}\right)$
Capacitive reactance, $X_C = \frac{1}{\omega C}$
 </td><td>1
½
1
½</td></tr>
<tr><td>3</td><td>R remains unaffected because it is independent of ϑ
inductive reactance get tripled because X_L=ωL=2пϑL (X_L α ϑ) and capacitive reactance become one third of the original value (X_C α 1/ϑ)</td><td>1
1
1</td></tr>
<tr><td>4</td><td><table>
<tr><th>RESISTANCE</th><th>REACTANCE</th><th>IMPEDANCE</th></tr>
<tr><td>It can be seen in both ac and dc circuits</td><td>It can be seen only in ac circuits</td><td>It can be seen only in ac circuits</td></tr>
<tr><td>Happen due to resistor in a circuit</td><td>Happen due to inductor or capacitor in a circuit</td><td>Happen due to resistor and inductor or capacitor or both in a circuit</td></tr>
<tr><td>Represented by R</td><td>Represented by X</td><td>Represented by Z</td></tr>
<tr><td>It doesn't have a phase angle</td><td>It has a phase angle</td><td>It has a phase angle</td></tr>
</table></td><td>1½(any two point)</td></tr>
<tr><td colspan="3">**LEVEL- II (3M QUESTIONS)**</td></tr>
<tr><td>1</td><td>We know that, an AC voltage $V = V_m sin\omega t$ applied to a series LCR circuit drives a current in the circuit given by $I = I_m \sin(\omega t + \emptyset)$.
Instantaneous Power = Instantaneous Voltage X Instantaneous Current
P = VI = $V_m sin\omega t$ X $I_m \sin(\omega t + \emptyset)$
$P = \frac{V_m i_m}{2}[2sin\omega t sin(\omega t + \emptyset)]$
$P = \frac{V_m i_m}{2}[cos\emptyset - cos(2\omega t + \emptyset)]$
$P = \frac{V_m i_m}{2} cos\emptyset = \frac{V_m}{\sqrt{2}}\frac{i_m}{\sqrt{2}} cos\emptyset$</td><td>1
1</td></tr>
</table>

	$P = V_{rms} i_{rms} cos\emptyset$ True power = virtual power X $cos\emptyset$ $P = I^2 Z cos\emptyset$	1
2	The impedance of the LR circuit, $Z_1 = \sqrt{R^2 + \omega^2 L^2}$ When a capacitor is connected in series with the LR circuit, the impedance becomes $Z_2 = \sqrt{R^2 + \left(\omega L + \frac{1}{\omega C}\right)^2}$ Clearly Z$Z_2 < Z_1$, i.e. the impedance decreases. Hence when a capacitor is connected in series with a series LR circuit, the current in the circuit increases.	1 1 1
3	Principle: Rotating coil kept in magnetic field produce ac current.  **Construction**: It consists of the four main parts: **Field Magnet:** It produces the magnetic field. **Armature:** It consists of a large number of turns of insulated wire in the soft iron drum or ring. It can revolve round an axle between the two poles of the field magnet. The drum or ring serves the two purposes: (a) It serves as a support to coils and (b) It increases the magnetic field due to air core being replaced by an iron core. **Slip Rings**: The slip rings are the two metal rings to which the ends of armature coil are connected. These rings are fixed to the shaft which rotates the armature coil so that the rings also rotate along with the armature. **Brushes**: These are two flexible metal plates or carbon rods) which are fixed and constantly touch the revolving rings. The output current in external load RL is taken through these brushes. **Expression for induced emf** When the coil is rotated with a constant angular speed ω, the angle θ between the magnetic field vector B and the area vector A of the coil at any instant t is θ = ωt (assuming θ = 0° at t = 0). As a result, the effective area of the coil exposed to the magnetic field lines changes with time, the flux at any time t is The flux at any time is, $\emptyset = \vec{B}.\vec{A}$=NBA cos θ=NBA cosωt The induced emf is, $\varepsilon = -\frac{d\emptyset}{dt} = -\frac{d(NBAcos\omega t)}{dt}$ $V = \varepsilon = -NBA\omega sin\omega t$	½ ½ 1 1

<table>
<tr><th colspan="3">LEVEL- III (3M QUESTIONS)</th></tr>
<tr><td>1</td><td>(i) We know that if the number of turns in the inductor decreases, then inductance L decreases. So, the net resistance of the circuit decreases and hence, the current through the circuit increases, increasing the brightness of the bulb.
(ii) If the soft iron rod is inserted in the inductor, then the inductance L increases. Therefore, the current through the bulb will decreases, decreasing the brightness of the bulb. $I_{rms}=v_{rms}/X_L$
(iii) If the capacitor of reactance XC=XL is connected in series with the circuit, then Z=R. This is a case of resonance. In this case, the maximum current will flow through the circuit. Hence, the brightness of the bulb will increase.</td><td>1
1
1</td></tr>
<tr><td>2</td><td>(i) $f=f_r$ occurs when $X_L=X_C$.
Then the circuit becomes purely resistive. So, current and voltage will be in the same phase.
(ii) $X_L=2\pi fL$ and $X_C=\frac{1}{2\pi fC}$. when $f<f_r$, X_L is small and X_C is large.
The circuit is capacitive, so current leads the voltage in phase.
(iii) when $f>f_r$, X_L is large and X_C is small.
The circuit is inductive. So current lags behind the voltage in phase.</td><td>1
1
1</td></tr>
<tr><th colspan="3">LEVEL- I (5M QUESTIONS)</th></tr>
<tr><td>1</td><td>(i)
<table>
<tr><th>INDUCTIVE REACTANCE</th><th>CAPACITIVE REACTANCE</th></tr>
<tr><td>Opposition offered by the inductor in flow of current</td><td>Opposition offered by the capacitor in flow of current</td></tr>
<tr><td>Depends directly on frequency of ac</td><td>Depends inversely on frequency of ac.</td></tr>
<tr><td>Allow dc</td><td>Block dc</td></tr>
</table>
(ii) $Z^2=R^2+X_L^2$, If frequency of applied signal is decreased, the term $X_L=\omega L$ also decreased and as a result value of impedance decreased consequently.</td><td>3
2</td></tr>
<tr><th colspan="3">LEVEL- II (5M QUESTIONS)</th></tr>
<tr><td>1</td><td>(i) Device X is a capacitor.
As the current is leading voltage by $\frac{\pi}{2}$
$$X_C=\frac{1}{\omega C}$$
(ii)

(iii) $X_C=\frac{1}{2\pi\vartheta C}$
$$X_C\propto\frac{1}{\vartheta}$$</td><td>1
1</td></tr>
</table>

	 (iv) 	1 1 1

LEVEL- III (5M QUESTIONS)

1	(i) Device X is a capacitor. As the current is leading voltage by $\pi/2$ (ii) Curve A represent power, Curve B represents voltage and curve C represents current. As $I = I_m sin\omega t$ $V = V_m sin\omega t$ As in the case of capacitor, $i = i_m sin\left(\omega t + \frac{\pi}{2}\right)$ Average power, $P = Vi = V_m I_m \cos\Phi/2$ (iii) as, Capacitive reactance, $X_C = \frac{1}{\omega C}$ So reactance or impedance decreases with increase in frequency.  (iv) for a capacitor V=q/c or q=CV $i = \frac{dq}{dt} = \frac{d}{dt}(CV_m sin\omega t) = \omega C V_m cos\omega t$ $= \frac{V_m}{1/_{\omega C}} sin\left(\omega t + \frac{\pi}{2}\right) = i_m sin\left(\omega t + \frac{\pi}{2}\right)$	1 2 1 1

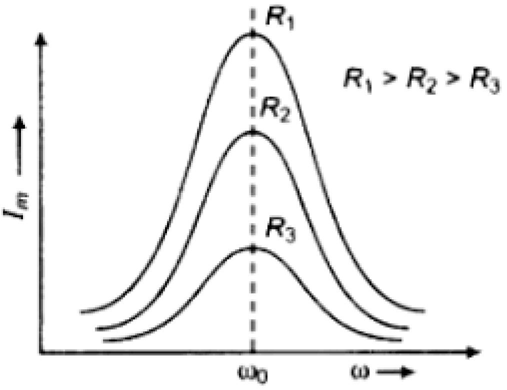
LEVEL- I (NUMERICALS)

1	Comparing it with $V = V_m sin\omega t$ $\omega = 50\pi$ $2\pi\vartheta = 50\pi$	

	$\vartheta = 25\ Hz$ V_m=280 V $V_{rms} = \frac{V_m}{\sqrt{2}} = \frac{280}{\sqrt{2}} = 140\sqrt{2}\ V$ $I_{rms} = \frac{V_{rms}}{R} = \frac{140\sqrt{2}}{40} = 3.5\sqrt{2}\ A$	1 1
2	(i) Resistance of the bulb, $R = \frac{V^2}{P} = \frac{220\times220}{150} = 322.7\Omega$ (ii) $I_{rms} = \frac{V_{rms}}{R} = \frac{220}{322.7} = 0.68\ A$	1 1
3	$\frac{\varepsilon_S}{\varepsilon_P} = \frac{N_S}{N_P}$ $\frac{220}{2200} = \frac{N_S}{3000}$ Number of turns in the secondary winding, N_S=300 turns	½ ½ 1
4	$Q - factor = \frac{1}{R}\sqrt{\frac{L}{C}}$ $= \frac{1}{10}\sqrt{\frac{2}{2\times10^{-6}}}$ =100	½ ½ 1
	LEVEL- II (NUMERICALS)	
1	(i) Reactance = $\lvert \omega L - \frac{1}{\omega C} \rvert = \lvert 100\times80\times10^{-3} - \frac{1}{100\times250\times10^{-3}} \rvert = \lvert 8 - \frac{1}{25} \rvert =$ 7.96 $I_{rms} = \frac{V_{rms}}{Reactance} = \frac{240}{7.96} = 30.15A$ (ii) The total average power consumed by circuit zero.	2 1
2	$X_L = \omega L = 2\pi\vartheta L = 100\Omega$ $Z = \sqrt{(R)^2 + (X_C - X_L)^2} = 100\sqrt{2}\Omega$ I_{rms}=V_{rms}/Z==$\frac{150\sqrt{2}}{100\sqrt{2}} = 1.5A$ $P_{dissipated}$= $V_{rms}I_{rms}$=318.2W	1 1 1
3	(i) Efficiency of transformer, $\eta = \frac{Output\ power}{Input\ power}\times100\%$ $\frac{90}{100} = \frac{Output\ power}{Input\ power} = \frac{\varepsilon_S I_S}{\varepsilon_P I_P}$ $Output\ power = \frac{90}{100}\times V_P I_P = \frac{90}{100}\times2.5\times10^3\times20 = 4.5\times10^4 W$ (ii) $\frac{\varepsilon_S}{\varepsilon_P} = \frac{N_S}{N_P}$ $\varepsilon_S = \frac{1}{10}\times2.5\times10^3 = 250\ V$ (iii) Output power = $4.5\times10^4 W$ $\therefore \varepsilon_S I_S = 4.5\times10^4$	1 1

	$I_S = \frac{4.5\times10^4}{\varepsilon_S} = \frac{4.5\times10^4}{250} = 180\ A$	1

LEVEL- III (NUMERICALS)

1	(i) To draw maximum current from a series LCR circuit, the Circuit at particular frequency, $X_L = X_C$ $\vartheta = \frac{1}{2\pi\sqrt{LC}} = \frac{1}{2\times3.14\times\sqrt{8\times2\times10^{-6}}} = 39.80\ Hz$ This frequency is known as resonance frequency. (ii) $i_m = \frac{V}{R} = \frac{200}{100} = 2A$ (iii)  (iv) It is define as the ratio of the voltage developed across the inductance or capacitance at resonance to the voltage developed across the resistance. $Q = \frac{1}{R}\sqrt{\frac{L}{C}}$ Circuit become more selective if the resonance is more sharp, maximum current is more, the circuit is close to resonance for smaller range of frequencies. Thus the tuning of the circuit will be good.	1 1 1 1 1
2	(i) N_s/N_p = 100, Ns = 100 x 100 = 10000 (ii) I_p=P_i/V_p = 1100/220 = 5A (iii) V_s= (N_s/N_p) X V_p = 100 X 220 = 22000 V (iv) i_s=P_o/V_s = 1100/22000 = 1/20 A (v) P_s = P_o = P_i = 1100W	3
3	(i) $\omega_r = \frac{1}{\sqrt{LC}} = \frac{1}{\sqrt{4\times100\times10^{-6}}} = \frac{1}{2\times10^{-2}}$ = 50 rad s^{-1} (ii) I_{rms} = v_{rms}/R= 240/60= 4A (iii) V_{rms} = $I_{rms}X_L$=$I_{rms}\omega L$= 4X50X4=800 V	1 1 1

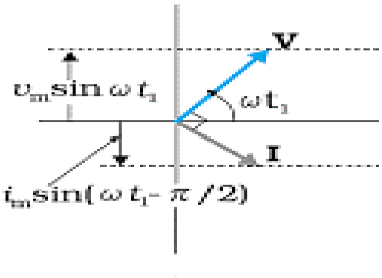
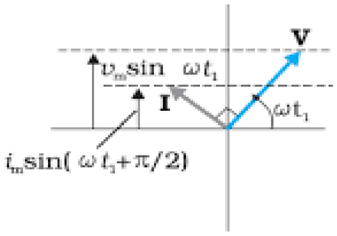
CASE BASED

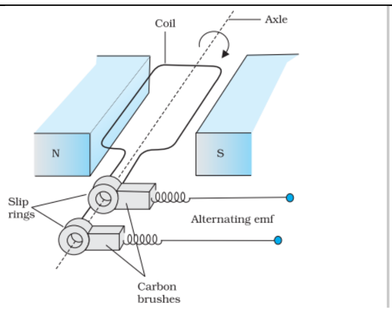
1	(1) Copper loss, Eddy current loss, Hysteresis loss, flux loss (2) Eddy current losses are reduced by using a laminated core. (3) Choosing a material having small Hysteresis loop area (4) Step down transformer.	1 1 1 1

COMPETENCY BASED

1	(i) rms (ii) T/4 (iii) 0	1 1 1

	(iv) $220\sqrt{2}$	1
2	(i) 1/f (ii) f (iii) 0 (iv) 1/314 C	1 1 1 1
	CCT	
1	(1) In LCR series circuit when inductive reactance become equal to capacitive reactance then the current in a circuit become maximum called resonance. (2) Resonance frequency depends on value of inductor L and capacitor C (3) Graph should be sharper for unique resonance frequency. (4) At resonance impedance is minimum i.e. Z= R	1 1 1 1
	SELF ASSESSMENT	
1	(B) voltage leads the current by $\frac{\pi}{2}$	1
2	(D) May lead or lag behind or be in phase with the voltage	1
3	(B) 0.4 A	1
4	(B) 4.5A	1
5	A	1
6	A	1
7	(i) X – an inductor, Y – a capacitor (ii) maximum $(\therefore X_L = X_C,\ cos\emptyset = 1)$	1 1
8	$\frac{\varepsilon_S}{\varepsilon_P} = \frac{N_S}{N_P}$ $\frac{220}{2200} = \frac{N_S}{3000}$ Number of turns in the secondary winding, N_S=300 turns OR $V_{rms} = i_{rms}R = 196\,V,$ $V_{rms} = i_{rms}X_C = 98\,V$	½ ½ 1 1 1
9	Inductive reactance is the opposition offered by the inductor in flow of AC. It is denoted by X_L. Let $V = V_m sin\omega t$ be the emf of AC source connected with inductor in the circuit, then an alternating current flows through the inductor, a back emf $-L\frac{di}{dt}$ is set up which opposes the applied emf. Net instantaneous emf = $V - L\frac{di}{dt}$ But this emf must be zero because there is no resistance in the circuit $V = V_m sin\omega t$ $V - L\frac{di}{dt} = 0$ (using Kirchhoff's rule) $\frac{di}{dt} = \frac{V}{L} = \frac{V_m}{L} sin\omega t$ $\int \frac{di}{dt} dt = \frac{V_m}{L} \int sin\omega t dt$ $i = -\frac{V_m}{\omega L} cos\omega t + C$ Over the time period T, cos wt = 0 and average value of I must be 0 so , integration constant = 0 hence	½

	$i = i_m sin\left(\omega t - \frac{\pi}{2}\right)$ $\left(i_m = \frac{V_m}{\omega L}\right)$ Inductive reactance, $X_L = \omega L$  OR Capacitive reactance is the opposition offered by the inductor in flow of ac. It is denoted by Xc. Let $V = V_m sin\omega t$ be the emf of ac source connected with inductor in the circuit Due to the continuous charging and discharging of capacitor plates, a continuous but alternating current exist in the circuit. At any time t, Potential difference across the capacitor plates = applied emf $V = \frac{q}{C}$ $V_m sin\omega t = \frac{q}{C}$ $i = \frac{dq}{dt} = \frac{d}{dt}(CV_m sin\omega t) = \omega C V_m cos\omega t$ $= \frac{V_m}{1/_{\omega C}} sin\left(\omega t + \frac{\pi}{2}\right) = i_m sin\left(\omega t + \frac{\pi}{2}\right)$ Capacitive reactance, $X_C = \frac{1}{\omega C}$  	1½ 1 ½ 1½ 1
10	(i) $\omega_r = \frac{1}{\sqrt{LC}} = \frac{1}{\sqrt{4\times100\times10^{-6}}} = \frac{1}{2\times10^{-2}}$ = 50 rad s^{-1} (ii) $I_{rms} = v_{rms}/R$= 240/60= 4A (iii) $V_{rms} = I_{rms}X_L = I_{rms}\omega L$= 4X50X4=800 V	1 1 1
11	(i) rms (ii) T/4 (iii) 0 (iv) $220\sqrt{2}$	1 1 1 1
12	Principle: Rotating coil kept in magnetic field produce ac current.	½



Construction: It consists of the four main parts:

Field Magnet: It produces the magnetic field.

Armature: It consists of a large number of turns of insulated wire in the soft iron drum or ring. It can revolve round an axle between the two poles of the field magnet. The drum or ring serves the two purposes: (a) It serves as a support to coils and (b) It increases the magnetic field due to air core being replaced by an iron core. 1

Slip Rings: The slip rings are the two metal rings to which the ends of armature coil are connected.

These rings are fixed to the shaft which rotates the armature coil so that the rings also rotate along with the armature.

Brushes: These are two flexible metal plates or carbon rods) which are fixed and constantly touch the revolving rings. The output current in external load RL is taken through these brushes.

Expression for induced emf

When the coil is rotated with a constant angular speed ω, the angle θ between the magnetic field vector B and the area vector A of the coil at any instant t is θ = ωt (assuming θ = 0° at t = 0). As a result, the effective area of the coil exposed to the magnetic field lines changes with time, the flux at any time t is 2½

1

The flux at any time is,

$\emptyset = \vec{B}.\vec{A}$=NBA cos θ=NBA cosωt 1

The induced emf is, 1

$$\varepsilon = -\frac{d\emptyset}{dt} = -\frac{d(NBAcos\omega t)}{dt}$$ 1

$$V = \varepsilon = -NBA\omega sin\omega t$$ 1

1

The emf produced is alternating and hence the current is also alternating. Current produced by an ac generator cannot be measured by moving coil ammeter; because the average value of ac over full cycle is zero

OR

(i) (a) A

(b) Zero

(c) L or C or LC Series combination of L and C

(ii) (a) R=V^2/P=(220X220)/150=322.7 Ω

(b) I_{rms}=V_{rms}/R=220/322.7=0.68A

UNIT V – ELECTROMAGNETIC WAVES

CHAPTER 8- ELECTROMAGNETIC WAVES

DETAILED ANSWERS

	L1-MCQs	**MARKS**
ANS:	1 (c) It is a transverse wave	1
	2 (b) no monopole exist	1
	3 (c) it is property of e.m. wave	1
	4 (d) Both electric and magnetic field vectors are parallel to each other.	1
	5.(a) LC oscillations is produced by oscillatory circuit	1
	6.C Explanation: Ratio = 1 because the speed of an electromagnetic wave in vacuum is independent of its wavelength or frequency. Therefore, the ratio of speed of infrared and ultraviolet rays in a vacuum is one.	1
	7. A as per frequency spectrum	1
	8. C	1
	9. A frequency and wavelengths are reciprocal to each other.	1
	10 .C It travels with speed of light	1
	L-2 MCQ	
	1. (d) c=E/B	1
	2. (a) C =E_0/B_0	1
	3. (d) E and B are perpendicular to each other and direction of propagation.	1
	4. (d) E and B are perpendicular to each other and direction of propagation	1
	L3 - MCQs	
	1(a) c= $1/\sqrt{\mu 0 \epsilon 0}$	1
	2(b) c = E0/B0	1
	3.(C) frequency independent of medium	1
	4.(C) μ =c/v	1
	L-3 HIGHER ORDER QUESTION(NEET/JEE)	
	1.(b) Beta rays stream of electron not e.m.waves	1
	2.(b) X- rays are used to investigate the structure of atom	1
	3.(b) E lies between 100 e V to 100keV so that e.m.wave are X ray	
	4 (a) In e.m. wave energy densities of electric and magnetic fields are equal. So both the field contribute equally to the intensity of the e.m.wave	1
	5.(a) For complete absorption of energy E, momentum transferred is p=E/c when radiation is totally reflected ,momentum transferred is 2p=2E/C	1
	6.(d) An accelerating charge produces a propagating e.m. wave	1
	7.(c) Z = $\sqrt{R2} + Xc^2$ = V100^2+100^2 = 200$\sqrt{2}$ Id max= Vmax/ Z = 220$\sqrt{2}$/100$\sqrt{2}$= 2.2A	1

	8.(c) $(\mu 0\varepsilon 0)^{-1/2}$ = $1/\sqrt{\mu 0\varepsilon 0}$ $= c$ = LT^{-1}	1
	ANSWER TO ASSERTION AND REASON QUESTION	
	1. (a)	1
	2. (c)	1
	3. (b)	1
	4. (b)	1
	5. (a)	1
	6. (d)	1
	7. (b)	1
	ANS TO L1 SHORT ANSWER QUESTIONS (2 MARKS)	
	1. Infrared waves are known as heat waves because they produce heat. When Electromagnetic waves hit body the mass is lost by the momentum is conserved that is transferred from Electromagnetic waves to the body.	2M
	2. Infrared red waves are the waves which are having frequency lower than the frequency of visible light range. This infrared wave causes the electrons, whole atoms or molecules also of that material. Due to such increased vibrations the internal energy of the material gets increased and thereby increases in the temperature of the material and heat is generated. Because of this reason infrared waves are also called the heat waves. Visible rays come next to infrared radiation in electromagnetic spectrum having shorter wavelength.	2M
	ANS L-2 SHORT ANSWER QUESTIONS (2 MARKS)	**MARKS**
	3. As we know that, the direction of electromagnetic wave is perpendicular to both electric and magnetic fields. Here, electromagnetic wave is travelling in z-direction, then electric and magnetic fields are in xy-direction and are perpendicular to each other. Frequency of waves, n = 30 MHz =30 X 10^6 Hz Speed, c = 3X10^8 m/s Using the formula, c = n.λ Wavelength of electromagnetic waves, λ = c/ n = (3x10^8)/ (30 x10^6) = 10 m Thus, the wavelength of electromagnetic waves is 10m.	2 M
	4.(a) (i)Microwaves range-1GHz-2GHz (ii)UV rays-range 1015-1017 Hz (b) UE= 1/2∈oE ^{2} UB = B^2/2 ; c= 1/√μo∈o E=BC ; Thus ,UE = 1/2∈o(BC) ^{2} = B^2/2 μo	2M
	L-1 SHORT ANSWER QUESTIONS (3 MARKS)	
	1.(i) Consider a plane perpendicular to the direction of propagation of the wave. An electric charge, on the plane will be set in motion by the electric and magnetic fields of EM wave, incident on this plane. This is	3M

	only possible, if EM wave constitutes momentum and energy. Thus, this illustrates that EM waves carry energy and momentum. (ii) Microwaves are produced by special vacuum tube like the klystron, magnetron and Gunn diode. The frequency of microwaves is selected to match the resonant frequency of water molecules, so that energy is transformed efficiently to increase the kinetic energy of the molecules. Thus, facilitating the food to cook properly. (iii) Uses of infrared rays (a) In knowing the molecular structure and therapy to heal muscular pain. (b) In remote control of TV, VCR, etc.	
	ANS L-2 SHORT ANSWER QUESTIONS (3 MARKS)	**MARKS**
	2. Microwave It is produced by special vacuum tubes such as klystron, magnetron and gun diode. The frequency range of microwaves is 109 Hz to 1011Hz. These waves undergoes reflection can be polarized. It is used in radar system for aircraft navigation, speed of the vehicle, microwave over for cooking and very long-distance wireless communication through satellite. ֍ X-Ray It is produced when there is sudden stopping of high-speed electrons at high atomic number target, and also by electronic transitions among the innermost orbits of atoms. The frequency range of X-rays is from 1017 Hz to 1019 Hz. X-rays have more penetrating power than ultraviolet radiation. X-rays are used extensively in studying structures of inner atomic electron shells and crystal structures. It is used in detecting fractures, diseased organs, formation of bones and stones, observing the progress of healing bones. Further, in a finished metal product, it is used to detect faults, cracks, flaws and holes. ֍ Radio Waves They are produced by accelerated motion of charges in conducting wires. The frequency range is from a few Hz to 109 Hz. They show reflection and diffraction	3M
	ANS L-3 SHORT ANSWER QUESTIONS (3 MARKS)	**MARKS**
	ANS 1.(i) The decreasing order of wavelengths of electromagnetic waves is Microwaves > Infrared >Ultraviolet radiation > γ -rays (ii) Microwaves -They are used in RADAR devices. γ -rays- It is used in radio therapy.	3M
	ANS: 2 1.Given: $B_y = 8 \times 10^{-6} \sin [2 \times 10^{11} t + 300 \pi x]$ T (i) Standard equation is,	3

	$B_y = B_0 \sin\left[2\pi\left(\frac{x}{\lambda}+\frac{t}{T}\right)\right]$ $\Rightarrow B_y = B_0 \sin\left[\frac{2\pi t}{T}+\frac{2\pi x}{\lambda}\right]$ Comparing it with the given expression: $\frac{2\pi}{\lambda} = 300\pi \quad \therefore \lambda = \frac{1}{150}$ m $=$ **0.67 cm** (*ii*) Speed of light, $C = \frac{E_0}{B_0}$ $\therefore E_0 = C \times B_0 = 3\times10^8\times8\times10^{-6}$ $= 2400\ \text{Vm}^{-1}$ $E_z = E_0 \sin(2\times10^{11}t + 300\pi x)\ \text{Vm}^{-1}$ $\therefore E_z = 2400 \sin(2\times10^{11}t + 300\pi x)\ \text{Vm}^{-1}$ The oscillations of E→ and B→ fields are perpendicular to each other as well as to the direction of propagation of the wave. So we take electric field in z-direction because oscillating magnetic field is in y-direction and propagation of the wave is in x-direction.	
	ANS 3 . (a) We compare the given expression with $E_y = E_0 \sin\left(\frac{2\pi}{T}t+\frac{2\pi}{\lambda}x\right)$ $\frac{2\pi}{\lambda} = 300\pi \quad \Rightarrow \lambda = \frac{2\pi}{300\pi}$ $\Rightarrow \lambda = \frac{1}{150}$ m $\quad \therefore \lambda = \frac{2}{3}$ cm (*b*) $B_Z = B_0 \sin(2\times10^{11}t + 300\pi x)$, $C = \frac{E_0}{B_0}$ $B_0 = \frac{E_0}{C} = \frac{30}{3\times10^8} = 10^{-7}$ T $\therefore B_Z = 10^{-7} \sin(2\times10^{11}t + 300\pi x)$ T	3
	ANSWERS TO CASE STUDY – 1	
	1. b	1
	2 b	1
	3. a	1
	4. b	1
	ANSWERS TO CCT QUESTIONS	
	1 (b) 54MHz to 890 MHz	1
	2. (d) microwave oven	1
	3 (d) 700 – 400 nm	1
	4. Because they heat up the objects which are coming in their path.	1

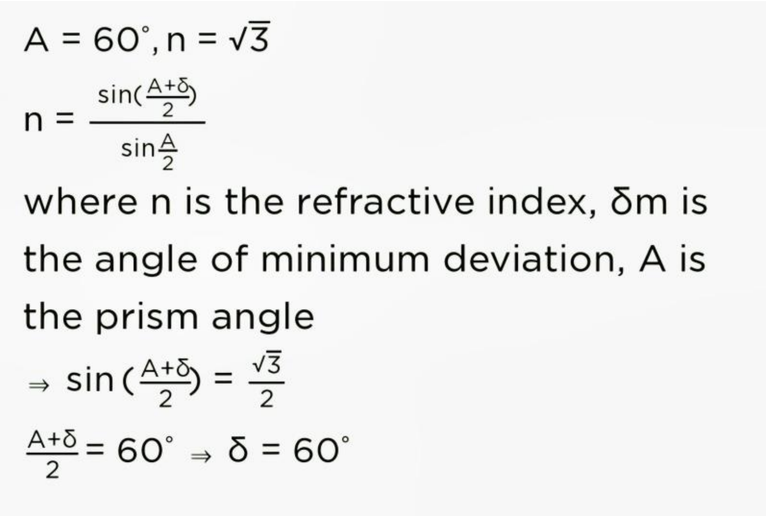
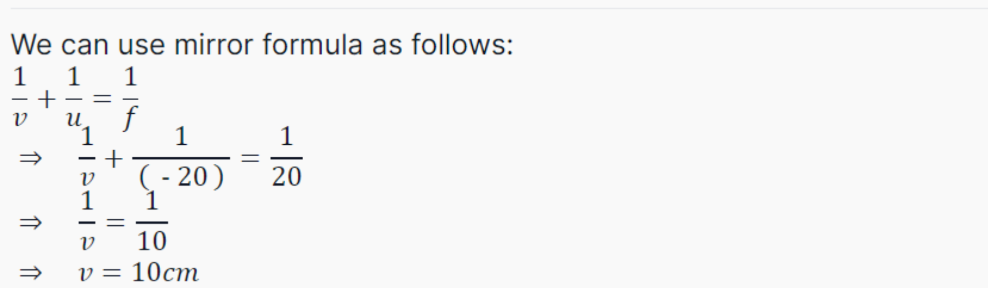
	OR The very harmful ultraviolet rays coming from the sun are absorbed by the ozone layer in the atmosphere which is at an altitude of 40 – 50 km from the earth's surface. And due to which very less ultraviolet light rays from the sun reach the earth. Ultraviolet rays are very harmful to humans which may cause skin cancer. In this way, the ozone layer in the atmosphere plays a very protective role.	
	ANS TO COMPETENCY BASED QUESTION	
	1.b)Infrared waves because it has heat waves to generate energy	
	2.(d) radio waves	
	3. (c) cathode rays	
	4. (a)	
	ANSWERS TO SELF ASSESMENT QUESTIONS	
	ANS 1. The wavelength of infrared region is 8×10^{-5} cm to (a) 3×10^{-3} cm. So maximum wavelength of infrared region $= 8 \times 10^{-5}$ cm 10^{-4} cm.	1M ≈
	2.Radiowaves are reflected by ionosphere	1M
	3. a) I.R.	1M
	4.(d) Displacement current arises when electric field in a region is changing with time,	
	5.(a)	1M
	6. (a)X rays - used in in detection of fractures in bones. (b)Gamma rays- used in radio therapy for treatment of cancer.	2 M
	7. i) and ii) UV rays	2M
	8. Conduction current is converted into electric field For detail answer refer NCERT text book	2M
	.9. IR radiation: • It is used in infrared photography •TV remote as a signal carrier •Heat therapy for muscular pain or sprain. Microwaves : • It is used in Radio and Television communication system • It is used in cellular phones (Voice communication) UV radiation: • It is used to destroy bacteria in sterilizing the surgical instruments. • It is used in Burglar alarm • It is used to detect the invisible writing, finger prints.	3M
	10.Refer NCERT text book/GIST of this chapter	3M
	CASE BASED QUESTION	
	1.(a)	
	2.(a)Greenhouse effect is due to infrared rays.	
	3.(a) Greenhouse effect is due to infrared rays.	
	4 (b) The atmosphere of earth is richest in infrared radiation.	

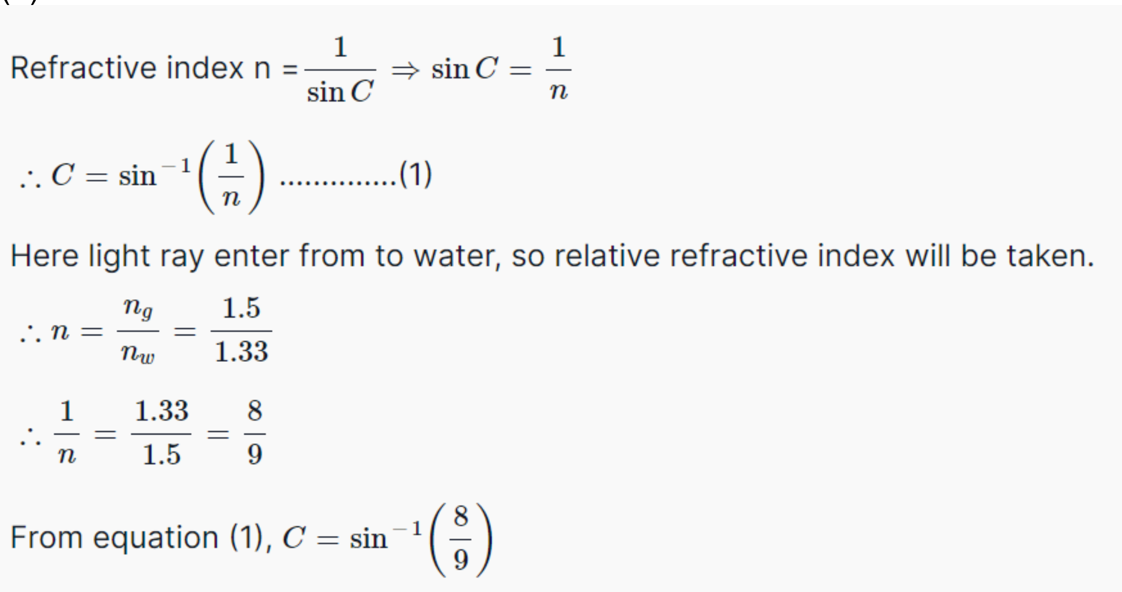
	FIVE MARKS QUESTION	
	1. a) (i) Microwaves are suitable for RADAR systems that are used in aircraft navigation. These rays are produced by special vacuum tubes, namely klystrons and magnetrons diodes. (ii) Infrared rays are used to treat muscular strain. These rays are produced by hot bodies and molecules. (iii) X-rays are used as a diagnostic tool in medicine. These rays are produced, when high energy electrons are stopped suddenly on a metal of high atomic number. b) LASER-Light amplification by stimulated emission of radiation RADAR-Radio detection and ranging. c) Whenever changing the electric flux (ΦE) in the region encircled by loop, then magnetic field is induced.	3M+1+1

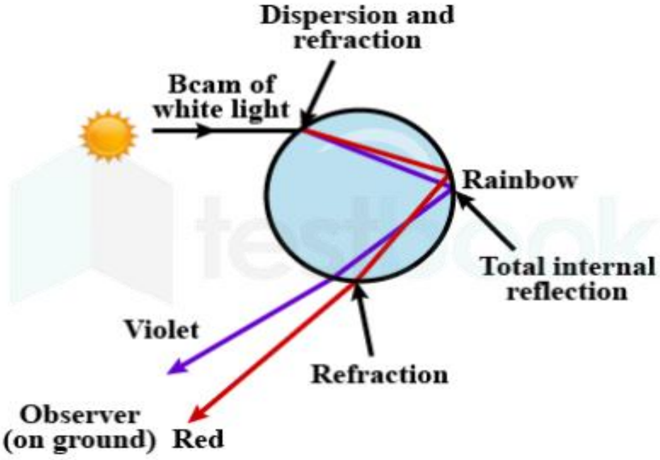
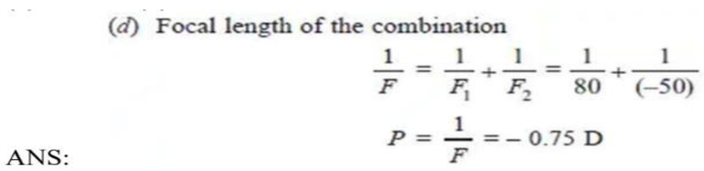
UNIT VI – OPTICS

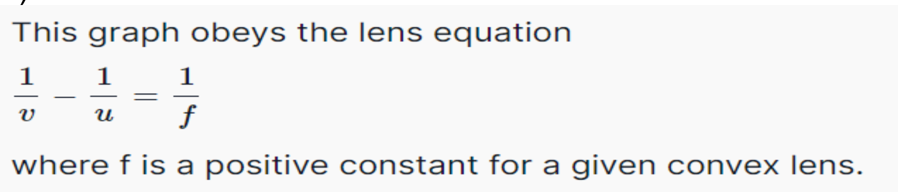
CHAPTER 9- RAY OPTICS AND OPTICAL INSTRUMENTS

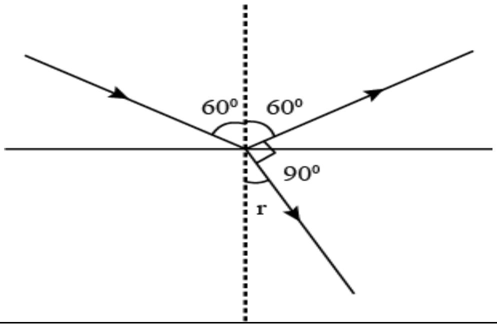
DETAILED ANSWERS

SN	ANSWERS	Marks
	LEVEL-1 (MCQ ANSWERS)	
1	c) 1D P= P1+P2 4-3=1	1
2	c) When an object approaches a convergent lens from the left of the lens with a uniform speed of the image moves away from the lens with a non-uniform acceleration.	1
3	b)  $A = 60^\circ, n = \sqrt{3}$ $n = \frac{\sin(\frac{A+\delta}{2})}{\sin\frac{A}{2}}$ where n is the refractive index, δm is the angle of minimum deviation, A is the prism angle $\Rightarrow \sin(\frac{A+\delta}{2}) = \frac{\sqrt{3}}{2}$ $\frac{A+\delta}{2} = 60^\circ \Rightarrow \delta = 60^\circ$	1
4	a) 10cm  We can use mirror formula as follows: $\frac{1}{v} + \frac{1}{u} = \frac{1}{f}$ $\Rightarrow \frac{1}{v} + \frac{1}{(-20)} = \frac{1}{20}$ $\Rightarrow \frac{1}{v} = \frac{1}{10}$ $\Rightarrow v = 10cm$	1
5	(c) u – v curve is a rectangular parabola	1
6	(b) Air bubble in water behaves as a concave lens. The refractive index of water is greater than that of air,	1

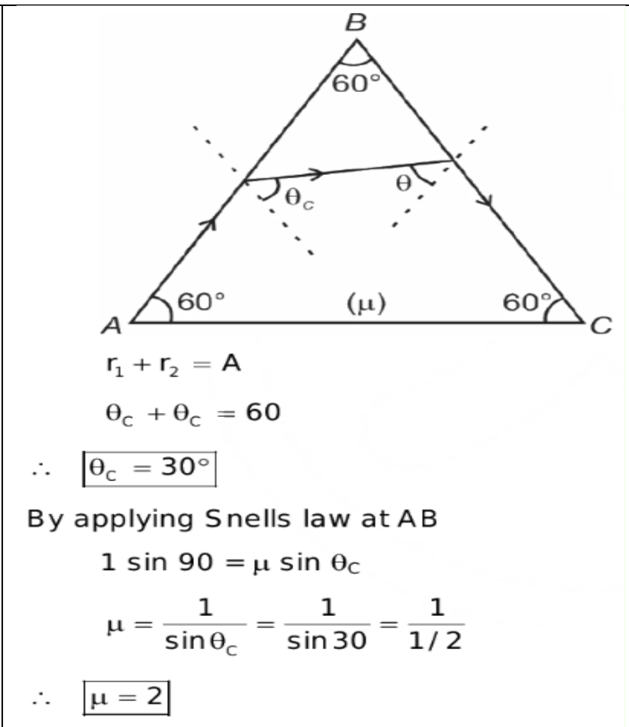
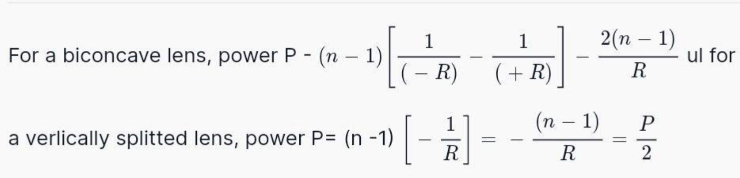
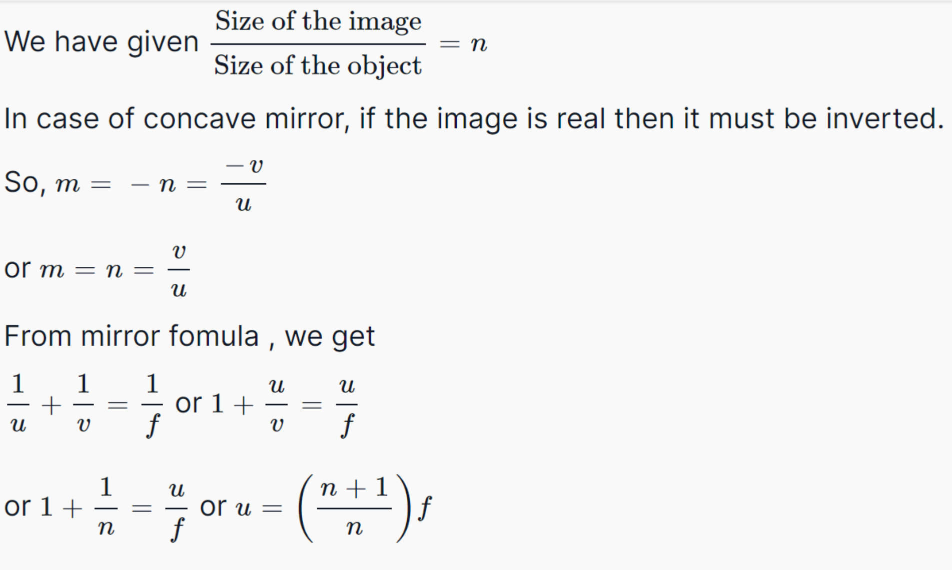
	ηwater>ηair. This implies that, water is a denser medium than air. Let us consider that a light ray passes through water and enters an air bubble. So, the light ray enters from a denser to rarer medium. So, a ray diagram can be drawn as given below. The ray of light entering the air bubble will diverge, since the ray of light entering from a denser to rarer medium bends away from the normal. Hence, it behaves like a concave lens.	
7	(a)  Refractive index n = $\frac{1}{\sin C} \Rightarrow \sin C = \frac{1}{n}$ $\therefore C = \sin^{-1}\left(\frac{1}{n}\right)$ ....(1) Here light ray enter from to water, so relative refractive index will be taken. $\therefore n = \frac{n_g}{n_w} = \frac{1.5}{1.33}$ $\therefore \frac{1}{n} = \frac{1.33}{1.5} = \frac{8}{9}$ From equation (1), $C = \sin^{-1}\left(\frac{8}{9}\right)$	1
8	(b) In a spherical mirror, when a beam of light passing through Focus falls on the mirror, the ray after reflection from the mirror becomes parallel to the principal axis of the mirror. The ray number (2) travels parallel to the principal axis after being reflected and remains on the same side of the incident ray. The ray number (4) is not possible because the ray cannot travel on the opposite side of the mirror after reflection. Hence, option (b) is correct.	1
9	(c) Rainbow is formed due to dispersion of sunlight by raindrops ,refraction and total internal reflection inside the raindrop. When sunlight falls on the drops of rain formation of a Rainbow occurs in the sky. These droplets work as a prism for the rays coming from the sun. When the sunlight gets through these droplets, it results in refraction and dispersion in seven colors known as VIBGYOR. Then it goes to total internal reflection. This happens due to combined phenomena of Dispersion, Refraction, and Total Internal reflection in the atmosphere.	1

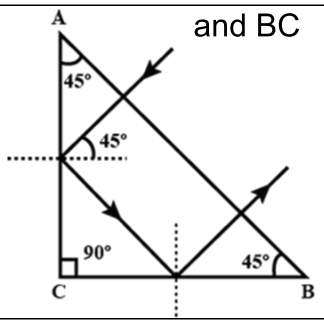
		
10	(c) Distance between object and image = 0.5 + 0.5 = 1.0 m The image formed by a plane mirror is as far behind the mirror as the object is in front of it. Therefore, if the object is at a distance of 0.5m in front of plane mirror, then the distance between the object and image is 1.0m.	1
11	(d) In normal vision, length of telescope L = fo + fe	1
12	(d)  (*d*) Focal length of the combination $\frac{1}{F} = \frac{1}{F_1} + \frac{1}{F_2} = \frac{1}{80} + \frac{1}{(-50)}$ ANS: $P = \frac{1}{F} = -0.75$ D	1
13	a)QR parallel to BC ∠AQR=60 ∠MQR=(90−60) =30 ∠LQR=(5°−30) =20 Similarly ∠LRQ=20 δ=20+20=40 or Aliter: D=2i−A=100−60=40	1
14	a) convergent lens of focal length 100cm P= P1+P2	1
15	a) 0° Incident ray is always parallel to emergent ray	1
16	d) Infinity	1
17	a)infinity	1

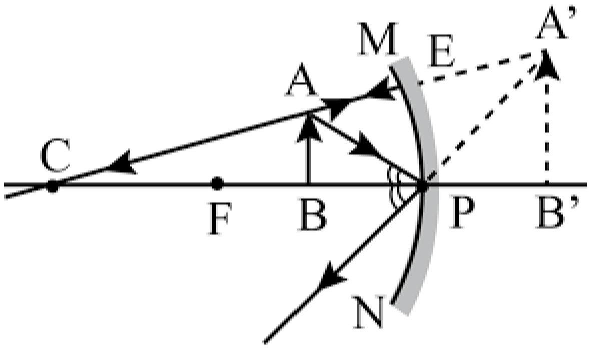
	u = -x v= + x put in mirror formula	
18	a)become infinite	1
19	Speed of light in glass, $v_G = \frac{c}{\mu_G} = \frac{3\times10^8}{\left(\frac{3}{2}\right)} = 2\times10^8$ m/s Speed of light in water, $v_w = \frac{c}{\mu_w} = \frac{3\times10^8}{\left(\frac{4}{3}\right)} = \frac{9}{4}\times10^8$ m/s $\therefore \frac{v_w}{v_G} = \frac{\frac{9}{4}\times10^8}{2\times10^8} = \frac{9}{8} \quad \Rightarrow \boxed{v_w = \frac{9}{8}v_G}$ Speed of light in water is $\frac{9}{8}$ times speed of light in glass c)	1
20	b) Intensity of image is halved if you cover half of a convex lens with black paper, the image formed will be complete, but its intensity will be reduced. This is because the black paper stops refraction through the lens, which decreases the area of the lens that's responsible for refraction. The rays that were previously passing through the covered region are no longer passing, so the intensity of the image will be reduced.	1
	LEVEL-2 (MCQ ANSWERS)	
1	a) This graph obeys the lens equation $\frac{1}{v} - \frac{1}{u} = \frac{1}{f}$ where f is a positive constant for a given convex lens. this equation should be satisfied, u is always negative.	1
2	(a) m= D/F 1/F = P So m= DP	1
3	(b) n1<n	1

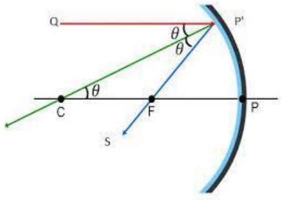
4	(d) 2f Solving by l;ens formula taking R1= infinity for plano convex lens R2= -R	1
5	(d) 5/3 $\mu a=1$ $\mu g=1.5$ $P_1=+5D$ $P1=1/f=(\mu g/\mu a-1)(1/R1-1/R2)=+5D$. . . . . .(1) Now, When convergent lens immersed in a liquid of refractive index μ, convergent lens act as a diverging lens of focal length −100cm $P2=1/f=(\mu g/\mu-1)(1/R1-1/R2)=-100/100=-1D$. . . . . . (2) Divide equation (1) by equation (2), we get $P1/P2=(\mu g/\mu a-1)/\mu g/\mu-1=-5$ $\mu g/\mu 1=-5(\mu g/\mu-1)$ $1.5-1=-5(1.5/\mu-1)$ $0.55=-(1.5/\mu-1)$ $\mu=5/3$	1
6	(b) √3  	1
7	(d) 4000	1

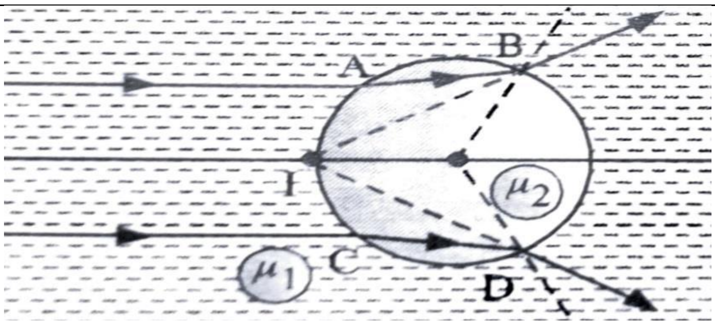
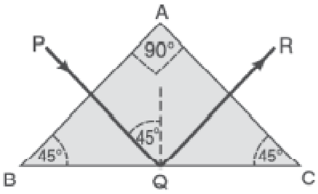
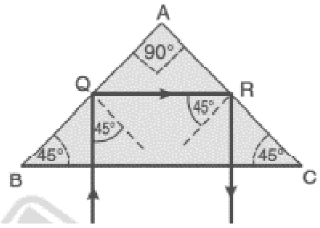
	$\lambda_{\text{medium}} = \frac{\lambda_{\text{air}}}{(R.I.)}$ In this case , $\lambda_{\text{air}} = \frac{1mm}{2000} = \frac{10^{-3} \times 10^{10}\text{Å}}{2000}$ = 5000 Å $\therefore \lambda_m = \frac{5000}{1.25} = 4000$ Å	
8	(b) 3.72 D When the lens is in air $\frac{1}{f_a} = (\mu_g - 1)\left(\frac{1}{R_1} - \frac{1}{R_2}\right)$ $\frac{1}{20} = (1.5 - 1)\left(\frac{1}{R_1} - \frac{1}{R_2}\right)$ ...(i) When lens is in water, $\frac{1}{f_w} = \left(\frac{\mu_g}{\mu_w} - 1\right)\left(\frac{1}{R_1} - \frac{1}{R_2}\right)$ or $\frac{1}{f_w} = \left(\frac{1.5 - 1.33}{1.33}\right)\left(\frac{1}{R_1} - \frac{1}{R_2}\right)$ ....(ii) Divide (i) by (ii), we get or, $\frac{f_w}{20} = (1.5 - 1)\left(\frac{1.33}{1.5 - 1.33}\right)$ or, $f_w = 20 \times 0.5 \times \frac{1.33}{0.17} = 78.2cm$ The change in focal length = $78.2 - 20 = 58.2\,cm$	1
9	(d) 2f at 2F, M=1	1

10	 $r_1 + r_2 = A$ $\theta_C + \theta_C = 60$ $\therefore \boxed{\theta_C = 30°}$ By applying Snells law at AB $1 \sin 90 = \mu \sin \theta_C$ $\mu = \frac{1}{\sin\theta_C} = \frac{1}{\sin 30} = \frac{1}{1/2}$ $\therefore \boxed{\mu = 2}$	1
	LEVEL-3 (MCQ ANSWERS)	
1	B  For a biconcave lens, power P - $(n-1)\left[\frac{1}{(-R)} - \frac{1}{(+R)}\right] - \frac{2(n-1)}{R}$ ul for a verlically splitted lens, power P= (n -1) $\left[-\frac{1}{R}\right] = -\frac{(n-1)}{R} = \frac{P}{2}$	1
2	B. The light undergoes minimum deviation through the prism (i.e., r1 = r2).	1
3	D. Increase in the focal length of the objective and decrease in the focal length of the eye piece.	1
4	A. (p+1)*f/p EXPLANATION  We have given $\frac{\text{Size of the image}}{\text{Size of the object}} = n$ In case of concave mirror, if the image is real then it must be inverted. So, $m = -n = \frac{-v}{u}$ or $m = n = \frac{v}{u}$ From mirror fomula , we get $\frac{1}{u} + \frac{1}{v} = \frac{1}{f}$ or $1 + \frac{u}{v} = \frac{u}{f}$ or $1 + \frac{1}{n} = \frac{u}{f}$ or $u = \left(\frac{n+1}{n}\right)f$	1

5	C. Statements II and III are correct.	1
6	A. The image moves slower initially and faster later on, away from the mirror As the object moves from infinity to centre of curvature the image formed by a concave mirror would be real and is moving from focus to centre of curvature but as the object crosses centre of curvature and moves towards focus the image is still real but moves from centre of curvature towards infinity and when the object is at focus the real image would be formed at infinity So image speed is smaller in beginning when the object is moving from infinity to centre of curvature and increases thereafter.	1
7	From figure it is clear that TIR takes place at surface AC and BC i.e. 45o > C ⇒sin45 > sinC ⇒1√2>1μ ⇒μ>√2 Hence μleast = √2 	1
8	:a) Snell's law for each of the interfaces: $n \sin\theta_1 = n/5. \sin(90) = n/5 \times 1$ $\sin\theta_1 = 1/5$ $\theta_1 = \sin^{-1}(1/5)$	1
9	D. Assertion is false but reason is true. Explanation: If the refractive index is the same for two mediums, then the light wave will travel in a straight line without any bending.	1
10	a) When a ray of light travels from a medium to another medium having different refractive index, the ray bends. Since in the above figure, ray of light passes through the first lens without deflection, this means that μ1=μ2	1
	LEVEL-1 (2 M ANSWERS)	
1	The phenomenon by which rays of light proceeding from an object in the denser medium return back to the same medium when incident at an angle greater than the critical angle for the pair of media is called total internal reflection. Conditions for TIR Objects should be placed in the denser medium. Angle of incidence in the denser medium should be greater than the critical angle for the pair of media. μ= Sin ic	1 1
2	a)NO change in focal length	.5

	b) If v1 and v2 denote the velocity of light in medium 1 and medium 2 respectively and λ1 and λ2 denote the wavelength of light in medium 1 and medium 2. f=v/λ The above equation implies that when a wave gets refracted into a denser medium (v1 > v2) the wavelength and the speed of propagation decreases but the frequency v (=v/λ) remains the same	.5 1
3	 m = positive and greater than 1	1 1
4	In general, any given value of deviation δ, (except for i= e) corresponds to two values i and e. This is expected from the symmetry of i and e as δ= i + e – A, i.e., δ remains the same if i and e are interchanged. Point P is the point of minimum deviation. This is related to the fact that the path of the ray as shown in Figure can be traced back resulting in the same angle of deviation. At the minimum deviation δm, the refracted ray inside the prism becomes parallel to the base.	1 1
5	Linear magnification Also known as lateral or transverse magnification, this is the ratio of the length of the image to the length of the object. It's constant for all objects and takes into account everything about the image. Angular magnification This is the ratio of the tangents of the angles subtended by an object and its image from a given point. It only considers the size of the field of view that the image occupies m= size of image/ size of object= h2/ h1 Total magnification, M = m1 * m2 * m3= 2 * 3 * 10 = 60	.5 .5 1
6	The relationship between the focal length f and the radius of curvature R = 2f.	1

	 Consider a ray of light QP', parallel to the principal axis and incident on a spherical mirror at point P'. The normal to the surface at point P' is CB and CP = CP' = R is the radius of curvature. The ray AB, after reflection from a mirror, will pass through F (concave mirror) or will appear to diverge from F (convex mirror) and obeys the law of reflection i.e. i = r. From the geometry of the figure, ∠CP'Q = θ = i In ∠ CP'F, θ = r ∴BF = FC (because i = r) If the aperture of the mirror is small, B lies close to P, and therefore BF = PF Or FC = FP = PF Or PC = PF + FC = PF + PF Or R = 2 PF = 2f Or f = R/2 Similar relation holds for convex mirror also. In deriving this relation, we have assumed that the aperture of the mirror is small.	1
7	(A) Spherical Aberration: It is the defect of lens due to which, all the parallel rays passing through the convex lens are not focussed at a single point on the principal axis and hence, the image of a point object formed by the lens is blurred. This is called spherical aberration. (B) Chromatic Aberration: It is the defect of lens due to which the image of a white object formed by a lens is coloured or blurred. This is called chromatic aberration Spherical aberration can be minimized by using stops. In this method either paraxial or marginal rays are cut off by putting black paper on the lens so that rent of the rays comes to a point focus.	½ ½ 1
8	a)No. A convex mirror always forms a virtual image which cannot be obtained on a screen. b)When a light ray passes from water into an air bubble, it enters from a denser to a rarer medium. This causes the light ray to bend away from the normal, or diverge, and behave like a concave lens.	½ ½ ½ ½

		
	LEVEL-2 (2 M ANSWERS)	
1	Power of the convex lens increases, because $P \propto (\mu - 1)$ and $\mu_V > \mu_R$ $\mu \propto 1/$ wavelength wavelength of violet is less than that of red light.	1 1
2	a)  b) 	1 1
3	a)speed of light wave = frequency X wavelength v= f X wavelength Reflection and refraction arise through the interaction of incident light with the atomic constituents of matter. Atoms may be viewed as oscillators that take up the frequency of the external agency (light) causing forced oscillations. The frequency of light emitted by a charged oscillator equals its frequency of oscillation. Thus the frequency of scattered light equals the frequency of incident light. b)Benefits of using a lens combination any two points Increasing the image's magnification. Increasing the sharpness of an image by reducing the flaws generated by a single image. Giving the constructed image about the thing. Expanding the field of view.	1 1

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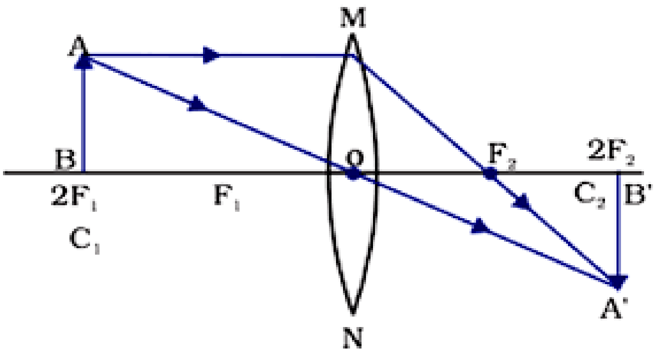

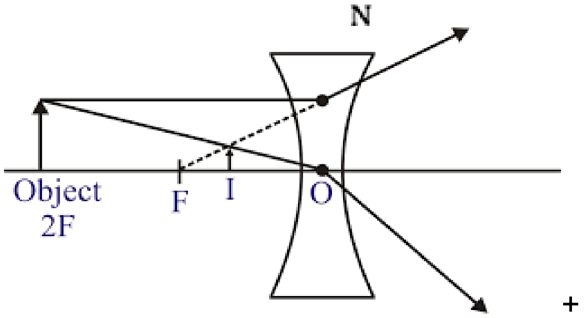

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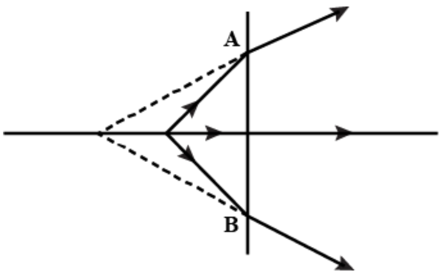
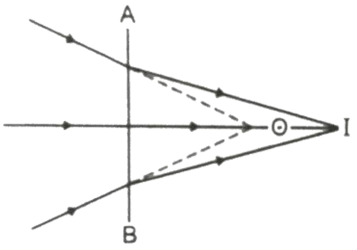
i) Convex —-The lens is concave because it diverges the light ray.



ii) Concave



The line AB represents a concave lens because rays converging towards O, diverge to meet at I.

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LEVEL-3 (2 M ANSWERS)

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(a) The scattering of light by the atmosphere is colour dependent. According to Rayleigh's law, the intensity of scattered light, $I \propto 1\lambda 4$
Blue light is scattered much more strongly than red light. The blue component of light is proportionately more in the light coming from different parts of the sky. This gives the impression of the blue sky.

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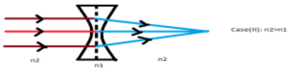
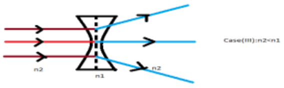
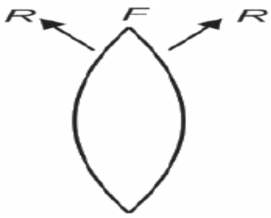
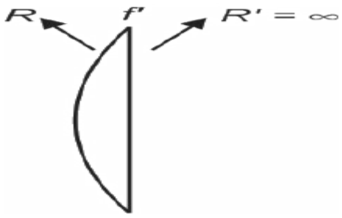
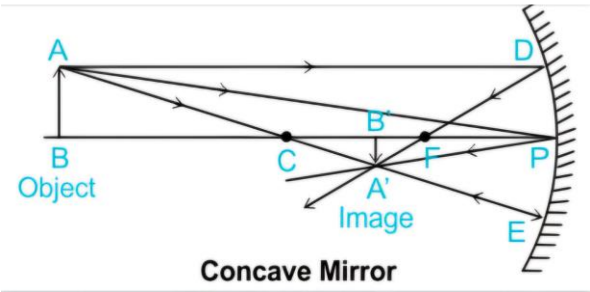
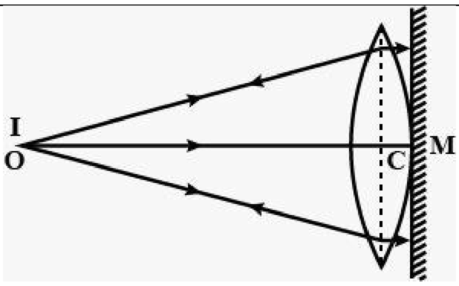
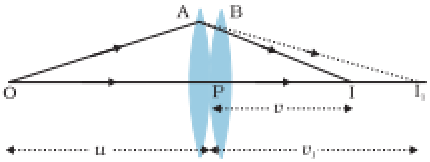
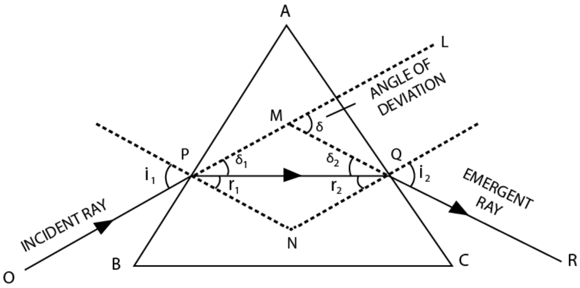
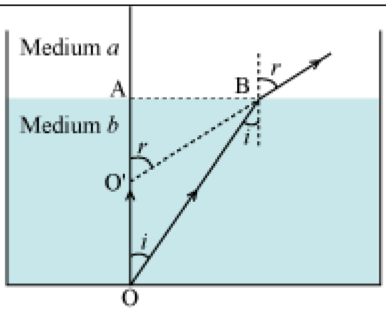
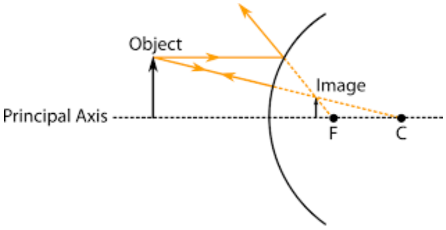
	(b) As refractive index of prism is different for different colours, therefore, different colours deviate through different angles on passing through the prism. As λviolet < λred therefore µviolet > µred. Hence δviolet > δred maximum deviation is of violet colour. That is why violet colour, is seen at the bottom of the spectrum when white light is dispersed by a prism	
2	Advantages of reflecting type telescope over refracting type : Chromatic aberration-Reflecting telescopes use mirrors instead of lenses, so they don't suffer from chromatic aberration, which is the dispersion of light according to wavelength. Size and weight-Mirrors can be made larger and thinner than lenses, making reflecting telescopes lighter and easier to support mechanically. Image brightness-Reflecting telescopes produce brighter images than refracting telescopes. Cost-Reflecting telescopes are cheaper to build, especially large ones. Spherical aberration-Reflecting telescopes can use parabolic mirrors to reduce spherical aberration. Tube length-Reflecting telescopes have shorter tubes than refracting telescopes of the same diameter, which reduces costs	.5 .5 .5 .5
3	  the lens will behave as plane glass when n1= n2 	.5 .5 .5 .5
	LEVEL-1 (3 M ANSWERS)	

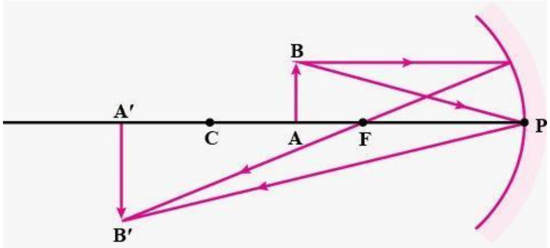
1.	 By lens maker formula, $\frac{1}{F} = (\mu - 1)\left[\frac{1}{R} - \frac{1}{(-R)}\right]$ $\frac{1}{F} = \frac{2(\mu - 1)}{R}$  $\frac{1}{f'} = (\mu - 1)\left[\frac{1}{R} - \frac{1}{(-\infty)}\right]$ $\frac{1}{f'} = \frac{\mu - 1}{R} = \frac{1}{2F}$ Focal length of each part, $f' = 2F$	1 1 1
2	ΔABC and $\Delta A'B'C$ are similar triangles.  $\frac{AB}{A'B'} = \frac{CB}{C'B'}$ Similarly, ΔABP, and $\Delta A'B'P$ are also similar triangles $\frac{AB}{A'B'} = \frac{PB}{P'B'}$ ′ Thus, combining both the relations we get, $AB/A'B' = CB/CB' = PB/PB'$ $\therefore CB/CB' = PB/PB'$ Measuring all the distances from the pole (P) we get, $CB = PB - PC$ $CB' = PC - PB'$ Putting the values of CB and CB' in the above equation, we get,	1 1

	$PB–PC/PC–PB'=PB/PB'$ Using cartesian sign convention, we get, $PB=–u$ $PC=–R$ $PB'=–v$ Here, u is the object distance, v is the image distance, and R is the radius of curvature. Now, substituting the values of PB,PB' and PC in the above equation, we get, $–u–(–R)–R–(–v)=–u–v$ $\therefore –u+R–R+v=uv$ Now, by simplifying the equation, we get, $v(–u+R)=u(–R+v)$ $–vu+vR=–uR+uv$ or $uR+vR=2uv$ Now, dividing both the sides by uvR, we get, $1/v+1/u=2/R$ But we know that, $f=R/2$ $\therefore 1/v+1/u=1/f$	1
3.	$\frac{1}{f} = (\mu - 1)\left(\frac{1}{R_1} - \frac{1}{R_2}\right)$ $\frac{1}{f} = \left(\frac{\mu_m}{\mu_w} - 1\right)\left(\frac{1}{R_1} - \frac{1}{R_2}\right)$ $\frac{\mu_m}{\mu_w} = \frac{1.25}{1.33}$ $\frac{\mu_m}{\mu_w} = 0.98$ The value of (μ – 1) is negative and ‘f’ will be negative. So it will behave like diverging lens. b) Figure shows a convex lens placed in contact with a plane mirror. An axial point object is placed at a distance O at a distance, OC = 20cm. As the image I of the object coincides with O, the rays refracted first from the lens and then refracted by the plane mirror must be retracing their path. This would happen when rays refracted by the convex lens fall normally on the mirror I.e, the refracted rays form a beam parallel to principal axis of the lens. Hence the object O must be at the focus of the convex lens. f = CO = 20 cm.	1 1 .5

		.5
4	Let us consider the two thin lenses A and B forming the image I and I_1 respectively, from the object (O) For I the distance is u and for I_1 the distance is v_1.  For lens 'A', the lens formula is ; $\frac{1}{f1}=\frac{1}{v1}-\frac{1}{u}$ Where v1 is the image distance, u is the object distance For lens 'B' , the lens formula is : $\frac{1}{f2}=\frac{1}{v}-\frac{1}{v1}$ On adding both $\frac{1}{f2}+\frac{1}{f1}=\frac{1}{v}-\frac{1}{u}$ $\frac{1}{f}=\frac{1}{f1}+\frac{1}{f2}$	1 1 1
5.	 in the case of minimum deviation,	

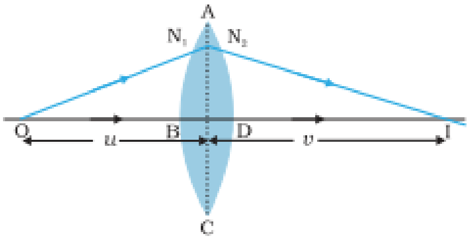
	$\angle r1=\angle r2=\angle r$ $\delta = i1 - r1 + i2 - r2$ $\delta = i1 + i2 - (r1 + r2)$ $r = A/2$ $i_1 + i_2 = A + \delta$ $i_1 + i_1 = A + \delta m$ $2i_1 = A + \delta m$ $i_1 = A + \delta m/2$ $\mu = \sin i/\sin r$ Therefore, we get $\mu = \dfrac{\text{Sin}\left[\dfrac{A+\delta_m}{2}\right]}{\text{Sin}\left(\dfrac{A}{2}\right)}$ This is the required prism formula for a thin prism.	1 1 1
	LEVEL-2 (3 M ANSWERS)	
1		1 1

	$\therefore \frac{\text{refractive index of air} \quad n_1}{\text{refractive index of denser medium} \quad n_2}$ $\therefore \frac{1}{n} = \frac{h_1}{h_2} [\therefore \text{For air} \quad n_1 = 1]$ $\therefore n = \frac{h_2}{h_1} = \frac{\text{real depth}}{\text{apparent depth}}$ $\therefore$ Apparent depth $h_1 = \frac{\text{real depth} \quad h_2}{\text{refractive index of denser medium n}}$ Remember : $\frac{\text{n(denser)}}{\text{n(rarer)}} = \frac{\text{apparent depth}}{\text{real depth}}$	1
2	For a convex mirror, f > 0 and for an object on left, u < 0 From mirror formula, $\frac{1}{v} = \frac{1}{f} - \frac{1}{u}$ As f is + ve and u is − ve, so > 0 ∴ v > 0 Thus, a convex mirror always produces a virtual image, independent of the location of the object 	1 1 1
3	a)Changes in the angle of deviation as we increase: (i) The wavelength of incident light As we increase the wavelength, the angle of deviation decreases. (ii) The refracting angle of the prism The angle of deviation increases with the increase in the angle of the prism b) Refractive index of a glass prism is given by	.5 .5

	μ= $\left(\frac{\sin(A+\delta_m)}{\sin\frac{A}{2}}\right)$ When the prism is held in water, If a glass prism is dipped in water then relative refractive index decreases. So minimum deviation angle will also decrease c) This happens when the prism is immersed in transparent medium having refractive index greater than that of the prism material.	1 1
	LEVEL-3 (3 M ANSWERS)	
1	i)  ii) It states that, on reversing the path of a ray of light suffering a number of reflections and refractions, the ray of light retraces its original path. Let us consider plane XY separating two-media Medium (say 1 and 2) of different refractive indices. When ray of light travels from medium i to medium 2, The refractive index n12= Sin i/Sin r ....(i) When ray of light travels from medium 2 to medium I. The refractive index n21= Sin r/Sin i ....(ii) Multiplying equation (i) and (ii),n21×n12=sinisinr/sinr sini n_{21}=1/n_{12}	1 1 1
2	i)Telescope: L1 as objective and L2 as eyepiece Reason: The objective should have large aperture and large focal length while the eyepiece should have small aperture and small focal length. Then the light gathering power and magnifying power will be larger. (ii) Microscope: L3 as objective and L2 as eyepiece Reason: Both the lenses of the microscope should have short focal lengths and the focal length of the objective should be smaller than that of the eyepiece. Magnifying power will be larger for short focal lengths of objective and eyepiece. iii) The aperture is preferred to be large so that the telescope can collect as much as light coming from the distant object as possible.	1 1 1

3	a)The two most important factors considered to increase the magnifying power of an optical instrument like a telescope or microscope are: 1. Focal Length of the Objective Lens: A larger focal length for the objective lens directly translates to higher magnification. This is because the objective lens gathers light and focuses it to form an enlarged image. A longer focal length allows for greater bending of light rays, resulting in a bigger image. 2. Focal Length of the Eyepiece: Conversely, a shorter focal length for the eyepiece contributes to increased magnification. The eyepiece acts like a magnifying glass, further enlarging the image formed by the objective lens. A shorter focal length allows the eyepiece to magnify the image to a greater extent. Additional factors: While the focal lengths are the primary factors, other aspects can also influence magnification, such as: Aperture of the objective lens: A larger aperture allows for gathering more light, resulting in a brighter and potentially more detailed image. Distance between objective and eyepiece: Adjusting this distance can fine-tune the magnification. Quality of the lenses: High-quality lenses with minimal aberrations provide sharper and clearer images, enhancing the perceived magnification. It's important to remember that increasing magnification alone doesn't necessarily guarantee better image quality. Other factors like resolution and image clarity also play crucial roles in the overall viewing experience. b) i)The objective lens of a telescope collects and focuses light from distant objects. It should have a large focal length to form a clear and magnified image. Lens B has a focal length of 20 cm, which is larger than lens A's 5 cm focal length. Therefore, lens B should be selected as the objective lens1. ii)Distance Between Lenses: To achieve normal adjustment, the distance between the lenses should be equal to the sum of their focal lengths. So, the distance between lenses = focal length lens A + focal length of lens B = 5 cm + 20 cm = 25 cm. iii) The magnifying power of a telescope is given by: Magnifying power=Focal length of objective lens/Focal length of eyepiece lens. = 20/5= 4	.5 .5 1 .5 .5
	LEVEL-1 (5 M ANSWERS)	
1	i) derivation If an object (at a medium with refractive index μ2) is placed at a distance u, in front of a spherical surface of refractive index μ2, having a radius of curvature R, an image is formed at a distance v from that surface such that,	

$$-\frac{\boldsymbol{\mu_1}}{u} + \frac{\mu_2}{v} = \frac{\mu_2 - \mu_1}{R}$$



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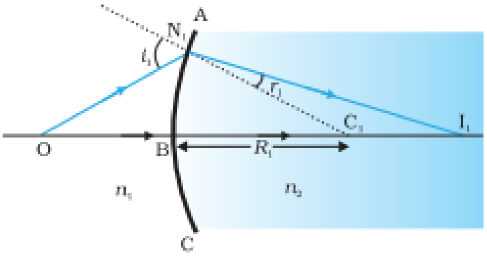
(a)



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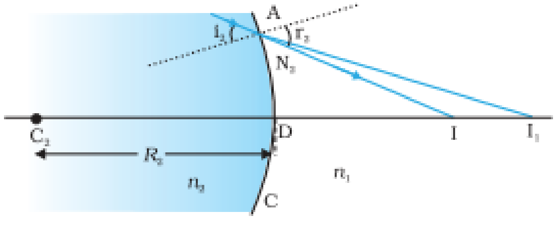
(b)



(c)

For refraction at the first surface, object distance OC ≈ OP = - u and image distance is =v'. The radius of curvature is R1. Then the object-image relation due to refraction at the first surface gives,

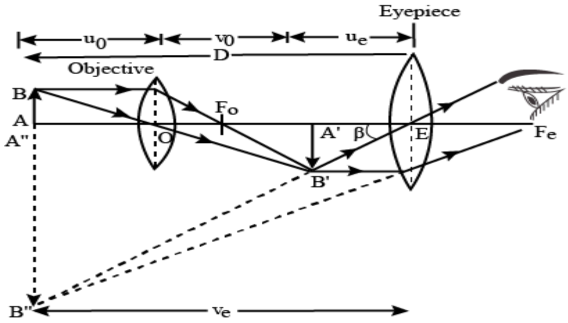
$$-\frac{\boldsymbol{\mu_1}}{u} + \frac{\mu_2}{v1} = \frac{\mu_2 - \mu_1}{R1}$$

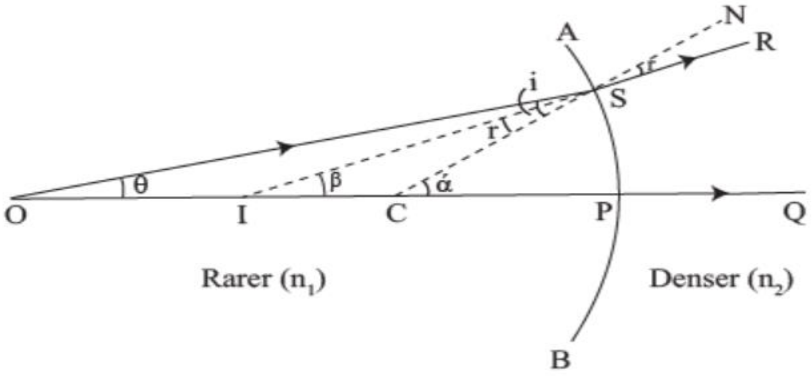
he intermediate image serves as the object for the second surface. Therefore, the object distance is =v' and the final image distance is =v. The radius of curvature is negative, i.e. -R2. Applying the object-image relation due to refraction at the second surface, .5

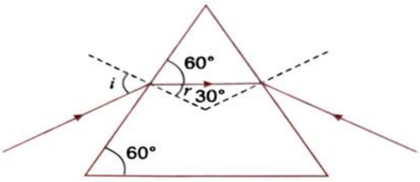
$$-\frac{\boldsymbol{\mu_2}}{v1} + \frac{\mu_1}{v} = \frac{\mu_1 - \mu_2}{R2}$$ .5

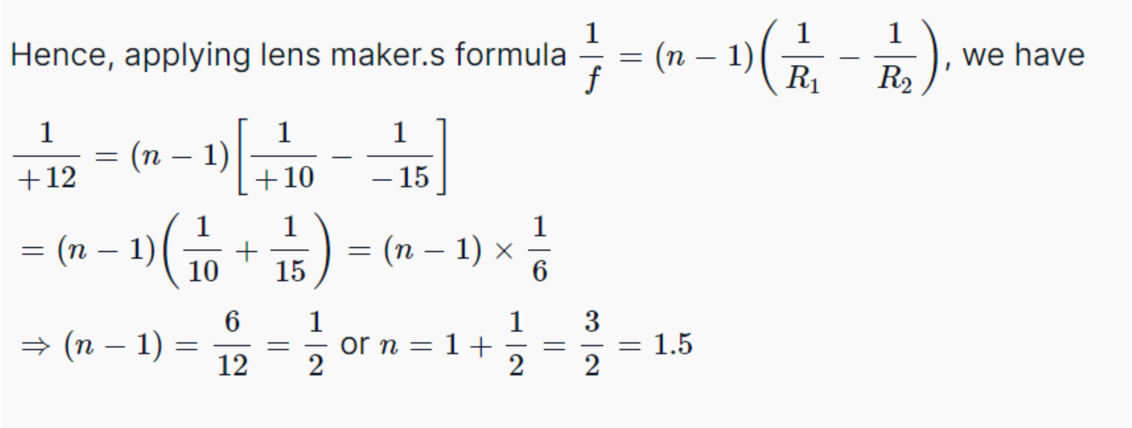
adding these two equations

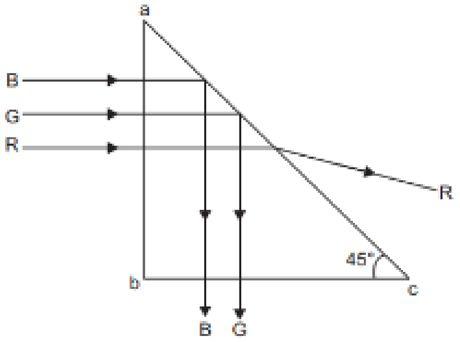
$$\frac{\mu_1}{v} - \frac{\mu_1}{u} = -\frac{\mu_2 - \mu_1}{R1} + \frac{\mu_1 - \mu_2}{R2}$$

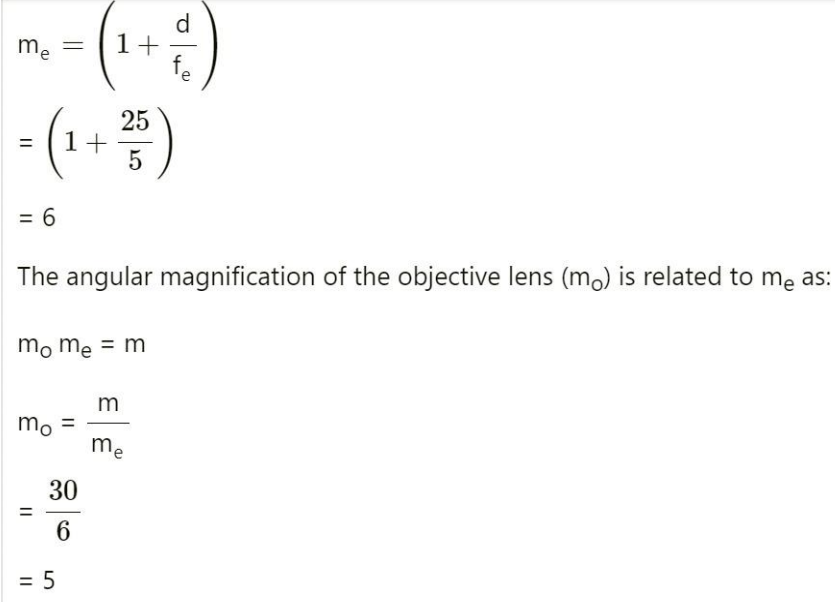
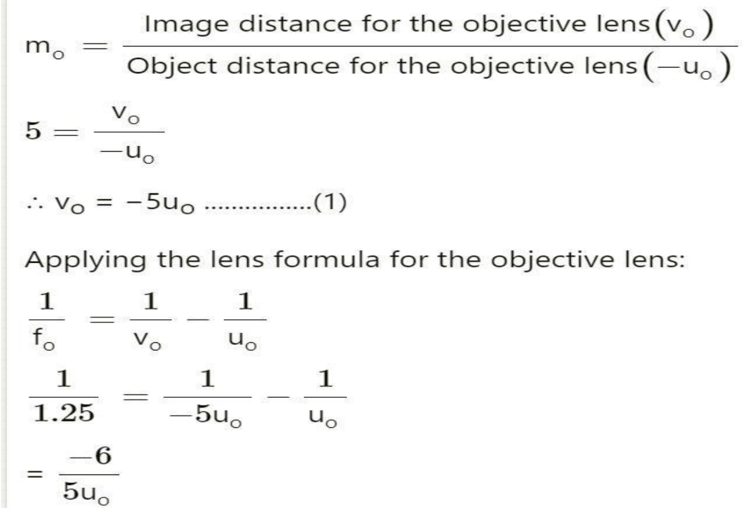
	$\frac{1}{v} - \frac{1}{u} = -\frac{\mu_2 - \mu_1}{R1} + \frac{\mu_1 - \mu_2}{R2}$ $-\frac{\boldsymbol{\mu_1}}{u} + \frac{\mu_2}{v} = \frac{\mu_2 - \mu_1}{R}$ ii)Assumptions made in derivation of Lens – maker's formula: (i) Aperture of the lens used should be very small (ii) The thickness of the lens should be less (iii) Object should be point sized and placed on the principal axis.	.5 .5 1
	LEVEL- 2 (5 M ANSWERS)	
1	a)  b)Derivation Now we can calculate the magnification due to the objective lens as follows: $m_o = \frac{h'}{h}$ In the figure we notice that $\tan\theta = \frac{h}{f_0} = \frac{h'}{L} \Rightarrow \frac{h'}{h} = \frac{L}{f_0}$. Using this, we get $m_o = \frac{L}{f_0}$ Now magnification due to eye piece is given as $m_e = \frac{D}{u_e} = 1 + \frac{D}{f_e}$ (Here we have used the lens formula) Now the total magnification is given as $m = m_o m_e = \left(\frac{L}{f_0}\right)\left(1 + \frac{D}{f_e}\right)$	1 1 1

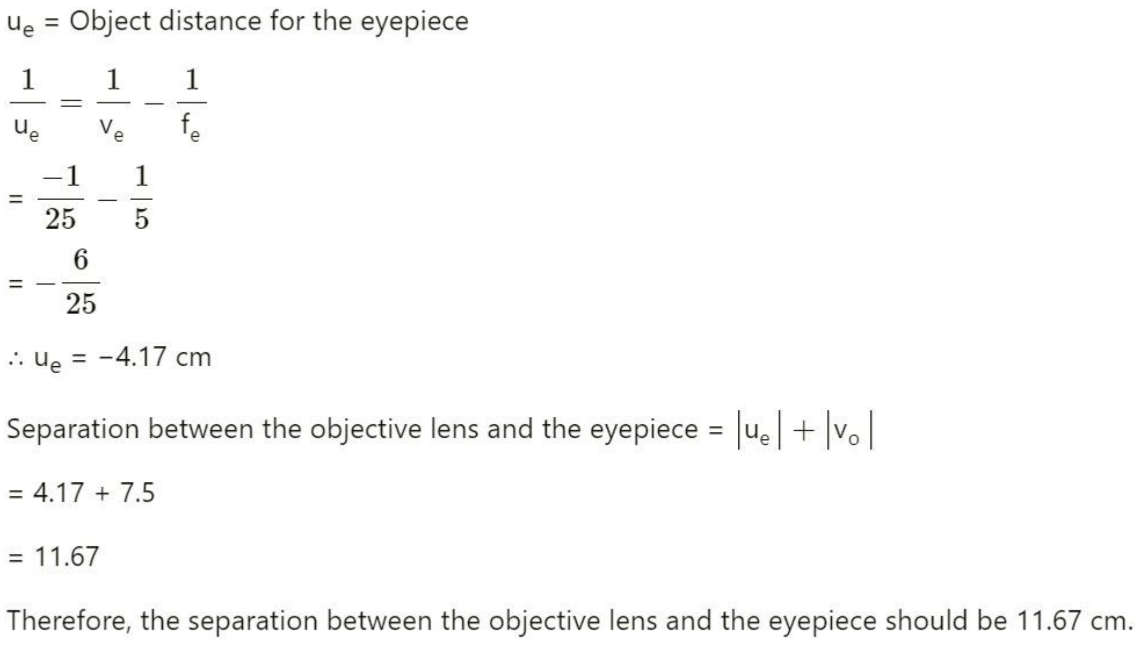
	$m = -\frac{v_0}{u_0}\left(\frac{D}{f_e}\right) \rightarrow$ normal adjustment and $m = -\frac{v_0}{u_0}\left(1+\frac{D}{f_e}\right) \rightarrow$ final image at D. i)Explanation Now for large magnification, m is to be large, so fe should be small and uo should be small. Now object is placed at a distance uo from the objective which is slightly greater than its focal length fo. So for uo to be small, fo should also be small. ii)When we place our eyes too close to the eyepiece of a compound microscope, we are unable to collect much refracted light. As a result, the field of view decreases substantially. Hence, the clarity of the image gets blurred.	1 .5 .5
	LEVEL -3 (5 M ANSWERS)	
1	i)The above figure shows the geometry of formation of image *I* of an object *O* and the principal axis of a spherical surface with centre of curvature *C*and radius of curvature *R*. Assumptions: (a) The aperture of the surface is small compared to other distance involved. (b)SP will be taken to be nearly equal to the length of the perpendicular from the point N on the principal axis.  At point O, a point object is placed on the principal axis of the concave surface. The ray OS, incident at the point S of the concave surface, travels along SR after refraction. As $n_2 > n1$, the refracted ray bends towards the normal CSN. Another ray OP, incident normally on the concave surface, is undeviated. The two	1 1

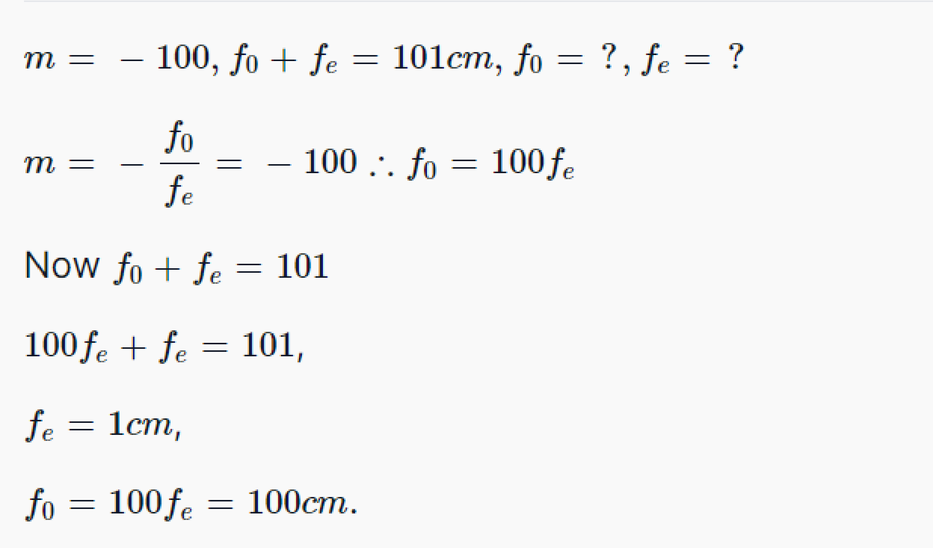
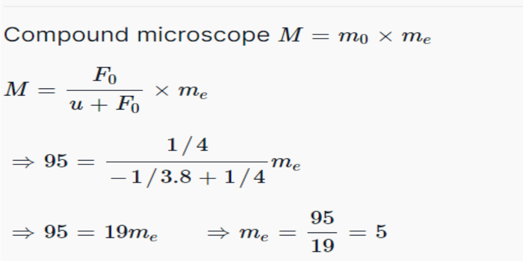
	refracted rays do not intersect in reality but appear to meet at point I in Medium 1. Thus, I is the virtual image of the object placed at O. In Figure,i=∠OSC,r=∠NSR=∠ISC, PO= object distance =-u, PI= image distance =-v and radius of curvature =PC=-R. Let SCP=,∠SIP= and SOP=. Snell's law is applied at the point of refraction S, n_1 sin i=n_2 sin r. For paraxial rays or small aperture, i and r will be small. Hence, sin i and sin r. Making this assumption, we can write as n_1i=n_2r If Medium 1 be air n_1=1 and Medium 2 has a refractive index n_2=n, then we can write the above Equation as n/v – 1/u = n-1 / R $\frac{n_2}{v}-\frac{n_1}{u}=\frac{n_2-n_1}{R}$ $\Rightarrow \frac{1.5}{V}-\frac{1}{(-100)}=\frac{1.5-1}{20}=\frac{1}{40}$ $\Rightarrow \frac{1.5}{V}=\frac{1}{40}-\frac{1}{100}=\frac{5-2}{200}=\frac{3}{200}$ $\Rightarrow v=\frac{1.5\times 200}{3}=100cm$ Hence, the image is formed 100 cm in the denser medium ii)	1 1 1
	LEVEL-1 (NUMERICALS)	
1	 From figure r=30°, μ=√3 μ=sini/sinr sin i = √3 sin30	1 1

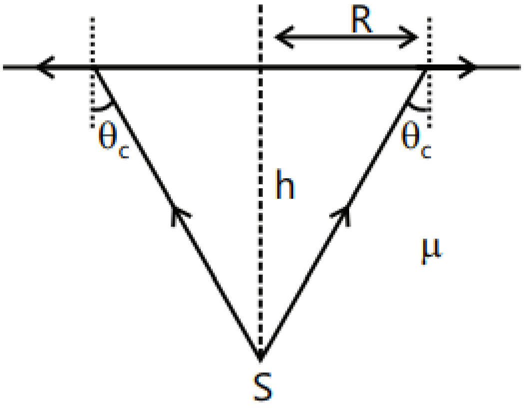
	i=60	
2	Given f1 = + 30 cm, f2 = – 20 cm The focal length (F) of combination of given by 1/F=1/f1+1/f2 F = f1f2/f1+f2 = 30 x-20/30+(-20) = -60cm Hence, the focal length of the combination of lenses is 60 cm. The negative sign indicates that the system of lenses acts as a diverging lens.	1 1
3	n =1/sinic =1/sin45 =√2 Yes, critical angle for a pair of media depends on wavelength, because n=a+b/λ2 where a and b are constants of the media.	1 1
4	Here it is given that R1=10m,R2=15cm and f=12cm. As per sign convention followed for a convex lens, f and R1are +ve but R2 is -ve.  Hence, applying lens maker.s formula $\frac{1}{f}=(n-1)\left(\frac{1}{R_1}-\frac{1}{R_2}\right)$, we have $\frac{1}{+12}=(n-1)\left[\frac{1}{+10}-\frac{1}{-15}\right]$ $=(n-1)\left(\frac{1}{10}+\frac{1}{15}\right)=(n-1)\times\frac{1}{6}$ $\Rightarrow (n-1)=\frac{6}{12}=\frac{1}{2}$ or $n=1+\frac{1}{2}=\frac{3}{2}=1.5$	1 1
	LEVEL-2 (NUMERICALS)	
1	Using lens maker formula $-\frac{\mu_1}{u}+\frac{\mu_2}{v1}=\frac{\mu_2-\mu_1}{R1}$ u=−30cm.R=+20cm 1.5v−1−30=1.5−120=140 ⇒1.5v=140−130=3−4120=−1120 ⇒v=−180cm i.e in the air side	1 1

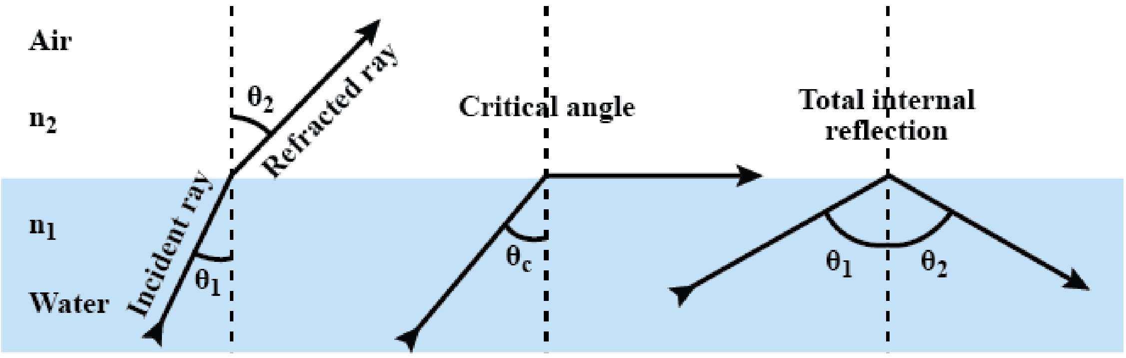
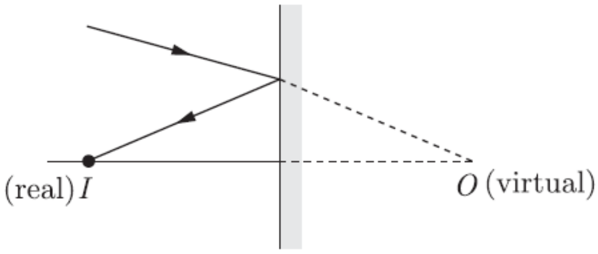
2	Given, $A = 75^\circ, \mu = \sqrt{2}$ $\mu_2 = i_c$ As, $\mu = \frac{1}{\sin i_c}$ $\Rightarrow i_c = \sin^{-1}\left(\frac{1}{\mu}\right) = \sin^{-1}\left(\frac{1}{\sqrt{2}}\right) = 45^\circ$ $\Rightarrow r_1 + r_2 = A$ $\Rightarrow r_1 = A - r_2 = 75^\circ - 45^\circ = 30^\circ$ As, $\frac{\sin i}{\sin r_1} = \mu$ $\Rightarrow \sin i = \mu \times \sin r_1 = \sqrt{2} \times \sin 30^\circ$ $\therefore$ Value of i is 45°	1 1
3	$f = +10cm$ $u = +15cm$ lens equation $\frac{1}{f} = \frac{1}{v} - \frac{1}{u}$ $\frac{1}{10} = \frac{1}{v} - \frac{1}{+15}$ $\frac{1}{v} = \frac{1}{10} + \frac{1}{15} = \frac{3+2}{30}$ $\frac{1}{v} = \frac{5}{30}$ $v = 60cm$	1 1 1
	LEVEL-3 (NUMERICALS)	
1	Angle of incidence at face ac for all three colours, i = 45° Refractive index corresponding to critical angle 45° 	1

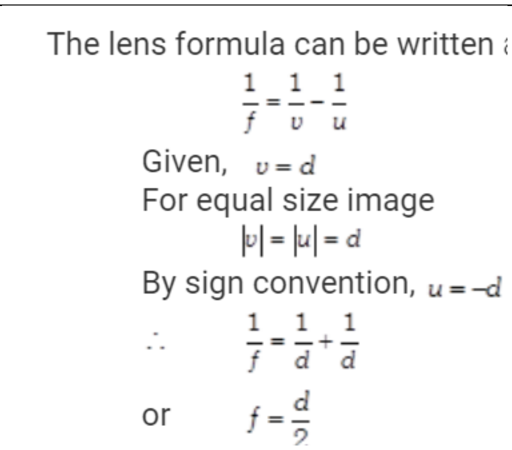
	μ= $\frac{1}{sin\ C}$ **μ=** $\frac{1}{sin\ 45^0}$ **μ=** √2= 1.414 **μ=** 1.414 The ray will be transmitted through face ‘ ac’ if i < ic. This condition is satisfied for red colour (u=1.39). So only red ray will be transmitted, Blue and Green rays will be totally reflected.	1 1
2	Focal length of the objective lens, fo = 1.25 cm Focal length of the eyepiece, fe = 5 cm Least distance of distinct vision, d = 25 cm Angular magnification of the compound microscope = 30X Total magnifying power of the compound microscope, m = 30  $m_e = \left(1 + \frac{d}{f_e}\right)$ $= \left(1 + \frac{25}{5}\right)$ = 6 The angular magnification of the objective lens (m_O) is related to m_e as: $m_O\ m_e = m$ $m_O = \frac{m}{m_e}$ $= \frac{30}{6}$ = 5 The angular magnification of the eyepiece is given by the relation:  $m_o = \frac{\text{Image distance for the objective lens}(v_o)}{\text{Object distance for the objective lens}(-u_o)}$ $5 = \frac{v_o}{-u_o}$ $\therefore v_O = -5u_O$ ....(1) Applying the lens formula for the objective lens: $\frac{1}{f_o} = \frac{1}{v_o} - \frac{1}{u_o}$ $\frac{1}{1.25} = \frac{1}{-5u_o} - \frac{1}{u_o}$ $= \frac{-6}{5u_o}$	1 1

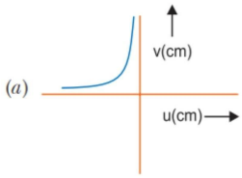
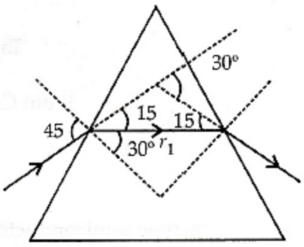
	 u_e = Object distance for the eyepiece $\frac{1}{u_e} = \frac{1}{v_e} - \frac{1}{f_e}$ $= \frac{-1}{25} - \frac{1}{5}$ $= -\frac{6}{25}$ $\therefore u_e = -4.17$ cm Separation between the objective lens and the eyepiece = $\lvert u_e \rvert + \lvert v_o \rvert$ = 4.17 + 7.5 = 11.67 Therefore, the separation between the objective lens and the eyepiece should be 11.67 cm.	1 1
3	i) focal length of the objective lens, fo=140cm Focal length of the eyepiece, fe=5cm the angle subtended by the tower at the telescope. Formula used: α=h1/u Height of the tower, h1=100, u=Distance of the tower (object) from the telescope=3km =3000 m The angle subtended by the tower at the telescope is given by, α=h1/u =100/3000 =1/30rad Let h2 be the height of the image formed by the objective. The angle subtended by the image produced by the objective lens, α=h2/fo=h/2 But the angle subtended by the tower at the telescope and the angle subtended by the image produced by the objective lens are equal. Therefore, 1/30=h2/140 h2=140/30 ≈4.7cm Final answer: 4.7cm ii)	1 1 1

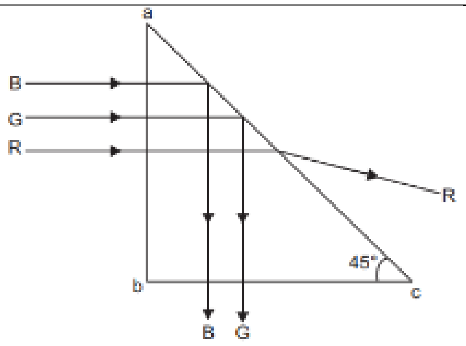
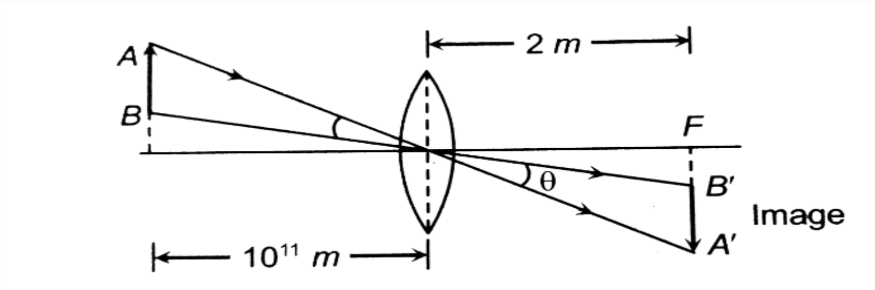
	Given focal length of eye piece,fe=10cm focal length of objective,fo=100cm D=25cm Magnifying power M= M = −f0/fe(1+fe/D) M=−100/10(1+10/25) M=−14	1 1
	CASE STUDY	
1	**i)** a) 1 cm and 10 cm respectively  $m = -100, f_0 + f_e = 101cm, f_0 = ?, f_e = ?$ $m = -\frac{f_0}{f_e} = -100 \therefore f_0 = 100f_e$ Now $f_0 + f_e = 101$ $100f_e + f_e = 101,$ $f_e = 1cm,$ $f_0 = 100f_e = 100cm.$ **ii)** The correct option is D The magnifying power of microscope will decrease but that of the telescope will increase A microscope consists of a lens of small focal lengths. A telescope consists of an objective lens of a large focal length. For a microscope, m=(L/f0) X(D/fe) and FOr telescope, m=fo/fe Therefore, The magnifying power of microscope will decrease but that of the telescope will increase. **iii)** a) 18 cm, 2 cm f0/ fe =9, f0 = 9fe Also f0+ fe= 20 (because final image is at infinity) 9fe + fe= 20, fe= 2cm, f0= 18cm **iv)** a) 5  Compound microscope $M = m_0 \times m_e$ $M = \frac{F_0}{u + F_0} \times m_e$ $\Rightarrow 95 = \frac{1/4}{-1/3.8 + 1/4} m_e$ $\Rightarrow 95 = 19m_e \quad \Rightarrow m_e = \frac{95}{19} = 5$	1 1 1 1

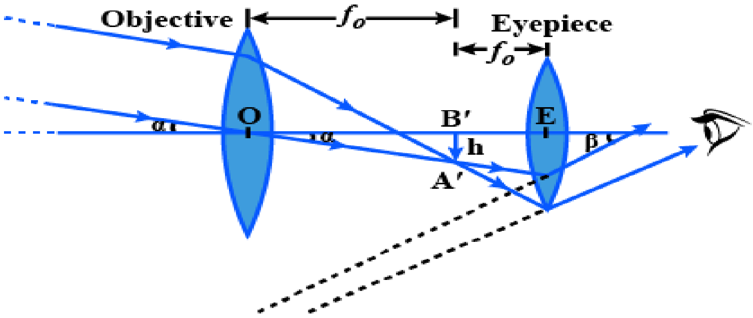
	COMPETENCY BASED QUESTION	
1	**i)** (a)The incidence angle is smaller than the critical angle. The refracted light will therefore deviate from the normal due to normal refraction from denser to rarer material.	1
	ii) (b)  $R = h \tan\theta_c = \frac{h \sin\theta_c}{\cos\theta_c}$ $\Rightarrow \quad R = \frac{h\sin\theta}{\sqrt{1 - \sin^2\theta_c}}$ $\text{Since} \quad \sin\theta_c = \frac{1}{\mu};$ $\therefore \; R = \frac{h}{\sqrt{\mu^2 - 1}}.$ area =∏ R^2	1
	iii) No. Because in its derivation the formula Sin i/sin r = μ has been used and keeping the angles i and r very small, the approximation sin i ≈ tan i, and sin r ≈tan r have been taken. When viewed from a position quite away from the normal these approximations do not hold good. Hence the formula "Real depth/ Apparent depth=μ" is not valid.	1
	iv) c) He has to direct the beam at an angle to the vertical which is slightly less than the critical angle of incidence for total internal reflection	

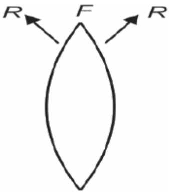
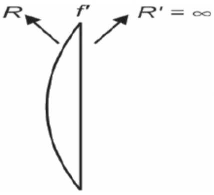
		1
2	**i)** b) Both Assertion and Reason are correct but Reason is not a correct explanation of the Assertion.  **ii)** No, it will behave as a diverging lens. Using thin lens maker formula On using convention R1 =+ Ve, R2 =- Ve and Hence fw =- Ve So it behaves as a diverging lens. **iii)** c) 10.5 Refractive index $(\mu) = \frac{\text{Real depth}}{\text{Apparent depth}}$ Refractive index $(\mu) = 1.5$ Apparent depth $= 2 + 5 = 7\ cm$ So, $1.5 = \frac{\text{Real depth}}{7}$ $\therefore$ Real depth $= 1.5 \times 7 = 10.5$ **iv)** b) d/2	1 1 1 1

	 The lens formula can be written $\frac{1}{f}=\frac{1}{v}-\frac{1}{u}$ Given, $v=d$ For equal size image $\lvert v\rvert=\lvert u\rvert=d$ By sign convention, $u=-d$ $\therefore$ $\frac{1}{f}=\frac{1}{d}+\frac{1}{d}$ or $f=\frac{d}{2}$	
	CCT BASED QUESTION	
1	**i)** d) 11 max. magnification = $1+\frac{D}{f}$ $m=1+\frac{25}{2.5}$ $m=1+10=11$ $m=11$ **ii)** a) 0.05 As we know, m=1+D/f ⇒6=1+25/f ⇒f=5cm=0.05m **iii)** a) 0.1mm The human eye can distinguish the two objects as close as 0.1 mm distance apart. So the resolving power of a human eye is 0.1 mm **iv)** a) $\frac{D}{F}$ or $\frac{25}{F}$	1 1 1 1
	SELF ASSESSMENT ANSWERS	
1	d) Intensity of image will be reduced	1

2	 	1
3	c) Assertion is correct but the reason is incorrect	1
4	d) Assertion is incorrect but the reason is correct	1
5	b) P/2	1
6	a)40º	1
7	Here, $f = -20cm$. As the image may be real//virtual, therefore, $m = \pm 3 = \frac{v}{u}$ or $v = \pm 3u$ As $\frac{1}{v} + \frac{1}{u} = \frac{1}{f} \therefore \frac{1}{\pm 3u} + \frac{1}{u} = -\frac{1}{20}$ or $\frac{\pm 1 + 3}{3u} = -\frac{1}{20}$ or $-3u = 40 \text{ or } 80$ $\therefore u = \frac{-40}{3} cm$ or $u = \frac{-80}{3} cm.$	1 1
8	$i = \frac{3}{4}A = \frac{3}{4} \times 60 = 45''$ $r = 45 - 15 = 30^{\circ}$ As $\mu = \frac{\sin i}{\sin r} = \sqrt{2}$ $v = \frac{c}{\mu} = \frac{3 \times 10^8}{\sqrt{2}} = 2.1 \times 10^8$ m/s  	1 1
9	Angle of incidence at face ac for all three colours, i = 45° Refractive index corresponding to critical angle 45°	1

	 $\mu = \frac{1}{\sin C}$ $\mu = \frac{1}{\sin 45^o}$ μ= √2= 1.414 μ= 1.414 The ray will be transmitted through face ‘ ac’ if i < ic. This condition is satisfied for red colour (u=1.39). So only red ray will be transmitted, Blue and Green rays will be totally reflected.	1 1
10	from Snell's Law, sin i/ sin r_1= √2/3 i=45º r1= 60º Let deviation for first ray be L1 and deviation for second ray be L2 L1=60−45= 15 Similarly, L2=15 ∴ Angle between emergent rays =15+15 =30	1 1 1
11	i).c) 13.5 d=2f/3 =3d/2=3x12/2= 18 cm equivalent focal length = 3f/4= 13.5 cm $\theta = \frac{AB}{10^{11}} = \frac{A'B'}{2} \Rightarrow A'B' = \frac{2 \times 1.4 \times 10^9}{10^{11}}$ $= 2.8$ ii).  	1 1

	iii) c) Since intensity ∞ (Aperture)^2, so intensity of image will decrease but no change in the size occurs. iv) c)	1 1
12	i)  $m = \left(\frac{\beta}{\alpha}\right)$ $\beta = \tan\beta = \frac{h}{f_e}$ Where h is image height and f_e is focal length of eyepiece. $\alpha = \tan\alpha = \frac{h}{f_o}$ Where f_o is focal length of objective lens. Hence, we get magnifying power m as, $m = \frac{h/f_e}{h/f_o} = \frac{f_o}{f_e}$ The magnifying power of a refracting type astronomical telescope is defined as the ratio of angle subtended by the final image at eye to the angle subtended by the object at eye. ii) a)We know that, Magnification, m = fo/fe =Pe/Po Therefore, the lens of 0.5 D should be used as objective and the lens of 10 D should be used as eye-piece in order to achieve higher magnification.	1 2 1

	b) The aperture of the objective lens is made larger so, that it receives as much light as coming from the distant object and the resolving power of the telescope increases.	1
13	**i)** The portion of the tube within water will shine like a mirror due to total internal reflection. If the tube is partially filled with water, the portion of tube containing water will no linger show this effect **ii)** d) 2f  By lens maker formula, $\frac{1}{F} = (\mu - 1)\left[\frac{1}{R} - \frac{1}{(-R)}\right]$ $\frac{1}{F} = \frac{2(\mu - 1)}{R}$  $\frac{1}{f'} = (\mu - 1)\left[\frac{1}{R} - \frac{1}{(-\infty)}\right]$ $\frac{1}{f'} = \frac{\mu - 1}{R} = \frac{1}{2F}$ Focal length of each part, $f' = 2F$ **iii)** d) 30º **iv)** d) 5/3	1 1 1 1

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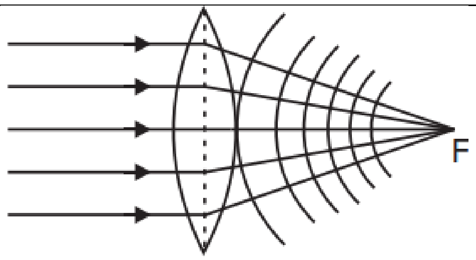
UNIT VI OPTICS
CHAPTER 10-WAVEOPTICS

LEVEL -1 MCQ		
Q.No.	**DETAILED SOLUTIONS**	**VALUE POINTS**
1	B	1
2	A	1
3	A	1
4	Wavelength of light, $\lambda'=\lambda/\mu$=6000/1.5=4000Å B	1
5	D	1
LEVEL -2 MCQ		
Q.No.	**DETAILED SOLUTIONS**	**VALUE POINTS**
6	d	1
7	$\frac{W_1}{W_2}=\frac{81}{1}$ $\frac{W_1}{W_2}=\frac{I_1}{I_2}=\frac{{a_1}^2}{{a_2}^2}$ so $\frac{a_1}{a_2}=\frac{9}{1}$ c	1
8	c	1
9	b	1
10	 a	1
LEVEL -3 MCQ		
Q.No.	**DETAILED SOLUTIONS**	**VALUE POINTS**
11	β = $\frac{\lambda D}{d}$ b	1
12	C	1
13	C	1

14	D	1
15	D	1

ASSERTION AND REASON

16	B	1
17	A	1
18	D	1
19	D	1
20	B	1

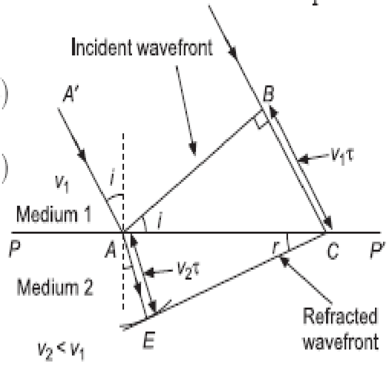
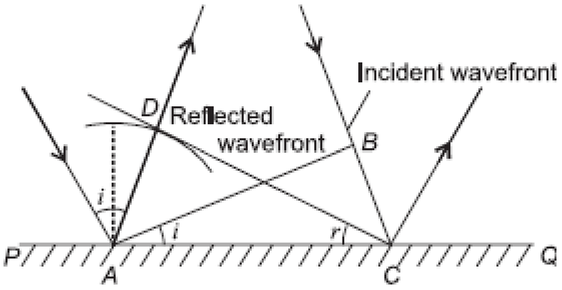
LEVEL- 1 (2M QUESTIONS)

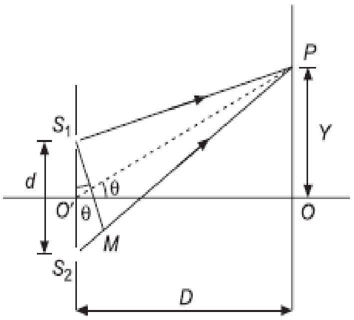
Q.No.	DETAILED SOLUTIONS	VALUE POINTS
1	(a) In the interference pattern the bright fringes are of the same width, whereas in the diffraction pattern they are not of the same width.	1
	(b) In interference all bright fringes are equally bright while in diffraction they are not equally bright.	1
2	There will be an interference pattern whose fringe width is the same as that of the original. But there will be a decrease in the contrast between the maxima and the minima, i.e. the maxima will become less bright and the minima will become brighter.	1 1
3	Given, $\lambda = 600$ nm $= 6 \times 10^{-7}$ m,	
	$D = 0.8$ m, $\gamma_2 = 15 \times 10^{-3}$ m	
	To calculate: Width of the slit ‘d’	
	Calculations: $\gamma_2 = 5/2 \times \lambda D/d$	1
	$d = 5/2 \times 6 \times 10^{-7} \times 0.8/15 \times 10^{-3}$	½
	∴ Distance, $d = 8 \times 10^{-5} = 80$ μm	½

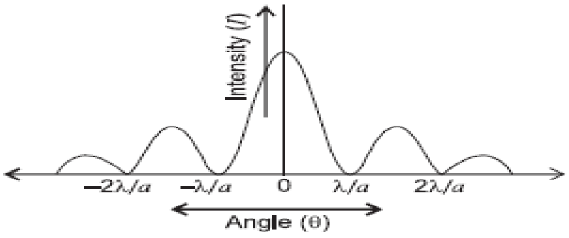
LEVEL-2 (2M QUESTIONS)

Q.No.	DETAILED SOLUTIONS	VALUE POINTS
4	(i) Working of an optical fibre is based on the principle of total internal reflection.	1
	(ii) (a) Light should travel from a denser to a rarer medium.	½
	(b) Angle of incidence should be more than critical angle given by $i_c = \sin^{-1}(1/\mu)$	½
5	Coherent sources have a constant phase difference and, therefore, produce a sustained interference pattern.	1 1

<table>
<tr><td></td><td>These sources are needed to ensure that the position of maxima and minima do not change with time.</td><td></td></tr>
<tr><td>6</td><td><table>
<tr><td>Interference pattern</td><td>Diffraction pattern</td></tr>
<tr><td>Interference is due to the superposition of two distinct waves coming from two coherent sources.</td><td>Diffraction is due to the superposition
of the secondary wavelets coming from different parts of the same wavefront.</td></tr>
<tr><td>Interference fringes may or may not be of the same width.</td><td>Diffraction fringes are not to be of the same width.</td></tr>
<tr><td>The intensity of minima is generally zero</td><td>The intensity of minima is never zero.</td></tr>
<tr><td>All bright fringes are of uniform intensity.</td><td>All bright fringes are not of uniform intensity.</td></tr>
</table></td><td>1+1</td></tr>
<tr><td>7</td><td>Diffraction from each slit is related to an interference pattern in a double-slit experiment in the following ways:
The intensity of minima for diffraction is never zero, while for interference it is generally zero.
All bright fringes for diffraction are not of uniform intensity, while for interference, these are of uniform intensity</td><td>1
1</td></tr>
<tr><td colspan="3">LEVEL -3 (2M QUESTIONS)</td></tr>
<tr><td>Q.No.</td><td>DETAILED SOLUTIONS</td><td>VALUE POINTS</td></tr>
<tr><td>8</td><td>Waves from the distant source are diffracted by the edge of the circular obstacle and these diffracted waves interfere constructively at the centre of the obstacle’s shadow producing a bright spot</td><td>1
1</td></tr>
<tr><td>9</td><td>Coherent sources of light. The sources of light, which emit continuously light waves of the same wavelength, same frequency and in the same phase are called Coherent sources of light.
The interference pattern is not obtained. This is because the phase difference between the light waves emitted from two different sodium lamps will change continuously.</td><td>1
1</td></tr>
<tr><td>10</td><td>Conditions for interference. The important conditions for obtaining interference of light are:
• The two sources of light must be coherent. i.e. they should exist continuous waves of the same wavelength or frequency.
• The two sources should be monochromatic.
• The phase difference of waves from two sources should be constant.
• The amplitude of waves from two sources should be equal.
• The coherent sources must be very close to each other.</td><td>1+1</td></tr>
</table>

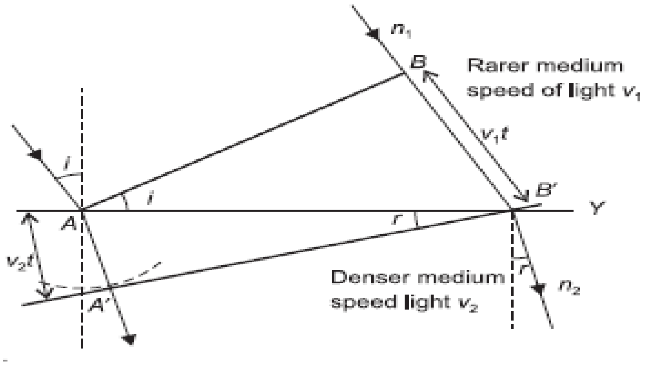
LEVEL-1 (3M QUESTIONS)		
Q.No.	**DETAILED SOLUTIONS**	**VALUE POINTS**
1	If v_1 and v_2 are the speeds of light in media 1 and 2 respectively, then distance travelled by light in a small time internal τ in two media will $BC = v_1\tau$ and $AE = v_2\tau$ respectively. In ΔABC, $\sin i = \frac{BC}{AC} = \frac{v_1\tau}{AC}$ ...(i) In ΔAEC, $\sin r = \frac{AE}{AC} = \frac{v_2\tau}{AC}$ ...(ii) Combining equations (i) and (ii), we get $\frac{\sin i}{\sin r} = \frac{v_1}{v_2} = \mu_{21}$ The above relation is known as Snell's law.  	½ ½ ½ ½ ½ ½
2	A wavefront is the locus of all points oscillating in same phase. A figure showing reflection of a plane wavefront using Huygen's construction is given below. In the figure AB is incident wavefront and *CD* is reflected wavefront.  If *v* is speed of the wave in the medium and t is the time taken by the wavefront to cover distance *BC*, then $BC = vt$ Obviously, $AD = vt$ As ΔABC and ΔADC are congruent. $\therefore$ $\angle i = \angle r$	½ ½ ½ ½ ½ ½

3	Two independent monochromatic sources cannot maintain a constant phase difference, therefore, the interference pattern will also change with time. Consider a point P on the screen. Suppose waves from the slits S_1 and S_2 superpose at the point to produce maximum intensity. Now, path difference between the waves to produce maxima would be  $\Delta P = n\lambda$ ...(i) Here $\Delta P = S_2P - S_1P = S_2M$ From ΔS_2MS_1, $S_2M = S_1S_2 \sin\theta$ ($\because S_1S_2 = d$) $S_2M = d\sin\theta$ As the angle is very small, i.e. $\sin\theta \simeq \tan\theta$ ∴ $\Delta P = d\tan\theta$ From Δ POO': $\tan\theta = \frac{Y}{D}$ $\Delta P = d\left(\frac{Y}{D}\right)$ ...(ii) From equations (i) and (ii), we get that n^{th} maximum is obtained at $Y_n^{max} = \frac{n\lambda D}{d}$ The separation between two consecutive maxima or minima is called fringe width. So, fringe width is given by $\beta = Y_n^{max} - Y_{n-1}^{max} = \frac{\lambda D}{d}$	½ ½ ½ ½ ½ ½
4	Given: $y = \frac{\lambda D}{3d}$ As $\Delta P = \frac{yd}{D} \Rightarrow \Delta P = \frac{\lambda}{3}$ or $\Delta\phi = \frac{2\pi}{3}$ ∴ $I = I_0\cos^2\Delta\phi = I_0\left(\cos\frac{2\pi}{3}\right)^2 = \frac{I_0}{4}$	1 1 1
	LEVEL 2 (3M QUESTIONS)	
Q.No.	**DETAILED SOLUTIONS**	**VALUE POINTS**
5	When a plane wavefront is incident on a single slit, all the point sources of light constituting the wavefronts are in same phase. The wavelets coming out from the wavefront might meet over the screen with some path difference, i.e., a phase difference is introduced between them. The brightness at a point on the screen depends on the phase difference between the wavelets meeting at the point. We imagine that the slit is divided into smaller parts and the wavelets coming out from these portions meet and superpose on the screen with proper phase difference. The wavelets from different parts of the wavefront, incident on the slit, meet with zero phase difference to constitute a central maximum. In case of secondary maxima, there are some	1 1 1

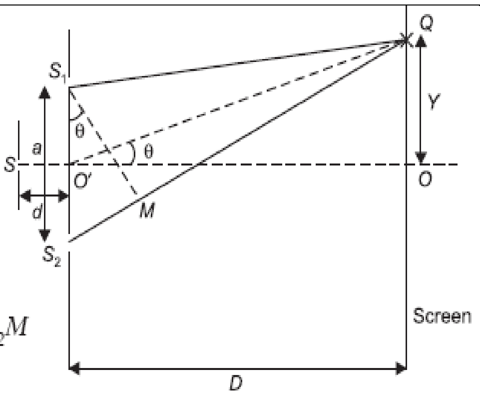
	wavelets meeting the screen out of phase, thus, reducing intensity of secondary maxima. 	
6	The resultant intensity is given by $I_R = I_1 + I_2 + 2\sqrt{I_1 I_2}\cos\phi$, where $I_1 = I, I_2 = I + \delta I$ At maxima, $\cos\phi = 1$ $\therefore \quad I_{max} = I + I + \delta I + 2\sqrt{I(I+\delta I)}$ $\therefore \quad I_{max} = 2I + 2I = 4I \qquad (\because \delta I << I)$ At minima, $\cos\phi = -1$ $I_{min} = I + I + \delta I - 2\sqrt{I(I+\delta I)}$ $I_{min} = 2I + \delta I - 2\left[I^2\left(1+\frac{\delta I}{I}\right)\right]^{1/2} = 2I + \delta I - 2I\left[1+\frac{1}{2}\frac{\delta I}{I} - \frac{1}{8}\left(\frac{\delta I}{I}\right)^2 + ...\right]$ Neglecting the higher power, we get $I_{min} = \frac{2I}{8}\left(\frac{\delta I}{I}\right)^2 = \frac{1}{4}\frac{(\delta I)^2}{I}$	½ ½ ½ ½ ½ ½
7	Linear width of central maximum β= 2Dλ/d Angular width of central maximum β/D= 2λ/d (i) When slit width d decreases, angular width increase. (ii) When distance D between the slit and screen is increased, angular width does not change. When light of smaller wavelength is used, angular width decrease	½ ½ ½ ½ 1
8	λ=550 nm, d= 0.1 mm,D = 1.1m, ω = ?, β = ? using ω = 2θ= 2λ/d, we get ω= .011 rad using β=2λD/d ,we get β = 12.1 mm When the screen is moved to 2.2 m from the slit, the angular width will not change, linear width will increase.	1 1 1
	LEVEL 3 (3M QUESTIONS)	
Q.No.	**DETAILED SOLUTIONS**	**VALUE POINTS**
9	λ=6000 Å , a=1X10^{-4}m , D= 1.5m The distance between two dark lines on either side of central maximum = width of central maximum = 2λD/a= (2X6000X10^{-10}X1.5) / (1X10^{-4}) =1.8X10^{-2}m= 1.8cm	1 1 1
10	λ=600nm , D= 0.8m The distance of second order maximum from the centre of the screen = 15mm = 15X10^{-3}m	1

	$$a = \frac{n\lambda}{\sin\theta} = \frac{n\lambda D}{x}$$ $$a = \frac{(2x600x10^{-9}x0.9)}{15x10^{-3}} = 6.4x10^{-5}m$$	1 ½+1/2
11	(a)y3 = n. Dλ/d = 3 x 1.2m x 6500 x 10^{-10}m / 2 x 10^{-3}m = 0.12cm (b) Let nth maxima of light with wavelength 6500 Å coincides with that of mth maxima of 5200Å. m x 6500Ao x D/d = n x 5200A° x D/d m/n = 5200/6500 = 4/5 Least distance = y4= 4.D (6500Ao)/d = 4 x 6500 x 10^{-10} x 1.2/ 2 x 10^{-3}m = 0.16cm.	½ ½ ½ ½ ½ ½
12	β = $\frac{\lambda D}{d}$ substituting values and calculate λ = 6x10^{-7}m D doubled then fringe width is doubled D doubled then fringe width is halved.	½ 1 ½ ½ 1/2

LEVEL-1(5M QUESTIONS)

Q.No.	DETAILED SOLUTIONS	VALUE POINTS
1	(a) According to the Huygen's principle, each point of the wavefront is the source of secondary disturbance and the wavelets emanating from these points spread out in all directions with the speed of the wave. A common tangent to all the wavelets in the forward direction gives the new position of wavefront at a later time 	½ ½ ½ ½ ½ ½ ½

	From $\Delta ABB'$, $\sin i = \frac{BB'}{AB'} = \frac{v_1 \times t}{AB'}$ ...(i) From $\Delta AA'B'$, $\sin r = \frac{AA'}{AB'} = \frac{v_2 \times t}{AB'}$ ...(ii) $\therefore \quad \frac{\sin i}{\sin r} = \frac{v_1}{v_2}$ We know $n_1 = \frac{c}{v_1}$ and $n_2 = \frac{c}{v_2}$ where n_1 and n_2 are the refractive indices of the 1st and 2nd media. So, $n_1 \sin i = n_2 \sin r$ which is Snell's law of refraction. (b) (i) Frequency remains the same. When the light of particular frequency is incident it interacts with the atoms of the matter, which further causes forced oscillations. As the frequency of charged oscillator and the frequency of wave emitted by charged oscillator is same, therefore the frequency of reflected and refracted light is same. (ii) No, energy carried by a light wave does not depend on its speed. Instead it depends on its amplitude	½ ½ ½
2	(a) (i) Light waves originating from two independent monochromatic sources, cannot have a constant phase difference. Therefore, sources will not be coherent, hence, they will not produce a sustained interference pattern.	½ ½ ½ 1 ½ ½ ½ ½ ½

	(*ii*) According to the superposition principle, $y = y_1 + y_2 = a\cos\omega t + a\cos(\omega t + \phi) = 2a\cos\frac{\phi}{2}\cos\left(\omega t+\frac{\phi}{2}\right)$ $y = A\cos\left(\omega t+\frac{\phi}{2}\right)$ where A is the amptitude of resultant displacement. $\therefore \quad A = 2a\cos\frac{\phi}{2}$ The intensity of resultant wave will be $I = k4a^2\cos^2\frac{\phi}{2}$. If $I_0 = ka^2$ is the intensity of light emitted from each source, then $I = 4I_0\cos^2\frac{\phi}{2}$ (*b*) The path difference of λ corresponds to a phase difference of 2π, that is why, the intensity at a point would be $k = 4a^2$ (∵ Here $I = k$) ⇒ $a^2 = \frac{k}{4}$ Path difference of $\frac{\lambda}{3}$ corresponds to phase difference of $\frac{2\pi}{3}$, that is why, the intensity at a point would be $I' = 4\times\frac{k}{4}\cos^2\frac{2\pi}{3} = \frac{k}{4}$	
3	(*a*) When waves from the slits meet at a point on the screen with same phase, the maxima are obtained and with a phase difference of π, the minima are obtained. According to the Young's experiment, the path difference between the waves is given by $\Delta P = S_2Q - S_1Q = S_2M$  	½ ½ ½ ½ ½ ½ 1

i.e. $\sin\theta = \frac{\Delta P}{a}$ ½

From $\Delta QOO'$, $\tan\theta = \frac{Y}{D}$ ½

For a small angle, $\sin\theta \approx \tan\theta$ i.e. $\Delta P = \frac{Ya}{D}$

For bright fringes, $\Delta P = n\lambda$

Thus, $\frac{Y_n a}{D} = n\lambda \Rightarrow Y_n = \frac{n\lambda D}{a}$

For dark fringes, $\Delta P = (2n - 1)\frac{\lambda}{2}$

Thus, $\frac{Y'_n a}{D} = (2n - 1)\frac{\lambda}{2} \Rightarrow Y'_n = \frac{(2n-1)D\lambda}{2a}$

The separation between two consecutive dark or bright fringes is called fringe width.

i.e., $\beta = Y_n - Y_{n-1} = \frac{n\lambda D}{a} - \frac{(n-1)\lambda D}{a} = \frac{\lambda D}{a}$

Here β is the fringe width.

(*b*) Given: For an interference pattern, $\frac{I_{\min}}{I_{\max}} = \frac{9}{25}$, $\frac{I_1}{I_2} = ?$

Here $\frac{I_1}{I_2} = \frac{a_1^2}{a_2^2}$ and $\frac{I_{\min}}{I_{\max}} = \frac{\left(\frac{a_1}{a_2} - 1\right)^2}{\left(\frac{a_1}{a_2} + 1\right)^2}$

$$\therefore \quad \frac{\left(\frac{a_1}{a_2} - 1\right)^2}{\left(\frac{a_1}{a_2} + 1\right)^2} = \frac{9}{25} \Rightarrow \frac{\frac{a_1}{a_2} - 1}{\frac{a_1}{a_2} + 1} = \frac{3}{5}$$

$$\Rightarrow \quad 3\left(\frac{a_1}{a_2} + 1\right) = 5\left(\frac{a_1}{a_2} - 1\right) \Rightarrow \frac{a_1}{a_2} = 4$$

$$\therefore \quad \frac{I_1}{I_2} = \frac{a_1^2}{a_2^2} = \frac{16}{1}$$

LEVEL 2 (5M QUESTIONS)

Q.No.	DETAILED SOLUTIONS	VALUE POINTS

4	**Secondary Maxima:** These are found at $\theta = \left(n+\frac{1}{2}\right)\frac{\lambda}{a}$	½
	For n^{th} secondary maxima, we can imagine as if the slit is divided into $(2n + 1)$ parts. The contributions from $2n$ parts of the slit get cancelled. Only $(2n + 1)^{th}$ part of the slit contributes to the intensity at a point between two minima. With an increase in n, the secondary maxima become weaker. **Secondary Minima:** These are found at $\theta = \frac{n\lambda}{a}$	½
	For n^{th} minima, we can imagine as if slit is divided into $2n$ parts. The separation between two point sources on consecutive parts will be $\frac{a}{2n}$.	½
	As $\Delta P = \theta y$ $\left[\because y = \frac{a}{2n}\right]$ $\Delta P = \frac{n\lambda}{a} \times \frac{a}{2n} = \frac{\lambda}{2}$	½
	The path difference of $\frac{\lambda}{2}$ corresponds to phase difference of π (i.e. waves meet out of phase). There are even number of parts so net intensity is zero at the point on the screen. (*b*) Condition for 1st minimum on the screen is $a \sin \theta_1 = \lambda$ As angle is very small i.e. $\sin \theta \approx \theta$	½
	(*a*) Consider two coherent sources S_1 and S_2. Suppose waves from these two sources meet at a point on the screen with a phase difference ϕ between their displacements.	½
	If the displacement produced by S_1 is $y_1 = a \cos \omega t$ and displacement produced by S_2 is $y_2 = a \cos (\omega t + \phi)$ then, then resultant displacement will be $y = y_1 + y_2$ $\therefore\ y = a[\cos \omega t + \cos (\omega t + \phi)] = 2a \cos \phi/2 \cos (\omega t + \phi/2)$ From the above equation, we find that the amplitude of resultant displacement is $A = 2\ a \cos (\phi/2)$.	½
	$\therefore$ Intensity at the point, $I = kA^2$ $I = k4a^2 \cos^2 \phi/2 = 4\ I_0 \cos^2 \phi/2 \quad [\because I_0 = ka^2]$	½
	Therefore, (*i*) For constructive interference leading to maximum intensity, $\phi = 0, \pm 2\pi, \pm 4\pi, \ldots$	½
	(*ii*) For destructive interference leading to zero intensity, $\phi = \pm \pi, \pm 3\pi, \pm 5\ \pi, \ldots$	½

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According to the Young's experiment, the path difference between the waves is

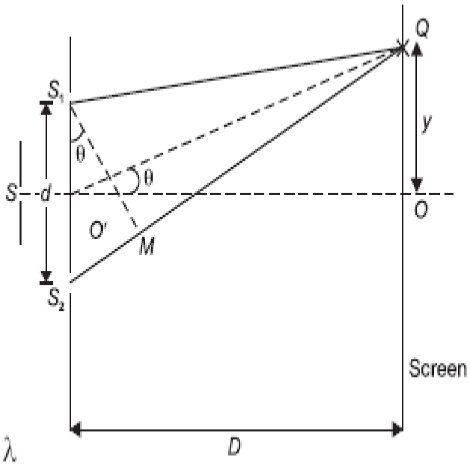
$$\Delta P = S_2Q - S_1Q = S_2M$$

i.e. $\sin\theta = \frac{\Delta P}{d}$

From $\Delta QOO'$, $\tan\theta = \frac{y}{D}$

For a small angle, $\sin\theta \approx \tan\theta$

i.e. $\Delta P = \frac{Yd}{D}$



(i) For bright fringes, $\Delta P = n\lambda$

Thus, $\frac{Y_n d}{D} = n\lambda \Rightarrow Y_n = \frac{n\lambda D}{d}$

(ii) For dark fringes, $\Delta P = (2n-1)\frac{\lambda}{2}$

Thus, $\frac{Y'_n d}{D} = (2n-1)\frac{\lambda}{2} \Rightarrow Y'_n = \frac{(2n-1)D\lambda}{2d}$

The separation between two consecutive dark or bright fringes is called fringe width.

$$\beta = Y_n - Y_{n-1} = \frac{n\lambda D}{d} - \frac{(n-1)\lambda D}{d} = \frac{\lambda D}{d}$$

Here β is the fringe width.

(b) When we close one of the slits, we obtain a diffraction pattern. With both the slits open, we get an interference pattern. It proves that the interference pattern is the superposition of two diffraction patterns.

(c) $n = 10, d = 1$ mm

$\because n\beta = \frac{2\lambda D}{a}; \frac{n\lambda D}{d} = \frac{2\lambda D}{a}$

a = size of aperture of each slit, d = separation between the slits

$\therefore \quad 10\frac{\lambda}{d} = 2\frac{\lambda}{a} \Rightarrow a = \frac{d}{5} = \frac{1}{5} = 0.2$ mm
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(a) To explain a diffraction pattern in case of a single slit (illuminated by monochromatic source), we divide the slit into much smaller parts and add their contributions at any point 'P' on the screen with proper phase differences. [Using Huygen's principle
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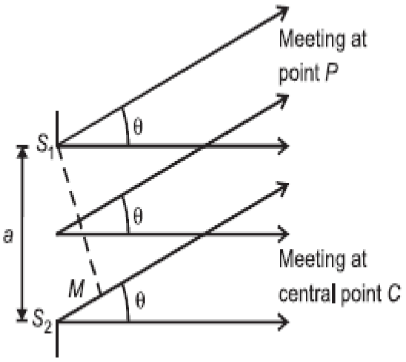
We treat each point on the wavefront at the slit, as secondary sources [Using Huygen's principle]. ½

As the incoming wavefront is parallel to the plane of the slit, these sources are in phase [using Huygen's principle]. ½ ½



[We are taking parallel beam of light because angles are very small]

The path difference between the waves coming out from the two edges of the slits is $S_2P - S_1P = S_2M$. ½

$\therefore \qquad S_2M = a \sin \theta \approx a\theta$

For any two point sources, S_1 and S_2 in the plane of the slit having a separation y, the path difference would be

$$S_2P - S_1P \approx y\theta \qquad \text{i.e. } \Delta P \approx y\theta$$

As the initial phase difference is zero, the phase difference between the waves is introduced only due to this path difference.

For the central point on the screen, $\theta = 0 \Rightarrow \Delta P = 0$

i.e. $\qquad \Delta\phi = 0$

All the parts of the slit contribute in phase. So, the maximum intensity is obtained at C.

Secondary Maxima: These are found at $\theta = \left(n + \frac{1}{2}\right)\frac{\lambda}{a}$

For n^{th} secondary maxima, we can imagine as if the slit is divided into $(2n + 1)$ parts.

The contributions from $2n$ parts of the slit get cancelled. Only $(2n + 1)^{\text{th}}$ part of the slit contributes to the intensity at a point between two minima.

With an increase in n, the secondary maxima become weaker.

Secondary Minima: These are found at $\theta = \frac{n\lambda}{a}$

For n^{th} minima, we can imagine as if slit is divided into $2n$ parts. The separation between two point sources on consecutive parts will be $\frac{a}{2n}$.

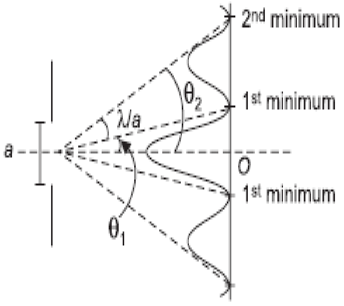
As $\qquad \Delta P = \theta y \qquad \left[\because y = \frac{a}{2n}\right]$

$$\Delta P = \frac{n\lambda}{a} \times \frac{a}{2n} = \frac{\lambda}{2}$$

The path difference of $\frac{\lambda}{2}$ corresponds to phase difference of π (i.e. waves meet out of phase). There are even number of parts so net intensity is zero at the point on the screen.

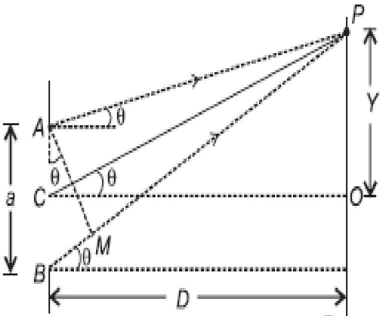
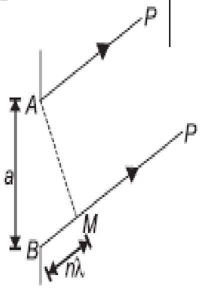
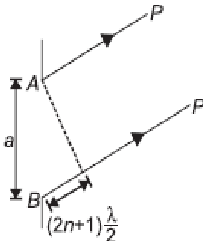
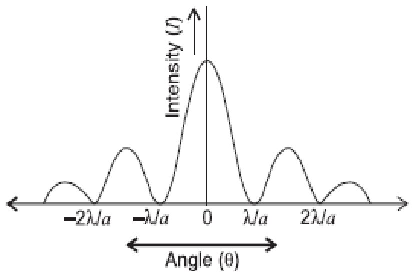
(*b*) Condition for 1st minimum on the screen is $a \sin \theta_1 = \lambda$

As angle is very small i.e. $\sin \theta \approx \theta$

	$\therefore \quad \theta_1 = \frac{\lambda}{a}$ For 2nd minimum, $\theta_2 = \frac{2\lambda}{a}$ Angular width of 1st secondary maximum, $\Delta\theta = \frac{2\lambda}{a} - \frac{\lambda}{a} = \frac{\lambda}{a}$  The central fringe lies between 1st minima on both sides of the central maximum. Hence, the angular width of central fringe is given by $2\theta = \frac{2\lambda}{a}$ Hence, the angular width of central fringe is twice the angular width of first fringe. (*c*) The maxima become weaker and weaker with increasing *n*. This is because the effective part of the wavefront, contributing to the maxima, becomes smaller and smaller, with increasing *n*.	
6	(a) (i) Interference is the superposition of light waves from two different wavefronts originating from the same source, while the diffraction is the interaction of light waves from different parts of the same wavefront. (ii) In an interference pattern, fringes may or may not be of the same width, while in diffraction pattern, they are never of the same width. (iii) In an interference pattern, bright fringes are of uniform intensity, while in diffractions pattern, they are of varying intensity. (*b*) Given: $\lambda = 5 \times 10^{-7}$ m, $D = 1$ m, $y = 2.5 \times 10^{-3}$m We know that the half of the width of the central maximum, $y = \frac{\lambda}{a}D$ $\Rightarrow 2.5 \times 10^{-3} = \frac{5 \times 10^{-7}}{a} \times 1$ $\therefore a = 2 \times 10^{-4}$ m or 200 μm	1 1 1 1 ½ ½

LEVEL 3 (5M QUESTIONS)

Q.No.	DETAILED SOLUTIONS	VALUE POINTS

7	 The wavelength of incident light should be comparable to the aperture of the slit/ opening or size of the obstacle. We consider a single slit *AB* on which a plane wavefront is incident. The slit width is so small in comparison to the distance of the screen from the slit that the rays coming out of it, can be considered almost parallel.  According to the Huygen's principle, each point on the slit will behave like a fresh source of secondary wavelets. The waves from the different parts of the same wavefront reach a point on the screen and superpose to form a diffraction pattern. For n^{th} secondary minimum, $a \sin \theta_n = n\lambda$, where $n = 1, 2, 3$ .... $a \sin \theta_n$ is the path difference between the waves reaching a point on the screen.  We can imagine as if the slit is divided into $2n$ parts. The separation between two adjacent parts of the slit is $a/2n$. For a separation of a, the path difference is $n\lambda$. So, for a separation of $a/2n$, the path difference between the waves will be $\Delta P = \frac{n\lambda}{a} \times \frac{a}{2n} = \frac{\lambda}{2}$ i.e. the phase difference, $\Delta\phi = \pi$ will be there and the waves will superpose destructively. We find the fringes of minimum intensity on the screen. For n^{th} maximum, $a \sin \theta'_n = (2n + 1)\frac{\lambda}{2}$, where $n = 1, 2, 3$, ... We can imagine as if the slit is divided into odd number of parts (e.g. 3, 5, 7, etc.). In this case, only $(2n+1)^{\text{th}}$ part of the slit illuminates the screen. This is the reason why the intensity of secondary maxima falls rapidly. The pattern given below shows the variation of intensity (I) with angle (θ).  	½ ½ ½ ½ ½ ½ ½ ½ ½ ½

8	(a) According to the question, $X_n = \frac{1}{4}.\beta$ $X_n = \frac{1}{4}\frac{\lambda D}{d}$ ∴ Path difference = $\frac{\lambda}{4}$ Phase difference, $\phi = \frac{2\pi}{\lambda}\times\frac{\lambda}{4} = \frac{2\pi}{2}$ ∴ $I = 4I_0\cos^2\frac{\phi}{2} = 4I_0\cos^2\frac{\pi}{4} = 2I_0$ (b) If I_1 and I_2 be the intensities of waves from the sources, then the net intensity will be $I_{net} = I_1 + I_2$ (c) $\theta_{10} = 10\frac{\lambda}{d}$ $\left[\because \theta_n = \frac{n\lambda}{d}\right]$ θ = angular fringe width of 10th maxima $\theta = \frac{\lambda}{d}$ (independent of *n*) (d) $x_5^{max} - x_3^{min} = \frac{5\lambda D}{d} - (2\times3-1)\frac{\lambda}{2}\frac{D}{d}$ $= [10-5]\frac{\lambda d}{2d}$ $= 2.5\frac{\lambda D}{d}$ (e) (i) θ = 5π ∴ $I = 4I_0\cos^2\frac{5\pi}{2} = 0$ Therefore, dark fringe will be formed. (ii) θ = 2π ∴ $I = 4I_0\cos^2\frac{2\pi}{2} = 4I_0$ Therefore, the colour of fringe will be bright red.	½ ½ ½ ½ ½ ½ ½ ½ ½ ½
9	**(a)** At the first minimum, n = 1 in equation [a sinθ = nλ, for n = 1,2,3,...]. Solving for a, we then find a = nλ / sinθ = (1) (650 nm) / (sin15°) = 2511 nm ≈ 2.5 μm Therefore, the value of a the first minimum for red light of λ = 650 nm be at θ = 15° would be 2.5 μm. For the incident light to flare out that much (±15°) the slit has to be very fine indeed, amounting to about four times the wavelength. Note that a fine human hair may be about 100 μm in diameter. **(b)** This maximum is about halfway between the first and second minima produced with wavelength λ'. we can find it without too much error by putting n = 1.5 in equation [a sinθ = nλ, for n = 1,2,3,...], obtaining a sinθ = 1.5 λ' Solving for λ' and substituting known data give	½ ½ ½ ½ ½ ½ ½ ½ ½ ½

	λ' = a sinθ/1.5 = (2511 nm) (sin15°)/1.5 = 430 nm From the above observation we conclude that, the wavelength λ' of the light whose first side diffraction maximum is at 15° would be 430 nm. Light of this wavelength is violet. The first side maximum for light of wavelength 430 nm will always coincide with the first minimum for light of wavelength 650 nm, no matter what the slit width. If the slit is relatively narrow, the angle θ at which this overlap occurs will be relatively large, and conversely	

LEVEL -1 (NUMERICALS)

Q.No.	**DETAILED SOLUTIONS**	**VALUE POINTS**
1	a=A and b=2A, θ=π/3 $R = \sqrt{a^2 + b^2 + 2ab\cos\theta}$ Substitution & calculation R= A$\sqrt{7}$	½ 1 ½
2	$\beta = \frac{\lambda D}{d}$ Substitution and calculation β=0.5mm	½ 1 ½

LEVEL -2 (NUMERICALS)

Q.No.	**DETAILED SOLUTIONS**	**VALUE POINTS**
1	$d\sin\theta = (2n+1)\frac{\lambda}{2}$ $on\ n = 1\ substitution\ and\ calculation$ d=1.5 x 10^{-6}m	½ 1 ½
2	For first secondary maxima position x= 3λ/2a $x_1 = \frac{3\lambda_1}{2a}$ $x_2 = \frac{3\lambda_2}{2a}$ Spacing = x_2-x_1= $\frac{(3D(\lambda_2-\lambda_1)}{2a}$ = 9 x 10^{-4}m	½ ½ ½ ½

LEVEL -3 (NUMERICALS)

Q.No.	**DETAILED SOLUTIONS**	**VALUE POINTS**
1	If a=b $I_1 = I_2$i.e $a^2 = b^2$ $when\ one\ slit\ is\ covered\ by\ glass$ $b^2 = \frac{50}{100}a^2 b = \frac{a}{\sqrt{2}}$ $\frac{I_{max}}{I_{min}} = \frac{(a+b)^2}{(a-b)^2} = \frac{(a+\frac{a}{\sqrt{2}})^2}{(a-\frac{a}{\sqrt{2}})^2} = 33.94$	½ ½ 1 1

CASE BASED

Q.No.	DETAILED SOLUTIONS	VALUE POINTS
1	(i) a (ii) a (iii) a (iv) d	1 1 1 1
2	(i) d (ii) c (iii) c (iv) c	1 1 1 1

COMPETENCY BASED

Q.No.	DETAILED SOLUTIONS	VALUE POINTS
1	$\beta_{double\ slit} = \frac{\lambda D}{d}$ $\beta_{single\ slit} = \frac{2\lambda D}{a}$ $10\beta_{double\ slit} = \beta_{single\ slit}$ Substitution and calculation a=0.2mm	½ ½ ½ 1 ½

CCT

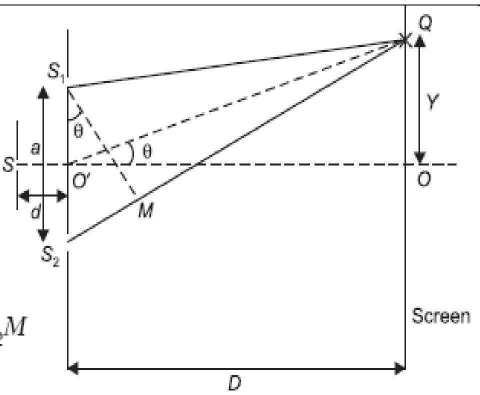
Q.No.	DETAILED SOLUTIONS	VALUE POINTS
1	In air angular width $\theta_o = \frac{\beta}{D} = 2^o$ In water angular width $\theta_w = \frac{\beta}{\mu D} = \frac{2^o}{4/3}$ = 0.15°	1 2

SELF ASSESSMENT TEST

Time allowed: 1 hour **Max. marks: 25**

Q.No.	QUESTIONS	MARKS
1	(d) same frequency, phase and amplitude	1
2	(d) 0.15 cm	1
3	a) the wavefront is spherical	1
4	(d) 0.6 nm	1
5	d	1
6	C	1
7	That phenomenon is called as diffraction. Diffraction occurs when the dimensions of diffracting body have a size equivalent to the size of the wavelength of light. Diffraction has application in holography, grating and more.	½ 1 ½
8	The distance of the nth minimum from the centre of the screen is, xn=nDλ/a where, D = distance of slit from screen	½

	λ= wavelength of the light a = width of the slit For first minimum, n = 1 $x_n=3\times10^3$m $\lambda=600\times10^{-9}$m D = 1.2 m $3\times10^{-3}=1\times1.2\times600\times10^{-9}/a$ $a=1\times1.2\times600\times10^{-9}$ / 3×10^{-3} a=0.24mm	½ ½ ½
9	a) Let the intensity through one of the slit be $I_1=I$. So, intensity of light through the slit covered by glass $I_2=0.5I$ Maximum intensity $I_{max}=(\sqrt{I_1}+\sqrt{I_2})^2$ $\Rightarrow I_{max}=(\sqrt{I}+\sqrt{0.5I})^2=2.9I$ Minimum intensity $I_{min}=(\sqrt{I_1}-\sqrt{I_2})^2$ $\Rightarrow I_{min}=(\sqrt{I}-\sqrt{0.5I})^2=0.086I$ Thus ratio of intensities ImaxImin=2.9: 0.086=33.8 b) If white light is used instead of monochromatic light, then a white fringe is observed at the center of the screen and the coloured fringes are formed at different positions of the screen.	½ ½ ½ ½ 1
10	$\lambda_1=590nm=5.9\times10^{-7}m$ Wavelength of another light beam, $\lambda-(2)=596nm=5.96\times10^{-7}m$ Distance the slits from the screen $=D=1.5m$ Distance between the two slits $\alpha=2\times10^{-4}m$ For the first secondary maxima, $\sin\theta=\frac{3\lambda_1}{2\alpha}=\frac{\chi_1}{D}$ $\chi_1=\frac{3\lambda_1 D}{2\alpha}$ and $\chi_2=\frac{3\lambda_2 D}{2\alpha}$ ∴ Separation between the positions of first secondary maxima of two sodium lines $\chi_1-\chi_2=\frac{3D}{2\alpha}(\lambda_2-\lambda_1)$ $=\frac{3\times1.5}{2\times2\times10^{-4}}(5.96\times10^{-7}-5.9\times10^{-7})$ $=6.75\times10^{-5}m$	½ ½ ½ ½ ½ ½
11	i) B ii) A iii) D iv) Wave nature	1 1 1 1

12	(*a*) When waves from the slits meet at a point on the screen with same phase, the maxima are obtained and with a phase difference of π, the minima are obtained. 	½
	According to the Young's experiment, the path difference between the waves is given by $\Delta P = S_2Q - S_1Q = S_2M$	½
	i.e. $\sin\theta = \dfrac{\Delta P}{a}$	
	From $\Delta QOO'$, $\tan\theta = \dfrac{Y}{D}$	
	For a small angle, $\sin\theta \approx \tan\theta$ i.e. $\Delta P = \dfrac{Ya}{D}$	
	For bright fringes, $\Delta P = n\lambda$	
	Thus, $\dfrac{Y_n a}{D} = n\lambda \Rightarrow Y_n = \dfrac{n\lambda D}{a}$	
	For dark fringes, $\Delta P = (2n-1)\dfrac{\lambda}{2}$	
	Thus, $\dfrac{Y'_n a}{D} = (2n-1)\dfrac{\lambda}{2} \Rightarrow Y'_n = \dfrac{(2n-1)D\lambda}{2a}$	½
	The separation between two consecutive dark or bright fringes is called fringe width.	
	i.e., $\beta = Y_n - Y_{n-1} = \dfrac{n\lambda D}{a} - \dfrac{(n-1)\lambda D}{a} = \dfrac{\lambda D}{a}$	½
	Here β is the fringe width.	
	(*b*) Given: For an interference pattern, $\dfrac{I_{\text{min}}}{I_{\text{max}}} = \dfrac{9}{25}$, $\dfrac{I_1}{I_2} = ?$	½
	Here $\dfrac{I_1}{I_2} = \dfrac{a_1^2}{a_2^2}$ and $\dfrac{I_{\text{min}}}{I_{\text{max}}} = \dfrac{\left(\dfrac{a_1}{a_2}-1\right)^2}{\left(\dfrac{a_1}{a_2}+1\right)^2}$	½
	∴ $\dfrac{\left(\dfrac{a_1}{a_2}-1\right)^2}{\left(\dfrac{a_1}{a_2}+1\right)^2} = \dfrac{9}{25} \Rightarrow \dfrac{\dfrac{a_1}{a_2}-1}{\dfrac{a_1}{a_2}+1} = \dfrac{3}{5}$	½ ½
	⇒ $3\left(\dfrac{a_1}{a_2}+1\right) = 5\left(\dfrac{a_1}{a_2}-1\right) \Rightarrow \dfrac{a_1}{a_2} = 4$	½
	∴ $\dfrac{I_1}{I_2} = \dfrac{a_1^2}{a_2^2} = \dfrac{16}{1}$	½

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UNIT VII DUAL NATURE OF RADIATION AND MATTER

CH 11 DUAL NATURE OF RADIATION AND MATTER

LEVEL-1 MCQ

Q.NO	DETAILED SOLUTIONS	VALUE POINTS
1	Answer: (c) Work function Explanation: minimum energy required to remove an electron	1
2	Answer: (b) X-rays emission Explanation: they are due to transition is the inner energy levels of the atom	1
3	Answer: (a) UV radiations Explanation: The ultraviolet photons have enough energy to knock the electrons out of the metal	1
4	Answer: (d) Cadmium Explanation: Cadmium is not sensitive to visible light.	1
5	Answer: (d) None of these Explanation: Because photos are chargeless	1
6	Answer: (d) X-Ray Emission Explanation: The emission of electrons does not take place in X-Ray Emission	1
7	Answer: (a) It varies with the frequency of light. Explanation: The kinetic energy of the emitted electrons varies with the frequency of light.	1
8	Answer: (a) Converts light energy into electricity. Explanation: A photoelectric cell is a device that converts light energy into electricity.	1
9	Answer: (a) Electrons Explanation: A cathode ray consists of electrons.	1
10	Answer: (c) R.A Millikan Explanation: R.A Millikan gave the theory of quantization of electric charge.	1
11	Answer: (d) Cadmium Explanation: Cadmium is not sensitive to visible light.	1
12	Answer: (b) Photocurrent Explanation: Wave theory can explain diffraction, polarization and interference but could not explain the photoelectric effect. The photoelectric effect is	1

	explained by a quantum theory which treats light as a particle.	
13	Answer: (d) None of the above Explanation: None of the given options deflect photons.	1
14	Answer: (a) Energy Explanation: The photoelectric effect is based on the law of conservation of energy.	1
15	Answer: (c) Rest Mass Explanation: Photon do not possess rest mass.	1
16	Answer: (b) h/λ Explanation: By de-Broglie hypothesis	1
17	Answer: (a) 4V Explanation: Stopping potential is the negative potential applied to stop the electrons having maximum kinetic energy.	1
18	Answer: (b) h/e Explanation: $v=hv_0+K.E$ at stopping potential KE=eV $\Rightarrow hv=hv_0+eV$ $V=h/e\ (v-v_0)$	1
19	Answer: (a) wave like behavior of light. *Explanation*: light is a particle containing energy corresponding to their wavelength.	1
20	Answer: (a) electron. *Explanation*: electron is faster because proton needs much more energy to get up to same speed.	1

LEVEL-2 MCQ

Q.NO	DETAILED SOLUTIONS	VALUE POINTS
1	**Answer*:*** (b) work function of surface ***Explanation***: This is minimum energy required to remove photo electron.	1
2	**Answer:** (c) 3000 A^o **Explanation**: $W.(eV)=12375 / \lambda_0$ $\Rightarrow \lambda_0=12375 / 4.125=3000\ A^o$	1
3	**Answer:** (a) 1V **Explanation**: $KE = eV_o$	1
4	**Answer:** (b) electron **Explanation**: At constant velocity, wavelength (λ) is inversely proportional to mass of the particle.	1
5	Answer: (c) 1:3	1

	Explanation: *K.E.* = Photon energy − Work function. ∴*K·E*2/*K·E*1= (1−0.5) / (2−0.5) = 0.5 / 1.5 =1 / 3	
6	Answer: (d) 3λ. Explanation: by using Einstein's photo electric equation.	1
7	Answer: (c) decrease by 4 times Explanation: by using formula $\lambda = 12.27 / \sqrt{V}$	1
8	Answer: (d) 1.82×10^{-15} m s−1 Explanation: *λparticle=λelectron* *h/mpVp=h/meVe* or, *mpVp=meVe*	1
9	Answer: (a) $< 2.75\times10^{-9}$ m Explanation: $\lambda = \frac{h}{\sqrt{2m\text{KE}}} = \frac{6.63\times10^{-34}}{\sqrt{2\times9.1\times10^{-31}\times0.21\times1.6\times10^{-19}}} = 2.668\times10^{-9}\ \text{m}$ $\lambda = 2.67\times10^{-9}\ \text{m}$	1
10	Answer: (d) hc/2λ Explanation: Kmax2=3Kmax1 ∴2hcλ−ϕ0=3(hcλ−ϕ0) ⇒3ϕ0−ϕ0=3hcλ−2hcλ ⇒2ϕ0=hcλ ⇒ϕ0=hc2λ	1

LEVEL-3 MCQ

Q.NO	DETAILED SOLUTIONS	VALUE POINTS
1	Answer: b Explanation: ½ $mv^2 = 3hv_0$ $v^2 = 6\ hv_0/m$ $v = \sqrt{6}\ hv_0/m$	1
2	Answer: b Explanation: $v_{max}=\sqrt{2m\ (KE_{max})} = \sqrt{2m\ (E_{Ph}-W)}$ $v_1/v_2=\sqrt{0.3/2.7}=\sqrt{1/9}=1:3$	1
3	Answer: c Explanation:	1

	$\mathrm{P} = \frac{\mathrm{E}}{t} = \frac{nh\upsilon}{t} = \frac{n}{t} \times \frac{hc}{\lambda}$ $\mathrm{P}_1 = \frac{1.04\times10^{15}\times1240}{520} = 2.48\times10^{15}$ $\mathrm{P}_2 = \frac{1.38\times10^{15}\times1240}{460} = 3.72\times10^{15}$ $\frac{\mathrm{P}_2}{\mathrm{P}_1} = \frac{3.72\times10^{15}}{2.48\times10^{15}} = 1.5$	
4	Answer: a Explanation: $\mathrm{P} = \frac{n}{t}\frac{hc}{\lambda}$ $\therefore \frac{n}{t} = \frac{\mathrm{P}\lambda}{hc} = \frac{3.8\times10^{26}\times550\times10^{-9}}{6.6\times10^{-34}\times3\times10^{8}} = 1\times10^{45}$	1
5	Answer: b Explanation: $\mathrm{E} = h\upsilon = \frac{hc}{\lambda} = \left(\frac{(6.6\times10^{-34}\times3\times10^{8})/1.6\times10^{-19}}{410\times10^{-9}}\right) = \frac{1240}{410}$ E = 3.04 eV	1
6	Answer: d Explanation: Incident Frequency<Threshold frequency Therefore, no photoelectrons will be emitted. ⇒ Incident Frequency>Threshold frequency then, $n \propto I$ 'n' is the number of emitted photoelectrons ∴ Photoelectric current will be 'Zero'	1
7	Answer: b *Explanation:* $\omega0=hc/\lambda$……. (1) $2\omega0=hc/\lambda1$…... (2) $2(hc/\lambda) = hc/\lambda1$ $\lambda1=\lambda / 2$	1
8	Answer: c Explanation: $KE_1=hv-W0$…..(1) When frequency is doubled. $KE_2=2hv-W0$…..(2) i.e., $(2hv-W0)>(2hv-2W0)$ So, kinetic energy of the photoelectrons will be more than doubled	1
9	Answer: b Explanation: $\lambda=h/\sqrt{2mKE}$ $\lambda\propto1/\sqrt{KE}$.	1

	if we double the kinetic energy, $\lambda \propto 1\sqrt{2KE}$ $\lambda \propto 1/\sqrt{2}$	
10	Answer: d Explanation: Maximum kinetic energy of the emitted electrons from the photosensitive plate is given by, $K_{max} = \frac{1}{2}m(v_{max})^2 = hv - \phi_0$ Hence, maximum velocity depends on frequency of incident light and work function of plate both.	1

LEVEL-1 (2 M QUESTIONS)

Q.NO	DETAILED SOLUTIONS	VALUE POINTS/STEP MARKING
1.	E = hc/λ E ∝ $1/\lambda$ clearly when wavelength λ is doubled, Energy of photon reduces to halved.	1 1
2.	Wavelength is inversely proportional to work function, so metal A with lower work function has higher threshold wavelength	1 1
3.	$\lambda = h/p = h/\sqrt{2mK}$, $\lambda e > \lambda p$	1 1
4.	B line represents particle of larger mass because slope 1/√m	1
5.	Gain in K.E = qV ½ mpvp ^{2} =qp V, ½ mαvα ^{2} =qα V ½ mαvα ^{2} / ½ mpvp^2 = qα Vα ^{2} / Vp ^{2} = qα /qα x mp /mα = 2/1 x 1/4 =1/2 Vα / Vp = 1/√2	1 1
6.	K.E. of photoelectron KEmax= = h (v – v0) KEmax = h($c\lambda$ − $c\lambda$0) = mv2 max/2, vmax∝ 1 √λ As the wavelength of incident light decreases, the velocity of photoelectrons increases.	1 1
7.	E = hc/λ = $6.6\times10^{-34}\times3\times10^{8}$ / 330 x10^{-9} = 3.767eV ϕo = 4.2eV Since E < W0 no photo electric emission.	1 1
8.	Since electron ejection is difficult from copper than sodium, so copper has greater work function than sodium. As threshold wavelength is inversely related with work function, so sodium has higher threshold wavelength than copper.	1 1

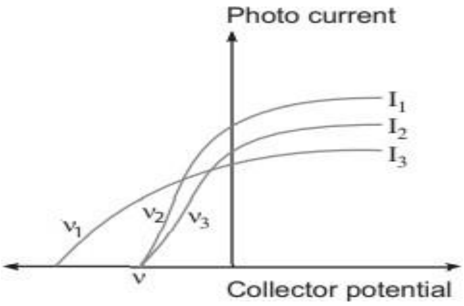
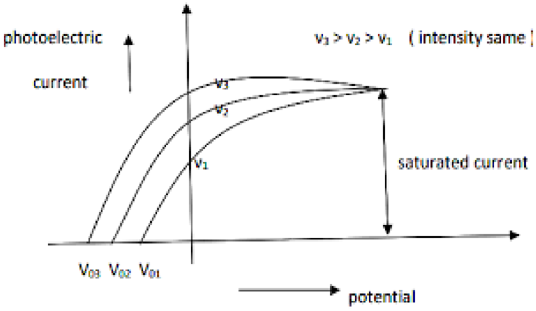
LEVEL-2 (2 M QUESTIONS)

Q.NO	DETAILED SOLUTIONS	VALUE POINTS/STEP MARKING
1.	Since photoelectrons are not emitted by yellow light, so electrons will not be emitted by red light. Since green light is able to emit electrons so blue light will emit electrons with large velocity.	1 1
2.	λ α 1/√m mα > mp = mn > me, λe < λp = λn > λα	1 1
3.	Non-metals have high work function.	2
4.	No, energy of photon is less than work function. $E = \frac{6.6\times10\times3\times10}{6800\times10\times1.6\times10}$ = 1.8Ev	1 1
5.	No, most electrons get scattered into the metal. Only a few come out of the surface of the metal.	1 1

LEVEL-3 (2 M QUESTIONS)

Q.NO	DETAILED SOLUTIONS	VALUE POINTS/STEP MARKING
1.	(i) From Einstein photoelectric equation, eV0 = hν- ϕ0 → V0 =hν/e − ϕ0/e ∴ slope of the line AB = ΔV0/Δν = h/e the threshold frequency of Metal A is greater than the Metal B, Therefore the work function of Metal A is more than Metal B (ii) Intercept on potential axis = − ϕ_0/e	1 1
2.	M_2.	2
3.	The momentum of a photon having energy (hv) is given as: $\lambda=h/p$ …. (i) De Broglie wavelength of the photon is given as: $\lambda=h/mv$ But, p = mv Therefore, $\lambda=h/p$…(ii) From equations (i) and (ii), it can be concluded that the wavelength of the electromagnetic radiation and the de Broglie wavelength of the photon is equal.	1 1

LEVEL-1 (3 M QUESTIONS)

Q.NO	DETAILED SOLUTIONS	VALUE POINTS/STEP MARKING
1.	The photoelectric current increases proportionally with the increase in intensity of incident radiation. Larger the intensity of incident radiation, larger is the number of incident photons and hence larger is the number of electrons ejected from the photosensitive surface.	1 1 1
2.	Metal B will yield more photo electrons. Work function of Metal B is lower than that of A for the same wavelength of light. Hence metal B will give more electrons.	1 1 1
3.		3
4.		3
5.	Definitions. From Einstein's photoelectric equation, eV0 = hv – φ0 for v > v0. Cut off voltage V0 = (h/e) v – (φ0/e) h/e is the slope of the graph. v0 = φ0/h	1 1 1

LEVEL-2 (3 M QUESTIONS)

Q.NO	DETAILED SOLUTIONS	VALUE POINTS/STEP MARKING
1.	(a)Einstein photoelectric equation can be used to determine the plank's constant 'h'. We know, the slope of the graph is plank's constant h= ml/2n	1 1

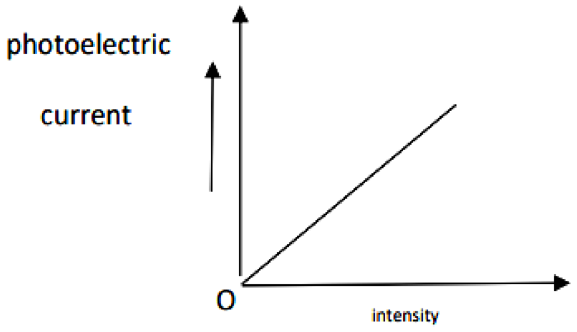
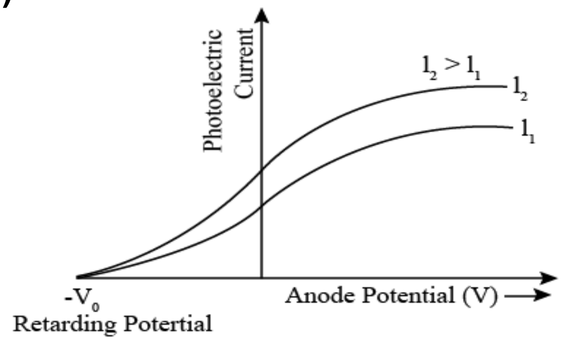
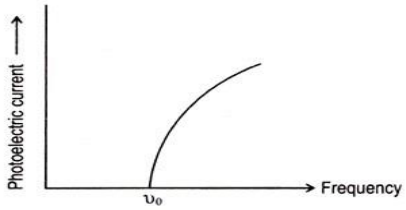
	(b) From the graph 2фo/m = I 249 Hence, the work function will be ф0 = ml/2 (c)The threshold frequency is the intercept on horizontal axis	1
2.	a) No kinetic energy or photoelectrons depends on the energy level from which it comes out. Electrons from different energy levels beer different kinetic energies. b) No kinetic energy depends on the energy of each photon only and not on the number of photons (i.e. intensity of light). c)The number of photoelectrons depends on the intensity of incident light.	1 1 1
3.	(i) X as has smaller threshold frequency (ii) Since фY > фX so KEy > KEx Therefore x gives out electrons with large KE (iii) no change	1 1 1

LEVEL-3 (3 M QUESTIONS)

Q.NO	DETAILED SOLUTIONS	VALUE POINTS/STEP MARKING
1.	(a) 1 and 2 correspond to same intensity but different material. (b) 3 and 4 correspond to same intensity but different material. This is because the saturation currents are same and stopping potentials are different. Intensity of light photoelectric current (a) 1 and 3 correspond to different intensity but same material. (b) 2 and 4 correspond to different intensity but same material. This is because the stopping potentials are same but saturation currents are different	1 1 1
2.	(i) Slope is determined by h and e (or slope is independent of the metal used). (ii) Intersect of lines depend on the work function.	1 ½ 1 ½

3.	$\lambda_A = \frac{h}{\sqrt{2m_1qV_A}}$ $\lambda_B = \frac{h}{\sqrt{2m_2qV_B}}$ $\therefore \frac{\lambda_A}{\lambda_B} = \sqrt{\frac{2m_2qV_B}{2m_1qV_A}} = \sqrt{\frac{m_2V_B}{m_1V_A}}$ $\because \frac{\lambda_A}{\sqrt{V_A}} = \frac{\lambda_B}{\sqrt{V_B}}$ m1 < m2 Therefore, mA < mB	1 1 1

LEVEL-1 (5 M QUESTIONS)

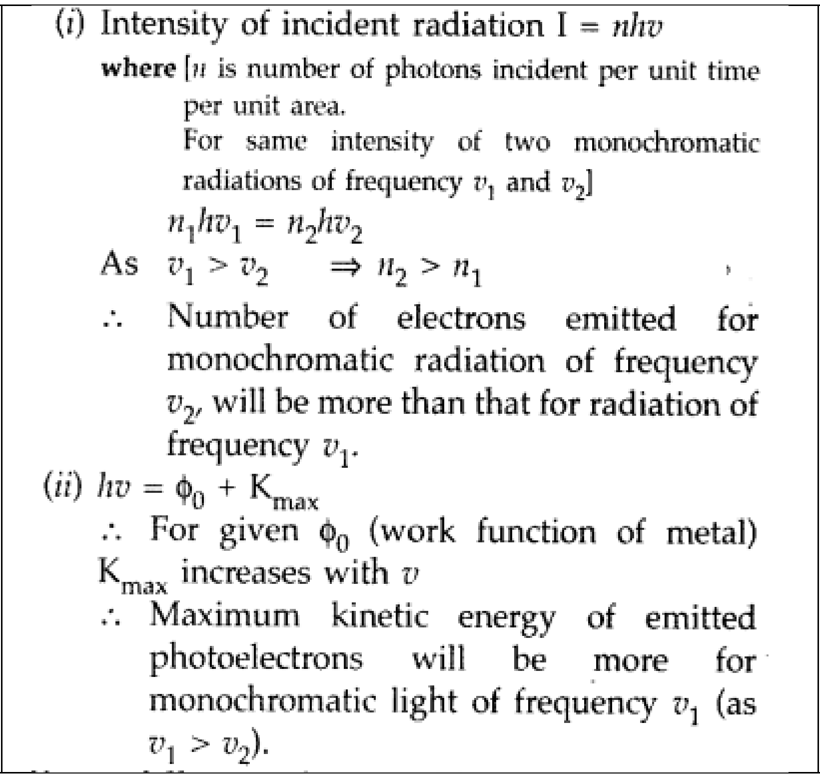
Q.NO	DETAILED SOLUTIONS	VALUE POINTS/STEP MARKING
1.	**i)**  **ii)**  **iii)** 	2 2 1

LEVEL-2 (5 M QUESTIONS)

Q.NO	DETAILED SOLUTIONS	VALUE POINTS/STEP MARKING
1.	(*i*) de Broglie wavelength $\lambda = \frac{h}{p} = \frac{h}{\sqrt{2mqV}}$	1
	For same $V, \lambda \alpha \frac{1}{\sqrt{mq}}$	1
	$\frac{\lambda_p}{\lambda_\alpha} = \sqrt{\frac{m_\alpha q_\alpha}{m_p q_p}} = \sqrt{\frac{4m_p}{m_p} \cdot \frac{2e}{e}}$ $= \sqrt{8} = 2\sqrt{2}$ Clearly, $\lambda_p > \lambda_\alpha$. Hence, proton has a greater de-Broglie wavelength.	1
	(*ii*) Kinetic energy, $K = qV$ For same $V, K \alpha q$	1
	$\frac{K_p}{K_\alpha} = \frac{q_p}{q_\alpha} = \frac{e}{2e} = \frac{1}{2}$ Clearly, $K_p < K_\alpha$. Hence, proton has less kinetic energy.	1

LEVEL-3 (5 M QUESTIONS)

Q.NO	DETAILED SOLUTIONS	VALUE POINTS/STEP MARKING

1.	 (*i*) Intensity of incident radiation I = $nh\upsilon$ **where** [n is number of photons incident per unit time per unit area. For same intensity of two monochromatic radiations of frequency υ_1 and υ_2] $n_1 h\upsilon_1 = n_2 h\upsilon_2$ As $\upsilon_1 > \upsilon_2 \quad \Rightarrow n_2 > n_1$ $\therefore$ Number of electrons emitted for monochromatic radiation of frequency υ_2, will be more than that for radiation of frequency υ_1. (*ii*) $h\upsilon = \phi_0 + K_{max}$ $\therefore$ For given ϕ_0 (work function of metal) K_{max} increases with υ $\therefore$ Maximum kinetic energy of emitted photoelectrons will be more for monochromatic light of frequency υ_1 (as $\upsilon_1 > \upsilon_2$).	1 1 1 1 1

LEVEL-1 (NUMERICALS)

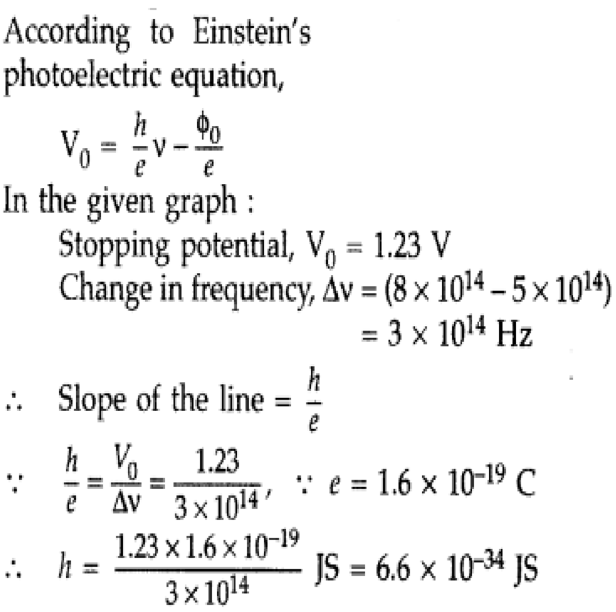
Q.NO	DETAILED SOLUTIONS	VALUE POINTS/STEP MARKING
1.	Energy E = 1 MeV = 1.6×10^{-13}J, p = E/c= 5.33×10^{-22}Kg m/s	1
2.	$\lambda = 12.27/\sqrt{V}\ \dot{A}$ 0 for V = 4 V, $\lambda = 12.27/\sqrt{4}\ \dot{A} = 6.135A^0$	1
3.	$\lambda = 1.227/\sqrt{V}$ nm = $1.227/\sqrt{100}$ =1.227A0 X rays	1
4.	KEmax = 3 eV => 3eV = eV0 => V0 = 3V	1

LEVEL-2 (NUMERICALS)

Q.NO	DETAILED SOLUTIONS	VALUE POINTS/STEP MARKING
1.	v = 6×10^{14} Hz, P = 2×10^{-3} W i) Energy of photon = E = hv = $6.6 \times 10^{-34} \times 6 \times 10^{14}$ = 3.98×10^{-19} J ii) If N is the number of photons emitted per second by the source then Power = N x energy of photon P = NE N = P/E = $2 \times 10^{-3} / 3.98 \times 10^{-19} = 5 \times 10^{15}$ photons per second	1 1
2.	Vs = 3 V and Kmax = eVo, so Kmax = 3 eV (ii) λ = 2000 Å = 2×10^{-7}m. Energy of incident photon = hc/ λ = $6.6 \times 10^{-34} \times 3 \times 10^{8} / 2 \times 10^{-7}$ = 6.20 eV W = E – Kmax = 3.2 Ev.	1 1

3.	Kmax = hv – ϕ0 i) 6.63x10-34x 6 x1014/1.6x10-19 – 2.14eV = 0.314eV ii) eV0 = Kmax = 0.314eV V0 = 0.314V iii)345.8 X 103 m/s	1 1

LEVEL-3 (NUMERICALS)

Q.NO	DETAILED SOLUTIONS	VALUE POINTS/STEP MARKING
1.	Ans: Given wavelength is λ = 2000A° = 2×10^{-7} m, ϕo= 4.2eV. The kinetic energy is K.E$_{max}$ = 1/2mv^{2}max = hv−½ mV^{2}max = hc/λ−ϕo = (6.6×10^{-34}×3×10^8 /2×10^{-7}) − 4.2 ½ mV2 max = 2eV. This is the K.E of the fastest electron is 2eV The velocity of the slowest electron would be zero, hence the kinetic energy it possesses is also zero	1 1 1
2.	 According to Einstein's photoelectric equation, $V_0 = \frac{h}{e}\nu - \frac{\phi_0}{e}$ In the given graph : Stopping potential, $V_0 = 1.23$ V Change in frequency, $\Delta\nu = (8 \times 10^{14} - 5 \times 10^{14})$ $= 3 \times 10^{14}$ Hz $\therefore$ Slope of the line $= \frac{h}{e}$ $\because \frac{h}{e} = \frac{V_0}{\Delta\nu} = \frac{1.23}{3 \times 10^{14}}, \because e = 1.6 \times 10^{-19}$ C $\therefore h = \frac{1.23 \times 1.6 \times 10^{-19}}{3 \times 10^{14}}$ JS $= 6.6 \times 10^{-34}$ JS	1 1 1

3.	**Given :** $\lambda = 5460 \text{ nm} = 5460 \times 10^{-9} \text{ m} \quad \lambda_B = ?$ Energy of the photon (K) $= \frac{hc}{\lambda} \quad \ldots(i)$ de-Broglie wavelength, $(\lambda_B) = \frac{h}{p} = \frac{h}{\sqrt{2mk}} \ldots(ii)$ $\therefore \quad \lambda_B = \frac{h}{\sqrt{2m.\frac{hc}{\lambda}}} = \sqrt{\frac{h\lambda}{2mc}}$ $= \left[\frac{(6.63 \times 10^{-34}) \times (5460 \times 10^{-9})}{2 \times (9.1 \times 10^{-31}) \times (3 \times 10^{8})}\right]^{\frac{1}{2}}$ $= \mathbf{25.75 \times 10^{-10}}$ **m**	1 1 1

CASE BASED

Q.NO	DETAILED SOLUTIONS	VALUE POINTS/STEP MARKING
1.	i) d ii) b iii) d iv) b	1 1 1 1

COMPETANCY BASED

Q.NO	DETAILED SOLUTIONS	VALUE POINTS/STEP MARKING
1.	i) a ii) a iii) b iv) a	1 1 1 1
2.	i) b ii) d iii) c iv) a	1 1 1 1

CCT

Q.NO	DETAILED SOLUTIONS	VALUE POINTS/STEP MARKING
1.	i) b ii) a iii) a iv) a	1 1 1 1

SELF ASSESSMENT

Q.NO	DETAILED SOLUTIONS	VALUE POINTS/STEP MARKING
1	b. electron	1
2	c. 1:3	1
3	d. 3λ	1
4	c. decrease by 4 times	1
5	D	1
6	B	1
7	Energy of incident photon *E=12400 eV / λ (in A°)* So *E=12400/6800=1.82 eV* Since the energy of photon is less than the work function of sodium. So sodium does not show photoelectric effect for orange light.	1 1
8	$eV_0=h\nu-h\nu_0$ On comparing with the $Y=mX+C$ We can observe that more the intercept on the Y-axis or $V0$ more is the frequency (ν_0). Hence from the graph, the threshold frequency of Metal A is greater than the Metal B, Hence the work function of Metal A is more than Metal B.	1 1
9	a. Mass of the deuteron is twice the mass of the proton, hence the proton will have a greater value of De-Broglie wavelength associated with it. b. Since, proton has a greater value of De-Broglie wavelength associated with it, hence it will have less momentum as compared to the momentum of deuteron.	1 ½ 1 ½
10	(i) $h\nu=\frac{hc}{\lambda}=\frac{6.63\times10^{-34}\times3\times10^{8}}{4\times10^{-7}}$ $=4.9725\times10^{-19}\,\mathrm{J}=\frac{4.9725\times10^{-19}}{1.6\times10^{-19}}\,\mathrm{eV}$ $=3.108\,\mathrm{eV}$ $\therefore\ V_0e=h\nu-\phi=3.108-1.8=1.308\,\mathrm{eV}$	½ 1

	(ii) $V_O e = \frac{1}{2}mv^2{}_{\text{max}}$ $\therefore\ v_{\text{max}} = \sqrt{\frac{2V_O e}{m}}$ $\therefore\ v_{\text{max}} = \sqrt{\frac{2 \times 1.308 \times 1.6 \times 10^{-19}}{9.1 \times 10^{-31}}}$ $= \mathbf{6.782 \times 10^5\ m/s}$	½ 1
11	i) a. diffraction and photo electric effect ii) d. become half iii) b. Momentum iv) d. v = h/ λm	1 1 1 1
12	a. Definition. Any two characteristics. b. Correct Graph 1 Correct Graph 2 Correct Graph 3 **OR** a. Correct derivation b. i) correct explanation ii) correct explanation	1 1 1 1 1 2 1½ 1½

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UNIT VIII ATOMS AND NUCLEI

CH 12 ATOMS

Level 1(MCQ QUESTIONS)

Q.NO	DETAILED SOLUTIONS	VALUE POINT /STEP MARKING
1	B) Thomson	1
2	B) Atoms have a nucleus	1
3	C) Protons and neutrons	1
4	B) Negative	1
5	B) Fixed orbits	1
6	B) Emits energy	1
7	B) Balmer series	1
8	B) Negative	1
9	A) Quantized	1
10	B) 1	1
11	C) Bohr’s model	1
12	C) The constant used in calculating the wavelengths of spectral lines	1
13	B) Balmer series	1
14	C) Rutherford	1
15	C) Electron	1
16	B) Quantized	1
17	C) Neutral	1
18	A) First orbit	1
19	A) Could not explain atomic spectra	1

20	C) Ultraviolet	1

Level 2 (MCQ QUESTIONS)

Q.NO	DETAILED SOLUTIONS	VALUE POINT /STEP MARKING
1	A) Electrons in higher orbits have higher energy.	1
2	A) Lyman series	1
3	A) Energy level of the electron	1
4	B) Electrons do not radiate energy while moving in orbits	1
5	A) The wavelength of light emitted or absorbed	1
6	c) – 3.4 eV	1
7	c) ⅛	1
8	(b) the presence of neutrons in the nucleus.	1
9	a) Lyman series	1
10	b) decreases	1

Level 3 (MCQ QUESTIONS)

Q.NO	DETAILED SOLUTIONS	VALUE POINT /STEP MARKING
1	.b) 10	1
2	c) – 3.4 eV	1
3	c) 9/4	1
4	a) Lyman series	1
5	b) unstable	1
6	a) such that the angular momentum should be integral multiple of h.	1

7	a)½	1
8	a)3E/4	1
9	- c) Angular momentum of electron	1
10	c) 40.8 eV	1

Level 1(2M QUESTIONS)

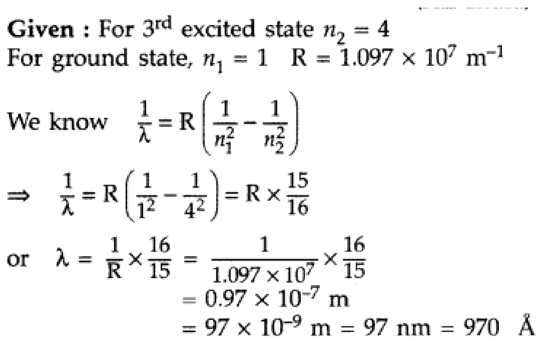
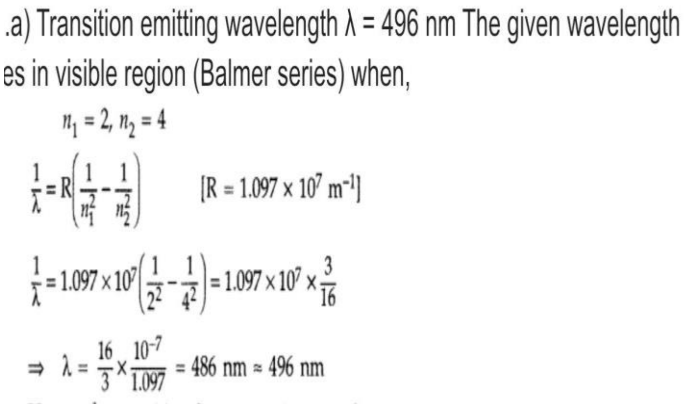
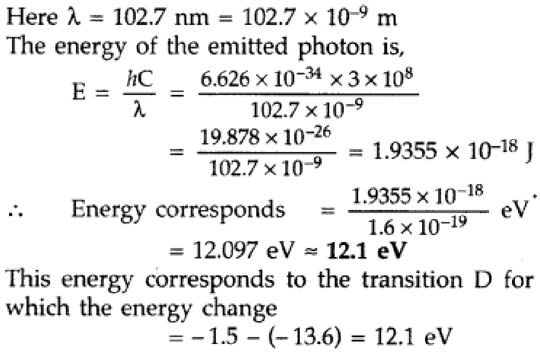
Q.NO	DETAILED SOLUTIONS	VALUE POINT /STEP MARKING
1	Ionisation energy : The energy required to knock out an electron from an atom is called ionisation energy of the atom. For hydrogen atom it is 13.6 eV.	1 1
2	Bohr's radius in hydrogen atom, $r_1 = \frac{\varepsilon_0 h^2}{\pi m e^2} = \mathbf{0.5.29 \times 10^{-10}\ m}$	1 1
3	Radius of Bohr's stationary orbits, $r = \frac{n^2 h}{4\pi^2 m K e^2}$ Clearly, $r \propto n^2$ and in ground state, $n = 1$ For 1st excited state, $n = 2$ $\therefore$ Ratio of radii of the orbits $= \frac{2^2}{1^2} = \frac{4}{1} = \mathbf{4:1}$	1 1
4	As the revolving electron loses energy continuously, it must spiral inwards and eventually fall into the nucleus. So it was not able to explain the atomic structure.	2
5	For the third excited state, $n_2 = 4$, and $n_1 = 3, 2, 1$ Hence there are 3 spectral lines.	1 1
6	This model could not explain scattering of alpha particle through large angles.	2
7	Paschen series ,Brackett series and pfund series.	2
8	13.6 V	2

Level 2 (2M QUESTIONS)

Q.NO	DETAILED SOLUTIONS	VALUE POINT /STEP MARKING
1	The first excitation potential of the hydrogen atom is -3.4-(-13.6) = 10.2eV. And 12.09 eV	1 1
2		1 1
3	1. The two series of hydrogen spectrum lying in the ultraviolet and visible region are – 1. Layman series in ultraviolet region 2. Balmer series in visible region	1 1
4	we know that mass of an alpha particle is 6.64×10^{-27} KG is much more than the mass of a hydrogen 1.67^{-27} KG. Therefore, scattering angle would not be large enough. There for alpha particle would not bounce back. The size of a nucleus cannot be deter mind.	1 1
5	The minimum energy required to remove an electron from atom to infinitely for away is called the ionisation energy. The ionisation energy for hydrogen atom is 13.6eV.	1 1

Level 3 (2M QUESTIONS)

Q.NO	DETAILED SOLUTIONS	VALUE POINT /STEP MARKING

1	 **Given :** For 3rd excited state $n_2 = 4$ For ground state, $n_1 = 1$ R = 1.097×10^7 m^{-1} We know $\frac{1}{\lambda} = R\left(\frac{1}{n_1^2}-\frac{1}{n_2^2}\right)$ $\Rightarrow \frac{1}{\lambda} = R\left(\frac{1}{1^2}-\frac{1}{4^2}\right) = R \times \frac{15}{16}$ or $\lambda = \frac{1}{R} \times \frac{16}{15} = \frac{1}{1.097 \times 10^7} \times \frac{16}{15}$ $= 0.97 \times 10^{-7}$ m $= 97 \times 10^{-9}$ m = 97 nm = 970 Å	½ ½ 1
2	Transition emitting wavelength λ = 496 nm The given wavelength lies in visible region (Balmer series) when,  .a) Transition emitting wavelength λ = 496 nm The given wavelength es in visible region (Balmer series) when, $n_1 = 2, n_2 = 4$ $\frac{1}{\lambda} = R\left(\frac{1}{n_1^2}-\frac{1}{n_2^2}\right)$ [R = 1.097×10^7 m^{-1}] $\frac{1}{\lambda} = 1.097 \times 10^7\left(\frac{1}{2^2}-\frac{1}{4^2}\right) = 1.097 \times 10^7 \times \frac{3}{16}$ $\Rightarrow \lambda = \frac{16}{3} \times \frac{10^{-7}}{1.097} = 486 \text{ nm} \approx 496 \text{ nm}$	½ 1 1/2
3	 Here λ = 102.7 nm = 102.7×10^{-9} m The energy of the emitted photon is, $E = \frac{hC}{\lambda} = \frac{6.626 \times 10^{-34} \times 3 \times 10^8}{102.7 \times 10^{-9}}$ $= \frac{19.878 \times 10^{-26}}{102.7 \times 10^{-9}} = 1.9355 \times 10^{-18}$ J ∴ Energy corresponds $= \frac{1.9355 \times 10^{-18}}{1.6 \times 10^{-19}}$ eV = 12.097 eV ≈ **12.1 eV** This energy corresponds to the transition D for which the energy change $= -1.5 - (-13.6) = 12.1$ eV	1 1

Level 1 (3 M QUESTIONS)

Q.NO	DETAILED SOLUTIONS	VALUE POINT /STEP MARKING
1	In Balmer series, an electron jumps from higher orbits to the second stationary orbit ($n_f = 2$). We know that $\frac{1}{\lambda} = R\left(\frac{1}{n_f^2} - \frac{1}{n_i^2}\right)$ and in this particular case $\frac{1}{\lambda} = R\left(\frac{1}{2^2} - \frac{1}{n_i^2}\right)$ For the shortest wavelength $n_i = \infty$ $\frac{1}{\lambda} = \frac{R}{4}$ $\therefore \quad \lambda = \frac{4}{R} = \frac{4}{10^7} = \mathbf{4 \times 10^{-7}\ m}$	1 2
2	The scattering of alpha particle occurs due to the electrostatic field of the nucleus. That is why the charge in a nucleus enter the expression for the impact parameter not its mass.	3
3	Radius of Bohr's stationary orbits, $r = \frac{n^2 h}{4\pi^2 mKe^2}$ Clearly, $r \propto n^2$ and in ground state, $n = 1$ For 1st excited state, $n = 2$ $\therefore$ Ratio of radii of the orbits $= \frac{2^2}{1^2} = \frac{4}{1} = \mathbf{4 : 1}$	1 2
4	$r = n^2 \times 5.3 \times 10^{-11}$ m $\therefore$ Radius of second excited state ($n = 3$) is : $r = (3)^2 \times 5.3 \times 10^{-11}\ \text{m} = 9 \times 5.3 \times 10^{-11}\ \text{m}$ $= \mathbf{4.77 \times 10^{-10}\ m}$	1 2
5	Postulates of Bohr.s theory of hydrogen atom : (i) In an atom, the electrons revolve around the nucleus in certain definite circular paths called orbits or shells. (ii) Each shell or orbit corresponds to a definite energy. Therefore, these circular orbits are also known as energy levels or energy shells.	

Level 2 (3 MQUESTIONS)

Q.NO	DETAILED SOLUTIONS	VALUE POINT /STEP MARKING
1	Kinetic energy, K_e = + T.E. = 13.6 eV Potential energy, P_e = 2 T.E. = 2 (-13.6) = – 27.2 eV	1 1 1
2	Important limitations of Rutherford Model : 1. According to Rutherford model, electron orbiting around the nucleus, continuously radiates energy due to the acceleration; hence the atom will not remain stable. 2. As electron spirals inwards; its angular velocity and frequency change therefore it. will emit a continuous spectrum.	1 2
3	The two series of hydrogen spectrum lying in the ultraviolet and visible region are 1. Lyman series in ultraviolet region 2. Balmer series in visible region	1 1 1

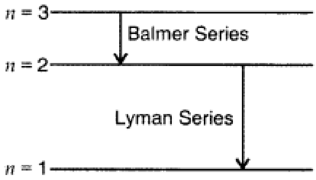
Level 3 (3 M QUESTIONS)

Q.NO	DETAILED SOLUTIONS	VALUE POINT /STEP MARKING
1	The limitations of Bohr's atomic model are: (1) It does not give any indication regarding the arrangement and distribution of electrons in an atom. (2) It could not account for the wave nature of electrons.	1 2

2	Definition of ionization energy : “The minimum energy, required to free the electron from the ground state of the hydrogen atom, is known as Ionization Energy.” The ionization energy is given by $E_0 = \frac{me^4}{8\epsilon_0^2 h^2}$ *i.e.*, $E_0 \propto m$ Ionization Energy will become 200 times, ∵ the mass of given particle is 200 times.	1 1 1
3	When an electron moves around hydrogen nucleus, the electrostatic force between electron and hydrogen nucleus provides necessary centrepetal force. $\frac{mv^2}{r} = \frac{1}{4\pi\epsilon_0}\frac{e^2}{r^2}$ or $mv^2r = \frac{e^2}{4\pi\epsilon_0}$ ...(*i*) Also we know from Bohr’s postulate, $mvr = \frac{nh}{2\pi}$ or $m^2v^2r^2 = \frac{n^2h^2}{4\pi^2}$ ...(*ii*) Dividing (*ii*) by (*i*), we have $mr = \frac{n^2h^2}{4\pi^2} \times \frac{4\pi\epsilon_0}{e^2}$ $\therefore \quad r = \frac{n^2h^2}{4\pi^2me^2}.4\pi\epsilon_0 \quad \therefore\ r \propto n^2$	1 1 1

Level 1(5 M QUESTIONS)

Q.NO	DETAILED SOLUTIONS	VALUE POINT /STEP MARKING

1	(i) $n_f = 2, \quad n_i = 3$ *Balmer series* $n_i = 2, \quad n_f = 1$ *Lyman series*  (ii) $\frac{1}{\lambda_B} = R\left[\frac{1}{2^2} - \frac{1}{3^2}\right] = R\left[\frac{1}{4} - \frac{1}{9}\right] = \frac{5}{36}R$ **...where** $\left[\begin{array}{l}\lambda_B \text{ is the wavelength for Balmer series.} \\ \lambda_L \text{ is the wavelength for Lyman series.}\end{array}\right.$ and $\frac{1}{\lambda_L} = R\left(\frac{1}{1^2} - \frac{1}{2^2}\right) = R\left[\frac{1}{1} - \frac{1}{4}\right] = \frac{3}{4}R$ $\therefore \frac{\lambda_B}{\lambda_L} = \frac{36}{5} \times \frac{3}{4} = \frac{27}{5}$ $\therefore$ *Ratio* $= \lambda_B : \lambda_L = 27 : 5$	1 2 2

Level 2 (5M QUESTIONS)

Q.NO	DETAILED SOLUTIONS	VALUE POINT /STEP MARKING
1	These transitions belong to : 1. Balmer series, 2. Lyman series (ii) $\frac{1}{\lambda_B} = R\left[\frac{1}{4} - \frac{1}{16}\right] = \frac{3}{16}R,$ $\frac{1}{\lambda_L} = R\left[\frac{1}{1^2} - \frac{1}{2^2}\right] = \frac{3}{4}R$ $\therefore \frac{\lambda_B}{\lambda_L} = \frac{16}{3} \times \frac{3}{4} = 4$ **...where** $\left[\begin{array}{l}\lambda_B \text{ is the wavelength for Balmer series.} \\ \lambda_L \text{ is the wavelength for Lyman series.}\end{array}\right.$ $\therefore$ *Ratio* $= \lambda_B : \lambda_L = 4 : 1$	1

Level 3 (5M QUESTIONS)

Q.NO	DETAILED SOLUTIONS	VALUE POINT /STEP MARKING
1	Rutherford's model proposed the negative charge electron surrounded that is nucleus of an atom He also claimed that the electrons surrounding the nucleus revolve around it with very high speed in circular paths. He named these circular paths as orbits.	1
	- The atom consists of a positively charged center called the nucleus. - Most of the mass of the atom is concentrated in the nucleus. - The size (or volume) of the nucleus is very small as compared to the size (or volume) of the atom. - The nucleus is surrounded by negatively charged electrons.	2
	His model failed to explain the stability of atom . The arrangement of electrons in a circular path was not defined. Any particle that is moving in a circular path would undergo acceleration and radiates energy. Thus, the revolving electron would lose energy and finally fall into the nucleus.	2

Level 1Numericals

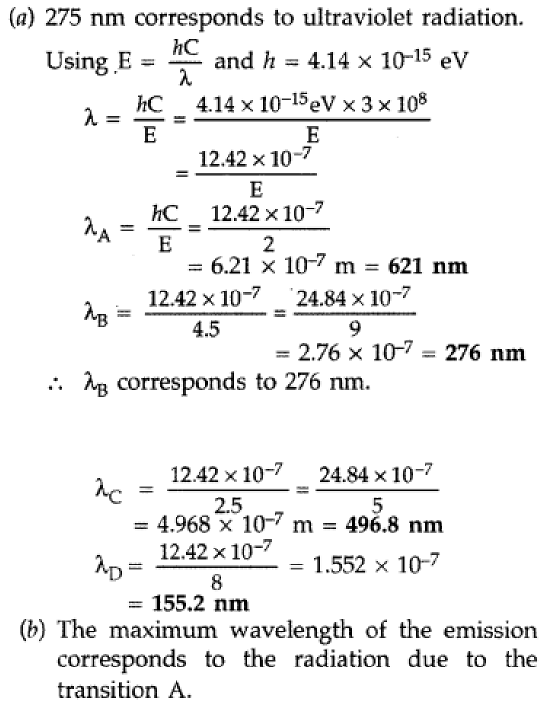
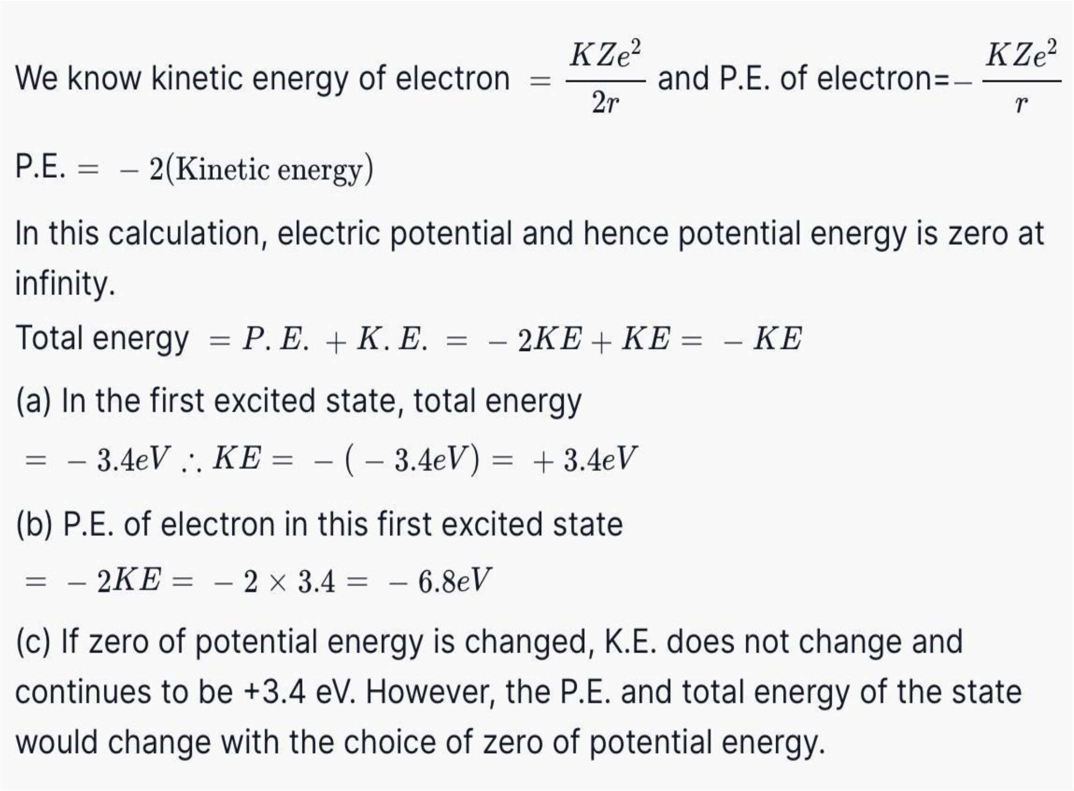
Q.NO	DETAILED SOLUTIONS
1	Total energy E = to -13.6 electron volt Kinetic energy is T= - 13.6 electron volt Potential energy V = -2T = - 2x13.6 = 27.2eV
2	zero $E_n = -13.6/n^2$ eV when n = infinity
3	$r2/r1= n2\ ^2/n1\ ^2 = 2\ ^2 / 1\ ^2 = 4: 1$
4	$r3/r1= n3\ ^2/n1\ ^2 = 3\ ^2 / 1\ ^2 = 9$ $r3 = 9\ r1 = 9x\ 5.3 \times 10^{-10}$ m

Level 2 Numericals

Q.NO	DETAILED SOLUTIONS
1	Energy of photon wavelength 275 nm $E = \frac{hc}{\lambda} = \frac{6.63\times10^{-34}\times3\times10^{8}}{275\times10^{-9}\times1.6\times10^{-19}}.\text{eV} = 4.5 \text{ eV}$ This componds to transition 'B'. (*i*) *Element A* has radiation of maximum wavelength *621 nm.* (*ii*) *Element D* has radiation of minimum wavelength *155 nm.*
2	We have, $E_{2-1} = \text{const.}\left(\frac{1}{1^2}-\frac{1}{2^2}\right) = \text{const.}\ \frac{3}{4}$ and $E_{\infty\to2} = \text{const.}\left(\frac{2}{2^2}-\frac{1}{\infty^2}\right) = \text{const.}\ \frac{1}{4}$ ∴ Ratio = **3 : 1**
3	Kinetic energy, K_e = + T.E. = 13.6 eV Potential energy, P_e = 2 T.E. = 2 (-13.6) = – 27.2 eV

Level 3 Numericals

Q.NO	DETAILED SOLUTIONS
1	(*i*) (*a*) $E_n \propto \frac{1}{n^2}$ (*b*) Energy of first excited state $= \frac{E_1}{(2)^2} = \frac{-13.6}{4} = \mathbf{-3.4\ eV}$ (*c*) Energy required = $[(-3.4) - (-13.6)]$ = **10.2 eV** (*ii*) (*a*) Kinetic energy of first excited state = – Energy of first excited state = – (–3.4) = **3.4 eV** (*b*) Orbital radius of first excited state $r_n \propto n^2 \quad \because n = 2$ or $r_n = r_0 n^2 = (0.53) \times (2)^2 = \mathbf{2.12\ Å}$

2	 (*a*) 275 nm corresponds to ultraviolet radiation. Using $E = \frac{hC}{\lambda}$ and $h = 4.14 \times 10^{-15}$ eV $\lambda = \frac{hC}{E} = \frac{4.14 \times 10^{-15} eV \times 3 \times 10^{8}}{E}$ $= \frac{12.42 \times 10^{-7}}{E}$ $\lambda_A = \frac{hC}{E} = \frac{12.42 \times 10^{-7}}{2}$ $= 6.21 \times 10^{-7}$ m = **621 nm** $\lambda_B = \frac{12.42 \times 10^{-7}}{4.5} = \frac{24.84 \times 10^{-7}}{9}$ $= 2.76 \times 10^{-7}$ = **276 nm** ∴ λ_B corresponds to 276 nm. $\lambda_C = \frac{12.42 \times 10^{-7}}{2.5} = \frac{24.84 \times 10^{-7}}{5}$ $= 4.968 \times 10^{-7}$ m = **496.8 nm** $\lambda_D = \frac{12.42 \times 10^{-7}}{8} = 1.552 \times 10^{-7}$ = **155.2 nm** (*b*) The maximum wavelength of the emission corresponds to the radiation due to the transition A.
3	 We know kinetic energy of electron $= \frac{KZe^2}{2r}$ and P.E. of electron= $-\frac{KZe^2}{r}$ P.E. $= -2(\text{Kinetic energy})$ In this calculation, electric potential and hence potential energy is zero at infinity. Total energy $= P.E. + K.E. = -2KE + KE = -KE$ (a) In the first excited state, total energy $= -3.4eV \therefore KE = -(-3.4eV) = +3.4eV$ (b) P.E. of electron in this first excited state $= -2KE = -2 \times 3.4 = -6.8eV$ (c) If zero of potential energy is changed, K.E. does not change and continues to be +3.4 eV. However, the P.E. and total energy of the state would change with the choice of zero of potential energy.

Case based study question

Q.NO	DETAILED SOLUTIONS	VALUE POINT /STEP MARKING
1	d) -13.6 Ev	1
2	b) L = nh/2π	1
3	b) 364.6 nm	1
4	c) n = 1	1

Competency Based Question

Q.NO	DETAILED SOLUTIONS	VALUE POINT /STEP MARKING
1	Each element has a unique set of energy levels, and thus emits or absorbs light at specific wavelengths characteristic of those energy levels. By analyzing the spectral lines observed in the light from distant stars, astronomers can determine which elements are present. This is done using spectroscopy, where the light from a star is split into its component wavelengths, and the resulting spectrum is compared to known spectra of elements. The presence of specific spectral lines indicates the presence of particular elements in the star.	4
2	The Balmer series is significant because it lies in the visible region of the electromagnetic spectrum, making it easily observable with optical telescopes. This series corresponds to electron transitions from higher energy levels ($n \geq 3$) to the $n = 2$ level in hydrogen. The distinct lines of the Balmer series serve as a key tool in identifying the presence of hydrogen in astronomical objects. By observing these lines in the spectra of stars and other celestial bodies, astronomers can determine the hydrogen	4

	content and infer other properties such as temperature, density, and chemical composition of these objects. The Balmer series also provides insights into the redshift or blueshift of spectral lines, helping in the study of the motion and distance of galaxies.	

CCT BASED QUESTION

Q.NO	DETAILED SOLUTIONS	VALUE POINT /STEP MARKING
1	1.Relation to Hydrogen Emission Spectrum:** - The wavelength of 656 nm corresponds to the red line in the Balmer series. - The wavelength of 122 nm falls in the ultraviolet region and corresponds to the Lyman series	2
	2. - Bohr's model explains these transitions by quantized electron orbits. Electrons can only occupy certain allowed orbits with fixed energies. - The transition from (n = 3) to (n = 2) involves the electron moving to a lower energy level, emitting a photon in the visible spectrum. - The transition from (n = 2) to (n = 1) involves the electron moving to the ground state, emitting a photon in the ultraviolet spectrum. - Bohr's model was able to successfully explain the discrete spectral lines of hydrogen, validating the idea of quantized energy levels in atoms. However, it could not explain more complex atoms or account for fine structure and other quantum mechanical phenomena.	2

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UNIT VIII ATOMS AND NUCLEI

CH 13 NUCLEI

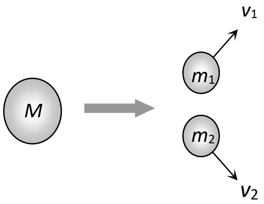
LEVEL 1

1	B
2	C
3	C
4	D
5	D
6	D
7	D
8	B
9	B
10	C
11	B
12	D
13	D
14	A
15	A
16	C
17	B
18	A
19	C
20	D

LEVEL 2

1	B
2	D
3	C
4	A
5	C
6	C
7	C
8	D
9	B
10	A

LEVEL 3

1	(a) By conservation of momentum $m_1v_1 = m_2v_2$ $\Rightarrow \frac{v_1}{v_2} = \frac{8}{1} = \frac{m_2}{m_1}$ …… (i)  Also from $r \propto A^{1/3} \Rightarrow \frac{r_1}{r_2} = \left(\frac{A_1}{A_2}\right)^{1/3} = \left(\frac{1}{8}\right)^{1/3} = \frac{1}{2}$
2	(b) $\Delta m = 1 - 0.993 = 0.007\ gm$ $\therefore E = \Delta mc^2 = 0.007 \times 10^{-3} \times (3 \times 10^8)^2 = 63 \times 10^{10}\ J$
3	(c) $O^{17} \rightarrow O^{16} + {}_0n^1$ $\therefore$ Energy required = Binding of O^{17} – binding energy of O^{16} = $17 \times 7.75 - 16 \times 7.97 = 4.23\ MeV$
4	C
5	C
6	B
7	A
8	C
9	*C* Radius of each nucleus $R = R_0(A)^{1/3} = 1.2(64)^{1/3} = 4.8\ fm$ Distance between two nuclei (r) = $2R$ So potential energy $U = \frac{k \cdot q^2}{r} = \frac{9 \times 10^9 \times (1.6 \times 10^{-19} \times 29)^2}{2 \times 4.8 \times 10^{-15} \times 1.6 \times 10^{-19}} = 126.15\ MeV.$
10	

LEVEL 1

Short Answer Type (2 MARKS)

1) Define Atomic Number and Mass Number.

ANS- The total number of protons present in the nucleus of an atom is called the atomic number. The total number of protons and neutrons present in the nucleus of an atom is called the mass number

2) What is nuclear fission, and provide an example of a fission reaction?

ANS-The process in nuclear physics in which the nucleus of an atom splits into two daughter nuclei. When Uranium-235 atom is bombarded with a neutron, it splits into two lighter nuclei Barium and Krypton.

3) Explain the concept of binding energy per nucleon and its significance.

ANS- Binding energy per nucleon basically tells the stability of a nucleus. Larger the binding energy per nucleon, the greater the work that must be done to remove the nucleon from the nucleus, the more stable the nucleus.

4) What are isotopes? Give two examples.

ANS-An element that have different atomic masses but same atomic number. For example, there are three isotopes of carbon: Carbon-12, Carbon-13, and Carbon-14.

5)Two nuclei have mass number in the ratio 1 : 3. What is the ratio of their nuclear densities?

ANS - As the nuclear density is independent of the mass number, so the ratio of nuclear densities of the two given nuclei is ***1 : 1***

LEVEL 2

Short Answer Type (2 MARKS)

1)Calculate the energy equivalent of 1amu in MeV.

ANS-

1 u =1.66×10^{-27} kg

1 eV =1.602×10^{-9} J

The energy equivalent to 1 u of mass = mc^2

=$(1.66\times10^{-27})(2.998\times10^{8})$

=1.492×10−10 J

=$(1.492\times10^{-10}/1.602\times10^{-19})$ eV

=931×10^{6} eV

=931 meV

2) Distinguish between nuclear fission and nuclear fusion.

ANS

Fission Reaction	**Fusion Reaction**
A fission reaction is splitting up of a large atom or a molecule into two or more smaller ones.	Fusion is the process of combination of two or more lighter atoms or molecules into larger ones.
Fission reaction doesn't occur normally in nature.	Fusion reaction process occurs in the stars, like in the sun, etc.
This reaction produces highly radioactive substances.	Few number of radioactive particles are developed by the process of a fusion reaction.
Neutrons must be slowed down by moderation to increase their capture probability in fission reactors.	This process requires high-temperature, high-density environment.

3) State the necessary condition for nuclear fission.

ANS- Extremely high energy is required to bring two or more protons close enough that nuclear forces overcome their electrostatic repulsion

4)Define atomic mass unit.

ANS-An atomic mass unit is defined as accurately 1/12 the mass of a carbon-12 atom

5) Write the number of proton and neutron in ${}_{56}Ba^{144}$.

ANS- PROTON-56 NEUTRON-88

6)Two nuclei have mass number 3:9 what is their nuclear redii ratio.

ANS -The relation between mass number A and nuclei radius R is given by $R=R_0A^{1/3}$

So, $R_1 / R_2=A_1{}^{1/3}/A_2{}^{1/3}=(3/9)^{1/3}=(1/3)^{1/3}$

LEVEL -3

Short Answer Type (2 MARKS)

1) When ${}_{92}U^{235}$ undergoes fission. 0.1% of its original mass is changed into energy. How much energy is released if 1 *kg* of ${}_{92}U^{235}$ undergoes fission

ANS-By using $E=\Delta m\cdot c^2 \Rightarrow E=\left(\frac{0.1}{100}\times 1\right)(3\times 10^8)^2=9\times 10^{13}\,J$

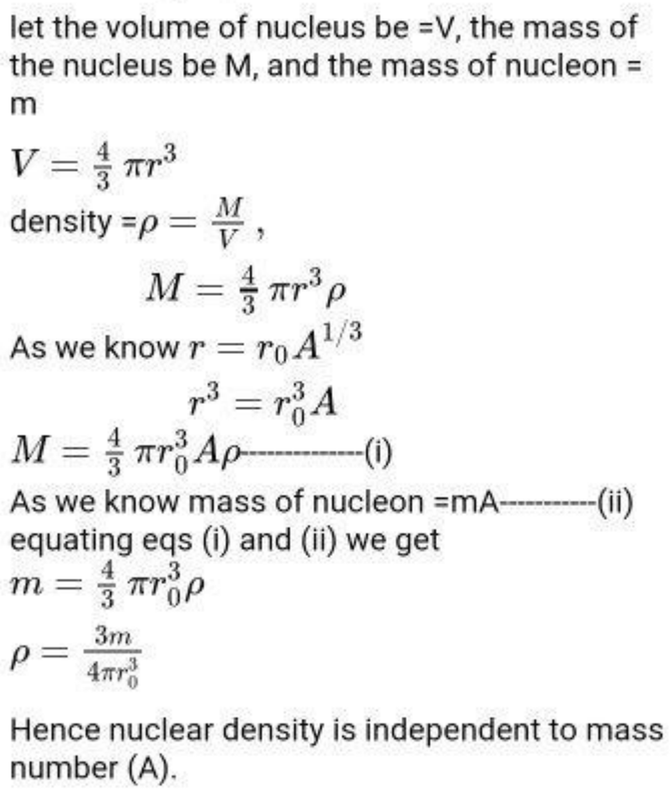
Level 1

Short Answer Type 3 MARKS

1) Write any three characteristic properties of nuclear force.

ANS-(i) It does not depend on the electric charge. (ii) It is the strongest force in nature. (iii) It is a very short range force.

2) Show that the nuclear density is independent of mass number.



let the volume of nucleus be =V, the mass of the nucleus be M, and the mass of nucleon = m

$V = \frac{4}{3}\pi r^3$

density $= \rho = \frac{M}{V}$,

$$M = \frac{4}{3}\pi r^3 \rho$$

As we know $r = r_0 A^{1/3}$

$$r^3 = r_0^3 A$$

$M = \frac{4}{3}\pi r_0^3 A\rho$-------------(i)

As we know mass of nucleon =mA-----------(ii)

equating eqs (i) and (ii) we get

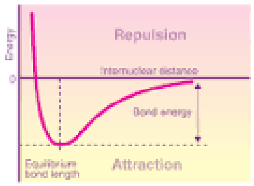
$m = \frac{4}{3}\pi r_0^3 \rho$

$\rho = \frac{3m}{4\pi r_0^3}$

Hence nuclear density is independent to mass number (A).

3) Plot a graph showing the variation of potential energy of a pair of nucleons as a function of their separation. Write its two characteristic properties.

ANS- POTENTIAL ENERGY CURVE



1) shows how the potential energy of two molecules and the force between them changes with their separation.

2) The force at any point is found from taking the gradient of he potential energy curve, in other words F = -dV/dr, where V is the potential energy.

LEVEL 2

Short answer type (3 MARKS)

1) The sun radiates energy in all directions. The average radiations received on the earth surface from the sun is $1.4\ kilowatt/m^2$ .The average earth- sun distance is $1.5 \times 10^{11} metres$. Find the mass lost by the sun per day.

(1 *day* = 86400 *seconds*)

Energy radiated $= 1.4\ kW/m^2$

$$= 1.4\ kJ/\sec\ m^2 = \frac{1.4\ kJ}{\frac{1}{86400} day\ m^2} = \frac{1.4 \times 86400}{day\ m^2}$$

Total energy radiated/day

$$= \frac{4\pi \times (1.5 \times 10^{11})^2 \times 1.4 \times 86400}{1} \frac{kJ}{day} = E$$

$$\therefore E = mc^2 \Rightarrow m = \frac{E}{c^2}$$

Level 3

Short answer type (3 MARKS)

1) Calculate the energy released in MeV in the following nuclear reaction:

$$^{238}_{92}U \longrightarrow {}^{234}_{90}Th + {}^{4}_{2}He + Q$$

[Mass of $^{238}_{92}U = 238.05079$ u,

Mass of $^{234}_{90}Th = 234.043630$ u,

Mass of $^{4}_{2}He = 4.002600$ u, $1u = 931.5$ MeV/c²]

Answer:

Nuclear reaction

$$^{238}_{92}U \rightarrow {}^{234}_{90}Th + {}^{4}_{2}He + Q$$

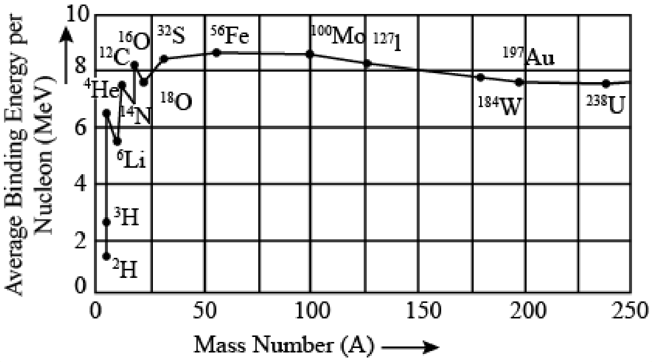
$$\begin{aligned} \text{Energy released, } Q &= \Delta mC^2 \\ &= (M_U - M_{Th} - M_{He})C^2 \\ &= 0.00456 \times 931.5 \text{ MeV} \\ &= \mathbf{4.25\ MeV} \end{aligned}$$

LEVEL -1

Long answer type(5 MARKS)

1) Using the curve for the binding energy per nucleon as a function of mass number A, state clearly how the release of energy in the processes of nuclear fission and nuclear fusion can be explained.

ANS-



we move from the heavy nuclei region to the middle region of the plot, there is a gain in the overall binding energy and hence release of energy. This indicates that energy can be released when a heavy nucleus (A ≈ 240) breaks into two roughly equal fragments. This process is called nuclear fission.

Similarly, when we move from lighter nuclei to heavier nuclei, we again find that there is a gain in the overall binding energy and hence release of energy. This indicates that energy can be released when two or more lighter nuclei fuse together to form a heavy nucleus. This process is called nuclear fusion

2) Calculate binding energy per nucleon of 209Bi83 nucleus. Given that mass of 209Bi83 = 208.980388u, mass of proton = 1.007825u, mass of neutron = 1.0086 MeV665 u and 1 u = 931 MeV.

ANS- 83Bi209 has 83 protons and 126 neutrons (209−83=126)

∴ Mass of 83Bi209=83×1.007825+126×1.008665

=210.741265 a.m.u.

Mass defect of 83Bi209=210.741265−208.980388

=1.760877 a.m.u.

∴ Binding energy of 83Bi209

=1.760877×931 M eV

So B.E./nucleons =1.760877×931209

=7.844 M eV/A.

Level -2

Long answer type(5 MARKS)

1)a) Suppose, we think of fission of a 56Fe26 nucleus into two equal fragments, 28Al13. Is the fission energetically possible? mass of 56Fe26 = 55.934939u, mass of 28Al13 = 55.934939u

b) How is the size of a nucleus experimentally determined? Write the relation between the radius and mass number of the nucleus is independent of its mass number ans -It is given that The atomic mass of Fe = 55.93494.0 u

The atomic mass of Al = 27.98191 u

The Q value of this nuclear reaction is given as ∆M = [(Mass of Fe) –(2 mass of Al)] c2

= [55.93494 − 2 × 27.9819119] c2

∆M = (−0.02888 c2) u

But we know that 1 u = 931.5 Mev/c2 ∆E = −0.02888 × 931.5 = −26.902 MeV

The Q value of the fission is negative. Therefore, fission is not possible. For a possible fission reaction, the Q value should be positive

LEVEL -3

Long answer type(5 MARKS)

1) A star initially has 10^{40} deuterons. It produces energy via the processes

$${}_1H^2 + {}_1H^2 \rightarrow {}_1H^3 + p$$

$${}_1H^2 + {}_1H^3 \rightarrow {}_2He^4 + n$$

The masses of the nuclei are as follows :

$$M(H^2) = 2.014\ amu;\ M(p) = 1.007\ amu;$$

$$M(n) = 1.008\ amu;\ M(He^4) = 4.001\ amu$$

If the average power radiated by the star is $10^{16} W$,the deuteron supply of the star is exhausted then find the order of time

ANS- m ass defect = $3 \times 2.014 - 4.001 - 1.007 - 1.008$

$$= 0.026\ amu = 0.026 \times 931 \times 10^6 \times 1.6 \times 10^{-19}\ J$$

$$= 3.82 \times 10^{-12}\ J$$

Power of star =$10^{16}W$

Number of deuterons used $= \frac{10^{16}}{\Delta M} = 0.26 \times 10^{28}$

Deuteron supply exhausts in $\frac{10^{40}}{0.26 \times 10^{28}} = 10^{12} s$.

NUMERICALS

Level 1

1) Solution

Binding energy of $_3Li^7$ = 7 x 5.60 = 39.2 MeV

Binding energy of $_2He^4$ = 4 x 7.06 = 28.24 MeV

Energy of proton = Energy of [2($_2He^4$)- $_3Li^7$]

= 2 × 28.24 – 39.2 = 17.28 MeV

Level 2

1) Solution

As $(v_1/v_2) = 8/27$; $(r_1/r_2) = ?$

Using law of conservation of linear momentum, $0 = m_1v_1 - m_2v_2$

(As both are moving in opposite directions)

Or $m_1/m_2 = v_2/v_1 = 27/8$

$\rho(4/3)\pi\ r_1{}^3 / \rho(4/3)\pi r_2{}^3 = 27/8$

Therefore, $(r_1/r_2) = 3/2$

Level 3

1) Kinetic energy of molecules of a gas at a temperature T is 3/2 kT

$\therefore$ To initiate the reaction $\frac{3}{2}kT = 7.7 \times 10^{-14}\ J \Rightarrow T = 3.7 \times 10^9\ K$.

CASE BASE STUDY

1	2	3	4
A	C	B	A

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UNIT IX ELECTRONIC DEVICES

Chapter–14: Semiconductor Electronics: Materials, Devices and Simple Circuits

MCQ LEVEL-1

Q	Correct option	EXPLANATION
1	C	All of the electrons in insulators are tied up in interatomic bonds. To remove these electrons from their bonds it takes a large amount of energy, several electron volts,
2	C	At absolute zero there are no electrons in conduction band
3	B	Doping is the process of adding some impurity atoms in a pure or (intrinsic) semiconductor so as to increase the conductivity of a semiconductor. Doping can be done in two ways:
4	B	Gallium is trivalent impurity provides holes for pure semiconductor
5	A	The pure semiconductor has less number of thermally generated charge carriers. But when it is doped with pentavalent or trivalent impurity atoms, the number of charge carriers i.e. electrons and holes increases. So conductivity increases.
6	A	σ metal >σ semiconductor > σ insulator
7	B	Aluminum: It is from III-A group gives acceptor impurity in terms of holes
8	A	Both (i)and(ii) : Doping inverses number of charge carriers and temperature gives energy to charge carriers to jum to conduction band
9	C	Movement of electrons to the p-type side exposes positive ion cores in the n-type side while movement of holes to the n-type side exposes negative ion cores in the p-type side,
10	B	photodiode is a semiconductor device that converts light into current. The current is generated when photons are absorbed in the photodiode. For this purpose, a p-n junction is reverse biased. When small amount of light falls on it, due to sensitivity to voltage changes in reverse bias, there is sudden change in current detected.
11	A	In an extrinsic semiconductor, there are both types of charge carriers i.e. holes and electrons. Therefore, total current in the semiconductor is equal to the sum of current due to holes and electrons.
12	B	The barrier potential develops a barrier field in the direction n to p side. This barrier field immediately pushes the electron towards the n- side and holes towards the p- side, and then a current is set up by the barrier field from n to p side. This current is known as drift current.

13	A	When a p-n junction is reverse biased, then the majority charge carriers cannot cross the junction. So, no forward current flows. But in reverse direction, a feeble current flows which is known as reverse saturation current.
14	D	The resistivity of semiconductor decreases with increase in temperature as more electrons jump into conduction band increasing its conductivity.
15	A	The resistivity of semiconductor decreases with increase in temperature as more electrons jump into conduction band increasing its conductivity
16	A	We know that $n_en_h=n_{2i}$ this formula is biased on law of mass action. In p-type semi conductor $n_h>n_i$ So $n_e<n_i$

MCQ LEVEL-2

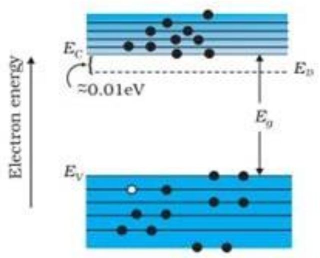
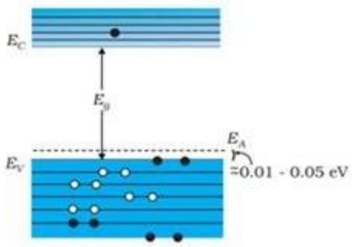
Q	Correct option	EXPLAINATION
1	B	P side is at lower potential as compared to N-side
2	A	the holes have a higher effective mass since they are close to each other. and the electrons have a low effective mass due to the loosely held. and electrons which are loosely held have a low effective mass. This is the reason why the mobility of a hole is less compared to an electron.
3	B	FOR Germanium band gap is 0.7 ev
4	C	The required voltage for semiconductor is low
5	C	When a forward bias is applied to a p-n junction, it lowers the value of potential barrier. In the case of a forward bias, the potential barrier opposes the applied voltage. Hence, the potential barrier across the junction gets reduced.
6	C	A full-wave rectifier rectifies both the half cycles of the AC input i.e., it conducts twice during a cycle. Output frequency is double to that of input frequency.
7	A	Electrons move from lower energy level to higher energy level in the conduction band due to external electric field.
8	A	for a given semiconductor the electron mobility (μn) is always higher than the hole mobility (μp). μn>μp (for a given semiconductor) we know that, the conductivity of a given n-type semiconductor
9	D	Both are incorrect In n-type semiconductors, the doped atom has 1 more valence Electron than silicon.

MCQ LEVEL-3

Q	Correct option	EXPLAINATION
1	C	no of holes in valance band represent P-type semiconductor
2	A	temperature provides energy to electrons in valance Band to cross the forbidden band
3	A	depletion region decrease with increase in forward biased voltage
4	B	rectifier is device used to convert AC into DC
5	C	P-side is at negative potential and N-side is at positive potential
6	A	Since the diode is reverse biased, so it will not conduct. So, potential difference across A and B will be same across the circuit is 6 V.
7	A	electron is lighter than hole
8	A	Study of junction diode characteristics shows that the junction diode offers a low resistance path, when forward biased and high resistance path when reverse biased. This feature of the junction diode enables it to be used as a rectifier.
9	A	A photodiode is a semiconductor device that converts light into current. The current is generated when photons are absorbed in the photodiode. For this purpose, a p-n junction is reverse biased. When small amount of light falls on it, due to sensitivity to voltage changes in reverse bias, there is sudden change in current detected.

2 MARK QUESTIONS

LEVEL-1

1	The four valence electrons of carbon are present in second orbit while that of silicon in third orbit. So, energy required to extricate an electron from silicon is much smaller than carbon.
2	1) n-TYPE SEMICONDUCTOR  2) p-TYPE SEMICONDUCTOR 

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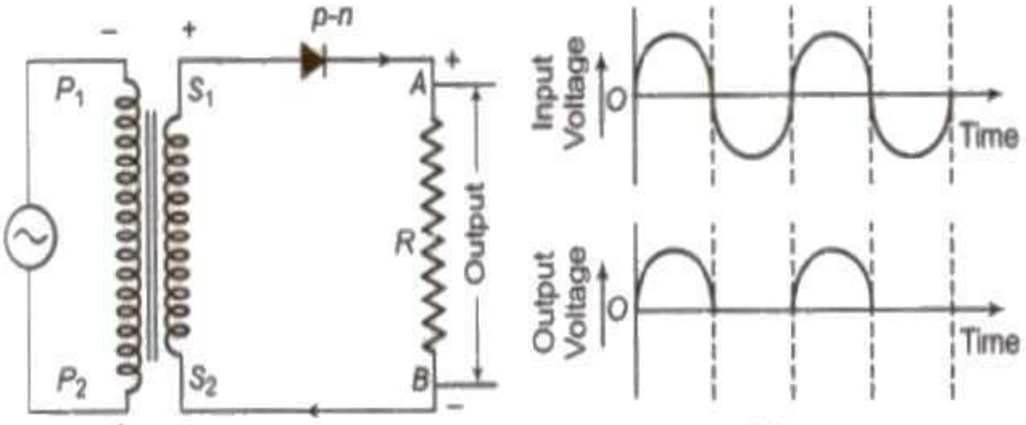


(a) (b)

AC voltage to be rectified is connected to the primary coil of a step-down transformer. Secondary coil is connected to the diode through resistor load resistance, across which output is obtained.

Working: During positive half cycle of the input AC, the p-n junction is forward biased. Thus, the resistance in p-n junction becomes low and current flows. Hence, we get output in the load. During negative half cycle of the input AC, the p-n junction is reverse biased. Thus, resistance of p-n junction is high and current does not flow. Hence, no output in the load. So, for complete cycle of AC, current flows through the load resistance in the same direction.

4

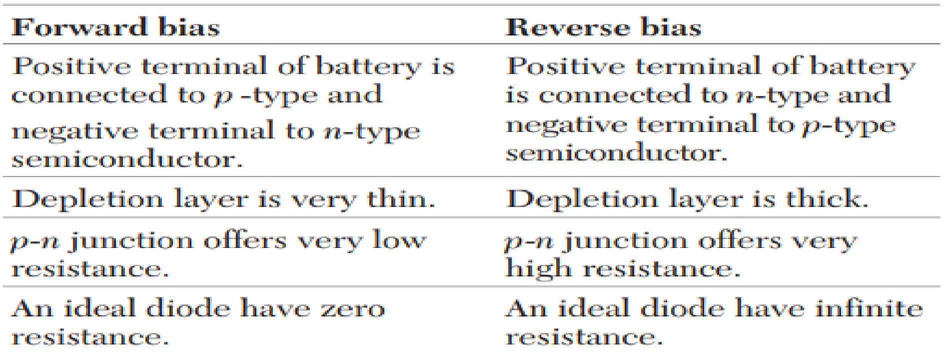
S.NO	INRINSIC SEMICONDUCTOR	EXTRINSIC SEMICONDUCTOR
1	Pure form of semiconductor.	Impure form of semiconductor.
2	Conductivity is low	Conductivity is higher than intrinsicsemiconductor.
3	The no of holes is equal to no offree electrons	In n-type, the no. of electrons is greater than that of the holes and inp-type, the no. holes is greater than that of the electrons.
4	The conduction depends on temperature.	The conduction depends on the concentration of doped impurity andtemperature.

5

P-type semiconductor is formed by doping it with trivalent impurities. These impurities or dopant takes the atoms in the crystal and its three electrons take part in chemical bonding with three electrons of intrinsic semiconductor or pure semiconductor, whereas the last bond are left free. Since, as whole atom is electrically neutral, so p-type semiconductor is also neutral.

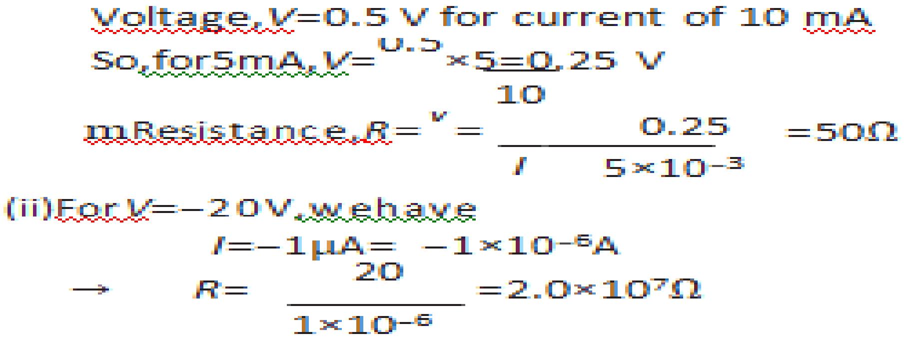
2 MARK QUESTIONS
LEVEL-2

1



Forward bias	Reverse bias
Positive terminal of battery is connected to p -type and negative terminal to n-type semiconductor.	Positive terminal of battery is connected to n-type and negative terminal to p-type semiconductor.
Depletion layer is very thin.	Depletion layer is thick.
p-n junction offers very low resistance.	p-n junction offers very high resistance.
An ideal diode have zero resistance.	An ideal diode have infinite resistance.

2



Voltage, $V=0.5$ V for current of 10 mA

So, for 5mA, $V=\frac{0.5}{10}\times 5=0.25$ V

mResistance, $R=\frac{V}{I}=\frac{0.25}{5\times10^{-3}}=50\Omega$

(ii) For $V=-20$ V, we have

$I=-1\,\mu\text{A}=-1\times10^{-6}\text{A}$

$\rightarrow R=\frac{20}{1\times10^{-6}}=2.0\times10^{7}\Omega$

3 The technique of adding impurities to a pure semiconductor is known as doping and the added impurity is called doping agent. Doping in the semiconductor improves conductivity of semiconductor because no of charge carriers are improved due to doping.

4 The difference in resistivity between conductors and semiconductors is due to their difference in charge carrier density. The resistivity of semiconductors decreases with temperature because the number of charge carriers increases rapidly with increase in temperature, making the fractional changes i.e. the temperature coefficient negative.

5 Yes it is better to use Full wave rectifier than half wave rectifier because of following advantages

The rectifier efficiency of a full-wave rectifier is high

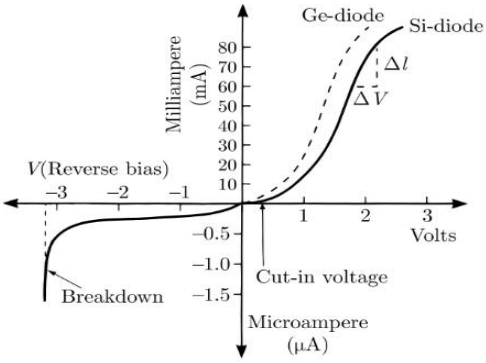
The power loss is very low

Number of ripples generated are less

3 MARK QUESTIONS
LEVEL-1

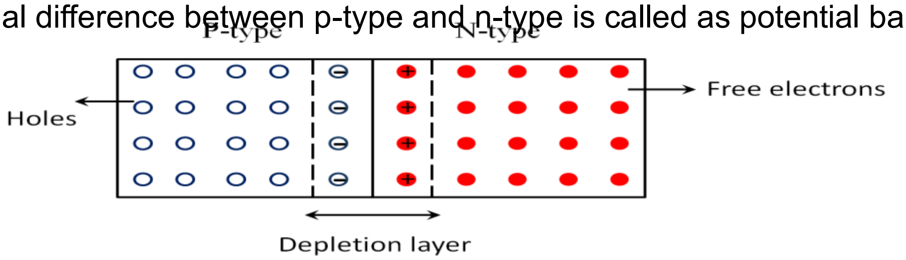
1

Ans :



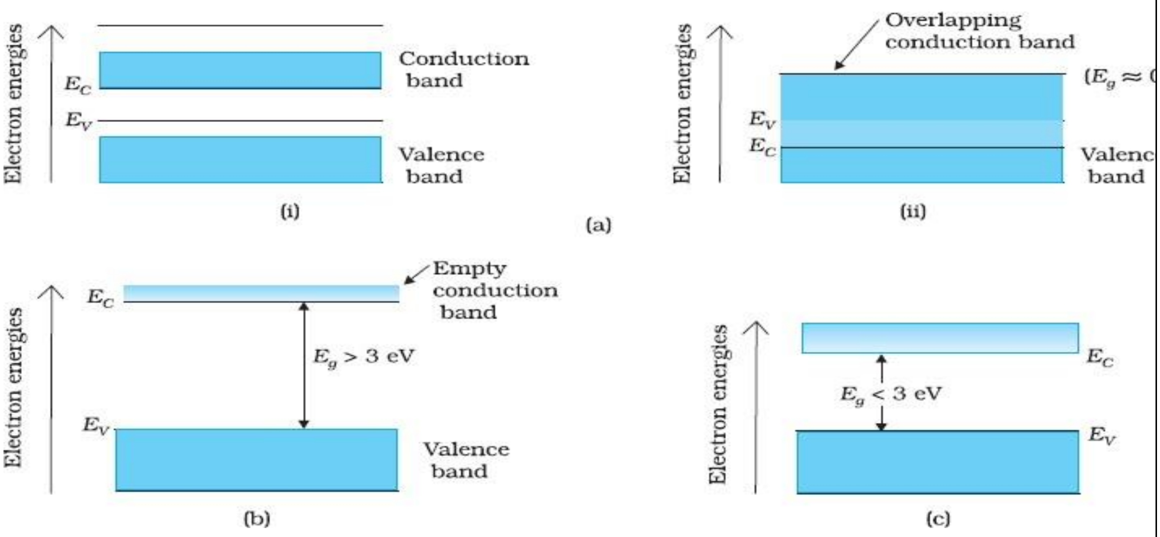
2

When the half side of the intrinsic semiconductor is doped with trivalent (p-type) impurity and remaining half side is doped with pentavalalnt (n-type) impurity then the boundary between p-type and n-type semiconductor is called as p-n junction. The concentration of electron in n-type and hole in p-type semiconductors is very high. The natural tendency of the charge carriers to flow from high concentration area to low concentration area this process is called as diffusion. The diffusion of electron from n-type to p type leaves +ve charge at n-type semiconductor near the junction and diffusion of holes from p type to n-type leaves negative charge in p-type semiconductor near the junction, these opposite charges will neutralize each other due to recombination. This develops the potential difference between p-type and n-type is called as potential barrier



and the region across the junction where diffusion of electrons and holes take place is depletion layer as shown in figure

3 MARK QUESTIONS
LEVEL-2

1	(i) D1 diode is forward biased, hence current will flow in B1 bulb and D2 is reverse biased, so there will be no current in B2 . Hence, B1 will glow
2	(on the basis of diagram any two distinguish features) 
3	(i)Two important processes that occur during the formation of p-n junction are diffusion and drift. (ii) explanation of formation of depletion region and potential barrier.
4	***Sol.*** The energy band gap is given by, $E_g = h\nu = \frac{hc}{\lambda}$ where, h = Planck's constant, c = speed of light and λ = wavelength at which solid absorbs energy. On putting the values of h, c and λ, we get $E_g = \frac{(6.626 \times 10^{-34}\ \text{J-s})(3 \times 10^{8}\ \text{m/s})}{(10000 \times 10^{-10}\ \text{m})}$ $= 1.98 \times 10^{-19}$ J $= \frac{1.98 \times 10^{-19}}{1.6 \times 10^{-19}}$ eV $= 1.24$ eV

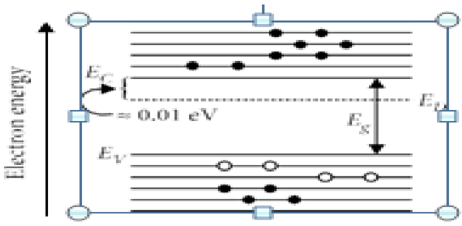
3 MARK QUESTIONS
LEVEL-3

1 i)

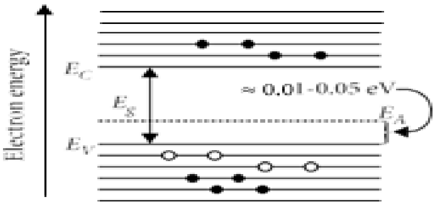
Sr. No	P-type semiconductor	n-type semiconductor
1.	Obtained by adding trivalent impurity to pure semiconductors	Obtained by adding pentavalalnt impurity to pure semiconductors
2.	Trivalent impurity accepts the electron	pentavalalnt impurity donates the electron
3.	Electrical conductivity is due to holes	Electrical conductivity due to electrons.

4.	The majority charge carriers are holes	The majority charge carriers are electrons
5.	The impurity atoms (holes)are present just above the top of valance band	The impurity atoms (electrons)are present just below the bottom of band
6.	Ex. GeAl	Ex. GeAS, GaAsP

ii)At absolute zero temperature (0 K), conduction band of semiconductor is completely empty. Hence the semiconductor behaves as an insulator. At room temperature, some valence electrons acquire enough thermal energy and jump to the conduction band where they are free to conduct electricity. Thus the semiconductor acquires a small conductivity at room temperature.

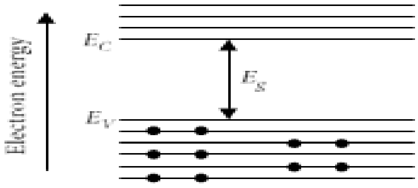


(a)
Energy band diagram of
n-type semiconductor
at $T > 0$ K



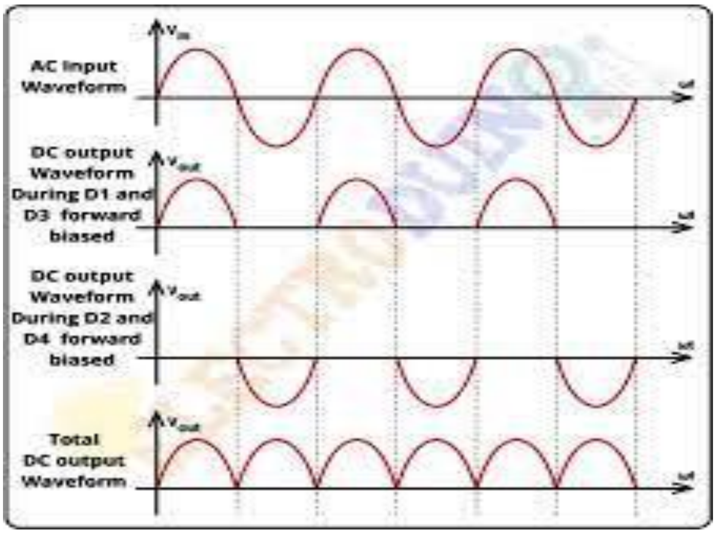
(b)
Energy band diagram of
p-type semiconductor
at $T > 0$ K

(b)

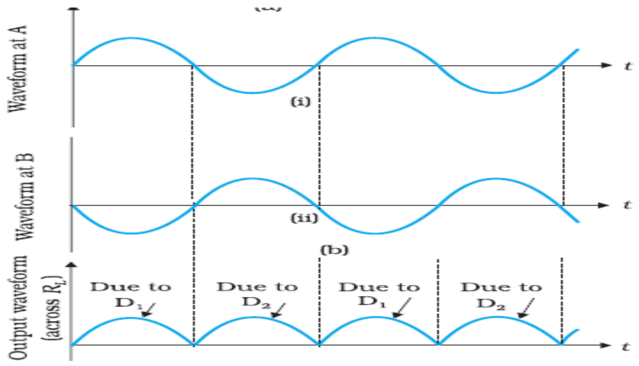


Energy band diagram of
semiconductor
at $T = 0$ K

2



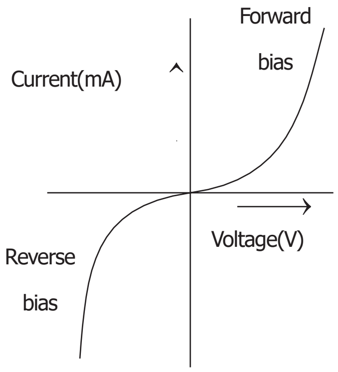
3



During the first half of the cycle, if A is at higher potential with respect to centre-tap and B is at lower potential, the diode D1 being forward biased conducts and the diodeD2 being reverse biased does not conduct. The current flows through the load in the sense H to L .During the second half of the cycle, conditions get reversed and only diodeD2 conducts Again, the current flows through the load in the sense H to L. Thus, in the output we get a unidirectional current.

5 MARK QUESTIONS
LEVEL-1

1 V-I characteristics of p-n junction diode is as shown below



I) under the reverse bias condition, the holes of p-side are attracted towards the negative terminal of the battery and the electrons of the n-side are attracted towards the positive terminal of the battery. This increases the depletion layer and the induced potential barrier is also increased. However, the minority charge carriers are drifted across a junction producing a small current. At any temperature, a number of minority charge carriers is constant, so there is the small current at any applied potential.

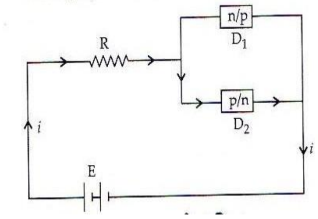
This is the reason for the current under reverse bias known as reverse saturation current, which is almost independent of applied potential. At the

	certain level of voltage, avalanche breakdown takes place which results in a sudden flow of large current. (ii) At the critical voltage, (the voltage at which breakdown takes place), the holes in then-side and conduction electrons in the p-side are accelerated due to the reverse bias voltage. These minority carriers acquire sufficient kinetic energy from the electric field and collide with a valence electron. Thus, the bond is finally broken and the valence electrons move into the conduction band resulting in enormous flow of electrons and thus formation of electron-hole pairs. Thus, there is a sudden increase in the current at the critical voltage. I) under the reverse bias condition, the holes of p-side are attracted towards the negative terminal of the battery and the electrons of the n-side are attracted towards the positive terminal of the battery. This increases the depletion layer and the induced potential barrier is also increased. However, the minority charge carriers are drifted across a junction producing a small current. At any temperature, a number of minority charge carriers is constant, so there is the small current at any applied potential. This is the reason for the current under reverse bias known as reverse saturation current, which is almost independent of applied potential. At the certain level of voltage, avalanche breakdown takes place which results in a sudden flow of large current. (ii) At the critical voltage, (the voltage at which breakdown takes place), the holes in then-side and conduction electrons in the p-side are accelerated due to the reverse bias voltage. These minority carriers acquire sufficient kinetic energy from the electric field and collide with a valence electron. Thus, the bond is finally broken and the valence electrons move into the conduction band resulting in enormous flow of electrons and thus formation of electron-hole pairs. Thus, there is a sudden increase in the current at the critical voltage.

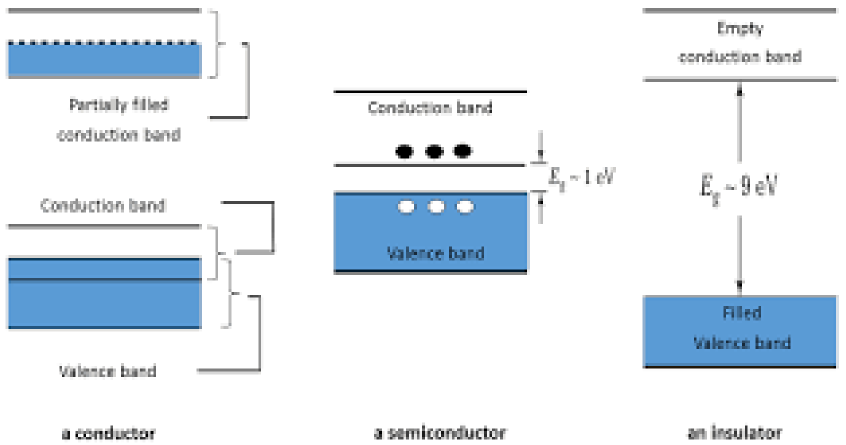
5 MARK QUESTIONS

LEVEL-2

1	i) When a trivalent impurity like aluminum, indium, boron, gallium etc. is doped with a pure germanium (or silicon), then the conductivity of the silicon increases due to deficiency of electrons i.e., and such a crystal is said to be p-type semiconductor while the impurity atoms are called acceptors. ii) This means if energy 1.1 eV is given to an electron in the valence band, it will jump to the conduction band. iii) An ideal diode is one which behaves as a perfect conductor when forward biased Under this situation, the forward resistance of diode is assumed to be zero and potential barrier is neglected.

	iv) Diode D1 is reverse biased so on current flows through it due to majority carriers. And diode D2 is forward biased. So a current flows through D2 and the resistance R as shown in the figure. 

5 MARK QUESTIONS
LEVEL-3

1	Adding a particular impurity in pure semiconductor is called as doping. The main goal of doping is to change the electrical properties of the semiconductor by adding impurities, which change the concentration of charge carriers or other electrons (n-type) or holes (p-type). This affects the conductivity of the material and hence its electrical properties. For N-type semiconductor, pentavalent impurities like Arsenic, Antimony and for P-type semiconductor, trivalent impurities like gallium, indium etc, are used. 

CASE BASED STUDY
LEVEL-1

Q.1			
i)	ii)	iii)	iv)
Definition of extrinsic semiconductor	1:1	to increase conduction	holes

Q.2			
i)	ii)	iii)	iv)
C	B	A	B

CASE BASED STUDY
LEVEL-2

Q.1				
i)	ii)	iii)	iv)	v)
D	D	A	D	A

CASE BASED STUDY
LEVEL-3

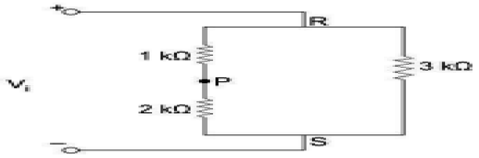
Q.1			
i)	ii)	iii)	iv)
B	C	A	C

Q.2			
i)	ii)	iii)	iv)
C	C	D	C

COMPETENCY BASED QUESTIONS
MCQ

Q.	OPTION	EXPLAINATION
1	D	both diodes are connected with same polarity
2	D	From figure, ideal diode D1 is reversed biased whereas ideal diode D2 is forward biased. Thus D1 acts as an open switch while D2 as a closed switch as shown in the equivalent circuit.
3	D	Eg=1.1 for Si
4	B	A p-n junction is a device in which current flows through the junction when it is forward biased whereas when reverse biased, it conducts a very small current (almost zero) untill the output voltage equals the breakdown voltage. Moreover, current through the intrinsic as well as extrinsic semiconductor does not depend on the polarity of the battery.

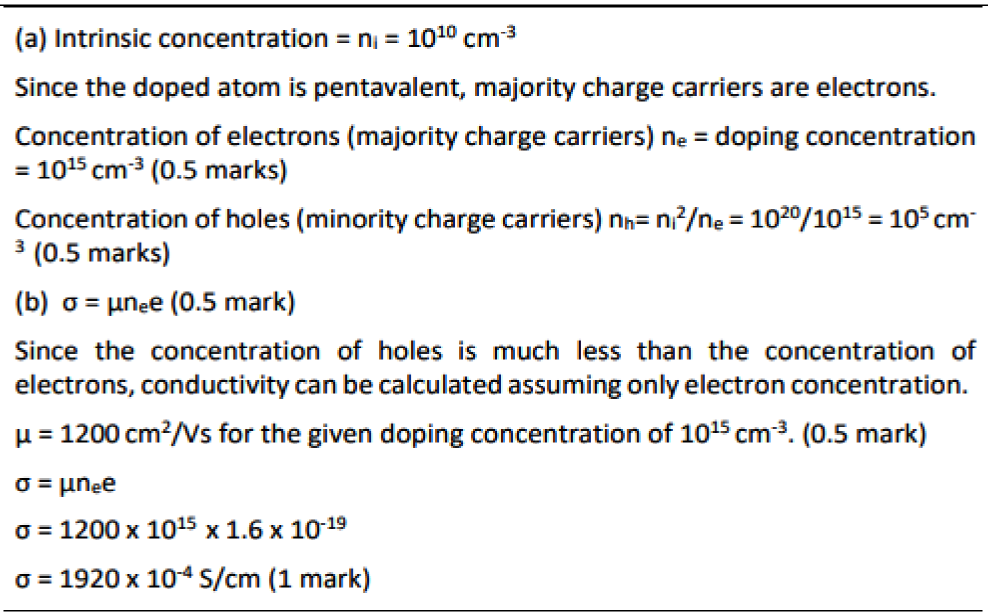
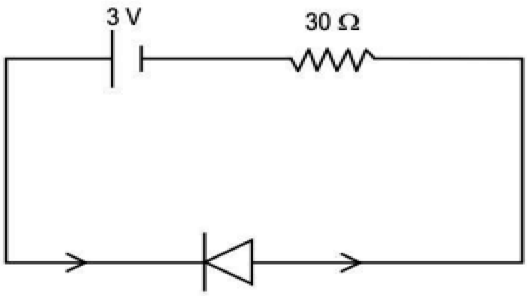
COMPETENCY BASED QUESTIONS
2 MARK QUESTIONS

Q.	EXPLAINATION
1	 [1 mark for the correct layout of the resistors in the equivalent network] (c) Voltage across R and S = 12 V $V_1 + V_2 = 12$ (here V_1 is p.d across 1 k-ohm and V_2 is p.d across 2 k-ohm) Also $V_1/V_2 = R_1/R_2 = 1/2$ $2V_1 = V_2$ Substituting and solving, $V_1 = 4$ V $V_2 = 8$ V These will be output voltages across 1kΩ and 2kΩ respectively. The output voltage across 3 kW, will be same as that of V_i that is, 12 V. [0.5 mark for each correct voltage value across the resistors]
2	The concentration of the holes never becomes equal in the p-region and n-region and hence diffusion current does not become zero. (1 mark) This is because as the holes diffuse into the n-region they recombine with the electrons. Hence, the decrease in the concentration of holes from the p-region to the n-region is maintained by the recombination of holes and electrons. (1 mark)
3	In circuit I : $V_{D1} = 0.3$ V $V_{D2} = 0.7$ V So $V_o = 10 - V_{D1} - V_{D2} = 10 - 0.3 – 0.7 = 9$ V $I_D = V_o/R = 9/(4 \times 10^{-3}) = 2.25$ mA [0.5 mark for correct value of V_o and I_D] In circuit II: D_1 is forward biased whereas D_2 is reverse biased, this means that the overall circuit is open circuit. So $I_D = 0$ $V_o = 0$ [0.5 mark for correct value of V_o and I_D]

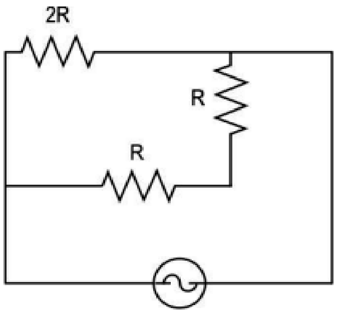
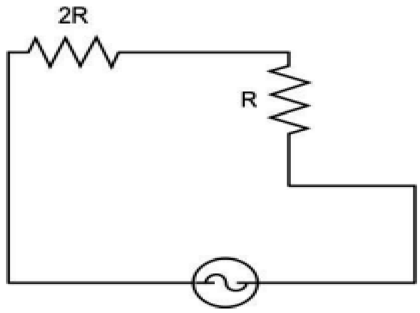
4	a. Electric field = V/d V = E. d = 16 x 10^5 x 500 x 10^{-9} volt = 0.8 volt [0.5 mark for the correct value] b. i. if the junction is unbiased : KE required = eV = 0.8 eV ii. if the junction is forward biased at 0.5 V KE required = (0.8 – 0.5) eV = 0.3 eV iii. if the junction is reverse biased at 0.5 V KE required = (0.8 + 0.5) eV = 1.3 eV [0.5 mark for the correct value of each of the KE values]
5	a. Given is the drift current = 20 μA and forward biasing current of 4 x 20 = 80 μA In case of unbiased condition, Diffusion current = drift current = 20μA [0.5 mark for the correct value] b. In case of reverse biased, Diffusion current = 0 [0.5 mark for the correct value] c. In case of forward biased, Diffusion current – drift current = Biasing current Diffusion current – 20 = 80

COMPETENCY BASED QUESTIONS
3 MARK QUESTIONS

Q.	EXPLAINATION

1	 (a) Intrinsic concentration = $n_i = 10^{10}$ cm^{-3} Since the doped atom is pentavalent, majority charge carriers are electrons. Concentration of electrons (majority charge carriers) n_e = doping concentration = 10^{15} cm^{-3} (0.5 marks) Concentration of holes (minority charge carriers) $n_h = n_i^2/n_e = 10^{20}/10^{15} = 10^5$ cm^{-3} (0.5 marks) (b) $\sigma = \mu n_e e$ (0.5 mark) Since the concentration of holes is much less than the concentration of electrons, conductivity can be calculated assuming only electron concentration. $\mu = 1200$ cm^2/Vs for the given doping concentration of 10^{15} cm^{-3}. (0.5 mark) $\sigma = \mu n_e e$ $\sigma = 1200 \times 10^{15} \times 1.6 \times 10^{-19}$ $\sigma = 1920 \times 10^{-4}$ S/cm (1 mark)
2	a. i. Forward biasing ii. Decreases. Holes are pushed through the pn junction in the direction opposite to the electric field across the barrier potential of the depletion region. [0.5 mark for each point] b. i. Reverse biasing ii. Increases. Holes are swept through the pn junction in the direction same as the electric field across the barrier potential of the depletion region. [0.5 mark for each point
3	(a) The potential drop across the 30 Ω resistor = 30 × 10 × 10-6 V = 300 ×10-6 = 0.0003 V (0.5 marks) Potential drop across the diode = 3 - 0.0003 = 2.9997 V (0.5 marks) (b) The diode is reverse-biased in the circuit (1 mark)  1 mark for circuit diagram.)

COMPETANCY BASED QUESTIONS
5 MARK QUESTIONS

Q.	EXPLANATION
1	During the positive half cycle, diodes D1 and D3 conduct while D2 does not. The circuit can be redrawn as follows:  Total resistance = R (1 mark) Power delivered = 1/2(V2 /R) (0.5 marks) During the negative half cycle, diodes D1 and D3 do not conduct while D2 conducts. The circuit can be redrawn as follows:  Total resistance = 3R (1 mark) Power delivered = $1/2(V^2/3R)$ (0.5 marks) Total power delivered = $1/2(V^2/R) + 1/2(V^2/3R) = 2V^2/3R$ (1 mark)
2	(a) C = 40 μF; V = 2500 V E = CV2/2 E = 40 x 10-6 x 2500 x 2500 / 2 E = 125 J (1.5 mark) (b) 60% of E = 125 x 60/100 = 75 J (0.5 marks) Power = E/t Power = 75/(3 x 10-3) = 25000 W (1.5 marks) (c) Power = 25000 W V = 2500 V I = P/V = 25000/2500 = 10 A (1 mark) (Please note this is a really high current which can be fatal in general. But in the case of a defibrillator, the current passes for an extremely small interval of time and can help save a person.) (d) R = V/I = 2500/10 = 250 ohm (1 mark)

COMPETENCY BASED QUESTIONS
5 MARK QUESTIONS
CCT/SOURCE BASED QUESTIONS

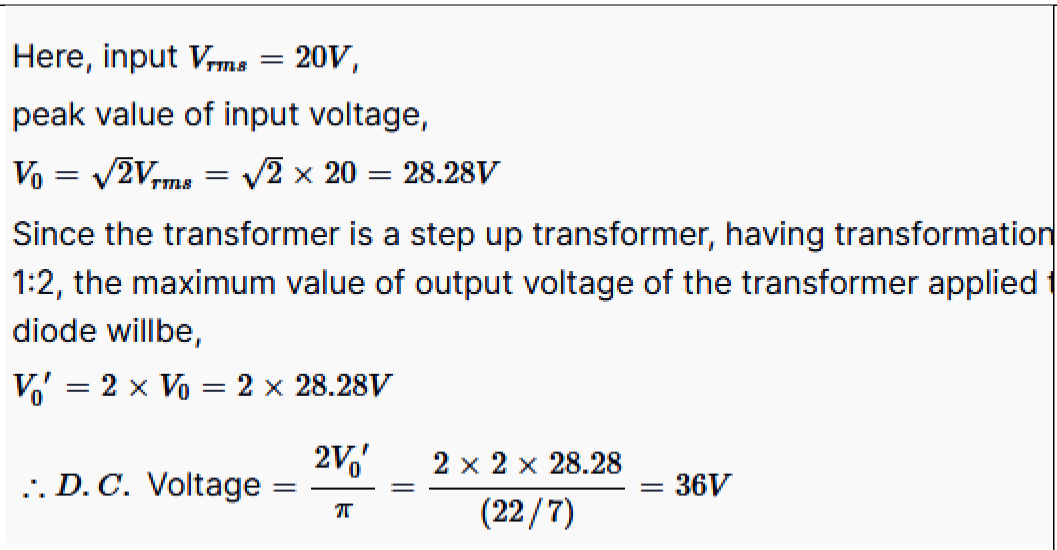
Q.	EXPLANATION
i	Only region I the ratio of majority charge carrier to the donor atoms is denoted in graph
ii	Ne<Nh No of holes are more from the graph
iii	Region –III Because of increase in temperature
Iv	With increase in temperature of extrinsic semiconductor, minority charge carriers increase because of bond breakage and minority charge carriers may become almost equal with majority charge carriers. Thus, extrinsic semiconductor behaves almost as an intrinsic semiconductor with increase in temperature.

SELF ASSESSMENT PAPER

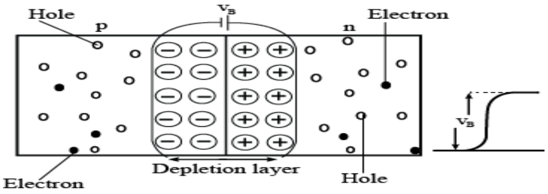
TOTAL MARKS 25

SECTION A

Q		MARKS
01	(b) Hole is a vacancy created when an electron leaves a covalent bond. The concept of hole describes the lack of an electron at a position where one could exist in an atom or atomic lattice. If an electron is excited into a giher state, it leaves a hole in its old state.	01
02	B) $E = \frac{V}{d} = \frac{0.3}{1 \times 10^{-6}} = 3 \times 10^{5} Vm^{-1}$	01
03	The breakdown in a reverse biased p-n junction diode is more likely to occur due to (a) large velocity of the minority charge carriers if the doping concentration is small When it comes to he breakdown in a reverse biased PN junction diode, it will probably happen only because of the accumulation of the higher charge at the biased region and large velocity of the minority charge if the doping concentration is small. This is the main cause the breakdown	01
04	(c) 36 V	01

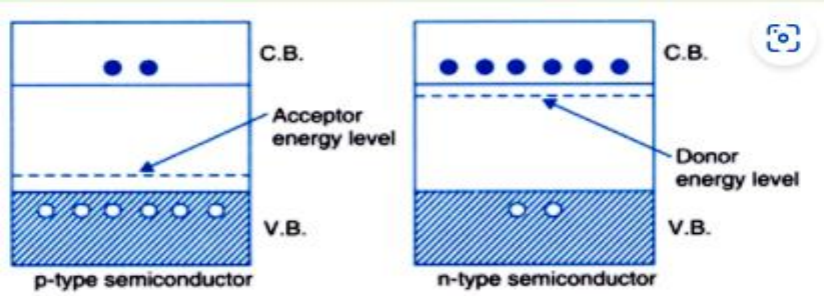
	 Here, input $V_{rms} = 20V$, peak value of input voltage, $V_0 = \sqrt{2}V_{rms} = \sqrt{2} \times 20 = 28.28V$ Since the transformer is a step up transformer, having transformation 1:2, the maximum value of output voltage of the transformer applied t diode willbe, $V_0{}' = 2 \times V_0 = 2 \times 28.28V$ $\therefore D.C.\text{ Voltage} = \frac{2V_0{}'}{\pi} = \frac{2 \times 2 \times 28.28}{(22/7)} = 36V$	
05	A In half wave rectifier, the one diode is biased only when ac is in positive half of its cycle. For negative half of the ac cycle the diode is reversed biased and there is no output corresponding to that. Since for only one-half cycle we get a voltage output, because of which it is called half wave Rectifier	01
06	B A reverse bias on a p-n junction opposes the movement of the majority charge carriers thus stopping the diffusion current. It makes the free electrons and holes to drift cross the junction. Therefore a small current in mA flows even when the p-n junction is reverse biased. The drift current is due to the thermal excitations of the electrons and holes.	01

SECTION B

07	(i) During the formation of p-n junction, the holes diffuse from p-type semiconductor to the n-type, and electrons diffuse from n-type to p-type. This is because of the concentration gradient across p-side and n-side.  When a hole diffuses from p to n type, it leaves an unmovable negative charge. Similarly, when an electron diffuses from n to p type, it leaves an unmovable positive charge. When the diffusion of holes and electrons takes place continuously across the junction, a layer of unmovable positive and negative charges are developed on either side of the junction. This layer is called the depletion layer or the depletion region and the potential difference across the region is called the barrier potential.	01 MARK DIAGRAM 1 MARKS 1 MARK

08	When a pure semiconductor is mixed with a small amount of impurities i.e., elements having number of valence electrons slightly different, the concentration of charge carries changes. The process of addition of impurity is called doping. The size of the dopant atom should be equivalent to the size of **Si** or **Ge**. So that the symmetry of pure **Si** or **Ge** does not disturb, and dopants can contribute the charge carrier on forming covalent bonds with **Si** or Germaniumatoms. As the silicon and germanium belongs to **XIV** group so similar size of atom will be **XIII** and **XV** group of modern periodic table.	02

SECTION C

<table>
<tr><td>08</td><td>t is given that the input frequency is 50 Hz.
In the case of half wave rectifier, the output frequency will be equal to input frequency.
The output frequency for half wave rectifier is,
f hw =50 Hz
In the case of full wave rectifier, the output frequency will be twice the input frequency.
So, the output frequency for full wave rectifier is,
f fw =2×50 =100 Hz
Thus, the output frequency in the case of half wave rectifier is 50 Hz and the output frequency in the case of full wave rectifier is 100 Hz.</td><td>01
01
01</td></tr>
<tr><td>09</td><td>
<table>
<tr><th>Sr. No</th><th>P-type semiconductor</th><th>n-type semiconductor</th></tr>
<tr><td>1.</td><td>Obtained by adding trivalent impurity to pure semiconductors</td><td>Obtained by adding pentavalalnt impurity to pure semiconductors</td></tr>
<tr><td>2.</td><td>Trivalent impurity accepts the electron</td><td>pentavalalnt impurity donates the electron</td></tr>
<tr><td>3.</td><td>Electrical conductivity is due to holes</td><td>Electrical conductivity due to electrons.</td></tr>
<tr><td>4.</td><td>The majority charge carriers are holes</td><td>The majority charge carriers are electrons</td></tr>
<tr><td>5.</td><td>The impurity atoms (holes)are present just above the top of valance band</td><td>The impurity atoms (electrons)are present just below the bottom of band</td></tr>
<tr><td>6.</td><td>Ex. GeAl</td><td>Ex. GeAS, GaAsP</td></tr>
</table>


</td><td>02
01</td></tr>
</table>

CASE BASED

i)	c) $n_h >> n_e$ no of holes are more than no of electrons
ii)	c) insulators At T=0K no electrons in conduction band
iii)	c) insulators above 3 eV it is not possible for the electron to jump to forbidden band
iv)	d) Aluminum Al is from III-A group gives holes in valance band

SECTION E

11	(i) No, the key to semiconductors is maintaining pristine interfaces. Physically putting together n and p type semiconductors would produce an uncontrolled interface. Remember that the p an n type doping are measured in parts per million. There are one million silicon atoms for every dopant atom. Physical welding of semiconductors would produce interface defects in the parts per thousand. That's one thousand times larger than the dopants! Growing an n type semiconductor on a p type semiconductor in ultra high vacuum is the only way to "put together" p and n type materials. The other method is to introduce the dopant into a pure semiconductor with diffusion or ion implantation. (ii) n forward bias the thickness of depletion region decreases and barrier potential is lowered and consequently forward bias resistance is low as compared to the reverse bias condition in which depletion region broadened and barrier potential is raised.	03 02

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SAMPLE PAPER-I

DETAILED SOLUTIONS

SAMPLE PAPER-1 ANSWER KEY		
Q.No.	Answer	Marks
1	A	1
2	A	1
3	B	1
4	D	1
5	C	1
6	D	1
7	A	1
8	B	1
9	C	1
10	B	1
11	B	1
12	A	1
13	C	1
14	C	1
15	A	1
16	B	1
17	Repulsive ball 2,3,4,5 charged with explanation.	2
18	Rg=40 ohm	2
19	A= 60 degree	2
20	4800 Angstorm unit	2
21	Si & Ge CdS, GaAs Polyrrole	1/2 1/2 1
22	Vd- Va= 18 X 10 8 V W= 1.8X 10 8 J	1 1

	Time =2.08 days	1
23	Diamagnetic 0<= ur<1 Paramagnetic 0<ur< e+1 Ii)diagram Iii)diagram	1/2 1/2 1 1
24	I)Derivation Ii)Opposite Lorentz force III)Power required to rotate rod	1 1 1
25	I)v>v0 Ii)v -v0 III) value of λ_0	1 1 1
26	Equation of B.E. And derivation of Value for given mass =104.66 MeV	1 2
27	Two statement Explanation of Non stability	2 1
28	Half Wave Rectifier Full Wave Rectifier Circuit diagram	1/2 1/2 2
29	i) A ii) C iii) C iv) D OR V) B	1 1 1 1 1
30	I) B II) B III) Real ,inverted and Magnified. OR focal lengths of both objects and eye - piece are decreased.	1 1 2
31	Equations by using Laws Correct solutions	2 3

	OR I) II)	 3 2
32	Correct diagram Derivations OR Diagram Of AC generator Explanation	2 3 2 3
33	Correct diagram I) II) OR I) II)	2 1 1 2 3

****

SAMPLE PAPER-4

DETAILED SOLUTIONS

Q.NO	**SAMPLE QUESTION PAPER 2025**	**Marks Distribution**
1	c) Zero	1
2	c) Ohmic conductors	1
3	b) Decreases	1
4	a) Total internal reflection	1
5	d) Electromagnetic induction	1
6	b) By connecting a low resistance shunt in parallel to the galvanometer	1
7	c) The surface of a charged conductor is equipotential	1
8	b) Ultraviolet Rays	1
9	a) $\beta_G < \beta_Y < \beta_O$	1
10	a) 6557×10^{-10} m	1
11	b) –Q/4	1
12	b) 10^4 H	1
13	B	1
14	D	1
15	B	1
16	A	1
17	Correct diagram, correct expression.	1 1
18	Any two points of each	1+1
19	Correct diagram, correct expression.	1 1
20	Microwaves or Radio waves (b) X-rays	1 1
21	Formula and Value substitution Ans = -8j	1 1
22	Formula R1 = 82.14 Ω and R2 = 71.87 Ω T_2 = 867.5 ° C	1 1 1
23	Correct statement Correct diagram Expression	1 1 1
24	Correct statement Diagram Correct expression	1 1 1
25	Diagram Explanation Correct expression	1 1 1

26	Formula Value substitution E_{max}== 5π V	1 1 1
27	Correct graph representation Correct explanation	1+1/2 1+1/2
28	Correct diagram Correct expression	1+1/2 1+1/2
29	A d b d	1 1 1 1
30	b d c d	1 1 1 1
31	Correct circuit diagram correct expression for voltage correct relation of current with turns ratio Formula Ans I_s=4.5 A **OR** Correct circuit diagram correct expression for voltage correct relation of current with turns ratio Formula Ans E_{max} = 157 kV.	1 1 1 1 1 1 1 1
32	Diagram Explanation Correct expression Formula Ans u= -40/3 and u = -80/3 **OR** Diagram Explanation Correct expression Formula Ans d=45°	1 1 1 1 1 1 1 1
33	Diagram Explanation Correct expression Any two points of each	1 1 1 2

SAMPLE PAPER-5

DETAILED SOLUTIONS

1-C	2-A	3-A	4-A,B	5-C	6-	7-C	8-D
9-B	10-A	11-C	12-D	13-D	14-D	15-A	16-A

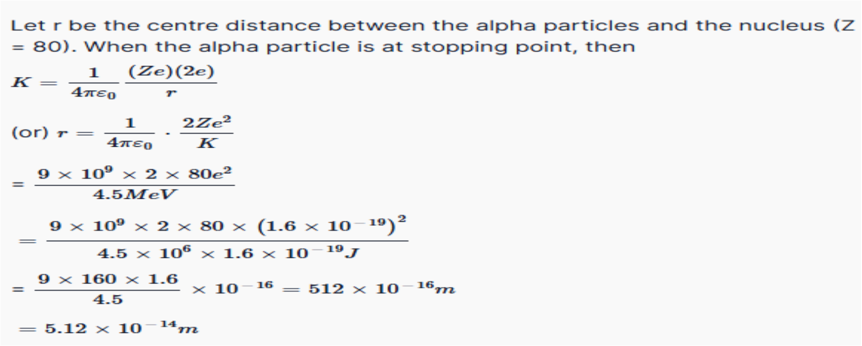
SECTION -A

SECTION -B

Q.17	Yes the net magnetic field acting on the wire carrying steady current is constant F=IdlB
Q.18	Magnetic field lines can be entirely confined within the core of a toroid but not within a straight solenoid. since no two magnetic field lines can intersect, and they are originating and ending at the same point (as it is in a ring) thus they are confined to the core of toroid.
Q.19	Infrared waves are produced by hot bodies and molecules. They are referred as heat waves because they are readily absorbed by water molecules in most materials which increases their thermal motion so they heat up the material. Use: For therapeutic purpose and long distance photography.
Q.20	A concave lens behaves as a diverging lens, when it is placed in a medium of refractive index less than the refractive index of the material of the lens and behaves as a converging lens, when it is placed in a medium of refractive index greater than the refractive index of the material of the lens. In the given case, concave lens is immersed in a medium having refractive index greater than the refractive index of the material of the lens (1.65 > 1.5). Therefore, it will behave as a converging lens.
Q.21	When the phase difference between the two vibrating sources changes rapidly with time, the two sources are incoherent and the intensities just add up. This is indeed what happens when two separate light sources illuminate a wall. OR When a tiny circular obstacle is placed in the path of light from a distant source, a bright spot is seen at the centre of the shadow of the obstacle. This is because light waves are diffracted from the edge of the circular obstacle, which interferes constructively at the centre of the shadow.

SECTION -C

Q.22



Let r be the centre distance between the alpha particles and the nucleus (Z = 80). When the alpha particle is at stopping point, then

$$K = \frac{1}{4\pi\varepsilon_0}\frac{(Ze)(2e)}{r}$$

$$\text{(or) } r = \frac{1}{4\pi\varepsilon_0}\cdot\frac{2Ze^2}{K}$$

$$= \frac{9\times10^9\times2\times80e^2}{4.5MeV}$$

$$= \frac{9\times10^9\times2\times80\times(1.6\times10^{-19})^2}{4.5\times10^6\times1.6\times10^{-19}J}$$

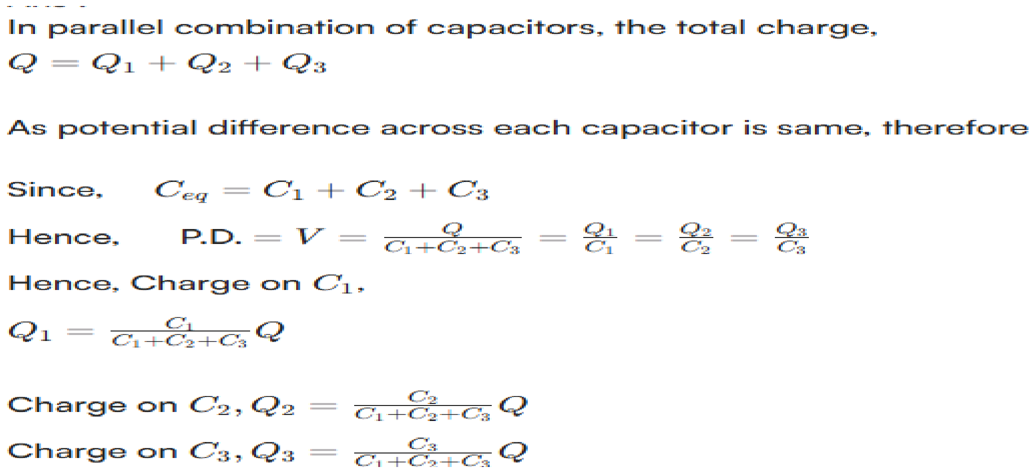
$$= \frac{9\times160\times1.6}{4.5}\times10^{-16} = 512\times10^{-16}m$$

$$= 5.12\times10^{-14}m$$

Q.23

S.NO	INRINSIC SEMICONDUCTOR	EXTRINSIC SEMICONDUCTOR
1	Pure form of semiconductor.	Impure form of semiconductor.
2	Conductivity is low	Conductivity is higher than intrinsic semiconductor.
3	The no of holes is equal to no offree electrons	In n-type, the no. of electrons is greater than that of the holes and inp-type, the no. holes is greater than that of the electrons.
4	The conduction depends ontemperature.	The conduction depends on the concentration of doped impurity and temperature.

Q.24



In parallel combination of capacitors, the total charge,

$$Q = Q_1 + Q_2 + Q_3$$

As potential difference across each capacitor is same, therefore

Since, $C_{eq} = C_1 + C_2 + C_3$

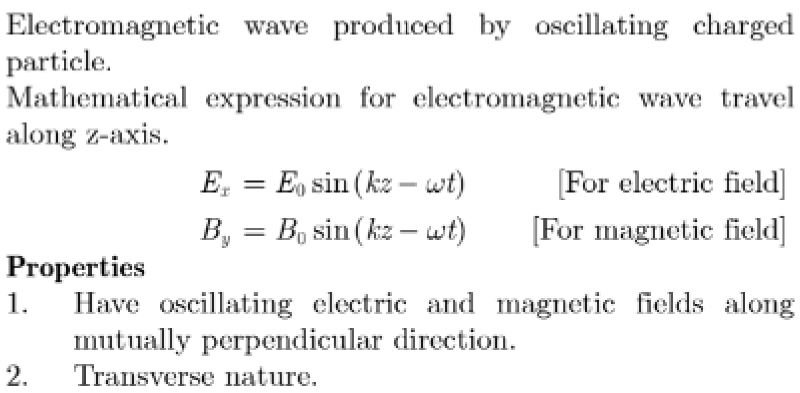
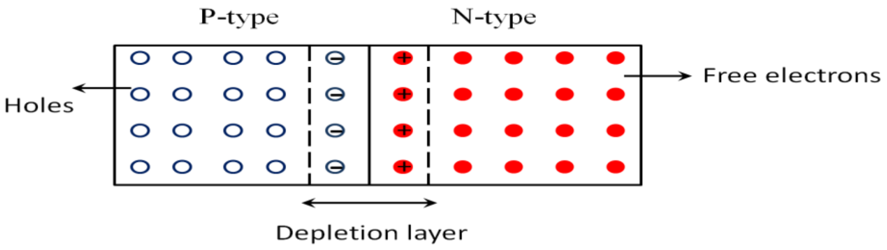
Hence, P.D. $= V = \frac{Q}{C_1+C_2+C_3} = \frac{Q_1}{C_1} = \frac{Q_2}{C_2} = \frac{Q_3}{C_3}$

Hence, Charge on C_1,

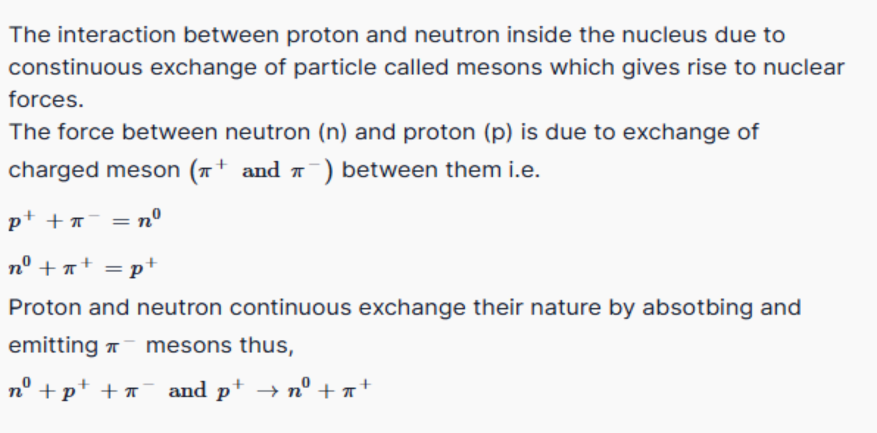
$$Q_1 = \frac{C_1}{C_1+C_2+C_3}Q$$

Charge on $C_2, Q_2 = \frac{C_2}{C_1+C_2+C_3}Q$

Charge on $C_3, Q_3 = \frac{C_3}{C_1+C_2+C_3}Q$

Q.25	 Electromagnetic wave produced by oscillating charged particle. Mathematical expression for electromagnetic wave travel along z-axis. $E_x = E_0 \sin(kz - \omega t)$ [For electric field] $B_y = B_0 \sin(kz - \omega t)$ [For magnetic field] **Properties** 1. Have oscillating electric and magnetic fields along mutually perpendicular direction. 2. Transverse nature.
Q.26	The twinkling of stars is due to atmospheric refraction of star-light. The atmosphere is made of several layers and the refractive indices which keep on changing continuously due to this path of light rays from the star keep on changing their path continuously. As a consequence the number of rays entering, the pupil of the eye goes on changing with time and the stars appear twinkling.
Q.27	P-N JUNCTION. The device obtained by bringing a p-type semiconductor crystal into close contact with n-type semiconductor crystal is called a p-n junction. It conducts in one direction only. It is also called a junction diode Depletion layer. It is a thin layer formed between the p and n-sections and devoid of holes and electrons. Its width is about 10-8 m. A potential difference of about 0.7 V is produced across the junction, which gives rise to a very high electric field (= 10^6 V/ m). Potential Barrier: The difference in potential between p and n regions across the junction makes it difficult for the holes and electrons to move across the junction. This acts as a barrier and hence called „potential barrier‟.Potential barrier for Si is nearly 0.7 V and for Ge is 0.3 V. The potential barrier opposes the motion of the majority carriers. 

Q.28



The interaction between proton and neutron inside the nucleus due to constinuous exchange of particle called mesons which gives rise to nuclear forces.

The force between neutron (n) and proton (p) is due to exchange of charged meson $(\pi^+ \text{ and } \pi^-)$ between them i.e.

$p^+ + \pi^- = n^0$

$n^0 + \pi^+ = p^+$

Proton and neutron continuous exchange their nature by absotbing and emitting π^- mesons thus,

$n^0 + p^+ + \pi^- \text{ and } p^+ \rightarrow n^0 + \pi^+$

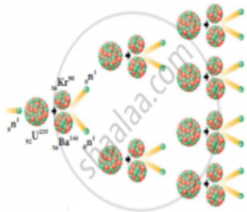
OR

- **Controlled chain reaction**

1. In the controlled chain reaction, the number of neutrons released is maintained to be one. This is achieved by absorbing the extra neutrons with a neutron absorber leaving only one neutron to produce further fission.
2. Thus, the reaction is sustained in a controlled manner. The energy released due to a controlled chain reaction can be utilized for constructive purposes.
3. The controlled chain reaction is used in a nuclear reactor to produce energy in a sustained and controlled manner.

- **Uncontrolled chain reaction:**

1. In the uncontrolled chain reaction, the number of neutrons multiplies indefinitely and causes fission in a large amount of the fissile material.
2. This results in the release of a huge amount of energy within a fraction of a second.
3. This kind of chain reaction is used in the atom bomb to produce an explosion.



Uncontrolled chain reaction

SECTION -D

Q.29				
i)	ii)	iii)	iv)	v)
C	B	A	d	B

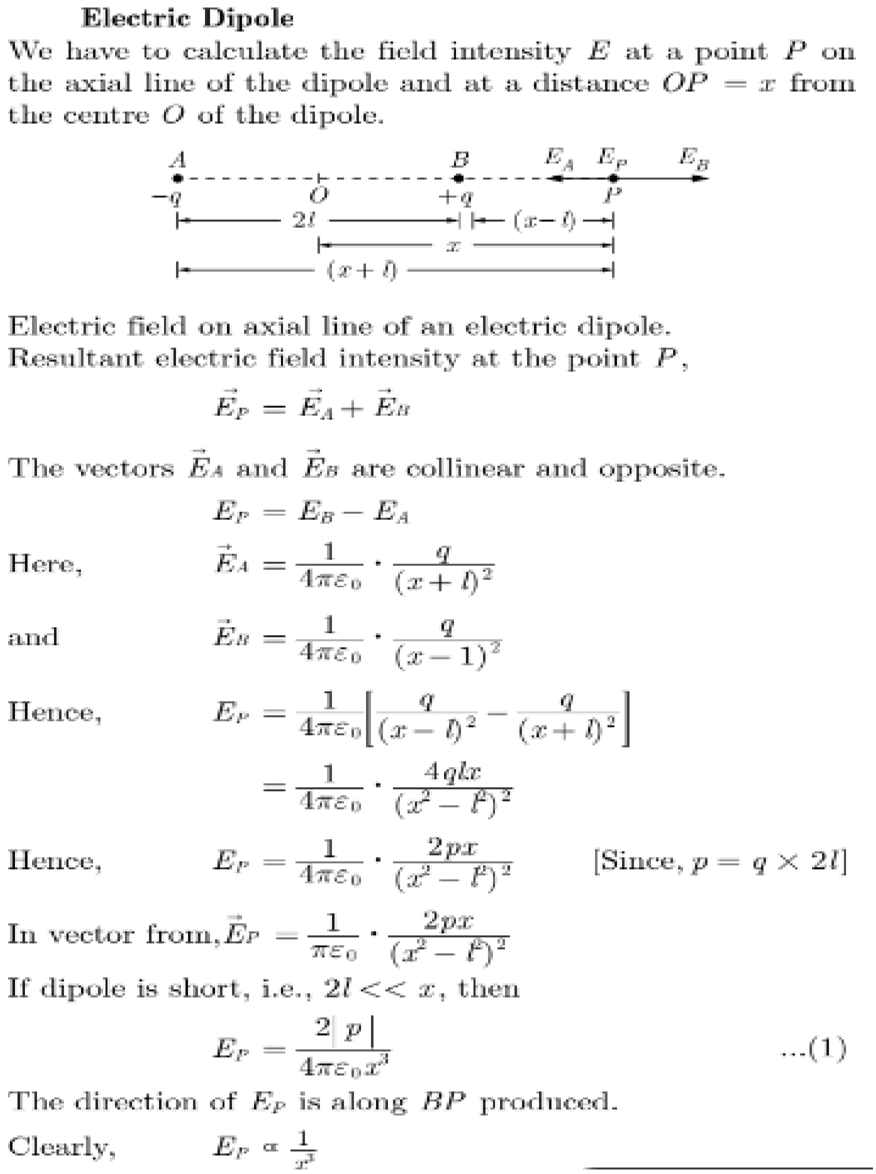
Q.30			
i)	ii)	iii)	iv)
Definition of extrinsic semiconductor	1:1	to increase conduction	Holes

SECTION -E

Q.31

1. Electric field intensity is the strengthof an electric field at any point. It is equal to the electric force per unit charge experienced by a test charge placed at that point. The unit of measurement is volts per meter or newtons per coulomb.

2.



Electric Dipole

We have to calculate the field intensity E at a point P on the axial line of the dipole and at a distance $OP = x$ from the centre O of the dipole.

Electric field on axial line of an electric dipole.
Resultant electric field intensity at the point P,

$$\vec{E}_P = \vec{E}_A + \vec{E}_B$$

The vectors $\vec{E}_A$ and $\vec{E}_B$ are collinear and opposite.

$$E_P = E_B - E_A$$

Here, $$\vec{E}_A = \frac{1}{4\pi\varepsilon_0} \cdot \frac{q}{(x+l)^2}$$

and $$\vec{E}_B = \frac{1}{4\pi\varepsilon_0} \cdot \frac{q}{(x-1)^2}$$

Hence, $$E_P = \frac{1}{4\pi\varepsilon_0}\left[\frac{q}{(x-l)^2} - \frac{q}{(x+l)^2}\right]$$

$$= \frac{1}{4\pi\varepsilon_0} \cdot \frac{4qlx}{(x^2-l^2)^2}$$

Hence, $$E_P = \frac{1}{4\pi\varepsilon_0} \cdot \frac{2px}{(x^2-l^2)^2} \qquad [\text{Since, } p = q \times 2l]$$

In vector from, $\vec{E}_P = \frac{1}{\pi\varepsilon_0} \cdot \frac{2px}{(x^2-l^2)^2}$

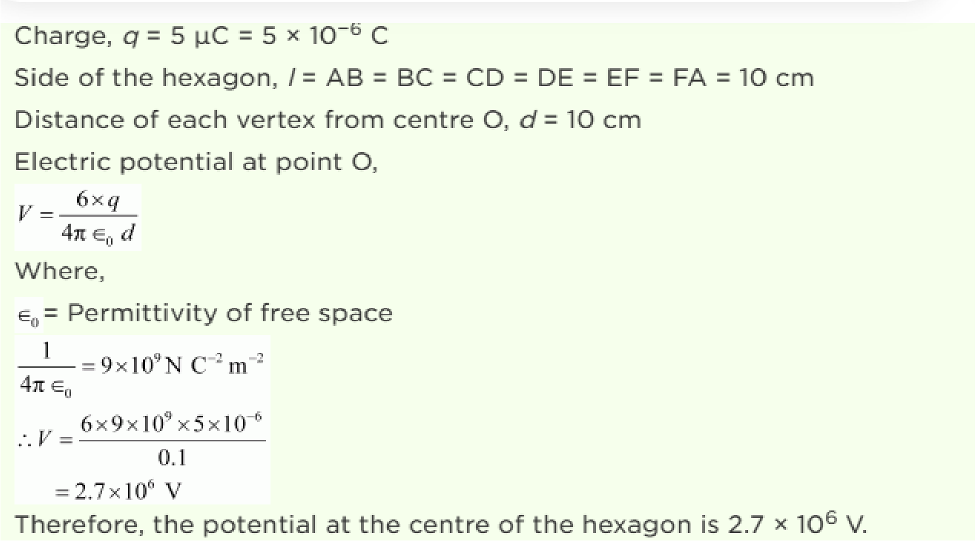
If dipole is short, i.e., $2l << x$, then

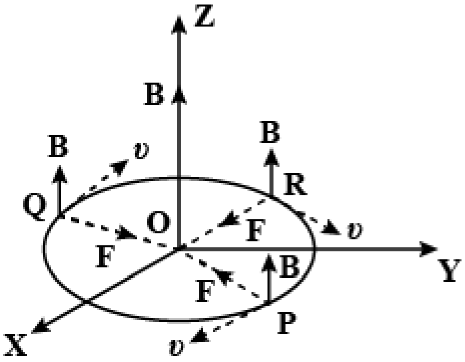
$$E_P = \frac{2|p|}{4\pi\varepsilon_0 x^3} \qquad \ldots(1)$$

The direction of E_P is along BP produced.

Clearly, $E_P \propto \frac{1}{x^3}$

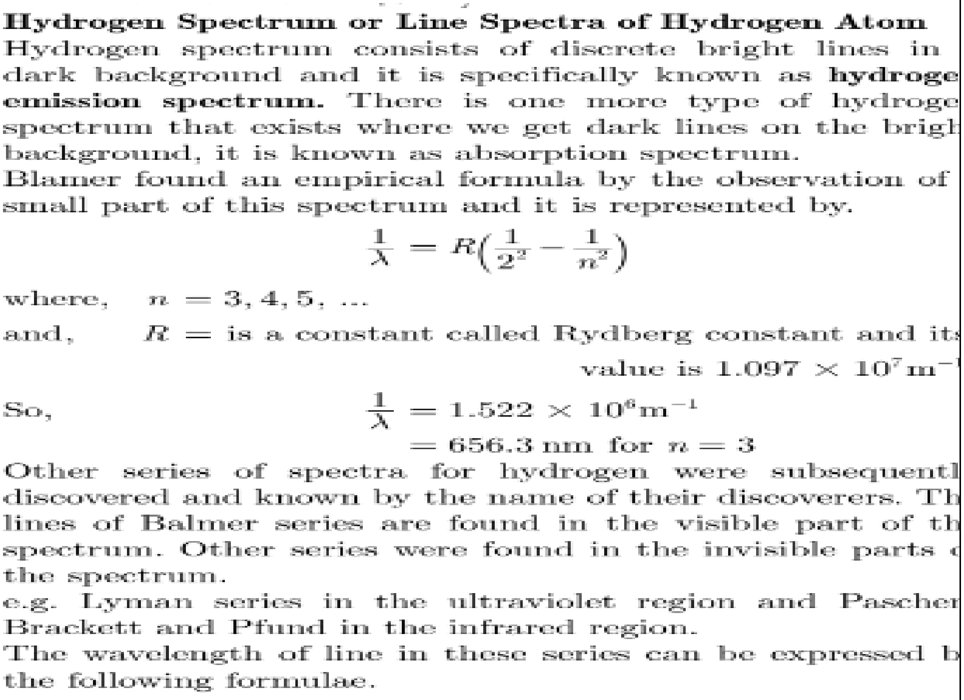
OR

	 Charge, $q = 5\ \mu C = 5 \times 10^{-6}$ C Side of the hexagon, l = AB = BC = CD = DE = EF = FA = 10 cm Distance of each vertex from centre O, d = 10 cm Electric potential at point O, $V = \frac{6 \times q}{4\pi \epsilon_0 d}$ Where, ϵ_0 = Permittivity of free space $\frac{1}{4\pi \epsilon_0} = 9 \times 10^9 \text{ N C}^{-2} \text{ m}^{-2}$ $\therefore V = \frac{6 \times 9 \times 10^9 \times 5 \times 10^{-6}}{0.1}$ $= 2.7 \times 10^6$ V Therefore, the potential at the centre of the hexagon is 2.7 × 10^6 V.
Q.32	Let us consider a uniform magnetic field of induction B acting along the Z-axis. A particle of charge q and mass m moves in XY plane. At a point P, the velocity of the particle is v (figure). The magnetic lorentz force on the particle is →F=q(→v×→B) Hence F acts along PO perpendicular to the plane containing →v and →B. Since the force acts perpendicular to its velocity, the force does not do any work. So, the magnitude of the velocity remains constant and only its direction changes. The force F acting towards the point O acts as the centripetal force and makes the particle to move along a circular path. At points Q and R, the particle experiences force along QO and RO respectively. Since →v and →B are at right angles to each other q(→v×→B)=Bqvsin90o=Bqv This magnetic lorentz force provides the necessary centripetal force. Bqv=mv2r r=mvBq ....(1) It is evident from this equation, that the radius of the circular path is proportional to (i) mass of the particle and (ii) velocity of the particle. From equation (1), vr=Bqm ω=Bqm ....(2) This equation gives the angular frequency of the particle inside the magnetic field. Period of rotation of the particle, T=2πω

	$T=2\pi mBq$ ....(3) From equations (2) and (3), it is evident that the angular frequency and period of rotation of the particle in the magnetic field do not depend upon (i) the velocity of the particle and (ii) radius of the circular path.  **OR** (a) According to Ampere's circuital law, the line integral of magnetic field induction along a closed curve is equal to the total current passing through the surface enclosed in the closed curve times the permeability of the medium. $\oint \rightarrow B.\rightarrow dl=\mu oI$ enclosed Applying ampere's law for the given toroid, $B(2\pi r)=\mu oNI$ But, $N=2\pi rn$ $B=\mu onI$ (b) The observer sees south pole as shown in the attached figure. Magnetic moment due to a loop is given by: $m=iA$ For N turns, $i=NI$ $m=NIA$
Q.33	1. An atom consists of a small and massive central core, called nucleus around which planetary electrons are revolving. The centripetal force required for their rotation is provided by the electrostatic attraction between the electrons and the nucleus. While revolving in the permissible orbits, an electron does not radiate energy. These non-radiating orbits are called ‘stationary orbits'. 2. According to the second postulate the electrons are permitted to revolve only in those orbits in which the angular momentum of an electron is an integral multiple of $\frac{n}{2\pi}$ h being Planck's constant. 3. An atom can emit or absorb radiation in the form of discrete energy

photons only when an electron jumps from a higher to a lower orbit or from a lower to a higher orbit, respectively. If and are the energies associated with these permitted orbits. Then the frequency v of the emitted of absorbed were radiation is given by,

$$En_2 - En_1 = hv = \frac{hc}{\lambda}$$



Hydrogen Spectrum or Line Spectra of Hydrogen Atom

Hydrogen spectrum consists of discrete bright lines in dark background and it is specifically known as **hydroge emission spectrum.** There is one more type of hydroge spectrum that exists where we get dark lines on the brigh background, it is known as absorption spectrum.

Blamer found an empirical formula by the observation of small part of this spectrum and it is represented by.

$$\frac{1}{\lambda} = R\left(\frac{1}{2^2} - \frac{1}{n^2}\right)$$

where, $n = 3, 4, 5, \ldots$

and, $R =$ is a constant called Rydberg constant and its value is $1.097 \times 10^7 \mathrm{m}^{-}$

So, $$\frac{1}{\lambda} = 1.522 \times 10^6 \mathrm{m}^{-1}$$ $$= 656.3\,\mathrm{nm} \text{ for } n = 3$$

Other series of spectra for hydrogen were subsequentl discovered and known by the name of their discoverers. Th lines of Balmer series are found in the visible part of th spectrum. Other series were found in the invisible parts o the spectrum.

e.g. Lyman series in the ultraviolet region and Pascher Brackett and Pfund in the infrared region.

The wavelength of line in these series can be expressed b the following formulae.

OR

For Lyman Series :

$$\frac{1}{\lambda} = R\left(\frac{1}{1^2} - \frac{1}{n^2}\right)$$

where, $n = 2, 3, 4, \ldots$

For Balmer Series :

$$\frac{1}{\lambda} = R\left(\frac{1}{2^2} - \frac{1}{n^2}\right)$$

where, $n = 3, 4, 5, \ldots$

For Paschen Series :

$$\frac{1}{\lambda} = R\left(\frac{1}{3^2} - \frac{1}{n^2}\right),$$

where, $n = 4, 5, 6, \ldots$

For Brackett Series :

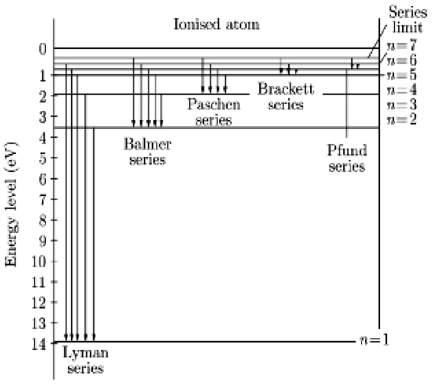
$$\frac{1}{\lambda} = R\left(\frac{1}{4^2} - \frac{1}{n^2}\right),$$

where, $n = 5, 6, 7, \ldots.$

For Pfund Series :

$$\frac{1}{\lambda} = R\left(\frac{1}{5^2} - \frac{1}{n^2}\right)$$

where, $n = 6, 7, 8, \ldots$



The line with the longer wavelength of the Balmer series is called H_α.

$$\frac{1}{\lambda} = R\left(\frac{1}{2^2} - \frac{1}{n^2}\right)$$

where, λ = wavelength

$R = 1.097 \times 10^7 \mathrm{m}^{-1}$ (Rydberg constant)

When the electron jumps from the orbit with $n = 3$ to $n = 2$

We have,

$$\frac{1}{\lambda} = R\left(\frac{1}{2^2} - \frac{1}{3^2}\right)$$

$$\frac{1}{\lambda} = \frac{5}{36} R$$

The frequency of photon emitted is given by,

$$v = \frac{c}{\lambda} = c \times \frac{5}{36} R$$

$$= 3 \times 10^8 \times \frac{5}{36} \times 1.097 \times 10^7 \mathrm{Hz}$$

$$= 4.57 \times 10^{14} \mathrm{Hz}$$

****

तत् त्वं पूषन् अपावृणु

केन्द्रीय विद्यालय संगठन

KENDRIYA VIDYALAYA SANGATHAN
18, Institutional Area
Shaheed Jeet Singh Marg
New Delhi – 110016 (India)
Phone : +91-11-26858570